

MT90520 8-Port Primary Rate Circuit Emulation AAL1 SAR Data Sheet

Features

- AAL1 Segmentation and Reassembly device compliant with Circuit Emulation Services (CES) standard (af-vtoa-0078.000)
- Supports both Unstructured and Structured Circuit Emulation of 8 independent DS1/E1/ST-BUS interfaces
- Supports AAL1 trunking, with up to 128 TDM channels per VC (af-vtoa-0089.001)
- Supports CAS transmission and reception in all structured modes of operation
- Supports simultaneous processing of up to 256 bidirectional Virtual Circuits
- Supports mixed DS1/E1 operation
- Supports mixed Unstructured and Structured CES operation
- Fully flexible DS0 assignment
- Complete clock recovery solution provided onchip: Synchronous, Adaptive, or Synchronous Residual Time Stamp (SRTS) via 8 independent PLLs

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Ordering Information MT90520AG 456 Pin Plastic BGA -40 to +85°C

ISSUE 1

- Dual-mode (ATM-end or PHY-end) UTOPIA port operates in Level 1 or Level 2 mode for connection to external PHY or ATM devices with UTOPIA clock rate up to 52 MHz
- TDM bus provides 8 bidirectional serial streams at 1.544, 2.048, or 4.096 MHz - compatible with Generic (1.544 Mbps or 2.048 Mbps) and ST-BUS (2.048 Mbps) interfaces
- Supports master and slave TDM backplane bus clock operation
- Supports TDM and UTOPIA loopback functions
- 16-bit microprocessor port, configurable to Motorola or Intel timing
- Master clock rate of 66.0 MHz

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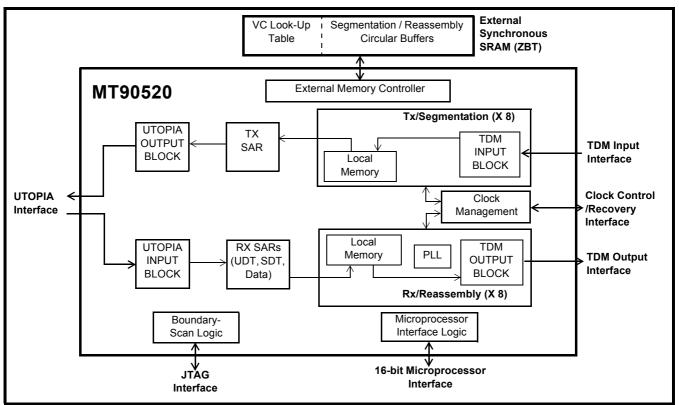


Figure A - MT90520 Block Diagram

Applications

- B-ISDN (Broadband ISDN) systems requiring flexible N x 64kbps transport
- Systems requiring af-vtoa-0078.000 (ATM Forum CES v2.0) "DS1 or E1 Nx64 Basic Service", "DS1 or E1 Nx64 Service with CAS", or "DS1 or E1 Unstructured Service" flexible CES allows one-board solution to support multiple CES modes
- Systems requiring af-vtoa-0089.001 (ATM Forum ATM Trunking Using AAL1 for Narrowband Services) transport of up to 128 channels per VC
- DSLAM
- IAD
- Voice gateway
- NGDLC
- ATM Public Network access for PBX or CO

Description

The MT90520 8-Port Primary Rate Circuit Emulation AAL1 SAR allows primary rate TDM circuits to be carried over ATM networks using Circuit Emulation Services. Up to 256 bidirectional ATM VC connections can be simultaneously processed by the MT90520 CES AAL1 SAR device.

The MT90520 supports several modes of Circuit Emulation Services for DS1 and E1 rates. These include Unstructured CES and Structured CES with and without Channel Associated Signalling (CAS).

On the TDM bus side, the MT90520 interfaces with 8 primary rate TDM ports operating at 1.544 Mbps or 2.048 Mbps. The configurable TDM ports interface directly with DS1 or E1 framers for Nx64 Structured operation, or with DS1 or E1 LIUs in Unstructured mode.

On the ATM interface side, the MT90520 device meets the ATM Forum standard for UTOPIA Bus Level 2. The MT90520 is capable of operating as a UTOPIA "master" (ATM-end), "slave" (PHY-end), or "multi-PHY slave" (PHY-end). The UTOPIA port can operate in 8-bit or 16-bit mode, with a clock rate up to 52 MHz.

Each of the eight ports of the device contains a PLL, allowing independent timing of each TDM port. Each PLL supports four modes of clock recovery: SRTS, Adaptive, Synchronous (from the Physical layer), or from the TDM line clock. Although a complete clock recovery solution is provided internally, an optional external PLL or external clock source is also supported.

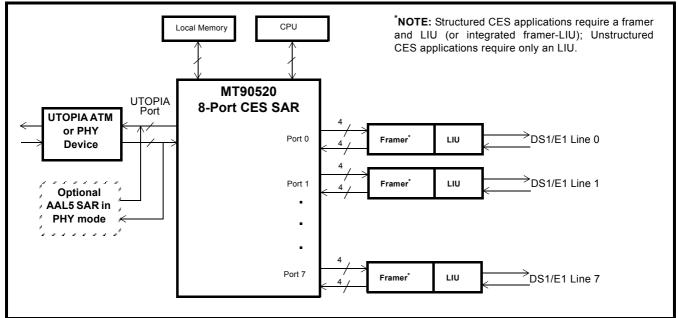




Table of Contents

Table of Contents							
Lis	List of Figures						
Lis	List of Tables						
	I. Introduction						
••	1.1 Functional Overview						
~							
2.	Features						
	2.1 Key Functionality.						
	2.2 Microprocessor Interface						
	2.3 External Memory Interface						
	2.4 TDM Interface						
	2.5 UTOPIA Interface						
	2.6 Segmentation and Reassembly Modules						
	2.7 Clock Management						
	2.8 Testing Modes						
	2.9 Miscellaneous						
	2.10 Interrupts						
	2.10.1 Module Level Service Requests						
	2.10.1.1 External Memory Interface Module						
	2.10.1.2 TDM Module						
	2.10.1.3 UTOPIA Module						
	2.10.1.4 TX_SAR Module						
	2.10.1.5 UDT RX_SAR Module						
	2.10.1.6 SDT RX_SAR Module						
	2.10.1.7 Data RX_SAR Module						
	2.10.1.8 UDT Reassembly-Side Timeout Module						
	2.11 Statistics						
	2.11.1 TDM Module						
	2.11.2 UTOPIA Module						
	2.11.3 TX_SAR Module						
	2.11.4 UDT RX_SAR Module						
	2.11.5 SDT RX_SAR Module	.17					
3.	Pin Descriptions	19					
	3.1 Functional Pin Descriptions	.19					
	3.2 Physical Pin Description						
	3.2.1 Pin Description by Ball Pin Number						
	3.2.2 Pin Diagram						
	3.2.3 Package Specifications						
4	Module Functional Descriptions						
ч.	4.1 Microprocessor Interface						
	4.1.1 Global Reset						
	4.1.2 CPU Interrupts.						
	4.2 External Memory Interface						
	4.3 TDM Interface Module						
	4.3.1 Overview						
	4.3.1.1 Segmentation Direction						
	4.3.1.2 Reassembly Direction						
	4.3.2 Functional Description						
	4.3.2.1 Segmentation Process						
	4.3.2.1.1 UDT Mode						
	4.3.2.1.2 SDT Mode						
	4.3.2.2 Reassembly Process						
	4.3.2.2 Reassembly Process						
	4.3.2.2.1 ODT format						
	T.J.Z.Z.Z JUT IUIIIIAL	40					

4.3.2.3 TDM Loopback	. 46
4.3.2.3.1 TDM Low-Latency Loopback.	. 46
4.3.2.3.2 TDM Circular Buffer Loopback (SDT Mode)	. 46
4.4 UTOPIA Interface Module	. 48
4.4.1 Functional Description	. 49
4.4.1.1 Segmentation Direction.	. 49
4.4.1.1.1 TX UTOPIA Interface.	. 49
4.4.1.1.2 TX UTOPIA FIFO	. 50
4.4.1.1.3 TX Parity	. 50
4.4.1.2 Reassembly Direction	. 50
4.4.1.2.1 RX UTOPIA Interface	. 50
4.4.1.2.2 OAM & VPI/VCI Filter	. 50
4.4.1.2.3 RX UTOPIA FIFO	. 52
4.4.1.2.4 UDT VCI/VPI Comparison and Look-up Table	. 52
4.4.1.2.5 RX Parity	. 54
4.5 TX_SAR Module	. 56
4.5.1 ATM Overview	. 56
4.5.2 UDT Mode of Operation	. 56
4.5.2.1 Control Structure Configuration.	. 57
4.5.2.2 Operation	. 57
4.5.3 SDT Mode of Operation	. 58
4.5.3.1 Control Structure Configuration.	. 58
4.5.3.1.1 SDT Segmentation Control Structures	. 58
4.5.3.1.2 SDT Segmentation Pointer Tables	. 60
4.5.3.2 Operation	. 61
4.5.4 Data TX_SAR Module	. 63
4.5.4.1 Mode of Operation	. 63
4.5.4.2 Error Handling	. 63
4.6 RX_SAR Modules	
4.6.1 UDT RX_SAR and SDT RX_SAR Modules	
4.6.1.1 Data Flow and Processing Path Overview	
4.6.1.2 Reassembly Control Structures	
4.6.1.2.1 UDT Reassembly Control Structures	
4.6.1.2.2 SDT Reassembly Control Structures.	
4.6.1.3 Sequence Number Checking (Correction/Detection State Machine)	
4.6.1.4 Sequence Number Checking (Fast SN Processing State Machine)	
4.6.1.5 Received Cell Processing	
4.6.1.5.1 UDT Mode of Operation	
4.6.1.5.2 SDT Mode of Operation.	
4.6.1.5.3 Complete Reassembly Data Flow Overview	
4.6.1.6 Clock Recovery Operations	
4.6.1.6.1 Digital Phaseword Generation for Adaptive Clock Recovery	
4.6.1.6.2 RTS Reception for SRTS Clock Recovery	
4.6.2 Timeout Circuitry	
4.6.2.1 Cut VC Monitoring	
4.6.2.2 Late Cell Insertion	
4.6.2.3 Underrun Detection	
4.6.3 Data RX_SAR Module	
4.6.3.1 Mode of Operation	
4.6.3.2 Error Handling.	
4.7 Clock Management Module	
4.7.1 Overview.	
4.7.1.1 Clock Control.	
4.7.1.2 Clock Recovery.	
4.7.2 Functional Description	
4.7.2.1 Interface to TDM Sub-Module.	
4.7.2.1.1 Operation of SDT/UDT Interface	. 92

	4.7.2.1.2 Operation in TDM Backplane Mode	93
	4.7.2.1.3 Common Clock Source Generation	
	4.7.2.2 Synchronous Clocking Circuit	
	4.7.2.2.1 Synchronous Clock #1 (Internal Digital PLL)	
	4.7.2.3 Network Clock Divider Circuit	
	4.7.2.4 Transmit SRTS Circuit Sub-module.	
	4.7.2.4.1 UDT Operation	
	4.7.2.4.2 SDT Operation	
	4.7.2.5 Receive SRTS Circuit Sub-Module	
	4.7.2.6 Adaptive Clock Recovery Circuit	
	4.7.2.7 Internal Digital PLL Sub-Module	
	4.7.2.7.1 Architecture	
	4.7.2.7.3 Sub-modes of Operation (PLL_MODE_SEL bits)	
	4.7.2.7.4 Locking Range	
	4.8 Test Interface	
	4.8.1 Test Access Port	. 107
	4.8.2 JTAG ID	
	4.8.3 Boundary Scan Instructions	
	4.8.4 BSDL	
5.	Memory	
	5.1 Internal Memory Map	
•	•	
6.	Registers	
	6.2 Register Description	
	6.2.1 Microprocessor Interface Module	
	6.2.2 TX_SAR Module	
	6.2.3 UDT RX_SAR Module	
	6.2.4 Data RX_SAR Module.	
	6.2.5 SDT RX_SAR Module.	
	6.2.6 Reassembly-Side Timeout Module	
	6.2.8 Clock Management Module.	
	6.2.9 TDM Interface Module	
	6.2.10 External Memory Interface Module	
7.	Electrical Specification	. 148
	7.1 DC Characteristics	
	7.2 AC Characteristics	
	7.2.1 CPU Interface	
	7.2.2 External Memory Interface	
	7.2.3 TDM Interface	
	7.2.4.1 UTOPIA Level 1	
	7.2.4.2 UTOPIA Level 2.	
8.	Applications	. 169
	8.1 Board-Level Applications	
	8.1.1 Power-Up and Power-Down Sequence	. 169
	8.1.2 External Memory Interface Connections	
	8.1.3 UTOPIA Interface Connections	
_	8.2 Segmentation and Reassembly Latency	
	erence Documents	
Glo	ssary	. 177

List of Figures

Figure 1 -	MT90520 Block Diagram	
Figure 2 -	PCB Pad Diagram for 35mm x 35mm PBGA (JEDEC MO-151)	32
Figure 3 -	Aerial View of Package Specifications	33
Figure 4 -	Side View of Package Specification	34
Figure 5 -	Sample Interrupt Generation (for Data RX_SAR Module)	37
Figure 6 -	Memory Read Pipeline Length	
Figure 7 -	Memory Write Pipeline Length	
Figure 8 -	Data Flow Through the TDM Module (1 port)	40
Figure 9 -	Per-Port SDT Segmentation Circular Buffers	42
Figure 10 -	Per-Channel SDT Reassembly Circular Buffer	44
Figure 11 -	TDM SDT Reassembly Control Structure	45
Figure 12 -	UTOPIA Reference Configurations	48
Figure 13 -	UTOPIA Block Diagram	49
Figure 14 -	OAM & VPI/VCI Filter Flowchart	51
Figure 15 -	Look-up Table Format	53
Figure 16 -	Overview of the UDT VCI/VPI Comparison and Look-up Table Filtering Process	55
Figure 17 -	AAL1 ATM Cell Formats	56
Figure 18 -	Segmentation Control Structure - UDT Format	57
Figure 19 -	Overview of CBR Data Segmentation Process (UDT Mode)	58
Figure 20 -	Segmentation Control Structure - SDT Format	
Figure 21 -	SDT Segmentation Pointer Table for Port p	61
Figure 22 -	Overview of CBR Data Segmentation Process (SDT Mode)	62
Figure 23 -	TX_SAR Cell Template - Data Cell (Non-CBR) Mode	
Figure 24 -	High-Level Overview of the Functionality of the RX_SAR Module	
Figure 25 -	Reassembly Control Structure - UDT Format	
Figure 26 -	Reassembly Control Structure - SDT Format	69
Figure 27 -	Per-Channel SDT Reassembly Circular Buffer	81
Figure 28 -	Overview of CBR Data Reassembly Process (UDT Mode)	84
Figure 29 -	Overview of CBR Data Reassembly Process (SDT Mode)	84
Figure 30 -	Functions of the Clock Management Module	
Figure 31 -	High-Level Block Diagram of the Clock Management Module	
Figure 32 -	Interface to TDM Bus Module and Common Clock Generation Circuitry	
Figure 33 -	Synchronous Source Multiplied to TDM Bus Rate by Internal PLL	95
Figure 34 -	Synchronous TDM-Rate Clock Generated by External PLL	96
Figure 35 -	Synchronous TDM Rate Clock Generated by External PLL User-Selectable References	97
Figure 36 -	Network Clock Dividers	98
Figure 37 -	Transmit SRTS Sub-module	99
Figure 38 -	Gapping Circuitry for SDT Operation	100
Figure 39 -	Receive SRTS Sub-module	
Figure 40 -	Adaptive Clock Recovery Sub-module	103
Figure 41 -	Block Diagram of the Digital PLL Module	104
Figure 42 -	A Typical JTAG Test Connection	107
Figure 43 -	Maximum External Memory Allocation - Example	112
Figure 44 -	Minimum External Memory Allocation - Example	113
Figure 45 -	Intel CPU Interface Timing - Read Access	151
Figure 46 -	Intel CPU Interface Timing - Write Access	
Figure 47 -	Motorola CPU Interface Timing - Read Access	
Figure 48 -	Motorola CPU Interface Timing - Write Access	
Figure 49 -	External Memory Interface Timing - Read Cycle	
Figure 50 -	External Memory Interface Timing - Write Cycle	156

Figure 51 -	Nominal UDT Mode Timing Diagram - DS1 (1.544 Mbps) and E1 (2.048 Mbps)	. 157
Figure 52 -	Nominal SDT Mode Timing Diagram - Generic and ST-BUS DS1 or E1 (2.048 Mbps)	. 157
Figure 53 -	Nominal SDT Mode Timing Diagram - Generic DS1 (1.544 Mbps)	. 157
Figure 54 -	TDM Bus Inputs - Generic Bus Sampling	. 158
Figure 55 -	TDM Bus Inputs - ST-BUS Sampling	. 159
Figure 56 -	TDM Bus Output Clocking Parameters - Generic	. 161
Figure 57 -	TDM Bus Output Clocking Parameters - ST-BUS	. 161
Figure 58 -	TDM Bus Outputs - Serial Output Timing	. 161
Figure 59 -	UTOPIA Level 1 Interface Timing - ATM Mode - Incoming Data (UTOPIA RX Bus)	. 162
Figure 60 -	UTOPIA Level 1 Interface Timing - ATM Mode - Outgoing Data (UTOPIA TX Bus)	. 163
Figure 61 -	UTOPIA Level 1 Interface Timing - PHY Mode - Incoming Data (UTOPIA TX Bus)	. 164
Figure 62 -	UTOPIA Level 1 Interface Timing - PHY Mode - Outgoing Data (UTOPIA RX Bus)	. 165
Figure 63 -	UTOPIA Level 2 Interface Timing - PHY Mode - Incoming Data (UTOPIA TX Bus)	. 166
Figure 64 -	UTOPIA Level 2 Interface Timing - PHY Mode - Outgoing Data (UTOPIA RX Bus)	. 168
Figure 65 -	External Memory Interface	. 169
Figure 66 -	ATM Mode: External UTOPIA Pin Connections	. 171
Figure 67 -	PHY Mode: External UTOPIA Pin Connections	. 172

List of Tables

Table 1 -	Microprocessor Interface Pins	19
Table 2 -	External Memory Interface Pins	20
Table 3 -	TDM Port Pins	21
Table 4 -	UTOPIA Bus Pins	23
Table 5 -	Clock Management Pins	25
Table 6 -	Master Clock, Test, and Power Pins	
Table 7 -	Pinout Summary	27
Table 8 -	Pinout by Ball Pin Number	
Table 9 -	Package Dimensions	34
Table 10 -	Possible Memory Configurations	
Table 11 -	Formation of the Reassembly Circular Buffer Base Address	45
Table 12 -	Fields within the SDT Reassembly Control Structure	70
Table 13 -	Operation of Correction/Detection State Machine in Correction State	71
Table 14 -	Operation of Correction/Detection State Machine in Detection State	71
Table 15 -	Operation of UDT Fast Sequence Number Processing State Machine	
Table 16 -	Examples of Operation of the UDT Fast Sequence Number Processing State Machine	
Table 17 -	Operation of SDT Fast Sequence Number Processing State Machine	75
Table 18 -	Examples of Operation of SDT Fast Sequence Number Processing State Machine	
Table 19 -	Formation of SDT Reassembly Circular Buffer Base Addresses to External Memory	
Table 20 -	Sample Gapping Circuitry Calculation (N = 18)	
Table 21 -	Center Frequency and Accuracy	
Table 22 -	Relevant Specifications	
Table 23 -	Minimum Input Wander and Jitter Tolerance	
Table 24 -	Maximum Allowed Intrinsic Output Jitter	
Table 25 -	Internal Memory Map	
Table 26 -	Register Summary	
Table 27 -	Chip Wide Reset Register	
Table 28 -	Main Status Register	
Table 29 -	Low Address Word Indirection Register	
Table 30 -	High Address Indirection Command Register	
Table 31 -	Indirection Data Register	
Table 32 -	Main Interrupt Enable Register	
Table 33 -	MT90520 Revision Register	
Table 34 -	TX_SAR Pointer Table Base Register (one per port)	
Table 35 -	Data TX_SAR Configuration Register	123
Table 36 -	Data TX_SAR Write Pointer Register	
Table 37 -	Data TX_SAR Read Pointer Register	
Table 38 -	Data TX_SAR Control Register	
Table 39 -	Data Cell Generation Time Out Register	
Table 40 -	Data TX_SAR Status Register	
Table 41 -	TX_SAR Master Enable Register	
Table 42 -	UDT Reassembly Control Register	
Table 43 -	UDT Reassembly Service Enable Register	
Table 44 -	UDT Reassembly Status Register	
Table 45 -	UDT Reassembly Cell Counter Register	
Table 46 -	Data RX_SAR Control Register	
Table 40 -	Data RX_SAR Control Register	
Table 47 -		
Table 46 -	Data RX_SAR Configuration Register	
	Data RX_SAR Write Pointer Register	
Table 50 -	Data RX_SAR Read Pointer Register	129

Data Sheet

MT90520

Table 51 -	Data RX_SAR Cell Counter Register	129
Table 52 -	SDT Reassembly Control Register	
Table 53 -	SDT Reassembly Service Enable Register	
Table 54 -	SDT Reassembly Status Register	
Table 55 -	SDT Reassembly Cell Counter Status Register	
Table 56 -	SDT Reassembly Cell Counter Register	
Table 57 -	MIB Timeout Configuration Register	
Table 58 -	MIB Timeout Status Register	
Table 59 -	Timeout Configuration Register (one per port)	
Table 60 -	UTOPIA Configuration Register	
Table 61 -	UTOPIA Number of Concatenated Bits Register	
Table 62 -	LUT Base Address Register	
Table 63 -	VC Match Register	
Table 64 -	VC Match Enable Register	
Table 65 -	VP Match Register	
Table 66 -	VP Match Enable Register	
Table 67 -	UTOPIA Parity Mismatches Register	
Table 68 -	UTOPIA FIFO Status Register	
Table 69 -	UTOPIA Status Register	
Table 70 -	UTOPIA Service Enable Register	
Table 71 -	UTOPIA Incoming Cell Counter	
Table 72 -	UDT VCI for Port p (one per port)	
Table 73 -	UDT VPI for Port p (one per port)	
Table 74 -	Clock Management Configuration Register	
Table 75 -	External PLL Clock Source Register	
Table 76 -	Clocking Configuration Register (one per port)	
Table 77 -	Clocking Phase Accumulator Register (one per port)	
Table 78 -	Clocking DCO Difference Register (one per port)	
Table 79 -	SRTS FIFO Status Register (one per port)	
Table 80 -	PLL Enable Register (one per port)	
Table 81 -	Main TDM Control Register 1	
Table 82 -	Main TDM Control Register 2	
Table 83 -	TDM Control Register 1 (one per port)	
Table 84 -	TDM Control Register 2 (one per port)	
Table 85 -	TDM Control Register 2 (one per port)	
Table 86 -	TDM Control Register 4 (one per port)	
Table 87 -	TDM Control Register 5 (one per port)	
Table 88 -	TDM Control Register 6 (one per port)	
Table 89 -	Memory Arbiter Configuration Register	
Table 90 -	Parity Error Status Register	
Table 90 -	Absolute Maximum Ratings	
Table 92 -	Recommended Operating Conditions	
Table 92 -	DC Characteristics	
Table 93 -	MCLK - Master Clock Input Parameters	
	·	
Table 95 - Table 96 -	PHY_CLK - Clock Input Parameters Intel Microprocessor Interface Timing - Read Cycle Parameters	
Table 96 - Table 97 -		
	Intel Microprocessor Interface Timing - Write Cycle Parameters	
Table 98 -	Motorola Microprocessor Interface Timing - Read Cycle Parameters	
Table 99 -	Motorola Microprocessor Interface Timing - Write Cycle Parameters	
Table 100 -	External Memory Interface Timing - Read Cycle Parameters	
Table 101 -	External Memory Interface Timing - Write Cycle Parameters	
Table 102 -	TDM Bus Input Clock Parameters	158

Table 103 -	TDM Bus Input Data Parameters	158
Table 104 -	TDM Bus Output Clock Parameters	160
Table 105 -	TDM Bus Data Output Parameters	160
Table 106 -	UTOPIA Level 1 Interface Timing - ATM mode - Incoming Data (UTOPIA RX Bus)	162
Table 107 -	UTOPIA Level 1 Interface Timing - ATM mode - Outgoing Data (UTOPIA TX Bus)	162
Table 108 -	UTOPIA Level 1 Interface Timing - PHY mode - Incoming Data (UTOPIA TX Bus)	163
Table 109 -	UTOPIA Level 1 Interface Timing - PHY mode - Outgoing Data (UTOPIA RX Bus)	165
Table 110 -	UTOPIA Level 2 Interface Timing - PHY mode - Incoming Data (UTOPIA TX Bus)	166
Table 111 -	UTOPIA Level 2 Interface Timing - PHY mode - Outgoing Data (UTOPIA RX Bus)	167
Table 112 -	MT90520 UTOPIA Signal Directions	170
TABLE 113.	Segmentation Latency	173
TABLE 114.	Reassembly Latency	174
TABLE 115.	End-to-End Latency	175

1. Introduction

1.1 Functional Overview

The MT90520 8-Port Primary Rate Circuit Emulation AAL1 SAR (Segmentation and Reassembly) device is intended to carry eight primary rate TDM (Time Division Multiplexed) circuits (DS1 or E1) over an ATM (Asynchronous Transfer Mode) network using Circuit Emulation Services (CES). At its interface to the TDM network, the MT90520 can be connected directly to a wide variety of industry-standard framers and LIUs (line interface units), or to a 2.048 Mbps ST-BUS TDM backplane. At its interface to the ATM network, the MT90520 supports a wide selection of UTOPIA-compliant Physical layer devices, and customer-specific ASICs which meet the UTOPIA (Level 1 or Level 2) specification.

The MT90520 provides several modes of Circuit Emulation Services in one device. The MT90520 implements CES for DS1 and E1 rates, as standardized in the ATM Forum CES standard (af-vtoa-0078.000 Version 2). The MT90520 supports both Unstructured and Structured circuit emulation of 8 independent TDM interfaces carrying DS1 or E1 traffic. In Unstructured CES mode, 8 VCCs (Virtual Circuit Connections) are supported. In Structured CES mode, flexible Nx64 kbps VCC assignment is supported, providing options ranging from a maximum of 256 VCCs carrying 64 kbps each (N = 1), to 8 VCCs carrying N = 32, to a smaller number of VCCs carrying up to N = 128. The MT90520 supports Structured CES with, or without, CAS (Channel Associated Signalling). MT90520 Management functions and statistics in accordance with the ATM Forum's CES MIB (Management Information Base) are supported.

On the TDM side, the MT90520 features eight primary rate TDM ports operating at 1.544 Mbps (Generic) or 2.048 Mbps (Generic or ST-BUS). The configurable TDM ports interface directly with DS1 or E1 framers for Nx64 Structured operation, as well as with DS1 or E1 LIUs in Unstructured mode for reduced delay in the segmentation (ATM transmit) direction. The TDM interfaces are capable of operating with the line-rate bit clocks (1.544 MHz or 2.048 MHz), or with framed bus clocks at 1.544 MHz, 2.048 MHz or 4.096 MHz.

Each of the eight TDM ports contains a PLL (Phase Locked Loop), allowing independent timing of each TDM port. Alternatively in SDT mode, the MT90520 can be operated in backplane mode with a single timing source. Each independent PLL supports four modes of clock recovery: from SRTS time-stamps, from the cell-stream through the Adaptive Clock Method, from the Physical layer (synchronous method), or from the TDM interface line-rate. Although clock recovery is fully supported internally, an optional external PLL or clock source is also supported.

On the ATM interface side, the MT90520 device meets the ATM Forum standard UTOPIA Bus Level 2. The MT90520 is capable of operating as a UTOPIA "master" (ATM-end) or "slave" (PHY-end). ATM-end operation supports connection to a range of standard physical layer transceivers. PHY-end operation allows the MT90520 to be used in systems where pre-existing ASICs are available as "master" and require a "slave" device for interconnection. In PHY-end mode, the MT90520 is capable of Multi-PHY operation and has address inputs for this purpose. The UTOPIA port can operate in 8-bit or 16-bit mode, with a clock rate up to 52 MHz.

The MT90520 features a 16-bit microprocessor interface, capable of operating in Intel or Motorola mode, that is used to configure the device and monitor the management functions.

External memory (synchronous ZBT SRAM) is used in Structured CES operation to provide circular buffers in the segmentation direction and to provide CDV buffering in the reassembly direction. In addition, if the application's non-CBR data throughput (signalling or other) is low, the external memory can be used to provide a Receive Data Cell Buffer and a Transmit Data Cell Buffer for non-CBR data cells to be read or written, for processing by the external CPU. Unstructured CES operation requires no external memory (except where non-CBR data cell buffers are desired).

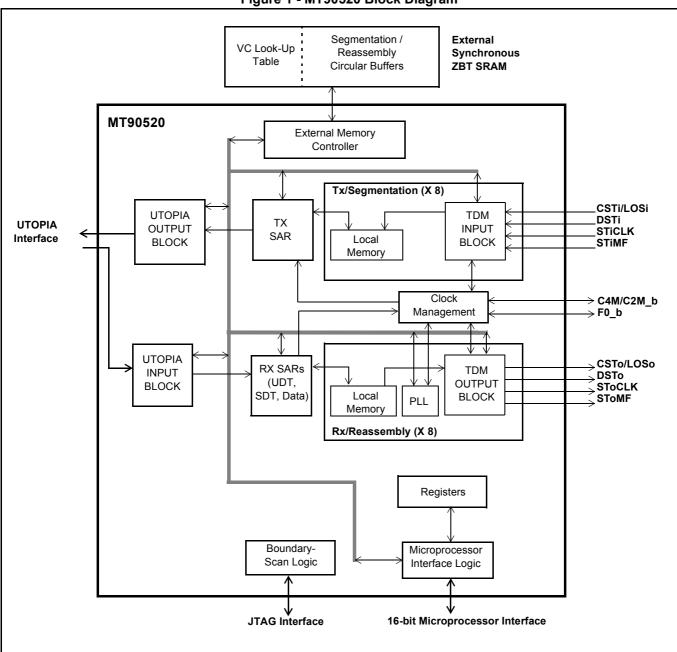


Figure 1 - MT90520 Block Diagram

2. Features

2.1 Key Functionality

- High-capacity AAL1 CES SAR device with 8 primary rate TDM ports operating at DS1 or E1 rates.
- Supports major modes of Circuit Emulation Services (CES) for DS1 and E1 as per af-vtoa-0078.000:
 - Logical Nx64 Structured Service, using 2.048 Mbps TDM bus
 - DS1 Nx64 Basic Service
 - DS1 Nx64 Service with CAS
 - E1 Nx64 Basic Service
 - E1 Nx64 Service with CAS
 - DS1 Unstructured Service
 - E1 Unstructured Service.
- Supports AAL1 Trunking as per af-vtoa-0089.000:
 - Up to 128 TDM channels can be carried per VCC (up to 256 TDM channels per device).
- Compliant with ITU-T Rec. I.363.1.
- Supports mixed DS1/E1 operation.
- Supports mixed UDT/SDT operation.
- Total clock recovery solution integrated on-chip.
- Supports non-CBR data cells and OAM cells destined for microprocessor with Transmit and Receive Data Cell Buffers.

2.2 Microprocessor Interface

- 16-bit microprocessor port, configurable to Motorola or Intel timing.
- Indirect reads and writes possible to internal and external memory blocks.
- Programmable interrupts for control and statistics.
- Allows access to internal registers and memory for initialization, control, and statistics.
- Allows access to external RAM for initialization, control, and observation.

2.3 External Memory Interface

- Supports common, commercially-available, no-latency flow-through and pipelined synchronous SRAM (ZBT, NoBL, NtRAM).
- Supports common SSRAM memory sizes 128K x 16, 256K x16, 512K x 16 and 1M x 16; 128K x 18, 256K x 18, 512K x 18 and 1M x 18 (parity is optional).

2.4 TDM Interface

- Flexible TDM port allows operation with a wide selection of framers, LIUs, switches and multiplexers.
- Eight independently-timed, highly configurable, TDM interfaces can operate using:
 - bit-clock rate (Unstructured CES)
 - framed ST-BUS or Generic TDM bus (Structured CES independent mode)
 - common TDM backplane clock using ST-BUS or Generic TDM bus (Structured CES backplane mode).
- Supports up to 256 bidirectional TDM channels.

2.5 UTOPIA Interface

- UTOPIA Level 2 compliant 16-bit or 8-bit bus, capable of running at up to 52 MHz.
 - Accepts data rate of up to 622 Mbps.
 - Supports both "master" (ATM-end) and "slave" (PHY-end) operation.
 - Supports multi-PHY (MPHY) mode when operating as a PHY device.
- Capable of operating in UTOPIA Level 1 mode (8-bit bus running at up to 25 MHz), for connection to older devices.
- Supports up to 256 bidirectional VCCs (Structured Nx64 mode).
- VPI/VCI Match and Match Enable filter prevents excessive look-up table accesses to external memory.
- Cell reception based on look-up table allows flexible VCC assignment for CBR VCCs (allows non-contiguous VCC assignment).
 - Automatically eliminates null cells (i.e., VPI and VCI = 0).
 - Look-up table supports up to 65536 VCC entries.

2.6 Segmentation and Reassembly Modules

- Supports AAL1 Segmentation and Reassembly for Structured and Unstructured CES as specified in af-vtoa-0078.000.
- Supports non-multiframe or multiframe circuit emulation, using AAL1 structure formats as described in af-vtoa-0078.000: Nx64 Basic Service (single frame structure), or DS1 or E1 Nx64 Service with CAS (multiframe structure).
- Supports transmission and reception of up to 128 TDM channels per VCC in accordance with af-vtoa-0089.001 (ATM Trunking using AAL1 for Narrowband Services).
- Supports Unstructured CES and Structured CES simultaneously on different ports.
- Supports 8 bidirectional VCCs, carrying 1.544 Mbps or 2.048 Mbps, in Unstructured CES mode.
- Supports up to 256 bidirectional VCCs, carrying from 1 to 128 DS0 (64 kbps) TDM channels, in Structured CES mode (up to 256 DS0 channels total).
- UDT reassembly works with 8 per-port timing engines for fast processing and low delay variation in Unstructured CES mode. (1 VCC per port, for 8 UDT VCCs total.)
- Low latency in Unstructured CES mode provided by on-chip CDV buffering which does not require any external memory.
- Internal CDV buffers of 2048 bytes for each UDT port.
- Maximum UDT CDV buffering of \pm 4.9 ms in DS1 mode and \pm 3.7 ms in E1 mode.
- External CDV buffers of 1024 bytes for each SDT port.
- Maximum SDT CDV buffering of ±± 63.75 ms (dependent on the Reassembly Circular Buffer size and number of channels per VC).
- Non-CBR data cell transmission and reception for software-implemented SAR function (through non-CBR Data Cell Buffers in external memory).
- Gathers statistical information and provides management statistics for network management through microprocessor interface
 - Per VCC monitoring compliant with ATMF CES specification Version 2.0 MIB.
- Low latency in segmentation and reassembly directions.

2.7 Clock Management

- Individual, per-port, integrated clock-recovery PLL allows for flexible, independent timing on each TDM port.
- Per-port Stratum 4 digital PLL supports several clock recovery modes:
 - Synchronous clocking generates DS1 or E1 clock from network reference (19.44 MHz or 8 kHz)
 - Adaptive clocking recovers clock from received-data buffer fill-level
 - SRTS recovers clock from received RTS (residual time stamp) nibbles
 - Line-rate clocking PLL locks to incoming DS1 or E1 clock and reduces jitter
 - Free-running clocks PLL provides free-running high-accuracy clock for start-up or no-signal conditions (accuracy limited by MCLK accuracy)
 - Direct control of PLL output frequency offset from centre frequency can be configured via CPU.
- Support for optional external PLL such as MT9042 or MT9044: primary & secondary network references and primary & secondary LOS references output to external PLL; TDM_CLOCK input from external PLL.
- Bus clock I/O for operation in backplane mode: C4M/C2M and F0.

2.8 Testing Modes

- Per-port TDM_in to TDM_out low-latency loopback (DSTi input stream to DSTo output stream).
- Per-port TDM_in to TDM_out loopback through the Segmentation and Reassembly Circular Buffers in external memory (SDT mode only).
- Flexible, multi-stream, per-channel TDM circular-buffer loopback possible in SDT Backplane mode.
- Loopback provided from incoming UTOPIA FIFO to outgoing UTOPIA FIFO (with or without filtering by Match and Match Enable registers).

2.9 Miscellaneous

- Master clock (MCLK) rate of 66.0 MHz.
- 2.5 Volt core supply and 3.3 Volt I/O supply (5V tolerant I/Os).
- Power consumption: 1.9 W.
- IEEE 1149 (JTAG) Boundary-Scan Test Access Port.
- 456-pin Plastic BGA.
- -40 to +85C (industrial temperature range).

2.10 Interrupts

- Wide variety of interrupt source bits, allowing for easy monitoring of MT90520 operation.
- Associated enable bits which enable or disable assertion of the service request and, ultimately, the IRQ interrupt pin.

2.10.1 Module Level Service Requests

- 2.10.1.1 External Memory Interface Module
 - External Memory Read Parity Error Alarm.

2.10.1.2 TDM Module

- Per-port Loss of Signal Alarm (UDT mode only).
- Per-port UDT TDM Output Buffer Error Alarm (UDT mode only).
- Per-port SDT TDM Output Buffer Error Alarm (SDT mode only).

- Per-port Simple Underrun Error Alarm (SDT mode only).
- Per-port Permanent Underrun Error Alarm (SDT mode only).

2.10.1.3 UTOPIA Module

- UTOPIA Incoming Cell Counter Rollover.
- Incoming Parity Mismatches Counter Rollover.

2.10.1.4 TX_SAR Module

• Data TX_SAR - Transmit Non-CBR Data Cell Buffer Empty Alarm.

2.10.1.5 UDT RX_SAR Module

- Reassembled Cell Counter Rollover.
- AAL1-byte Header Error (i.e., CRC and/or Parity Error) Counter Rollover.
- AAL1-byte Sequence Error Counter Rollover.
- Lost Cell Counter Rollover.
- Misinserted Cell Counter Rollover.
- Write Underrun Counter Rollover.
- Write Overrun Counter Rollover.
- Late Cell Arrival Counter Rollover.
- Overall UDT Cell Counter Rollover.

2.10.1.6 SDT RX_SAR Module

- Reassembled Cell Counter Rollover.
- AAL1-byte Header Error (i.e., CRC and/or Parity Error) Counter Rollover.
- AAL1-byte Sequence Error Counter Rollover.
- Lost Cell Counter Rollover.
- Misinserted Cell Counter Rollover.
- Pointer Reframe Counter Rollover.
- Pointer Parity Error Counter Rollover.
- Write Underrun Counter Rollover.
- Write Overrun Counter Rollover.
- Pointer Out-of-Range Indicator.
- CAS Changed Status Indicator (only in CAS mode).
- Overall SDT Cell Counter Rollover.

2.10.1.7 Data RX_SAR Module

- Data RX_SAR Cell Arrival Indicator.
- Data RX_SAR Non-CBR Data Cell Buffer Overrun Alarm.
- Data RX_SAR Buffer Half Full Indicator.
- Data Cell Counter Rollover.

2.10.1.8 UDT Reassembly-Side Timeout Module

- Per-port Cut VC Alarm.
- Per-port Late Cell Arrival Alarm.

2.11 Statistics

The MT90520 provides a number of statistics to allow monitoring of the MT90520. These statistics generally parallel the operation of some of the service request source bits.

2.11.1 TDM Module

- Per-port Simple Underrun Channel Indicator status field indicates which channel of the TDM port last experienced a simple underrun (SDT mode only).
- Per-port Permanent Underrun Channel Indicator status field indicates whether or not a particular channel of the TDM port has experienced a permanent underrun (SDT mode only).

2.11.2 UTOPIA Module

- UTOPIA Incoming Cell Counter.
- Incoming Parity Mismatch Counter.

2.11.3 TX_SAR Module

• Per-VC Transmitted Cell Counter.

2.11.4 UDT RX_SAR Module

- Within each VC's UDT Reassembly Control Structure, there is a bit (V = VC Arrival) which is set each time that a cell arrives on the VC. CPU monitoring of this bit can be used to provide per-VC timeout monitoring.
 - As well, there is a late VC status bit and a cut VC status bit for each port (and therefore VC). These bits are set when user-programmable timeout periods are passed without cells arriving on the VCs in question.
- In addition to the counters themselves, if one of the following per-VC counters rolls over and the corresponding service enable bit for the counter is set, a status field indicates the number of the TDM port associated with the last UDT Reassembly Control Structure to generate a serviceable event.
 - Per-VC Reassembled Cell Counter.
 - Per-VC AAL1-byte Header Error Counter.
 - Per-VC AAL1-byte Sequence Error Counter.
 - Per-VC Lost Cell Counter.
 - Per-VC Misinserted Cell Counter.
 - Per-VC Write Underrun Counter.
 - Per-VC Write Overrun Counter.
 - Per-VC Late Cell Arrival Counter.
- Overall UDT Cell Counter.

2.11.5 SDT RX_SAR Module

- Within each VC's SDT Reassembly Control Structure, there is a bit (V = VC Arrival) which is set each time that a cell arrives on the VC. CPU monitoring of this bit can be used to provide per-VC timeout monitoring.
- In addition to the counters themselves, if one of the following per-VC counters rolls over and the corresponding service enable bit for the counter is set, a status field indicates the address in internal memory of the last SDT Reassembly Control Structure to generate a serviceable event.
 - Per-VC Reassembled Cell Counter.
 - Per-VC AAL1-byte Header Error Counter.
 - Per-VC AAL1-byte Sequence Error Counter.
 - Per-VC Lost Cell Counter.
 - Per-VC Misinserted Cell Counter.

- Per-VC Pointer Reframe Counter.
- Per-VC Pointer Parity Error Counter.
- Per-VC Write Underrun Counter.
- Per-VC Write Overrun Counter.
- Overall SDT Cell Counter.

3. Pin Descriptions

3.1 Functional Pin Descriptions

Ball pin numbers are given in the following tables as defined in Figure 2 on page 32. Pins for buses are listed with the MSB appearing first.

I/O definitions are: Output (O), Input (I), Bidirectional (I/O), Power (PWR), or Ground (GND).

Input pad types are: CMOS or Schmitt, 3.3V. The notations "PU" and "PD" are used, respectively, to indicate that a pad has a weak internal pullup or pulldown resistor. All 3.3V inputs are 5V tolerant. The 3.3V CMOS inputs have a switching threshold of 1.6V, and tolerate input levels of up to 5V; therefore they are 5V TTL compatible.

Output pad types are described by voltage rail and current capability. 3.3V CMOS outputs will satisfy 5V TTL input thresholds at the rated current of the output.

Ball Pin #	Pin Name	I/O	Туре	Description
E9	Intel/Moto	Ι	3.3V CMOS PD	This input selects the microprocessor interface mode as Intel (pulled HIGH) or Motorola (pulled LOW). This pin must be configured before power-up.
Α7	CS	I	3.3V CMOS PU	Active LOW chip select signal.
D8	WR/R_W	ļ	3.3V CMOS PU	Active LOW Write Strobe (Intel) / Read_Write (Motorola).
C7	RD/DS	I	3.3V CMOS PU	Active LOW Read Strobe (Intel) / Active LOW Data Strobe (Motorola).
В7	AEM	I	3.3V CMOS PD	Access External Memory - CPU accesses external memory when HIGH (internal memory and registers when LOW). This pin is usually connected to a high-order CPU address line.
C15, A16, E15, D15, B16, C16, A17, B17, D16, C17, A18, B18, C18, D17, A19, B19, C19, D18, A20, E17	CPU_ADD[20:1]	I	3.3V CMOS PD	CPU Address lines A20-A1. All microprocessor accesses to the device are word-wide, but addresses in this document are given as byte addresses. The virtual A[0] bit would select between high and low bytes within a word.
D9, C8, B8, A8, D10, C9, B9, A9, D11, E11, C10, B10, A10, C11, B11, D12	CPU_DATA[15:0]	I/O	3.3V CMOS PD / 12mA	CPU data bus. All CPU accesses are word accesses.
C12	RDY/DTACK	0	3.3V, 24mA	Ready (Intel) / Data Transfer Acknowledge (Motorola). Acts as normal output in Intel mode, tristated when CS is HIGH; acts as active LOW pseudo-open-drain output in Motorola mode.
A11	ĪRQ	0	3.3V, 24mA	Active LOW interrupt line (operates as open-drain: high-imped- ance when inactive).

Table 1 - Microprocessor Interface Pins

Ball Pin #	Pin Name	I/O	Туре	Description
H26	MEM_CS_1	0	3.3V, 8mA	Active LOW memory chip select signal for bank 1. This signal is used in all memory configurations to select bank 1 of external memory.
H25	MEM_CS_2	0	3.3V, 8mA	Active LOW memory chip select signal for bank 2. This signal is used to enable memory bank 2 when 2 or more banks of external RAM are connected to the MT90520.
H24	MEM_CS_3	0	3.3V, 8mA	Active LOW memory chip select signal for bank 3. This signal is used to enable memory bank 3 when 4 banks of external RAM are connected to the MT90520.
J23	MEM_CS_4	0	3.3V, 8mA	Active LOW memory chip select signal for bank 4. This signal is used to enable memory bank 4 when 4 banks of external RAM are connected to the MT90520.
G26	MEM_WR	0	3.3V, 8mA	Active LOW write enable.
B21, D20, C21, A22, B22, D21,	MEM_ADD[19:0]	0	3.3V, 8mA	Memory address lines. Connect these lines to external memory as follows:
A23, C22, D22, B23, A24, C23,				Bank Size of 1M: MEM_ADD[19:0] are connected to memory.
D23, B24, A25,				Bank Size of 512K: MEM_ADD[18:0] are connected to memory.
A26, B26, C24,				Bank Size of 256K: MEM_ADD[17:0] are connected to memory.
B25, C25				Bank Size of 128K: MEM_ADD[16:0] are connected to memory.
D24, C26, D25, E23, E24, D26, G22, F23, E25, E26, J22, F24, G23, F25, F26, G24, H23, G25	MEM_DATA[17:0]	I/O	3.3V CMOS PD / 8mA	Memory data lines. MEM_DATA[15:8] represent the upper byte; MEM_DATA[7:0] represent the lower byte. Optional lines [17] and [16] represent the high and low byte parity values, respectively.

Table 2 - External M	emory Interface Pins
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Table 3 - TDM Port Pins

Ball Pin #	Pin Name	I/O	Туре	Description
AC3, AB2, W4,	STiCLK[7:0]	Ι	3.3V CMOS	PCM Input Clocks.
V3, U1, P3, N2, K2			PD	These inputs are used to sample the incoming PCM data/ CAS from the E1 or DS1 lines.
				In Structured CES mode, ST-BUS format STiCLK is 4.096 MHz; Generic format STiCLK is 1.544 MHz or 2.048 MHz for DS1; or 2.048 MHz for E1.
				In Unstructured CES mode, these pins accept 1.544 MHz for DS1 or 2.048 MHz for E1.
AD3, AC1, AA1,	STiMF[7:0]	I	3.3V CMOS	Input Frame Pulses.
W2, R4, R3, N4, L2			PD	In Structured CES mode, these pins are input frame pulses which set the frame boundaries for the incoming data and CAS. These signals can be either multiframe or frame inputs.
				Not used in Unstructured CES mode.
AD2, AA4, V5,	DSTi[7:0]	Ι	3.3V CMOS	Serial PCM Data Inputs.
U4, U2, R1, N1, K1			PD	In Unstructured CES mode, each pin carries a 1.544 Mbps or 2.048 Mbps serial stream.
				In Structured CES mode, each pin carries a 1.544 Mbps or 2.048 Mbps serial stream which contains a 24-channel data stream in DS1 operation or a 32-channel data stream in E1 operation.
AC4,Y5, Y3, W1,U3, R2, N3,	CSTi/LOSi[7:0]	I	3.3V CMOS PD	Serial PCM Signalling Inputs or Input Loss of Signal (LOS) Indicators.
L3				In Structured CES mode, these pins carry CAS signalling inputs.
				In Unstructured CES mode, these pins input LOS signals from external LIUs.
AE1,AB3, AA2,	SToCLK[7:0]	0	3.3V, 4mA	PCM Output Clocks.
W3, T4, T1, M5, L1				These outputs are used to drive the PCM data/CAS out to the E1 or DS1 lines.
				In Structured CES mode, ST-BUS format SToCLK is 4.096 MHz; Generic format SToCLK is 1.544 MHz or 2.048 MHz for DS1; or 2.048 MHz for E1.
				In Unstructured CES mode, these pins provide 1.544 MHz for DS1 or 2.048 MHz for E1.
AF2, AD1, AB1,	SToMF[7:0]	0	3.3V, 4mA	Output Frame Pulses.
Y2, T5, T3, P4, M1				In Structured CES mode, these pins are output frame pulses which set the frame boundaries for the outgoing data and CAS. These signals are programmable as either multiframe pulses or frame pulses.
				Not used in Unstructured CES mode.

Table 3 - TDM Port Pins

Ball Pin #	Pin Name	I/O	Туре	Description
AE2, AB4, Y4,	DSTo[7:0]	0	3.3V, 4mA	Serial PCM Data Outputs.
V4, V1, T2, P1, M3				In Unstructured CES mode, each pin carries a 1.544 Mbps or 2.048 Mbps serial stream.
				In Structured CES mode, each pin carries a 1.544 Mbps or 2.048 Mbps serial stream which contains a 24-channel data stream in DS1 operation or a 32-channel data stream in E1 operation.
AF1, AC2, AA3, Y1, V2, P5, P2,	CSTo/LOSo[7:0]	0	3.3V, 4mA	Serial PCM Signalling Outputs or Output Loss of Signal (LOS) Indicators.
M2				In Structured CES mode, these pins output CAS signalling.
				In Unstructured CES mode, each of these pins outputs an LOS or general purpose signal based on a user-programma- ble value in TDM Control Register 3 for the corresponding port.

Ball Pin #	Pin Name	I/O	Туре	Description
H2	UTO_IN_CLK	I/O	3.3V CMOS PD / 24mA	Synchronization clock for data transfer on UTO_IN_DATA. This clock can be output from an internal divider (equal to MCLK/2) or input from an external source. (RxClk when the MT90520 is in ATM mode; TxClk when the MT90520 is in PHY mode.)
L4, J1, J2, J3, K4	UTO_IN_ADD[4:0]	Ι	3.3V CMOS PD	Multi-PHY address signals. These address inputs are used to poll the MT90520 and to select the next MPHY device to receive data on UTO_IN_DATA. These signals are driven from the ATM-end to the PHY-end, and only used when the MT90520 is in PHY mode. (Inactive when the MT90520 is in ATM mode; TxAddr when the MT90520 is in PHY mode.)
H3, J4, G1, G2, H4, G3, F1, F2, H5, G4, F3, E1, E2, F4, D1, E3	UTO_IN_DATA[15:0]	I	3.3V CMOS PD	16-bit UTOPIA input bus for cell-based data. When in 8-bit mode, only bits[7:0] are active. (RxData[15:0] when the MT90520 is in ATM mode; TxData[15:0] when in PHY mode.)
K5	UTO_IN_PAR	I	3.3V CMOS PD	Odd parity bit over UTO_IN_DATA[15:0]. When in 8-bit mode, odd parity bit over UTO_IN_DATA[7:0]. (RxPrty when the MT90520 is in ATM mode; TxPrty when in PHY mode.)
КЗ	UTO_IN_SOC	I	3.3V CMOS PD	Start of Cell for UTO_IN_DATA. Active HIGH input signal indicat- ing the first word/byte of the cell being received. (RxSOC when the MT90520 is in ATM mode; TxSOC when in PHY mode.)
M4	UTO_IN_CLAVATM_	I	3.3V CMOS PD	Handshake input for UTO_IN_DATA.
	ENBPHY			When the MT90520 is in ATM mode, this input is RxClav, indicat- ing that the PHY-end has a complete cell to transfer on UTO_IN_DATA.
				When the MT90520 is in PHY mode, this input is TxEnb*, indicat- ing that the ATM-end is transferring valid data on UTO_IN_DATA.
H1	UTO_IN_ENBATM_	0	3.3V, 16mA	Handshake output for UTO_IN_DATA.
	CLAVPHY			When the MT90520 is in ATM mode, this output is RxEnb*, indi- cating that the MT90520 will begin to sample UTO_IN_DATA and UTO_IN_SOC at the end of the next clock cycle.
				When the MT90520 is in PHY mode, this output is TxClav, indi- cating that the MT90520 can accept a complete cell on UTO_IN_DATA.

Table 4 - UTOPIA Bus Pins

Ball Pin #	Pin Name	I/O	Туре	Description
D5	UTO_OUT_CLK	I/O	3.3V CMOS PD / 24mA	Synchronization clock for data transfer on UTO_OUT_DATA. This clock can be output from an internal divider (equal to MCLK/2) or input from an external source. (TxClk when the MT90520 is in ATM mode; RxClk when the MT90520 is in PHY mode.)
E4, D2, C1, D3, D4	UTO_OUT_ADD[4:0]	I	3.3V CMOS PD	Multi-PHY Address signals. These address inputs are used to poll the MT90520, and to select the next MPHY device to drive data on UTO_OUT_DATA. These signals are driven from the ATM-end to the PHY-end, and only used when the MT90520 is in PHY mode. (Inactive when the MT90520 is in ATM mode; RxAddr when the MT90520 is in PHY mode.)
A2, B3, C3, C4, A3, B4, C5, A4, D6, E7, B5, A5, C6, D7, B6, A6	UTO_OUT_DATA[15:0]	0	3.3V, 12mA	16-bit UTOPIA output data bus for cell-based data. When in 8-bit mode, only bits[7:0] are active. In Level 2 operation, this bus is tristated between cell transmissions. (TxData when the MT90520 is in ATM mode; RxData when in PHY mode.)
B1	UTO_OUT_PAR	0	3.3V, 12mA	Odd parity bit over UTO_OUT_DATA[15:0]. When in 8-bit mode, odd parity bit over UTO_OUT_DATA[7:0]. In Level 2 operation, this signal is tristated between cell transmissions. (TxPrty when the MT90520 is in ATM mode; RxPrty when in PHY mode.)
C2	UTO_OUT_SOC	0	3.3V, 12mA	Start of Cell for UTO_OUT_DATA. Active HIGH output signal indi- cating the first word/byte of the cell being transmitted. In Level 2 operation, this signal is tristated between cell transmissions. (TxSOC when the MT90520 is in ATM mode; RxSOC when in PHY mode.)
B2	UTO_OUT_CLAVATM_	I	3.3V CMOS PD	Handshake input for UTO_OUT_DATA.
	ENBPHY			When the MT90520 is in ATM mode, this input is TxClav, indicat- ing that the PHY-end can accept a complete cell on UTO_OUT_DATA.
				When the MT90520 is in PHY mode, this input is RxEnb*, indicat- ing that the ATM-end will begin to sample UTO_OUT_DATA and UTO_OUT_SOC at the end of the next clock cycle.
A1	UTO_OUT_ENBATM_	0	3.3V, 16mA	Handshake output for UTO_OUT_DATA.
	CLAVPHY			When the MT90520 is in ATM mode, this output is TxEnb*, indi- cating that the data on UTO_OUT_DATA is valid.
				When the MT90520 is in PHY mode, this output is RxClav, indi- cating that the MT90520 has a complete cell ready to output on UTO_OUT_DATA.

Ball Pin #	Pin Name	I/O	Туре	Description
A15	TDM_CLK	Ι	3.3V CMOS PD	Clock input from external PLL, operating at DS1/E1/ST-BUS line rate.
B15	PHY_CLK	Ι	3.3V CMOS PD	PRS-traceable clock input (8 kHz reference clock or 19.44 MHz clock from PHY network layer).
C14	C4M/C2M_b	I/O	3.3V CMOS PD / 24mA	- Backplane clock to be used when all 8 TDM ports are to have the same input and output clock.
				- TDM clock running at either 4.096 MHz or 2.048 MHz.
				- Input in TDM backplane slave mode; output in TDM backplane mas- ter mode.
D14	F0_b	I/O	3.3V CMOS PD / 24mA	- Frame pulse which delineates the 8 kHz frame boundary on PCM input and output streams.
				- In 2.048 Mbps ST-BUS applications, this is a negative-going pulse straddling the frame boundary and lasting for one cycle of the 4.096 MHz clock.
				- In Generic bus applications, this signal may be a positive-going or negative-going pulse following the frame boundary and lasting for one bit cycle (i.e., one cycle of the 2.048 MHz clock).
				- Input in TDM backplane slave mode; output in TDM backplane mas- ter mode.
B14	PRI_REF	0	3.3V, 2mA	Output clock running at DS1/E1/ST-BUS line rate, used to provide a primary reference clock for an external PLL.
				Note: This pin will still present a clock (derived from an internal PLL) even if its source clock is experiencing an LOS condition. Therefore, the PRI_LOS signal should be used to qualify the quality of this clock.
A14	PRI_LOS	0	3.3V, 2mA	If high, indicates to an external PLL that the primary reference clock has experienced an LOS condition.
B13	SEC_REF	0	3.3V, 2mA	Output clock running at DS1/E1/ST-BUS line rate, used to provide a secondary reference clock for an external PLL.
A13	SEC_LOS	0	3.3V, 2mA	If high, indicates to an external PLL that the secondary reference clock has experienced an LOS condition.

Ball Pin #	Pin Name	I/O	Туре	Description
C13	MCLK	Ι	3.3V CMOS	Master Clock.
				This signal drives the internal logic. The same clock should be driven to the external memory
A12	RESET	Т		Chip reset signal (active LOW).
			PU	Note that internal reset activity is synchronous to MCLK; this signal is latched internally and held, and MCLK must be applied to bring the MT90520 out of reset.
				The $\overline{\text{TRST}}$ pin (JTAG reset) should also be asserted LOW during chip reset. Also see RESET bit in Chip Wide Reset Register at address 0000h.
C20	TMS	I	3.3V CMOS PU	JTAG Test Mode Select.
B20	TCK	I	3.3V CMOS	JTAG Test Clock.
A21	TDI	I	3.3V CMOS	JTAG Test Data In.
			PU	Should be pulled HIGH if boundary-scan not in use.
D19	TRST	I	3.3V CMOS	JTAG Test Reset input (active LOW).
			PU	Should be asserted LOW on power-up and during reset. Must be HIGH for JTAG boundary-scan oper- ation. Note: This pin has an internal pull-down.
E19	TDO	0	3.3V, 4mA	JTAG Test Data Out.
AB22, AE3, AE26, AD17, AD15, AD13,	TEST_IN	I		Test input pins.
AB12, AE9, AD8, AF5, AD26, AE17, AE15, AE13, AE11, AC10, AC8, AD6, AD25, AC16, AF16, AF13, AF11, AF9, AF7, AC7				These pins must be grounded.
AC23, AD18, AE16, AC14, AE12, AE10, AC9,	TEST_OUT	0	3.3V, 4mA	Test output pins.
AF6				These pins should be left unconnected.
AA5, AB6, AB9, AB13, AB17, AB21, E6, E10, E14, E18, E21, F5, F22, J5, K22, N5, P22, U5, V22	VDD_3.3V	PWR		Power for I/O logic (3.3V).

Table 6 - Master	Clock, Test,	and Powe	er Pins
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Table 6 - Master Clock, Test, and Power Pins

Ball Pin #	Pin Name	I/O	Туре	Description
AB5, AB7, AB11, AB15, AB19, E8, E12, E13, E16, E20, E22, G5, H22, L5, M22, R5, T22, W5, Y22	VDD_2.5V	PWR		Power for core logic.
B12, D13, E5, L11, L12, L13, L14, L15, L16, M11, M12, M13, M14, M15, M16, N11, N12, N13, N14, N15, N16, P11, P12, P13, P14, P15, P16, R11, R12, R13, R14, R15, R16, T11, T12, T13, T14, T15, T16	VSS	GND		Ground for device.
P24, M25, K25, K23, AB25, Y24, V24, T24, AD20, AC21, AE24, AD4,R25, N25, N22, L22, AC26, W22, W26, U25, AF20, AD21, AE23, AF26, AF18, AB14, AF14, AC12, AC11, AE8, AE6, AE4, P25, M26, M23, J24, AA23, Y23, V25, T23, AC19, AE22, AD23, AF3, R24, N24, K26, J25, AB24, Y25, V23, U26, AE20, AF22, AF24, AC5, R26, R23, L24, N23, AC25, AA26, W24, U24, AC18, AC20, AC22, AE25, AE18, AC15, AE14, AD12, AD10, AB10, AD7, AD5, T25, P23, M24, K24, AC24, AB26, Y26, U22, AF19, AB18, AB20, AF25, AC17, AF17, AF15, AC13, AD11, AF8, AB8, AE5, T26, N26, L25, J26, AB23, AA24, W25, U23, AD19, AE21, AD22, AC6, R22, P26, L26, L23, AA22, AA25, W23, V26, AE19, AF12, AF10, AD9, AE7, AF4	NC	NC		No connect.

Table 7 - Pinout Summary

Туре	Input	Output	I/O	Power	Ground	Unused	Total
Microprocessor Interface	25	2	16	-	-	-	43
External Memory Interface	-	25	18	-	-	-	43
TDM Interface	32	32		-	-	-	64
UTOPIA	30	20	2	-	-	-	52
Clock Management	2	4	2	-	-	-	8
Miscellaneous	32	9	-	-	-	128	169
Power & Ground	-	-	-	38	39	-	77
Total	121	92	38	38	39	128	456

3.2 Physical Pin Description

3.2.1 Pin Description by Ball Pin Number

The following table lists each ball of the PBGA package and the corresponding functional pin name.

Ball Pin #	Pin Name
A1	UTO_OUT_ENBATM_ CLAVPHY
A2	UTO_OUT_DATA[15]
A3	UTO_OUT_DATA[11]
A4	UTO_OUT_DATA[8]
A5	UTO_OUT_DATA[4]
A6	UTO_OUT_DATA[0]
A7	CS
A8	CPU_DATA[12]
A9	CPU_DATA[8]
A10	CPU_DATA[3]
A11	IRQ
A12	RESET
A13	SEC_LOS
A14	PRI_LOS
A15	TDM_CLK
A16	CPU_ADD[19]
A17	CPU_ADD[14]
A18	CPU_ADD[10]
A19	CPU_ADD[6]
A20	CPU_ADD[2]
A21	TDI
A22	MEM_ADD[16]
A23	MEM_ADD[13]
A24	MEM_ADD[9]
A25	MEM_ADD[5]
A26	MEM_ADD[4]
B1	UTO_OUT_PAR
B2	UTO_OUT_CLAVATM _ ENBPHY
B3	UTO_OUT_DATA[14]
B4	UTO_OUT_DATA[10]
B5	UTO_OUT_DATA[5]
B6	UTO_OUT_DATA[1]
B7	AEM
B8	CPU_DATA[13]
B9	CPU_DATA[9]
B10	CPU_DATA[4]
B11	CPU_DATA[1]

Ball Pin #	Pin Name	
B12	VSS	
B13	SEC_REF	
B14	PRI_REF	
B15	PHY_CLK	
B16	CPU_ADD[16]	
B17	CPU_ADD[13]	
B18	CPU_ADD[9]	
B19	CPU_ADD[5]	
B20	ТСК	
B21	MEM_ADD[19]	
B22	MEM_ADD[15]	
B23	MEM_ADD[10]	
B24	MEM_ADD[6]	
B25	MEM_ADD[1]	
B26	MEM_ADD[3]	
C1	UTO_OUT_ADD[2]	
C2	UTO_OUT_SOC	
C3	UTO_OUT_DATA[13]	
C4	UTO_OUT_DATA[12]	
C5	UTO_OUT_DATA[9]	
C6	UTO_OUT_DATA[3]	
C7	RD/DS	
C8	CPU_DATA[14]	
C9	CPU_DATA[10]	
C10	CPU_DATA[5]	
C11	CPU_DATA[2]	
C12	RDY/DTACK	
C13	MCLK	
C14	C4M/C2M_b	
C15	CPU_ADD[20]	
C16	CPU_ADD[15]	
C17	CPU_ADD[11]	
C18	CPU_ADD[8]	
C19	CPU_ADD[4]	
C20	TMS	
C21	MEM_ADD[17]	
C22	MEM_ADD[12]	
C23	MEM_ADD[8]	
C24	MEM_ADD[2]	

Ball Pin #	Pin Name	
C25	MEM_ADD[0]	
C26	MEM_DATA[16]	
D1	UTO_IN_DATA[1]	
D2	UTO_OUT_ADD[3]	
D3	UTO_OUT_ADD[1]	
D4	UTO_OUT_ADD[0]	
D5	UTO_OUT_CLK	
D6	UTO_OUT_DATA[7]	
D7	UTO_OUT_DATA[2]	
D8	WR/R_W	
D9	CPU_DATA[15]	
D10	CPU_DATA[11]	
D11	CPU_DATA[7]	
D12	CPU_DATA[0]	
D13	GND	
D14	F0_b	
D15	CPU_ADD[17]	
D16	CPU_ADD[12]	
D17	CPU_ADD[7]	
D18	CPU_ADD[3]	
D19	TRST	
D20	MEM_ADD[18]	
D21	MEM_ADD[14]	
D22	MEM_ADD[11]	
D23	MEM_ADD[7]	
D24	MEM_DATA[17]	
D25	MEM_DATA[15]	
D26	MEM_DATA[12]	
E1	UTO_IN_DATA[4]	
E2	UTO_IN_DATA[3]	
E3	UTO_IN_DATA[0]	
E4	UTO_OUT_ADD[4]	
E5	VSS	
E6	VDD_3.3V	
E7	UTO_OUT_DATA[6]	
E8	VDD_2.5V	
E9	Intel/Moto	
E10	VDD_3.3V	
E11	CPU_DATA[6]	

Table 8	Pinout b	v Ball	Pin N	umber -	Cont'd
Table 0.	FIIIOULL	ју Бан		unner -	cont u

Ball Pin #	Pin Name	
E12	VDD_2.5V	
E13	VDD	
E14	VDD_3.3V	
E15	CPU_ADD[18]	
E16	VDD_2.5V	
E17	CPU_ADD[1]	
E18	VDD_3.3V	
E19	TDO	
E20	VDD_2.5V	
E21	VDD_3.3V	
E22	VDD_2.5V	
E23	MEM_DATA[14]	
E24	MEM_DATA[13]	
E25	MEM_DATA[9]	
E26	MEM_DATA[8]	
F1	UTO_IN_DATA[9]	
F2	UTO_IN_DATA[8]	
F3	UTO_IN_DATA[5]	
F4	UTO_IN_DATA[2]	
F5	VDD_3.3V	
F22	VDD_3.3V	
F23	MEM_DATA[10]	
F24	MEM_DATA[6]	
F25	MEM_DATA[4]	
F26	MEM_DATA[3]	
G1	UTO_IN_DATA[13]	
G2	UTO_IN_DATA[12]	
G3	UTO_IN_DATA[10]	
G4	UTO_IN_DATA[6]	
G5	VDD_2.5V	
G22	MEM_DATA[11]	
G23	MEM_DATA[5]	
G24	MEM_DATA[2]	
G25	MEM_DATA[0]	
G26	MEM_WR	
H1	UTO_IN_ENBATM_ CLAVPHY	
H2	UTO_IN_CLK	
H3	UTO_IN_DATA[15]	

Ball Pin #	Pin Name	
H4	UTO_IN_DATA[11]	
H5	UTO_IN_DATA[7]	
H22	VDD_2.5V	
H23	MEM_DATA[1]	
H24	MEM_CS_3	
H25	MEM_CS_2	
H26	MEM_CS_1	
J1	UTO_IN_ADD[3]	
J2	UTO_IN_ADD[2]	
J3	UTO_IN_ADD[1]	
J4	UTO_IN_DATA[14]	
J5	VDD_3.3V	
J22	MEM_DATA[7]	
J23	MEM_CS_4	
J24	NC	
J25	NC	
J26	NC	
K1	DSTi[0]	
K2	STiCLK[0]	
K3	UTO_IN_SOC	
K4	UTO_IN_ADD[0]	
K5	UTO_IN_PAR	
K22	VDD_3.3V	
K23	NC	
K24	NC	
K25	NC	
K26	NC	
L1	SToCLK[0]	
L2	STiMF[0]	
L3	CSTi/LOSi[0]	
L4	UTO_IN_ADD[4]	
L5	VDD_2.5V	
L11	VSS	
L12	VSS	
L13	VSS	
L14	VSS	
L15	VSS	
L16	VSS	
L22	NC	

Ball Pin #	Pin Name	
L23	NC	
L24	NC	
L25	NC	
L26	NC	
M1	SToMF[0]	
M2	CSTo/LOSo[0]	
M3	DSTo[0]	
M4	UTO_IN_CLAVATM_ ENBPHY	
M5	SToCLK[1]	
M11	VSS	
M12	VSS	
M13	VSS	
M14	VSS	
M15	VSS	
M16	VSS	
M22	VDD_2.5V	
M23	NC	
M24	NC	
M25	NC	
M26	NC	
N1	DSTi[1]	
N2	STiCLK[1]	
N3	CSTi/LOSi[1]	
N4	STiMF[1]	
N5	VDD_3.3V	
N11	VSS	
N12	VSS	
N13	VSS	
N14	VSS	
N15	VSS	
N16	VSS	
N22	NC	
N23	NC	
N24	NC	
N25	NC	
N26	NC	
P1	DSTo[1]	
P2	CSTo/LOSo[1]	

Table 8. Pinout by Ball Pin Number - Cont'd

Ball Pin #	Pin Name	
P3	STiCLK[2]	
P4	SToMF[1]	
P5	CSTo/LOSo[2]	
P11	VSS	
P12	VSS	
P13	VSS	
P14	VSS	
P15	VSS	
P16	VSS	
P22	VDD_3.3V	
P23	NC	
P24	NC	
P25	NC	
P26	NC	
R1	DSTi[2]	
R2	CSTi/LOSi[2]	
R3	STiMF[2]	
R4	STiMF[3]	
R5	VDD_2.5V	
R11	VSS	
R12	VSS	
R13	VSS	
R14	VSS	
R15	VSS	
R16	VSS	
R22	NC	
R23	NC	
R24	NC	
R25	NC	
R26	NC	
T1	SToCLK[2]	
T2	DSTo[2]	
Т3	SToMF[2]	
T4	SToCLK[3]	
T5	SToMF[3]	
T11	VSS	
T12	VSS	
T13	VSS	
T14	VSS	

T15 VSS T16 VSS T22 VDD_2.5V T23 NC T24 NC T25 NC T26 NC U1 STICLK[3] U2 DSTi[3] U3 CSTI/LOSi[3] U4 DSTi[4] U5 VDD_3.3V U22 NC U23 NC U24 NC U25 NC U26 NC U27 NC U28 NC U29 NC U21 NC U22 NC U23 NC U24 NC V25 NC V26 NC V21 DSTi[4] V3 STICLK[4] V4 DSTo[4] V24 NC V25 NC V26 NC W4 STICLK[5] <tr< th=""><th>Ball Pin #</th><th colspan="2">Pin Name</th></tr<>	Ball Pin #	Pin Name	
T22 VDD_2.5V T23 NC T24 NC T25 NC T26 NC U1 STICLK[3] U2 DSTi[3] U3 CSTi/LOSi[3] U4 DSTi[4] U5 VDD_3.3V U22 NC U23 NC U24 NC U25 NC U26 NC U26 NC V1 DSTo[3] V2 CSTo/LOSo[3] V3 STICLK[4] V4 DSTo[4] V4 DSTo[4] V5 DSTi[5] V22 VDD_3.3V V23 NC V24 NC V25 NC V26 NC V26 NC W1 CSTi/LOSi[4] W2 STIMF[4] W3 STOCLK[4] W3 STOCLK[5] W5 <td>T15</td> <td>VSS</td>	T15	VSS	
T23 NC T24 NC T25 NC T26 NC U1 STICLK[3] U2 DSTI[3] U3 CSTI/LOSI[3] U4 DSTI[4] U5 VDD_3.3V U22 NC U23 NC U24 NC U25 NC U26 NC U26 NC U26 NC V1 DSTo[3] V2 CSTo/LOSo[3] V3 STICLK[4] V4 DSTo[4] V5 DSTi[5] V22 VDD_3.3V V23 NC V24 NC V25 NC V26 NC V26 NC W4 STICLK[4] W3 STOCLK[4] W4 STICLK[5] W5 VDD_2.5V W22 NC W23 <t< td=""><td>T16</td><td>VSS</td></t<>	T16	VSS	
T24 NC T25 NC T26 NC U1 STICLK[3] U2 DSTi[3] U3 CSTI/LOSi[3] U4 DSTi[4] U5 VDD_3.3V U22 NC U23 NC U24 NC U25 NC U24 NC U25 NC U24 NC U25 NC U26 NC V1 DSTo[3] V2 CSTo/LOSo[3] V3 STICLK[4] V4 DSTo[4] V5 DSTi[5] V22 VDD_3.3V V23 NC V24 NC V25 NC V26 NC V26 NC W4 STICLK[4] W4 STICLK[5] W5 VDD_2.5V W22 NC W23 NC </td <td>T22</td> <td>VDD_2.5V</td>	T22	VDD_2.5V	
T25 NC T26 NC U1 STICLK[3] U2 DSTi[3] U3 CSTi/LOSi[3] U4 DSTi[4] U5 VDD_3.3V U22 NC U23 NC U24 NC U25 NC U24 NC U25 NC U26 NC V1 DSTo[3] V2 CSTo/LOSo[3] V3 STICLK[4] V4 DSTo[4] V5 DSTi[5] V22 VDD_3.3V V23 NC V24 NC V25 NC V24 NC V25 NC V26 NC W1 CSTi/LOSi[4] W3 SToCLK[4] W3 SToCLK[4] W3 STOCLK[4] W4 STICLK[5] W5 VDD_2.5V W22<	T23	NC	
T26 NC U1 STICLK[3] U2 DSTi[3] U3 CSTi/LOSi[3] U4 DSTi[4] U5 VDD_3.3V U22 NC U23 NC U24 NC U25 NC U24 NC U25 NC U26 NC V1 DSTo[3] V2 CSTo/LOSo[3] V3 STICLK[4] V4 DSTo[4] V4 DSTo[4] V5 DSTi[5] V22 VDD_3.3V V23 NC V24 NC V25 NC V24 NC V25 NC V26 NC W1 CSTi/LOSi[4] W2 STIMF[4] W3 SToCLK[5] W4 STICLK[5] W5 VDD_2.5V W22 NC W23 <td>T24</td> <td>NC</td>	T24	NC	
U1 STICLK[3] U2 DSTI[3] U3 CSTI/LOSI[3] U4 DSTI[4] U5 VDD_3.3V U22 NC U23 NC U24 NC U25 NC U24 NC U25 NC U26 NC V1 DSTo[3] V2 CSTo/LOSo[3] V3 STICLK[4] V4 DSTo[4] V5 DSTi[5] V22 VDD_3.3V V23 NC V24 NC V25 NC V26 NC V27 STIMF[4] W3 SToCLK[4] W4 STICLK[5] W5 VDD_2.5V W22 NC W23 NC W24 NC W25 NC W26 NC W26 NC	T25	NC	
U2 DSTi[3] U3 CSTi/LOSi[3] U4 DSTi[4] U5 VDD_3.3V U22 NC U23 NC U24 NC U25 NC U24 NC U25 NC U26 NC V1 DSTo[3] V2 CSTo/LOSo[3] V3 STiCLK[4] V4 DSTo[4] V4 DSTo[4] V5 DSTi[5] V22 VDD_3.3V V23 NC V24 NC V25 NC V26 NC V25 NC V26 NC W1 CSTi/LOSi[4] W3 SToCLK[4] W4 STiCLK[5] W5 VDD_2.5V W22 NC W23 NC W24 NC W25 NC W26 <	T26	NC	
U3 CSTi/LOSi[3] U4 DSTi[4] U5 VDD_3.3V U22 NC U23 NC U24 NC U25 NC U24 NC U25 NC U26 NC V1 DSTo[3] V2 CSTo/LOSo[3] V3 STICLK[4] V4 DSTo[4] V5 DSTi[5] V22 VDD_3.3V V23 NC V24 NC V25 NC V26 NC V25 NC V26 NC W1 CSTi/LOSi[4] W2 STIMF[4] W3 SToCLK[4] W4 STICLK[5] W5 VDD_2.5V W22 NC W23 NC W24 NC W25 NC W26 NC W26	U1	STiCLK[3]	
U4 DSTi[4] U5 VDD_3.3V U22 NC U23 NC U24 NC U25 NC U26 NC V1 DSTo[3] V2 CSTo/LOSo[3] V3 STiCLK[4] V4 DSTo[4] V5 DSTi[5] V22 VDD_3.3V V23 NC V24 NC V25 NC V26 NC V25 NC V26 NC V25 NC V26 NC W1 CSTi/LOSi[4] W2 STiMF[4] W3 SToCLK[4] W4 STiCLK[5] W5 VDD_2.5V W22 NC W23 NC W24 NC W25 NC W26 NC W26 NC Y1 CSTo/LOSo[U2	DSTi[3]	
U5 VDD_3.3V U22 NC U23 NC U24 NC U25 NC U26 NC V1 DSTo[3] V2 CSTo/LOSo[3] V3 STiCLK[4] V4 DSTo[4] V5 DSTi[5] V22 VDD_3.3V V23 NC V24 NC V25 NC V24 NC V25 NC V26 NC V26 NC V27 STiMF[4] W3 SToCLK[4] W3 SToCLK[4] W4 STiCLK[5] W5 VDD_2.5V W22 NC W23 NC W23 NC W24 NC W25 NC W26 NC W26 NC Y1 CSTo/LOSo[4]	U3	CSTi/LOSi[3]	
U22 NC U23 NC U24 NC U25 NC U26 NC V1 DSTo[3] V2 CSTo/LOSo[3] V3 STiCLK[4] V4 DSTo[4] V5 DSTi[5] V22 VDD_3.3V V23 NC V24 NC V25 NC V26 NC V23 NC V24 NC V25 NC V26 NC W1 CSTi/LOSi[4] W2 STiMF[4] W3 SToCLK[4] W4 STiCLK[5] W5 VDD_2.5V W22 NC W23 NC W24 NC W25 NC W26 NC W26 NC	U4	DSTi[4]	
U23 NC U24 NC U25 NC U26 NC V1 DSTo[3] V2 CSTo/LOSo[3] V3 STiCLK[4] V4 DSTo[4] V5 DSTi[5] V22 VDD_3.3V V23 NC V24 NC V25 NC V26 NC V27 STiH[4] W1 CSTi/LOSi[4] W2 STIMF[4] W3 SToCLK[4] W3 SToCLK[4] W4 STiCLK[5] W5 VDD_2.5V W22 NC W23 NC W24 NC W25 NC W26 NC W26 NC Y1 CSTo/LOSo[4]	U5	VDD_3.3V	
U24 NC U25 NC U26 NC V1 DSTo[3] V2 CSTo/LOSo[3] V3 STiCLK[4] V4 DSTo[4] V5 DSTi[5] V22 VDD_3.3V V23 NC V24 NC V25 NC V26 NC V27 STiMF[4] W2 STiMF[4] W2 STiMF[4] W3 SToCLK[4] W4 STiCLK[5] W5 VDD_2.5V W22 NC W23 NC W24 NC W25 NC W24 NC W25 NC W26 NC W26 NC	U22	NC	
U25 NC U26 NC V1 DSTo[3] V2 CSTo/LOSo[3] V3 STiCLK[4] V4 DSTo[4] V5 DSTi[5] V22 VDD_3.3V V23 NC V24 NC V25 NC V26 NC V26 NC W1 CSTi/LOSi[4] W2 STIMF[4] W3 SToCLK[4] W4 STICLK[5] W5 VDD_2.5V W22 NC W23 NC W24 NC W23 NC W24 NC W25 NC W26 NC W26 NC Y1 CSTo/LOSo[4]	U23	NC	
U26 NC V1 DSTo[3] V2 CSTo/LOSo[3] V3 STiCLK[4] V4 DSTo[4] V5 DSTi[5] V22 VDD_3.3V V23 NC V24 NC V25 NC V26 NC V26 NC W1 CSTi/LOSi[4] W2 STiMF[4] W3 SToCLK[4] W4 STiCLK[5] W5 VDD_2.5V W22 NC W23 NC W24 NC W23 NC W24 NC W25 NC W24 NC W25 NC W26 NC Y1 CSTo/LOSo[4]	U24	NC	
V1 DSTo[3] V2 CSTo/LOSo[3] V3 STiCLK[4] V4 DSTo[4] V5 DSTi[5] V22 VDD_3.3V V23 NC V24 NC V25 NC V26 NC V21 STiMF[4] W2 STiMF[4] W2 STiMF[4] W3 SToCLK[4] W4 STiCLK[5] W5 VDD_2.5V W22 NC W23 NC W24 NC W23 NC W24 NC W25 NC W26 NC W26 NC W26 NC Y1 CSTo/LOSo[4]	U25	NC	
V2 CSTo/LOSo[3] V3 STiCLK[4] V4 DSTo[4] V5 DSTi[5] V22 VDD_3.3V V23 NC V24 NC V25 NC V26 NC V27 STiMF[4] W2 STiMF[4] W3 SToCLK[4] W4 STiCLK[5] W5 VDD_2.5V W22 NC W23 NC W24 NC W25 NC W26 NC W23 NC W24 NC W25 NC W24 NC W25 NC W26 NC Y1 CSTo/LOSo[4]	U26	NC	
V3 STICLK[4] V4 DSTo[4] V5 DSTi[5] V22 VDD_3.3V V23 NC V24 NC V25 NC V26 NC W1 CSTi/LOSi[4] W2 STiMF[4] W3 SToCLK[4] W4 STICLK[5] W5 VDD_2.5V W22 NC W23 NC W24 NC W25 NC W26 NC W23 NC W24 NC W25 NC W26 NC W26 NC Y1 CSTo/LOSo[4]	V1	DSTo[3]	
V4 DSTo[4] V5 DSTi[5] V22 VDD_3.3V V23 NC V24 NC V25 NC V26 NC W1 CSTi/LOSi[4] W2 STiMF[4] W3 SToCLK[4] W4 STiCLK[5] W5 VDD_2.5V W22 NC W23 NC W24 NC W25 NC W26 NC W25 NC W26 NC W27 NC W28 NC W24 NC W25 NC W26 NC Y1 CSTo/LOSo[4]	V2	CSTo/LOSo[3]	
V5 DSTi[5] V22 VDD_3.3V V23 NC V24 NC V25 NC V26 NC W1 CSTi/LOSi[4] W2 STiMF[4] W3 SToCLK[4] W4 STiCLK[5] W5 VDD_2.5V W22 NC W23 NC W24 NC W25 NC W26 NC W23 NC W24 NC W25 NC W26 NC W26 NC Y1 CSTo/LOSo[4]	V3	STiCLK[4]	
V22 VDD_3.3V V23 NC V24 NC V25 NC V26 NC W1 CSTi/LOSi[4] W2 STiMF[4] W3 SToCLK[4] W4 STiCLK[5] W5 VDD_2.5V W22 NC W23 NC W24 NC W25 NC W26 NC W27 NC W28 NC W24 NC W25 NC W26 NC Y1 CSTo/LOSo[4]	V4	DSTo[4]	
V23 NC V24 NC V25 NC V26 NC W1 CSTi/LOSi[4] W2 STiMF[4] W3 SToCLK[4] W4 STiCLK[5] W5 VDD_2.5V W22 NC W23 NC W24 NC W25 NC W26 NC W26 NC W26 NC W27 NC W28 NC	V5	DSTi[5]	
V24 NC V25 NC V26 NC W1 CSTi/LOSi[4] W2 STiMF[4] W3 SToCLK[4] W4 STiCLK[5] W5 VDD_2.5V W22 NC W23 NC W24 NC W25 NC W26 NC W26 NC Y1 CSTo/LOSo[4]	V22	VDD_3.3V	
V25 NC V26 NC W1 CSTi/LOSi[4] W2 STiMF[4] W3 SToCLK[4] W4 STiCLK[5] W5 VDD_2.5V W22 NC W23 NC W24 NC W25 NC W26 NC W26 NC Y1 CSTo/LOSo[4]	V23	NC	
V26 NC W1 CSTi/LOSi[4] W2 STiMF[4] W3 SToCLK[4] W4 STiCLK[5] W5 VDD_2.5V W22 NC W23 NC W24 NC W25 NC W26 NC Y1 CSTo/LOSo[4]	V24	NC	
W1 CSTi/LOSi[4] W2 STiMF[4] W3 SToCLK[4] W4 STiCLK[5] W5 VDD_2.5V W22 NC W23 NC W24 NC W25 NC W26 NC Y1 CSTo/LOSo[4]	V25	NC	
W2 STiMF[4] W3 SToCLK[4] W4 STiCLK[5] W5 VDD_2.5V W22 NC W23 NC W24 NC W25 NC W26 NC Y1 CSTo/LOSo[4]	V26	NC	
W3 SToCLK[4] W4 STiCLK[5] W5 VDD_2.5V W22 NC W23 NC W24 NC W25 NC W26 NC Y1 CSTo/LOSo[4]	W1	CSTi/LOSi[4]	
W4 STiCLK[5] W5 VDD_2.5V W22 NC W23 NC W24 NC W25 NC W26 NC Y1 CSTo/LOSo[4]	W2	STiMF[4]	
W5 VDD_2.5V W22 NC W23 NC W24 NC W25 NC W26 NC Y1 CSTo/LOSo[4]	W3	SToCLK[4]	
W22 NC W23 NC W24 NC W25 NC W26 NC Y1 CSTo/LOSo[4]	W4	STiCLK[5]	
W23 NC W24 NC W25 NC W26 NC Y1 CSTo/LOSo[4]	W5	VDD_2.5V	
W24 NC W25 NC W26 NC Y1 CSTo/LOSo[4]	W22	NC	
W25 NC W26 NC Y1 CSTo/LOSo[4]	W23	NC	
W26 NC Y1 CSTo/LOSo[4]	W24	NC	
Y1 CSTo/LOSo[4]	W25	NC	
	W26	NC	
Y2 SToMF[4]	Y1	CSTo/LOSo[4]	
	Y2	SToMF[4]	

Ball Pin # Pin Name Y3 CSTi/LOSi[5] Y4 DSTo[5] Y5 CSTi/LOSi[6] Y22 VDD_2.5V Y23 NC Y24 NC Y25 NC Y26 NC AA1 STIMF[5] AA2 SToCLK[5] AA3 CSTo/LOSo[5] AA4 DSTi[6] AA4 DSTi[6] AA4 DSTi[6] AA4 DSTi[6] AA4 DSTi[6] AA4 DSTi[6] AA4 NC AA2 NC AA2 NC AA4 DSTi[6] AA5 VDD_3.3V AA26 NC AB1 SToCLK[6] AB2 STICLK[6] AB3 STOCLK[6] AB4 DSTo[6] AB5 VDD_2.5V AB6 NC AB10 NC AB11 VD			
Y4 DSTo[5] Y5 CSTi/LOSi[6] Y22 VDD_2.5V Y23 NC Y24 NC Y25 NC Y26 NC AA1 STiMF[5] AA2 SToCLK[5] AA3 CSTo/LOSo[5] AA4 DSTi[6] AA5 VDD_3.3V AA22 NC AA23 NC AA24 NC AA25 NC AA26 NC AB1 SToHF[5] AB2 STICLK[6] AB3 STOCLK[6] AB4 DSTo[6] AB5 VDD_2.5V AB6 VDD_2.5V AB7 VDD_2.5V AB8 NC AB9 VDD_3.3V AB10 NC AB11 VDD_2.5V AB8 NC AB13 VDD_3.3V AB14 NC AB13 VDD_3.3V AB14 NC AB15 VDD_2.5V AB16 NC AB17 VDD_3.3V AB18 NC AB19 VDD_2.5V	Ball Pin #	Pin Name	
Y5 CSTi/LOSi[6] Y22 VDD_2.5V Y23 NC Y24 NC Y25 NC Y26 NC AA1 STIMF[5] AA2 STOCLK[5] AA3 CSTo/LOSo[5] AA4 DSTi[6] AA5 VDD_3.3V AA22 NC AA23 NC AA4 DSTi[6] AA4 DSTi[6] AA4 NC AA23 NC AA44 DSTi[6] AA5 VDD_3.3V AA26 NC AA26 NC AB1 SToK[6] AB2 STICLK[6] AB3 STOCLK[6] AB4 DSTo[6] AB5 VDD_2.5V AB6 VDD_3.3V AB7 VDD_2.5V AB8 NC AB11 VDD_2.5V AB13 VDD_2.5V AB14 NC	Y3	CSTi/LOSi[5]	
Y22 VDD_2.5V Y23 NC Y24 NC Y25 NC Y26 NC AA1 STIMF[5] AA2 SToCLK[5] AA3 CSTo/LOSo[5] AA4 DSTi[6] AA5 VDD_3.3V AA22 NC AA23 NC AA24 NC AA25 NC AA26 NC AB1 SToMF[5] AB2 STICLK[6] AB3 SToCLK[6] AB4 DSTo[6] AB5 VDD_2.5V AB6 VDD_2.5V AB7 VDD_2.5V AB8 NC AB9 VDD_3.3V AB11 VDD_2.5V AB13 VDD_2.5V AB14 NC AB13 VDD_2.5V AB14 NC AB13 VDD_2.5V AB14 NC AB15 VDD_2.5V	Y4	DSTo[5]	
Y23 NC Y24 NC Y25 NC Y26 NC AA1 STIMF[5] AA2 SToCLK[5] AA3 CSTo/LOSo[5] AA4 DSTI[6] AA5 VDD_3.3V AA22 NC AA4 DSTI[6] AA5 VDD_3.3V AA23 NC AA24 NC AA25 NC AA26 NC AB1 SToMF[5] AB2 STICLK[6] AB3 SToCLK[6] AB4 DSTo[6] AB5 VDD_2.5V AB6 VDD_3.3V AB7 VDD_2.5V AB8 NC AB9 VDD_3.3V AB1 VDD_2.5V AB1 VDD_2.5V AB1 VDD_2.5V AB1 VDD_2.5V AB1 VDD_2.5V AB1 VDD_2.5V AB1 VDD_2.5	Y5	CSTi/LOSi[6]	
Y24 NC Y25 NC Y26 NC AA1 STiMF[5] AA2 SToCLK[5] AA3 CSTo/LOSo[5] AA4 DSTi[6] AA5 VDD_3.3V AA22 NC AA23 NC AA24 NC AA25 NC AA26 NC AB1 SToMF[5] AB2 STICLK[6] AB3 SToCLK[6] AB4 DSTo[6] AB5 VDD_2.5V AB6 VDD_3.3V AB7 VDD_2.5V AB8 NC AB1 VDD_2.5V AB6 VDD_3.3V AB10 NC AB11 VDD_2.5V AB12 TEST_IN AB13 VDD_3.3V AB14 NC AB15 VDD_2.5V AB16 NC AB17 VDD_3.3V AB18 NC AB19 VDD_2.5V	Y22	VDD_2.5V	
Y25 NC Y26 NC AA1 STIMF[5] AA2 SToCLK[5] AA3 CSTo/LOSo[5] AA4 DSTi[6] AA5 VDD_3.3V AA22 NC AA23 NC AA24 NC AA25 NC AA26 NC AB1 SToMF[5] AB2 STICLK[6] AB3 SToCLK[6] AB4 DSTo[6] AB5 VDD_2.5V AB6 VDD_3.3V AB7 VDD_2.5V AB8 NC AB11 VDD_2.5V AB8 NC AB11 VDD_2.5V AB6 VDD_3.3V AB10 NC AB11 VDD_2.5V AB12 TEST_IN AB13 VDD_3.3V AB14 NC AB15 VDD_2.5V AB16 NC AB17 VDD_3.3V AB18 NC AB19 VDD_2.5	Y23	NC	
Y26 NC AA1 STiMF[5] AA2 SToCLK[5] AA3 CSTo/LOSo[5] AA4 DSTi[6] AA5 VDD_3.3V AA22 NC AA23 NC AA24 NC AA25 NC AA26 NC AA26 NC AB1 SToMF[5] AB2 STiCLK[6] AB3 SToCLK[6] AB4 DSTo[6] AB5 VDD_2.5V AB6 VDD_3.3V AB7 VDD_2.5V AB8 NC AB1 VDD_3.3V AB1 VDD_3.3V AB1 VDD_3.3V AB1 VDD_3.3V AB1 NC AB13 VDD_3.3V AB14 NC AB15 VDD_2.5V AB16 NC AB17 VDD_3.3V AB18 NC AB19 VDD_2.5V	Y24	NC	
AA1 STIMF[5] AA2 SToCLK[5] AA3 CSTo/LOSo[5] AA4 DSTi[6] AA5 VDD_3.3V AA22 NC AA23 NC AA24 NC AA25 NC AA26 NC AB1 SToMF[5] AB2 STICLK[6] AB3 STOCLK[6] AB4 DSTo[6] AB5 VDD_2.5V AB6 VDD_3.3V AB7 VDD_2.5V AB8 NC AB1 VDD_3.3V AB1 VDD_2.5V AB8 NC AB1 VDD_2.5V AB1 VDD_2.5V AB1 VDD_2.5V AB1 VDD_2.5V AB1 VDD_2.5V AB1 NC AB13 VDD_3.3V AB14 NC AB15 VDD_2.5V AB16 NC AB17 V	Y25	NC	
AA2 STOCLK[5] AA3 CSTo/LOSo[5] AA4 DSTi[6] AA5 VDD_3.3V AA22 NC AA23 NC AA24 NC AA25 NC AA26 NC AA26 NC AB1 SToMF[5] AB2 STICLK[6] AB3 SToCLK[6] AB4 DSTo[6] AB5 VDD_2.5V AB6 VDD_3.3V AB7 VDD_2.5V AB8 NC AB10 NC AB11 VDD_2.5V AB8 NC AB11 VDD_2.5V AB11 VDD_2.5V AB12 TEST_IN AB13 VDD_3.3V AB14 NC AB15 VDD_2.5V AB16 NC AB17 VDD_3.3V AB18 NC AB19 VDD_2.5V	Y26	NC	
AA3 CSTo/LOSo[5] AA4 DSTi[6] AA5 VDD_3.3V AA22 NC AA23 NC AA24 NC AA25 NC AA26 NC AB1 SToMF[5] AB2 STICLK[6] AB3 STOCLK[6] AB4 DSTo[6] AB5 VDD_2.5V AB6 VDD_3.3V AB7 VDD_2.5V AB8 NC AB1 VDD_3.3V AB1 VDD_3.3V AB1 VDD_3.3V AB13 VDD_3.3V AB14 NC AB13 VDD_3.3V AB14 NC AB15 VDD_2.5V AB14 NC AB15 VDD_2.5V AB14 NC AB15 VDD_2.5V AB16 NC AB17 VDD_2.5V AB16 NC AB17 VDD_2.	AA1	STiMF[5]	
AA4 DSTi[6] AA5 VDD_3.3V AA22 NC AA23 NC AA24 NC AA25 NC AA26 NC AA26 NC AB1 SToMF[5] AB2 STICLK[6] AB3 SToCLK[6] AB4 DSTo[6] AB5 VDD_2.5V AB6 VDD_2.5V AB7 VDD_2.5V AB8 NC AB10 NC AB11 VDD_2.5V AB8 NC AB10 NC AB11 VDD_2.5V AB13 VDD_3.3V AB14 NC AB15 VDD_2.5V AB14 NC AB15 VDD_2.5V AB14 NC AB15 VDD_3.3V AB16 NC AB17 VDD_3.3V AB18 NC AB19 VDD_2.5V <	AA2	SToCLK[5]	
AA5 VDD_3.3V AA22 NC AA23 NC AA24 NC AA25 NC AA26 NC AA26 NC AB1 SToMF[5] AB2 STICLK[6] AB3 STOCLK[6] AB4 DSTo[6] AB5 VDD_2.5V AB6 VDD_3.3V AB7 VDD_2.5V AB8 NC AB1 VDD_3.3V AB1 VDD_2.5V AB1 VDD_2.5V AB1 VDD_3.3V AB10 NC AB11 VDD_2.5V AB12 TEST_IN AB13 VDD_3.3V AB14 NC AB15 VDD_2.5V AB16 NC AB17 VDD_3.3V AB18 NC AB19 VDD_2.5V	AA3	CSTo/LOSo[5]	
AA22 NC AA23 NC AA24 NC AA25 NC AA26 NC AA26 NC AB1 SToMF[5] AB2 STiCLK[6] AB3 SToCLK[6] AB4 DSTo[6] AB5 VDD_2.5V AB6 VDD_2.5V AB8 NC AB9 VDD_3.3V AB10 NC AB11 VDD_2.5V AB8 NC AB10 NC AB11 VDD_2.5V AB13 VDD_2.5V AB14 NC AB13 VDD_2.5V AB14 NC AB15 VDD_2.5V AB16 NC AB17 VDD_3.3V AB16 NC AB17 VDD_3.3V AB18 NC AB19 VDD_2.5V	AA4	DSTi[6]	
AA23 NC AA24 NC AA25 NC AA26 NC AA26 NC AB1 SToMF[5] AB2 STiCLK[6] AB3 SToCLK[6] AB4 DSTo[6] AB5 VDD_2.5V AB6 VDD_3.3V AB7 VDD_2.5V AB8 NC AB9 VDD_3.3V AB10 NC AB11 VDD_2.5V AB12 TEST_IN AB13 VDD_3.3V AB14 NC AB15 VDD_2.5V AB14 NC AB13 VDD_3.3V AB14 NC AB15 VDD_2.5V AB16 NC AB17 VDD_3.3V AB18 NC AB19 VDD_2.5V	AA5	VDD_3.3V	
AA24 NC AA25 NC AA26 NC AB1 SToMF[5] AB2 STiCLK[6] AB3 SToCLK[6] AB4 DSTo[6] AB5 VDD_2.5V AB6 VDD_2.5V AB7 VDD_2.5V AB8 NC AB9 VDD_3.3V AB10 NC AB11 VDD_2.5V AB8 NC AB10 NC AB11 VDD_2.5V AB13 VDD_2.5V AB14 NC AB15 VDD_2.5V AB13 VDD_2.5V AB14 NC AB15 VDD_2.5V AB16 NC AB17 VDD_3.3V AB16 NC AB17 VDD_3.3V AB18 NC AB19 VDD_2.5V	AA22	NC	
AA25 NC AA26 NC AB1 SToMF[5] AB2 STiCLK[6] AB3 SToCLK[6] AB4 DSTo[6] AB5 VDD_2.5V AB6 VDD_2.5V AB7 VDD_2.5V AB8 NC AB9 VDD_3.3V AB10 NC AB11 VDD_2.5V AB12 TEST_IN AB13 VDD_3.3V AB14 NC AB13 VDD_3.3V AB14 NC AB15 VDD_2.5V AB14 NC AB15 VDD_3.3V AB14 NC AB15 VDD_2.5V AB16 NC AB17 VDD_3.3V AB18 NC AB19 VDD_2.5V	AA23	NC	
AA26NCAB1SToMF[5]AB2STiCLK[6]AB3SToCLK[6]AB4DSTo[6]AB5VDD_2.5VAB6VDD_3.3VAB7VDD_2.5VAB8NCAB9VDD_3.3VAB10NCAB11VDD_2.5VAB12TEST_INAB13VDD_3.3VAB14NCAB15VDD_2.5VAB14NCAB15VDD_2.5VAB16NCAB17VDD_2.5VAB18NCAB19VDD_2.5VAB18NCAB19VDD_2.5VAB19NC	AA24	NC	
AB1 SToMF[5] AB2 STiCLK[6] AB3 SToCLK[6] AB4 DSTo[6] AB5 VDD_2.5V AB6 VDD_2.5V AB7 VDD_2.5V AB8 NC AB9 VDD_3.3V AB10 NC AB11 VDD_2.5V AB12 TEST_IN AB13 VDD_3.3V AB14 NC AB15 VDD_2.5V AB14 NC AB15 VDD_3.3V AB14 NC AB15 VDD_3.3V AB16 NC AB17 VDD_3.3V AB18 NC AB19 VDD_2.5V	AA25	NC	
AB2 STICLK[6] AB3 SToCLK[6] AB4 DSTo[6] AB5 VDD_2.5V AB6 VDD_2.5V AB7 VDD_2.5V AB8 NC AB9 VDD_3.3V AB10 NC AB11 VDD_2.5V AB12 TEST_IN AB13 VDD_3.3V AB14 NC AB15 VDD_2.5V AB14 NC AB15 VDD_3.3V AB14 NC AB15 VDD_2.5V AB14 NC AB15 VDD_2.5V AB16 NC AB17 VDD_2.5V AB18 NC AB19 VDD_2.5V	AA26	NC	
AB3 SToCLK[6] AB4 DSTo[6] AB5 VDD_2.5V AB6 VDD_3.3V AB7 VDD_2.5V AB8 NC AB8 NC AB9 VDD_3.3V AB10 NC AB11 VDD_2.5V AB12 TEST_IN AB13 VDD_3.3V AB14 NC AB15 VDD_2.5V AB14 NC AB15 VDD_3.3V AB14 NC AB15 VDD_2.5V AB16 NC AB17 VDD_3.3V AB18 NC AB19 VDD_2.5V	AB1	SToMF[5]	
AB4 DSTo[6] AB5 VDD_2.5V AB6 VDD_3.3V AB7 VDD_2.5V AB8 NC AB9 VDD_3.3V AB10 NC AB11 VDD_2.5V AB12 TEST_IN AB13 VDD_3.3V AB14 NC AB15 VDD_2.5V AB16 NC AB17 VDD_2.5V AB18 NC AB19 VDD_2.5V	AB2	STiCLK[6]	
AB5 VDD_2.5V AB6 VDD_3.3V AB7 VDD_2.5V AB8 NC AB9 VDD_3.3V AB10 NC AB11 VDD_2.5V AB12 TEST_IN AB13 VDD_3.3V AB14 NC AB15 VDD_2.5V AB14 NC AB15 VDD_2.5V AB14 NC AB15 VDD_2.5V AB16 NC AB17 VDD_3.3V AB18 NC AB19 VDD_2.5V	AB3	SToCLK[6]	
AB6 VDD_3.3V AB7 VDD_2.5V AB8 NC AB9 VDD_3.3V AB10 NC AB11 VDD_2.5V AB12 TEST_IN AB13 VDD_3.3V AB14 NC AB15 VDD_2.5V AB16 NC AB17 VDD_2.5V AB18 NC AB19 VDD_2.5V	AB4	DSTo[6]	
AB7 VDD_2.5V AB8 NC AB9 VDD_3.3V AB10 NC AB11 VDD_2.5V AB12 TEST_IN AB13 VDD_3.3V AB14 NC AB15 VDD_2.5V AB14 NC AB15 VDD_2.5V AB16 NC AB17 VDD_3.3V AB18 NC AB19 VDD_2.5V	AB5	VDD_2.5V	
AB8 NC AB9 VDD_3.3V AB10 NC AB11 VDD_2.5V AB12 TEST_IN AB13 VDD_3.3V AB14 NC AB15 VDD_2.5V AB16 NC AB17 VDD_3.3V AB18 NC AB19 VDD_2.5V	AB6	VDD_3.3V	
AB9 VDD_3.3V AB10 NC AB11 VDD_2.5V AB12 TEST_IN AB13 VDD_3.3V AB14 NC AB15 VDD_2.5V AB16 NC AB17 VDD_3.3V AB18 NC AB19 VDD_2.5V	AB7	VDD_2.5V	
AB10 NC AB11 VDD_2.5V AB12 TEST_IN AB13 VDD_3.3V AB14 NC AB15 VDD_2.5V AB16 NC AB17 VDD_3.3V AB18 NC AB19 VDD_2.5V	AB8	NC	
AB11 VDD_2.5V AB12 TEST_IN AB13 VDD_3.3V AB14 NC AB15 VDD_2.5V AB16 NC AB17 VDD_3.3V AB18 NC AB19 VDD_2.5V	AB9	VDD_3.3V	
AB12 TEST_IN AB13 VDD_3.3V AB14 NC AB15 VDD_2.5V AB16 NC AB17 VDD_3.3V AB18 NC AB19 VDD_2.5V	AB10	NC	
AB13 VDD_3.3V AB14 NC AB15 VDD_2.5V AB16 NC AB17 VDD_3.3V AB18 NC AB19 VDD_2.5V AB20 NC	AB11	VDD_2.5V	
AB14 NC AB15 VDD_2.5V AB16 NC AB17 VDD_3.3V AB18 NC AB19 VDD_2.5V AB20 NC	AB12	TEST_IN	
AB15 VDD_2.5V AB16 NC AB17 VDD_3.3V AB18 NC AB19 VDD_2.5V AB20 NC	AB13	VDD_3.3V	
AB16 NC AB17 VDD_3.3V AB18 NC AB19 VDD_2.5V AB20 NC	AB14	NC	
AB17 VDD_3.3V AB18 NC AB19 VDD_2.5V AB20 NC	AB15	VDD_2.5V	
AB18 NC AB19 VDD_2.5V AB20 NC	AB16	NC	
AB19 VDD_2.5V AB20 NC	AB17	VDD_3.3V	
AB20 NC	AB18	NC	
	AB19	VDD_2.5V	
	AB20	NC	
ADZI VUU_3.3V	AB21	VDD_3.3V	

Table 8. Pinout	t by Ball Pin Numb	er - Cont'd

Ball Pin #	Pin Name	
AB22	TEST_IN	
AB23	NC	
AB24	NC	
AB25	NC	
AB26	NC	
AC1	STiMF[6]	
AC2	CSTo/LOSo[6]	
AC3	STiCLK[7]	
AC4	CSTi/LOSi[7]	
AC5	NC	
AC6	NC	
AC7	TEST_IN	
AC8	TEST_IN	
AC9	TEST_OUT	
AC10	TEST_IN	
AC11	NC	
AC12	NC	
AC13	NC	
AC14	TEST_OUT	
AC15	NC	
AC16	TEST_IN	
AC17	NC	
AC18	NC	
AC19	NC	
AC20	NC	
AC21	NC	
AC22	NC	
AC23	TEST_OUT	
AC24	NC	
AC25	NC	
AC26	NC	
AD1	SToMF[6]	
AD2	DSTi[7]	
AD3	STiMF[7]	
AD4	NC	
AD5	NC	
AD6	TEST_IN	
AD7	NC	
AD8	TEST_IN	

Ball Pin #	Pin Name
AD9	NC
AD10	NC
AD11	NC
AD12	NC
AD13	TEST_IN
AD14	NC
AD15	TEST_IN
AD16	NC
AD17	TEST_IN
AD18	TEST_OUT
AD19	NC
AD20	NC
AD21	NC
AD22	NC
AD23	NC
AD24	NC
AD25	TEST_IN
AD26	TEST_IN
AE1	SToCLK[7]
AE2	DSTo[7]
AE3	TEST_IN
AE4	NC
AE5	NC
AE6	NC
AE7	NC
AE8	NC
AE9	TEST_IN
AE10	TEST_OUT
AE11	TEST_IN
AE12	TEST_OUT
AE13	TEST_IN
AE14	NC
AE15	TEST_IN
AE16	TEST_OUT
AE17	TEST_IN
AE18	NC
AE19	NC
AE20	NC
AE21	NC

Ball Pin #	Pin Name							
AE22	NC							
AE23	NC							
AE24	NC							
AE25	NC							
AE26	TEST_IN							
AF1	CSTo/LOSo[7]							
AF2	SToMF[7]							
AF3	NC							
AF4	NC							
AF5	TEST_IN							
AF6	TEST_OUT							
AF7	TEST_IN							
AF8	NC							
AF9	TEST_IN							
AF10	NC							
AF11	TEST_IN							
AF12	NC							
AF13	TEST_IN							
AF14	NC							
AF15	NC							
AF16	TEST_IN							
AF17	NC							
AF18	NC							
AF19	NC							
AF20	NC							
AF21	NC							
AF22	NC							
AF23	NC							
AF24	NC							
AF25	NC							
AF26	NC							

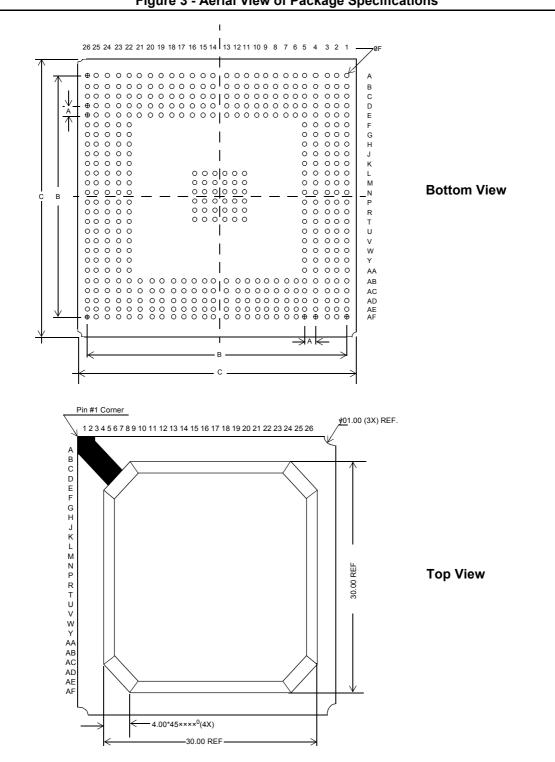
3.2.2 Pin Diagram

The package is a 456 ball Plastic Ball Grid Array (PBGA). It has 420 signal balls and 36 balls for ground (VSS) and thermal conduction at the center. The outside dimensions are 35mm x 35mm. The pin pitch is 1.27mm.

	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21	22	23	24	25	26
A	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
3	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
;	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
)	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
	0	0	0	0	0								1									0	0	0	0	0
i	0	0	0	0	0								1									0	0	0	0	0
1	0	0	0	0	0								1										0			
		0											1										0			
C I		0											,										0			
		0											0										0			
1		0											0										0			
!		_0											0										0			
		0											0										0			
2		0											0										0			
		0									0	0	0	0	0	0							0			
)		0											ہ ہ										0			
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/		0											1										0			
,		0											1 1										0			
A		0				\sim			\sim		0															
в																							0 0			
C																							0			
D																							0			
E													,										0			
F	0	U	U	U	U	U	U	U	U	U	U	U	0	U	U	U	U	0	U	U	U	U	U	U	U	U

Figure 2 - PCB Pad Diagram for 35mm x 35mm PBGA (JEDEC MO-151)

3.2.3 Package Specifications





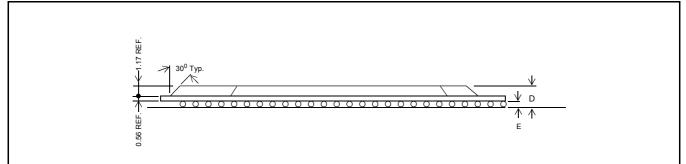


Table 9 - Package Dimensions

DIM	MIN	MAX	NOTES
A	1.27 ((REF)	solder ball grid pitch
В	31.75	(REF)	
С	34.80	35.20	
D	2.20	2.46	
E	0.50	0.70	stand-off height
F	0.60	0.90	solder ball diameter

Notes:

1) Dimensions are given in millimeters.

2) 456-pin BGA package complies to JEDEC Standard MO-151.

4. Module Functional Descriptions

As shown in Figure 1, "MT90520 Block Diagram," on page 12, the MT90520 consists of the following major components: Microprocessor Interface Module, External Memory Interface Module, TDM Interface Module, UTOPIA Interface Module, TX_SAR Module, RX_SAR Modules (consisting of the UDT RX_SAR, SDT RX_SAR, and Data RX_SAR), the Clock Management Module, and the Test Interface (JTAG) Module. This section describes each module in detail.

4.1 Microprocessor Interface

The microprocessor interface permits an external microcontroller to access registers and internal memories within the MT90520 device. In addition, this interface provides the microcontroller with access to the external memory (synchronous ZBT SRAM) connected to the MT90520 device.

The MT90520 microprocessor interface is compatible with both Intel and Motorola processors. The user selects the mode of operation of the internal CPU block via the Intel/Motorola pin.

The synchronous microprocessor interface supports word (i.e., 16-bit) data accesses only. Although all microprocessor accesses to the device are word-wide, CPU addressing of the MT90520 is on a byte-wide basis. There is a 20-bit address bus between the microcontroller and the MT90520 interface, featuring address lines CPU_ADD[20] to CPU_ADD[1]. The virtual CPU_ADD[0] bit would select between high and low bytes in a word. The AEM (Access External Memory) pin is effectively address line CPU_ADD[21] (or any higher address line selected by the user) and determines if the CPU is accessing the internal registers and memories of the MT90520 (AEM = '0') or the external memory (AEM = '1').

All registers within the MT90520 device are accessed (for reads or writes) with fixed low latency. However, there is a variable delay between a CPU access and the successful completion of an access to a memory, whether internal to the device, or within external memory. In order to reduce this latency, the MT90520 supports indirect accesses to internal and external memory via indirection registers. The user can designate a memory address which is to be written or read, along with the data to be written to that memory location, and then initiate an indirect memory access. The CPU must then wait for the access to be completed by either polling a register bit (waiting for the ACC bit within the High Address Indirection Command Register at byte address 0006h to be cleared) or, if the service request was enabled, by waiting for an interrupt. Then, if the access was a read, the user can read the accessed data from the Indirection Data Register located at byte address 0008h. More information about the timing of CPU accesses can be found in Section 7.2.1 on page 150.

Interrupt signals from the various modules of the MT90520 are gated together within the microprocessor interface module to produce a single interrupt request signal, IRQ, which is presented to the CPU. There is a status register within the microprocessor interface module indicating which module of the MT90520 generated the interrupt request. As well, the microprocessor interface module contains an interrupt enable register which may be programmed by the user to enable or disable interrupt sources. Details regarding interrupt handling within the MT90520 are given in Section 4.1.2.

4.1.1 Global Reset

During a hardware reset (when the RESET pin is driven low), the CPU-accessible registers of the MT90520 go to their respective reset states, as indicated in the register descriptions of Section 6.2. At that time, the RESET bit in the Chip Wide Reset Register (CWRR) at 0000h is set high, "latching" the reset state. No registers other than the CWRR can be accessed until the RESET bit is cleared. The steps to reset and restart the MT90520 are therefore:

- 1. Assert hardware reset by driving the RESET pin low, or initiate a software reset by writing 0001h to the CWRR at byte address 0000h.
- 2. After at least 100 ns, remove hardware reset.
- 3. After at least 2 µs, clear the CWRR (de-assert software reset).
- 4. Write other MT90520 registers. (Note that configuration bits must generally be programmed before setting process enable bits.)

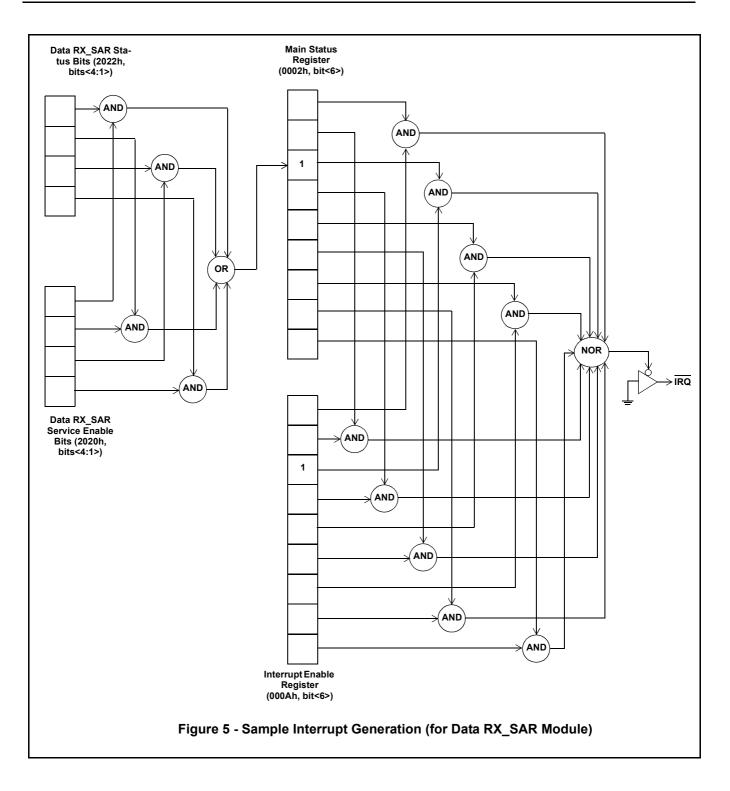
4.1.2 CPU Interrupts

The CPU interrupt mechanism works in a common way for all modules. Each module of the MT90520 has a status register and a service request enable register. One or more additional status-related registers may also be located within a module's address space.

When a status bit is asserted, the corresponding service enable bit is checked. If the bit is set, the module's service request will be raised. The service request of the module will be asserted and stay high as long as any one of the status/service enable pairs remains asserted.

This module's service request is sent to the device's Main Status Register (0002h). Within the microprocessor block, there is an Interrupt Enable Register, located at byte address 000Ah. If any of the individual module service requests is high, the corresponding interrupt enable bit is checked. If the appropriate interrupt enable bit is set, the CPU module generates a global interrupt by driving the IRQ pin low. Note that the IRQ pin is tristated when there is no active interrupt source. Refer to Figure 5 for an example of how an interrupt is generated within the MT90520.

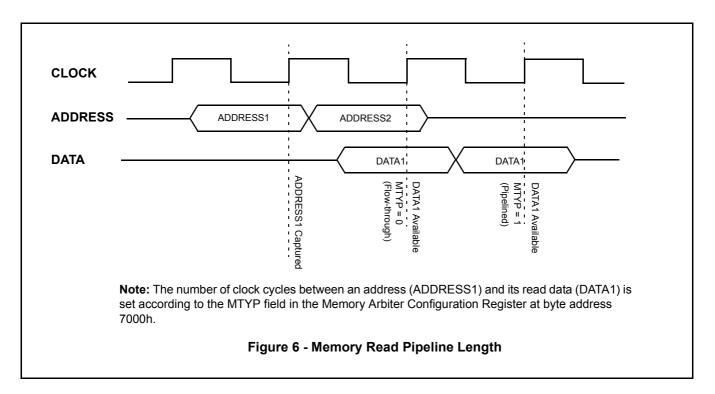
Note that some of the modules within the MT90520 feature an additional level of interrupt masking. The memory- and register-based interrupt mechanisms for these modules (UDT RX_SAR, SDT RX_SAR, and TDM) are explained in the module descriptions for the blocks later in this document.

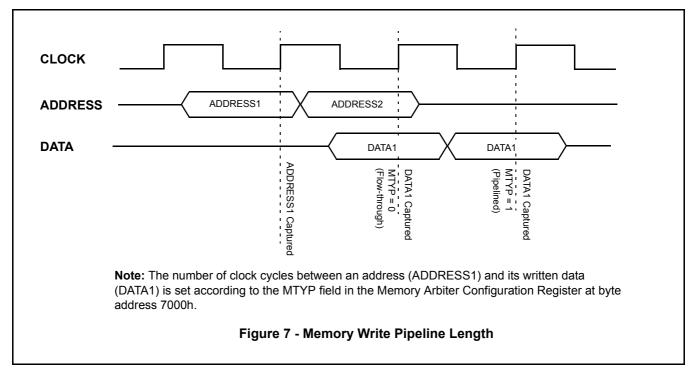


4.2 External Memory Interface

The external memory interface module of the MT90520 provides access to external memory devices by various MT90520 modules (i.e., TDM, TX_SAR, UTOPIA, SDT RX_SAR, Data RX_SAR) and by the CPU.

The MT90520 can interface with both the pipelined and flow-through types of synchronous zero bus turnaround (ZBT) RAM. The difference between flow-through and pipelined memories is illustrated in Figure 6 and Figure 7. In the case of flow-through memory, read cycle data is available on the next rising clock edge after the address is sampled by the memory. Contrarily, the data from pipelined memory is available two rising clock edges after the address is sampled by the memory. A flow-through write cycle requires that valid data be placed on the data bus before the next rising clock edge after the address is sampled. On the other hand, data must be valid before the second rising edge of the clock after the address is presented to memory in the case of pipelined RAM.





Accesses to/from the external memory are made on a word-wide (i.e., 16-bit) basis. 2 optional bits, MEM_DATA[17:16], can provide parity data regarding the external memory data. The external memory interface module of the MT90520 generates MEM_DATA[17] to represent the even parity bit over MEM_DATA[15:8]. Similarly, MEM_DATA[16] represents the even parity bit over MEM_DATA[7:0]. When data is read from external memory, the external memory interface module checks the parity bits of the data which is read. If there are parity errors, they are reported in the Parity Error Status Register at byte address 7004h. A service enable bit may be set to cause a CPU interrupt to be generated due to the occurrence of a parity error on reads of external memory data.

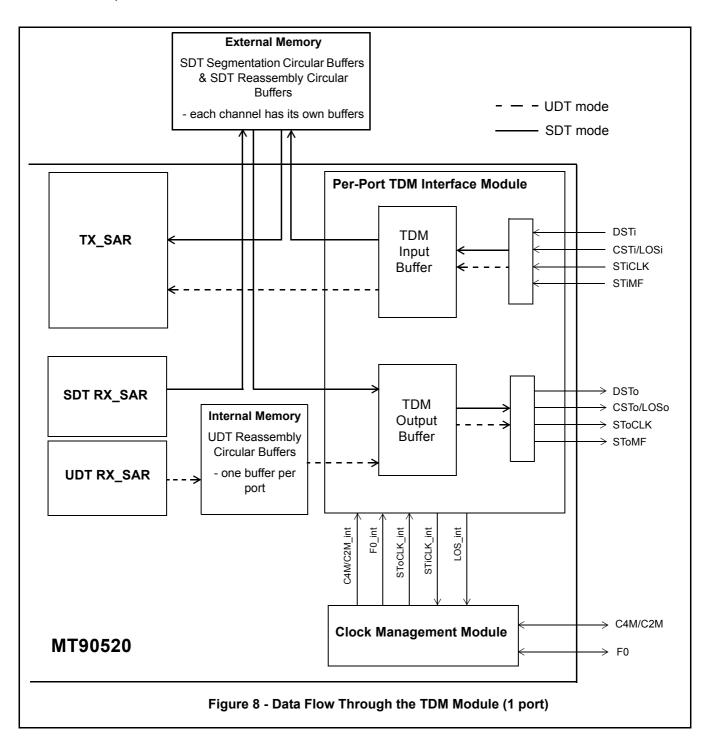
The external memory interface of the MT90520 supports up to 1 Mword of external memory. The configuration is programmable via the Memory Arbiter Configuration Register at byte address 7000h, and some of the possible configurations are listed in Table 10 below:

Number of Memory Banks	Maximum Size of Each Memory Bank (words)	Maximum Total Memory Size (words)
1	1 M	1 M
2	512 K	1 M
4	256 K	1 M

Table 10 -	Possible	Memory	Configurations
	1 0331010	wichitory	ooningurations

4.3 TDM Interface Module

The TDM Interface module of the MT90520 device is designed to interface to a time division multiplexed backplane bus, to external framers, and to external line interface units (LIUs). Thus, the TDM module can interface with buses which carry Nx64 kbps data or bit stream data. The TDM module is responsible for performing Structured Data Transfer with and without CAS, and Unstructured Data Transfer, as required to meet the CES specification, af-vtoa-0078.000.



4.3.1 Overview

4.3.1.1 Segmentation Direction

In the UDT mode of operation, the segmentation process samples serial data received on DSTi and converts it to an 8-bit parallel stream. Data is then written to the TDM Input Buffer on a byte-by-byte basis and is read by the TX_SAR module in 47-byte blocks. Upon assertion of the LOSi (CSTi/LOSi pin) input signal, "all ones" data is written to the TDM Input Buffer.

In the SDT mode of operation, serial data and CAS are sampled from the DSTi and CSTi inputs respectively, and converted to separate 8-bit parallel streams. Data and CAS are then written to the Segmentation Circular Buffers (one for each TDM channel), located in external memory. The data written to external memory is then read by the TX_SAR module.

4.3.1.2 Reassembly Direction

In the UDT mode of operation, data is written to internal UDT Reassembly Circular Buffers (one per port) by the UDT RX_SAR module. This data is read by the TDM module and written to the TDM Output Buffer. The data is then read out of this buffer, converted to a serial stream and sent to the TDM output, DSTo.

In the SDT mode of operation, data and CAS are written by the SDT RX_SAR module to SDT Reassembly Circular Buffers (one for each TDM channel) located in external memory. Data and CAS are then read from external memory, converted to separate serial streams, and sent to the TDM outputs, DSTo and CSTo.

4.3.2 Functional Description

4.3.2.1 Segmentation Process

The incoming data on DSTi[p] can be sampled using the corresponding external pin STiCLK[p], C4M/C2M (for SDT backplane mode), or, in special circumstances (e.g., UDT LOS condition), an internal clock generated by the Clock Management Module.

STiMF[p] is defined as an input pin and is supplied by a framer. This pin is not used in UDT mode; in SDT mode, the user may choose to use either frame pulses or multiframe pulses on STiMF.

In ST-BUS mode, data and CAS are sampled on the falling edge of the selected TDM input clock. In Generic mode, data and CAS can be sampled either on the rising edge or the falling edge of the TDM input clock, depending upon the user's selected configuration.

4.3.2.1.1 UDT Mode

Since there is no CAS in the UDT mode of operation, the CSTi/LOSi pin is used as an input for the Loss of Signal (LOS) line from an LIU. Loss of Signal polarity is specified by the user's programming the TDM_LOS_POL bit in the per-port TDM Control Register 1.

Serial data which is received on the DSTi pin need not be aligned to any framing. If a framing signal is provided (on STiMF[p]), it will be ignored. Data is sampled using the TDM input clock STiCLK[p]. However, if a Loss of Signal is detected, an internally generated clock can (depending on the user-configuration) be used to sample the data: upon a Loss of Signal condition, if the TDM_LOS_CLK bit is set (in the per-port TDM Control Register 1), the internal clock will be used to sample the data. If a Loss of Signal is detected and the TDM_LOS_CLK bit is not set, the STiCLK input will continue to be used as the sampling clock.

If no Loss of Signal is detected, the sampled data is written to the TDM Input Buffer, where it is read by the TX_SAR. On the other hand, upon detecting a Loss of Signal, the TDM module ignores the data input on DSTi and writes all ones data to the TDM Input Buffer, for transfer to the TX_SAR.

4.3.2.1.2 SDT Mode

Data and CAS, received on the DSTi and CSTi/LOSi pins, respectively, are sampled on edges of either STiCLK[p] or C4M/C2M. If the TDM port is configured to be in backplane mode, the common clock C4M/C2M is used; if not, STiCLK[p] is used. Similarly, if the TDM port is in backplane mode, the frame pulse F0 is used to indicate the beginning of a frame, whereas STiMF[p] is used if the port is configured to be in independent mode.

In ST-BUS applications, a falling edge on STiMF[p]/F0 indicates the beginning of a frame/multiframe pulse. In Generic applications (and depending on the configuration specified by the user via register bits), either a rising or falling edge on STiMF[p]/F0 indicates the beginning of a frame/multiframe pulse.

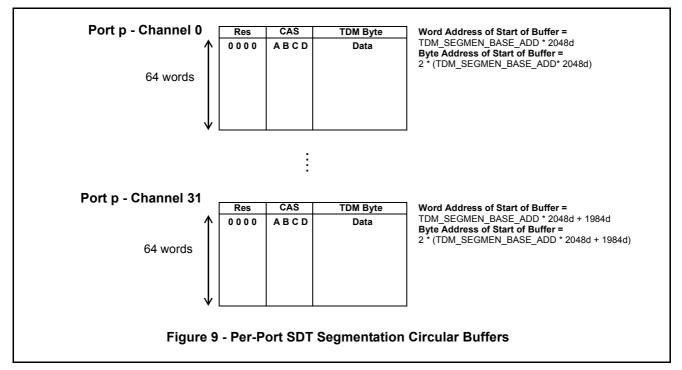
The sampled data and CAS bytes are written to the TDM Input Buffer. In Generic DS1-1.544MHz mode, the framing bit (aligned with the frame pulse) is discarded by the TDM block, and therefore not transmitted in the ATM cells. The TDM segmentation process then transfers data and CAS to the SDT Segmentation Circular Buffers, located in external memory.

SDT Segmentation Circular Buffers

The main function of the SDT Segmentation Circular Buffers is to store data and CAS, coming from the TDM Input Buffer, for transfer to the TX_SAR. The buffers are composed of 16-bit wide entries, each of which is composed of the following fields, as shown in Figure 9:

- **Res (Reserved)** bits<15:12> are unused.
- CAS bits<11:8> are used to store the CAS nibbles.
- TDM Data bits<7:0> store bytes of data received on DSTi.

The location of the SDT Segmentation Circular Buffers in external memory is determined by the Segmentation Circular Buffer Base Address (configured via TDM_SEGMEN_BASE_ADD in the per-port TDM Control Register 2). The SDT Segmentation Circular Buffer for the first channel of the DS1/E1 stream is located at the word address specified by TDM_SEGMEN_BASE_ADD. The second is located at TDM_SEGMEN_BASE_ADD + 64 words (128 bytes), etc., as seen in Figure 9. There is one circular buffer for each TDM channel and each buffer is 64 entries long.



4.3.2.2 Reassembly Process

In the reassembly direction, the outgoing data on DSTo[p] is driven with its clock reference on the external pin SToCLK[p] or the backplane clock, C4M/C2M.

In SDT mode, the frame/multiframe pulse signal is either SToMF[p] in independent mode or F0 in backplane mode. The frame pulses are not used in UDT mode.

In ST-BUS mode, data and CAS are driven out on DSTo and CSTo/LOSo, respectively, on the falling edge of SToCLK[p] or C4M/C2M. In Generic mode, data and CAS can be driven out on either the rising or falling edge of the outgoing clock, depending on the configuration selected by the user.

4.3.2.2.1 UDT format

In this format, the data is written by the UDT RX_SAR to a UDT Reassembly Circular Buffer (one per port) in internal memory. The TDM module retrieves this data and writes it to the port's TDM Output Buffer. The data is then converted to a serial stream and sent out on DSTo, driven on the selected edge of SToCLK[p]. SToMF[p] is kept low by the TDM module. The CSTo/LOSo pin drives out the value specified by the user in the TDM_REASS_LOS bit (programmed in the per-port TDM Control Register 3).

In the case of an underrun, the TDM reassembly process continues to read from the port's internal circular buffer, but ignores the actual data read and instead writes "all ones" data to the TDM Output Buffer. The underrun detection is performed by the UDT RX_SAR. See Section 4.6.1.5.1 and Section 4.6.2.3 for more details.

4.3.2.2.2 SDT format

In SDT mode, data and CAS are written to the SDT Reassembly Circular Buffers in external memory by the SDT RX_SAR (one buffer per channel). The data is then extracted from the SDT Reassembly Circular Buffers by the SDT TDM reassembly process and transferred to the per-port TDM Output Buffers.

Data and CAS are read out of the TDM Output Buffer, converted to separate bit streams and driven out on DSTo and CSTo/LOSo, on the selected edge of the TDM clock (SToCLK[p] if the device is in independent mode, or the common clock C4M/C2M if the device is in backplane mode). In DS1-1.544MHz mode, no framing bit is received in the ATM cells. Therefore, when the time comes to send out a framing bit (aligned with the frame pulse), the DSTo line is tristated for the duration of that bit.

The user can select either a multiframe or a frame pulse to be sent out on SToMF[p] by setting the TDM_PULSE_SEL bit (in the per-port TDM Control Register 1). However, if the device is in backplane mode, only frame pulses can be sent out on the common frame pulse pin, F0. The user can also select the format of the frame/multiframe pulse by setting the polarity control bit (TDM_PULSE_POL in TDM Control Register 1). The multiframe or the frame pulse is driven out on the selected edge of the appropriate TDM clock.

SDT Reassembly Circular Buffers

The main function of the SDT Reassembly Circular Buffers is to store reassembled TDM data and CAS for output onto the TDM bus. These circular buffers, which are located in external memory, are composed of 16-bit wide entries, each of which is composed of the following fields, as shown in Figure 10:

- **MF** multiframe indicator; this bit is used only when a VC is carrying CAS data (if a VC isn't carrying CAS, the MF bits are always zero).
- **Res** reserved field; this field always contains a zero.
- **Turn** this field contains a copy of the two most-significant bits of the SDT RX_SAR write pointer for the VC. These bits are used by the TDM module for underrun detection.
- **CAS** If CAS data is being processed, this field contains the nibble of data which was last received by this channel (i.e., in the previous multiframe). CAS data is repeated for an entire multiframe (i.e., 24 consecutive entries in DS1 case, 16 consecutive entries in E1 case).
- **TDM Byte** This field contains the TDM data bytes which are extracted from received cells. If dummy cells have been inserted, this field contains the value of the dummy data programmed by the user.

The size of the SDT Reassembly Circular Buffers is variable, and there is one buffer for each TDM channel. For more details regarding fields of the SDT Reassembly Circular Buffers, refer to page 79.

MF	Res	Turn	CAS	TDM Byte
0	0	01	X X X X	XXXXXXXX
0	0	01	XXXX	X X X X X X X X X
0	0	0 1	X X X X	X X X X X X X X X
0	0	0 1	X X X X	X X X X X X X X X
0	0	0 1	X X X X	X X X X X X X X X
0	0	01	X X X X	X X X X X X X X X
0	0	0 1	X X X X	X X X X X X X X X
0	0	0 1	X X X X	X X X X X X X X X
0	0	01	X X X X	X X X X X X X X X
0	0	01	X X X X	X X X X X X X X X
0	0	01	X X X X	*****
0	0	01	X X X X	X X X X X X X X X
1	0	01	ABCD	00101010
0	0	0 0	X X X X	x x x x x x x x x
0	0	0 0	XXXX	X X X X X X X X X
0	0	0 0	X X X X	X X X X X X X X X
0	0	0 0	X X X X	X X X X X X X X X
0	0	0 0	XXXX	XXXXXXXX
0	0	0 0	X X X X	X X X X X X X X X
0	0	0 0	X X X X	*****
0	0	0 0	XXXX	XXXXXXXX

TDM SDT Reassembly Control Structure

Each TDM SDT Reassembly Control Structure is used to determine which TDM output channels of a particular port are valid, which ones are idle and whether to report underruns on particular channels. There is one entry per channel and one Control Structure per port. The TDM SDT Reassembly Control Structures are located in internal memory at byte addresses A0000h + p*800h. The format of the 16-bit entries is shown in Figure 11.

The Reassembly Circular Buffer Address field in each entry tells the hardware where the reassembly data and CAS are located (points to the location of the per-channel SDT Reassembly Circular Buffers in external memory). These addresses in external memory are formed using the TDM_REASS_BASE_ADD field (located in TDM Control Register 3) and the addresses programmed in the TDM SDT Reassembly Control Structure. Refer to Table 11 for more information on how the addresses are formed.

Data Sheet

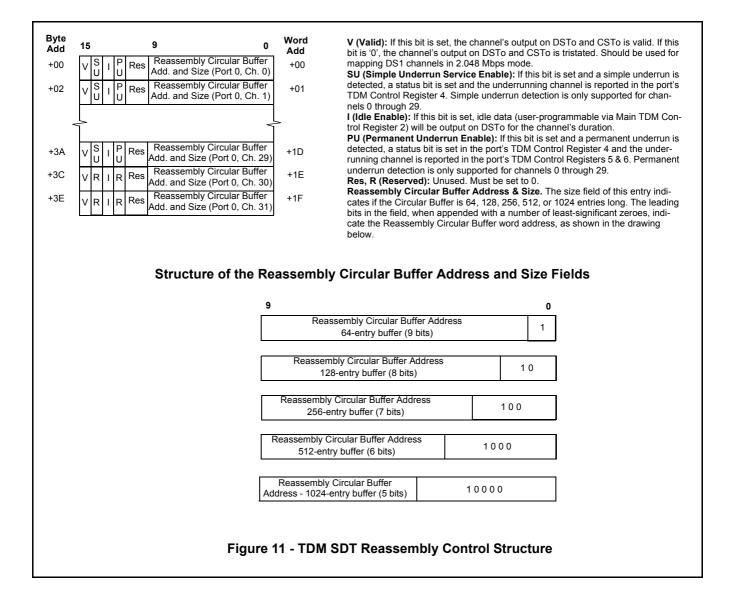


Table 11 - Formation of the Reassembly Circular Buffer Base Address

Buffer Size	Address to External Memory
64 entries	{TDM_REASS_BASE_ADD, Reassembly Circ. Buffer Add. and Size<9:1>, 6'b0}
128 entries	{TDM_REASS_BASE_ADD, Reassembly Circ. Buffer Add. and Size<9:2>, 7'b0}
256 entries	{TDM_REASS_BASE_ADD, Reassembly Circ. Buffer Add. and Size<9:3>, 8'b0}
512 entries	{TDM_REASS_BASE_ADD, Reassembly Circ. Buffer Add. and Size<9:4>, 9'b0}
1024 entries	{TDM_REASS_BASE_ADD, Reassembly Circ. Buffer Add. and Size<9:5>, 10'b0}

Underrun Detection in SDT Mode

The SDT TDM reassembly process reads data which was written to the SDT Reassembly Circular Buffers by the SDT RX_SAR block. Because the SDT RX_SAR and the TDM module don't operate at the same rate (i.e., data is written to the buffers based on the cell arrival rate while data is read from the buffers at a constant rate determined by the TDM output clock rate), there is a possibility of underruns. The SDT TDM reassembly process therefore performs underrun detection, on channels 0 through 29. Underrun detection is not available on channels 30 and 31. The SDT TDM reassembly process compares the two most significant bits of the TDM

channel's read pointer with the two bits called "turn" which are stored in the SDT Reassembly Circular Buffer entries:

1- If the comparison is true (i.e., 2 MSB of the read pointer = turn), there is no underrun.

2- If the previous comparison is false, a second comparison (2 MSB of the read pointer = turn + 1 or 2 MSB of the read pointer = turn + 2) is performed. If this comparison is true, a simple underrun has occurred. The REPLAY_NSILENCE bit is checked: if it is set, the reassembly process keeps reading (old data) from the circular buffer. If it is not set, a silence byte (as configured in Main TDM Control Register 1) is written to the port's TDM Output Buffer for the underrunning channel. If the SU bit is set in the TDM SDT Reassembly Control Structure, a simple underrun is reported in the port's TDM Control Register 4.

3- If the two previous comparisons are false, a third comparison (2 MSB of the read pointer = turn + 3) is performed. If this comparison is true, a permanent underrun has occurred. The REPLAY_NSILENCE bit is checked: if it is set, the reassembly process keeps reading (old data) from the circular buffer. If it is not set, a silence byte (as configured in Main TDM Control Register 1) is written to the port's TDM Output Buffer for the underrunning channel. If the PU bit is set in the TDM SDT Reassembly Control Structure, a permanent underrun is reported in the port's TDM Control Registers 4, and 5 or 6.

Once a permanent underrun is detected on a TDM channel, underrun data (silence or old buffer data) will be sent out on DSTo[p] until the channel's permanent underrun bit is cleared in TDM5_Pp or TDM6_Pp.

4.3.2.3 TDM Loopback

There are two loopback modes implemented in the TDM module.

4.3.2.3.1 TDM Low-Latency Loopback

The first loopback mode is TDM low-latency loopback, and is enabled by setting the TDM_LOW_LATENCY_LPBK bit in a port's TDM Control Register 1. When this bit is set, the TDM data coming in on DSTi is directly output on the DSTo output line of the same TDM port, with a delay through the device of about two TDM clock cycles.

4.3.2.3.2 TDM Circular Buffer Loopback (SDT Mode)

The second loopback is performed at the Circular Buffer level. It can only be used in SDT mode and it is selected by setting the TDM_CIR_BUF_LPBK bit in a port's TDM Control Register 1. In this loopback mode, the TDM SDT reassembly process uses the TDM_SEGMEN_BASE_ADD (in the per-port TDM Control Register 2) as the base address for the SDT Reassembly Circular Buffers in external memory. This loopback mode can be used to:

- loop back an entire stream
- loop back certain channels while tristating others
- switch the data between various channels (within the same port)

To determine which channels to loop back and their order, the TDM reassembly process reads the TDM SDT Reassembly Control Structure (refer to Figure 11 on page 45), which should be programmed in the following manner:

- V The valid bits should be set for those channels which should be output on DSTo/CSTo. If the valid bit for a channel is not set, the output channel is tristated.
- SU, I, and PU bits These bits should be cleared.
- Reassembly Circular Buffer Address bits -
 - **bits<9:6>** These bits should be cleared as they are not used in loopback mode.
 - **bits<5:1>** These five bits identify the input channel whose data is being output on the timeslot associated with this entry.

• **bit<0> -** This bit must be set to '1' (the SDT Segmentation Circular Buffers onto which the SDT Reassembly Circular Buffers are mapped always contain 64 entries).

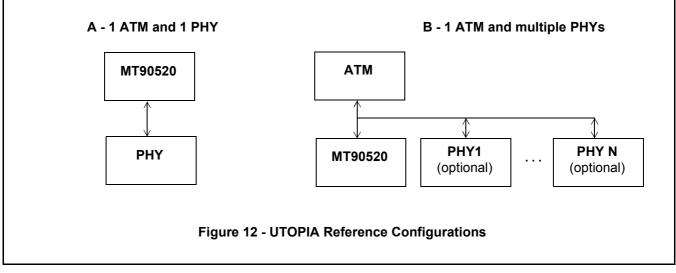
It is also possible to loop the TDM data back by manually programming the TDM module to look for reassembly data in the Segmentation Circular Buffers. The user can then switch channels between various ports.

4.4 UTOPIA Interface Module

The MT90520's UTOPIA interface is compliant with the ATM Forum Level 2 specification for the UTOPIA interface (af-phy-0039.000). The Level 2 specification is backwards-compatible with the Level 1 specification (af-phy-0017.000); therefore, the MT90520 interface also supports Level 1 applications. The UTOPIA interface is capable of emulating either a PHY device or an ATM device.

The MT90520's UTOPIA interface addresses reference configuration A of Figure 12 when it is operating in ATM mode. This means that the interface communicates with one, and only one, PHY. When the UTOPIA module is operating in PHY mode, it addresses reference configuration B of Figure 12.

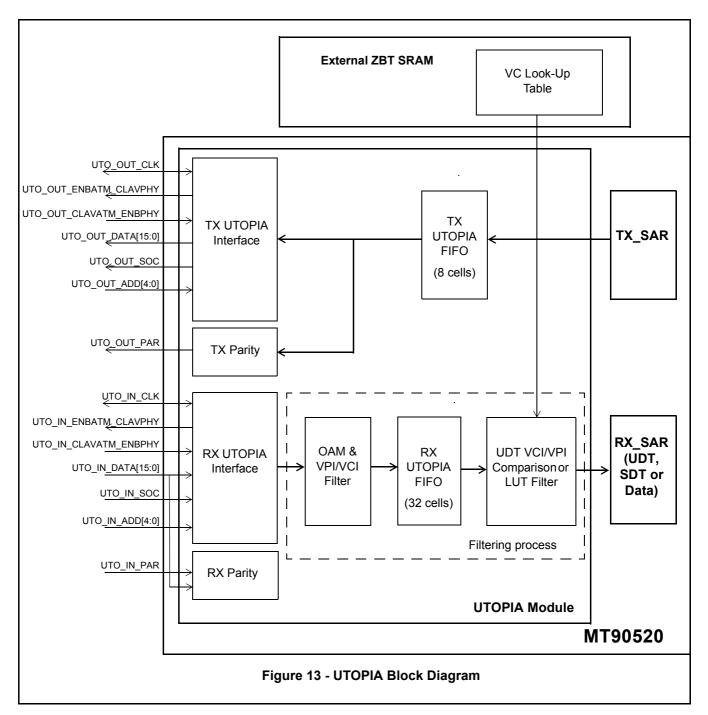
The UTOPIA module does not address multi-PHY (MPHY) operation in ATM mode, nor does it address the use of multiple CLAV signals.



The UTOPIA interface allows the user to choose between an 8-bit or 16-bit interface. The 8-bit interface is only specified to a maximum UTOPIA clock-rate of 33 MHz (in the UTOPIA Level 2 specification); however, the MT90520 interface is capable of operating up to 52 MHz.

The user can choose to have the UTOPIA interface emulate a PHY device or an ATM device. When the MT90520 is operating in PHY mode, it is capable of being polled; this allows the ATM device accessing the MT90520 to operate in multi-PHY mode.

The UTOPIA interface contains a loopback configuration, where data received on the incoming port can be looped back to the outgoing port. This is implemented to assist developers with debug and diagnostics.



4.4.1 Functional Description

4.4.1.1 Segmentation Direction

4.4.1.1.1 TX UTOPIA Interface

The TX UTOPIA Interface's primary function is to transmit ATM cells to devices outside the MT90520 chip, according to the ATM Forum's Level 2 UTOPIA specification. The port can operate in either ATM or PHY mode. When the port is operating in ATM mode, it complies with the transmit portion of the ATM Forum specification; when operating in PHY mode, it complies with the receive portion of the specification. Additionally, when operating in PHY mode, the TX UTOPIA Interface complies with the receive sub-section of the multi-PHY section of the ATM Forum specification.

The TX UTOPIA Interface can be configured to operate in a variety of modes. The TX UTOPIA can operate in PHY or ATM mode, using Level 1 or Level 2 mode, with a 16-bit or 8-bit interface. The user selects between these different modes by programming the UTOPIA Configuration Register at byte address 4000h.

When operating in 16-bit mode, the cells transmitted by the interface are 54 bytes long, whereas when operating in 8-bit mode, the cells transmitted by the interface are 53 bytes long. When operating in 8-bit mode, the upper 8 bits of the outgoing data bus (UTO_OUT_DATA[15:8]) are not used.

When operating in Level 1 mode, the ATM Forum only specifies UTO_OUT_CLK to a maximum clock speed of 25 MHz. The user, however, is able to use the interface at speeds of up to 52 MHz, if desired.

4.4.1.1.2 TX UTOPIA FIFO

The main role of the TX UTOPIA FIFO is to act as a buffer between the TX_SAR and the TX UTOPIA Interface. This buffer is necessary because it is possible for the UTOPIA bus to be halted (i.e., not able to transmit) while the TX_SAR continues to assemble cells. This is an 8-cell deep FIFO.

4.4.1.1.3 TX Parity

The TX Parity sub-module generates an odd parity bit over the outgoing UTOPIA data (UTO_OUT_DATA[7:0] in 8-bit mode, and UTO_OUT_DATA[15:0] in 16-bit mode). The resulting parity bit (UTO_OUT_PAR) is transmitted to the external device to which the TX UTOPIA Interface is connected.

4.4.1.2 Reassembly Direction

4.4.1.2.1 RX UTOPIA Interface

The primary function of the RX UTOPIA Interface is to receive ATM cells (in accordance with the ATM Forum's Level 2 UTOPIA specification), from devices which are external to the MT90520 chip. The interface can operate in either ATM or PHY mode. When the interface is operating in ATM mode, it complies with the receive portion of the ATM Forum specification. When the interface operates in PHY mode, it complies with the transmit portion of the ATM Forum specification. In addition, when operating in PHY mode, the RX UTOPIA Interface complies with the transmit sub-section of the multi-PHY section of the ATM Forum specification.

In the same manner as the TX UTOPIA Interface, the RX UTOPIA Interface can be configured to operate in a variety of modes. It can operate in PHY or ATM mode, in Level 1 or Level 2 mode, with a 16-bit or an 8-bit interface. The user selects between these different modes by programming the UTOPIA Configuration Register (at byte address 4000h).

When operating in 16-bit mode, the cells received by the interface are 54 bytes long; when operating in 8-bit mode, the cells being received are 53 bytes long. When operating in 8-bit mode, the upper 8 bits of the incoming data bus (UTO_IN_DATA[15:8]) are not used.

When operating in Level 1 mode, the ATM Forum only specifies UTO_IN_CLK to a maximum clock speed of 25 MHz. However, the user is able to use the interface at speeds of up to 52 MHz, if desired.

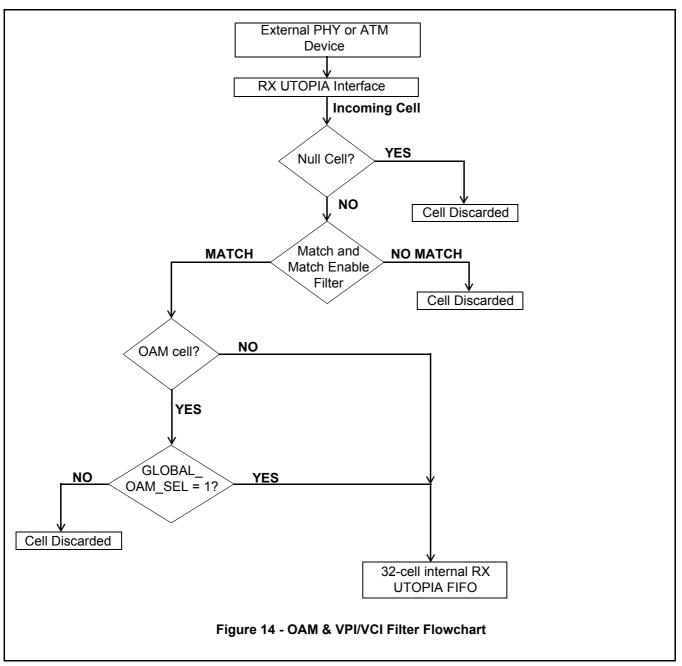
4.4.1.2.2 OAM & VPI/VCI Filter

The role of the OAM & VPI/VCI filter sub-module is to limit unnecessary VPI/VCI comparison and look-up table accesses. The filter allows only certain cells to be written into the Receive UTOPIA FIFO of the MT90520 and discards unwanted cells. Unwanted cells fall into three categories:

- null cells (i.e., cells with VPI = 0 and VCI = 0); these cells are automatically discarded.
- cells whose VPI and/or VCI fall outside the Match and Match Enable filters which are configured via the registers at byte addresses 4008h 400Ch.
- OAM cells (i.e., cells where the most significant bit of the PTI field in the cell header is set). OAM cells are discarded if the user clears the GLOBAL_OAM_SEL bit in the UTOPIA Configuration Register at 4000h

The filter considers the headers of cells received at the RX UTOPIA Interface; if cells pass through the Match and Match Enable filters successfully, the "accepted" cells are written to the RX UTOPIA FIFO.

The operation of OAM & VPI/VCI filter sub-module can be summarized by the flow chart in Figure 14.



The header of the incoming cell is transferred from the RX UTOPIA Interface to the OAM & VPI/VCI filter. Once the header has been received, the VPI and VCI fields are examined. If all the bits of the VPI field and all the bits of the VCI field are equal to zero, the cell is a filler cell (i.e., a null cell), and it is discarded. Otherwise, the processing of the cell continues in the Match and Match Enable filter.

In the Match and Match Enable filter, the cell's VPI field is examined first (all 12 bits, including the GFC). A bit-bybit comparison of the VPI is performed using the contents of both the VPI Match Register (400Ah) and the VPI Match Enable Register (400Ch). If a bit value in the VPI Match Enable Register is '0', no comparison is performed on the corresponding bit in the VPI Match Register (and the bit is automatically accepted). If a bit value in the VPI Match Enable Register is '1', the comparison result is only true if the received VPI bit and the corresponding VPI Match Register bit are identical. The cell is only processed further if each of the 12 bitcomparisons produces a true result. Otherwise the cell is discarded. If the VPI comparison is true, the same process is applied to the cell's VCI field, using the VCI Match Register (4006h) and the VCI Match Enable Register (4008h). The cell is only processed further if each of the 16 bit-comparisons produces a true result. Otherwise the cell is discarded.

If the VCI comparison is true, the most significant bit of the PTI field in the cell header is examined to determine if the cell is identified as carrying OAM information. If the received cell is not an OAM cell, it is automatically sent to the internal RX UTOPIA FIFO. If the received cell is an OAM cell and the GLOBAL_OAM_SEL bit in the UTOPIA Control Register is set, the cell is sent to the internal RX UTOPIA FIFO; OAM cells that are sent to this internal FIFO are treated as non-CBR data cells and are eventually sent to the Receive Data Cell Buffer in external memory. If the received cell is an OAM cell, but the GLOBAL_OAM_SEL bit is cleared, the cell is discarded.

Note: The VPI/VCI Match and Match Enable filter serves two important purposes. It can eliminate non-unique look-up table entries (this is important, because the look-up-table space is smaller than the entire VPI/VCI space of 16M addresses), and it eliminates null cells. The Match and Match Enable filter can reduce the number of unnecessary look-up table accesses (and therefore unnecessary memory-access bandwidth) by eliminating cells with VPI/VCI combinations known not to be destined for the MT90520 device. The user is advised to set the VPI/VCI Match and Match Enable filter as narrowly as practical for the application.

4.4.1.2.3 RX UTOPIA FIFO

The primary role of the RX UTOPIA FIFO is to act as a buffer between the OAM & VPI/VCI Filter and the UDT VPI/VCI comparison and look-up table search sub-modules. This buffer is necessary because the RX UTOPIA Interface may be receiving cells while the next filtering modules are not yet ready to process them. The 32-cell deep FIFO therefore allows these cells to be stored until they can be processed.

4.4.1.2.4 UDT VCI/VPI Comparison and Look-up Table

This sub-module's primary function is to determine the destination of the cells; the module is responsible for determining to which of the RX_SARs (UDT, SDT or Data) cells should be directed. The RX_SARs are responsible for processing the received cells and transferring their contents to either a buffer in external memory or the TDM data bus.

UDT Operation

In the UDT case, the routing task is performed using a number of pre-defined match registers (one per port) which identify which cells are associated with a particular TDM port.

Up to twenty-eight (28) bits of the cell header may be used to perform this search: the GFC<3:0> field, the VPI<7:0> field, and the VCI<15:0> field. The 4-bit GFC field is only used when NNI-type cells are received. A global register bit (UNI_N_NNI in the UTOPIA Configuration Register) determines whether the GFC field is used in the search. Because the comparison sub-module operates as a pseudo-CAM, the incoming cell header is compared with all of the UDT search registers (4200h to 426Eh) simultaneously.

If the incoming cell is matched with a particular port, an additional comparison is performed to see whether the cell contains OAM data:

- If the cell contains OAM data (determined by the most significant bit of the PTI header field being set to '1') and the 'OAM_SEL' bit is set in the corresponding UDT VPI Register (located at 4202h + p*4h), the UTOPIA module sends the cell to the Data RX_SAR. The Data RX_SAR (if enabled) is responsible for copying the cell into the Receive Data Cell Buffer in external memory.
- If the cell is carrying OAM data but the user has selected not to process OAM cells for that port (i.e., 'OAM_SEL' bit for port = 0), the UTOPIA module discards the cell.
- If the cell is not carrying OAM data, the UTOPIA module sends the cell to the UDT RX_SAR for processing.

If external memory is present in the system configuration containing the MT90520, any received cells whose headers do not match those in the UDT search registers are passed to the look-up table sub-module and are processed as detailed in the SDT Operation section that follows. This additional processing is provided primarily to permit the reception of non-CBR data cells, and for additional OAM-cells (cells with VCI = 3h or VCI = 4h). This extra processing also allows the user to process both SDT and UDT cells simultaneously. If no

external memory is present, the cells with unmatched headers (after passing through the VPI/VCI comparison registers) are simply discarded.

SDT Operation

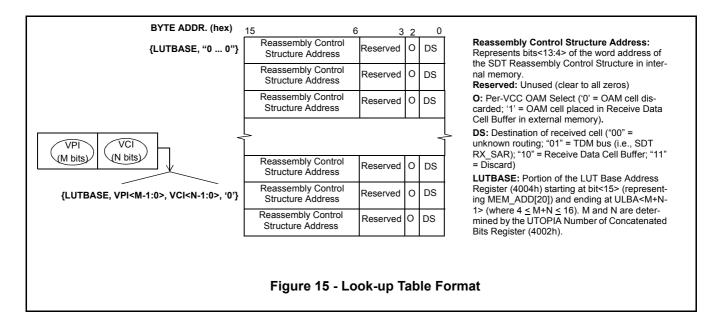
In the SDT case, the destination of the received cell is determined using a user-programmed look-up table. Unlike the UDT case, all 28 bits of the header are not used to perform the look-up. Rather, a VPI/VCI concatenation register (4002h) is provided for the user to choose how many bits of the cell header are to be used to form the look-up table addresses. The user selects up to 16 of the bits of the combined GFC/VPI and VCI fields to be used for the look-up table search. The look-up table itself is located in external memory, with each entry occupying one 16-bit word. As such, the external memory requirement for this structure is $2^{(VPI_bits + VCI_bits)}$ words.

- minimum: 2⁴ words (must use at least 4 bits from VCI field) = 16 words
- maximum: 2¹⁶ words (can use at most 16 bits from combined header fields) = 64 Kwords

Each successful look-up search provides two pieces of information:

- the destination of the received cell (e.g., TDM bus, Receive Data Cell Buffer)
- the address of the SDT Reassembly Control Structure associated with this VC (this field is ignored when the received cell is not a CBR-type cell).

Refer to Figure 15 for the structure of a look-up table entry.



Depending on the value of the DS field of a look-up table entry, the UTOPIA module can process the cell in one of the following ways:

- if DS = "00", and the global UKSEL bit is set (in the UTOPIA Configuration Register), the cell is sent to the Data RX_SAR for eventual storage in the Receive Data Cell Buffer in external memory
- if DS = "00", and the global UKSEL bit is cleared, the cell is discarded and the UTOPIA module simply starts
 processing the next cell
- if DS = "01", the cell as well as the SDT Reassembly Control Structure Address from the look-up table entry are sent to the SDT RX_SAR
- if DS = "10", the complete cell is sent to the Data RX_SAR. F4 level OAM cells (cells with VCI = 3 or VCI = 4) should be set to DS = "10"

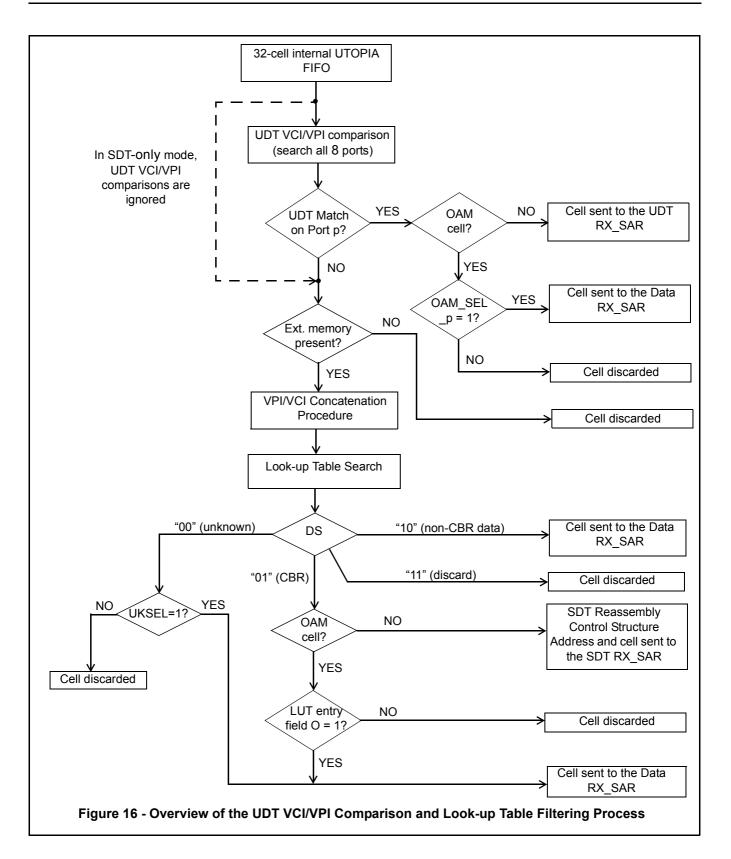
• if DS = "11", the cell is discarded and the UTOPIA module simply starts processing the next cell.

Refer to Figure 16 on page 55 for an overview of the complete UDT VCI/VPI comparison and look-up table searches.

4.4.1.2.5 RX Parity

The RX Parity sub-module's role is to calculate the odd parity bit over UTO_IN_DATA[15:0] (over UTO_IN_DATA[7:0] when operating in 8-bit mode). The module then compares the internally calculated value with the one supplied by the external system on UTO_IN_PAR. If the parity bits do not match, a counter is incremented in the UTOPIA Parity Mismatches Register (400Eh).

Data Sheet



4.5 TX_SAR Module

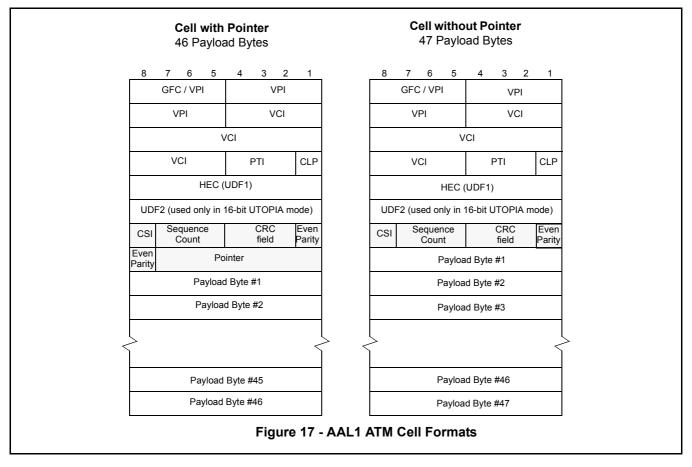
The TX_SAR modules of the MT90520 device (consisting of the CBR-handling TX_SAR and the non-CBR Data TX_SAR) are primarily responsible for organizing TDM data into ATM cells. Since the cells contain constant-bit-rate traffic, they must be assembled at a rate which is synchronized to the 8 plesiochronous TDM ports.

The TX_SAR generates AAL1 cells which may contain TDM data and CAS signalling information. In both the UDT and SDT modes of operation, the TX_SAR is capable of inserting SRTS clock recovery information into outgoing cells.

A secondary Data TX_SAR transfers non-CBR cells from a CPU-accessible cell buffer in external memory to the UTOPIA interface for transfer onto the ATM network.

4.5.1 ATM Overview

As mentioned above, the TX_SAR is responsible for the generation of AAL1 cells, in accordance with the formats set out in ITU-T I.363.1. There are two basic cell formats which are used in AAL1 systems: cells with pointers (used only in the Structured Data Transfer mode of operation) and cells without pointers (used in both the UDT and SDT modes of operation). When operating in the 8-bit UTOPIA mode of operation, AAL1 cells are 53 bytes long; when using the 16-bit UTOPIA mode of operation, AAL1 cells are 54 bytes long and feature an extra field, UDF2. The formats of the cell types are shown below in Figure 17. Note that the 46-byte or 47-byte payload in the cells may contain TDM data or CAS signalling information.



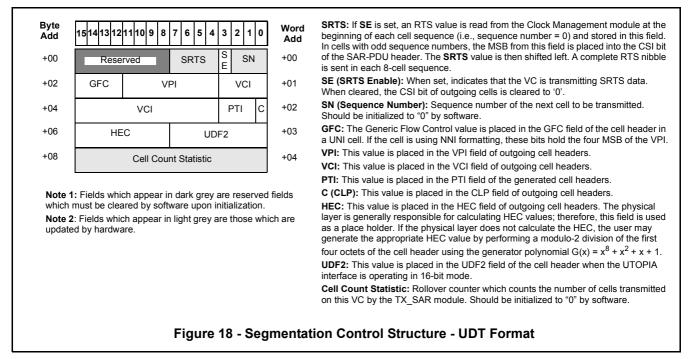
4.5.2 UDT Mode of Operation

In the UDT mode of operation, the TX_SAR is capable of generating and transmitting cells for 8 independent VCs, representing each of the 8 TDM ports of the MT90520 device.

4.5.2.1 Control Structure Configuration

The first step in setting up the TX_SAR for UDT operation is the configuration of a UDT Segmentation Control Structure, as shown in Figure 18.

There must be one control structure for each UDT VC that the TX_SAR is to transmit. A control structure may be located at any address within the internal memory space which is reserved for Segmentation Control Structures (starting at byte address 80000h). The TX_SAR hardware identifies the location of a particular control structure by reading the TX_SAR Pointer Table Base Register for the corresponding TDM port. These registers are located at byte addresses 1000h + p*2h, where p represents the particular port number. Within these registers, the user must configure the least-significant 14 bits to point to the word address of the start of a UDT Segmentation Control Structure in internal memory. As well, the TXCFG bits in the register must be set to "01" to indicate that the control structure being pointed to is formatted for UDT transmission.



All of the fields within the control structure are explained in the text accompanying Figure 18. Upon initialization, several of the fields within the UDT Segmentation Control Structure need to be explicitly configured by the user. The **GFC**, **VPI**, and **VCI** fields must be programmed to configure the header of the outgoing cells to contain the correct routing information. The user may also program the **PTI** and **CLP** fields to configure the networking properties for the cells on the VC. Additionally, the user can configure the **HEC** and **UDF2** fields of outgoing cells. The **HEC** field is used primarily as a place-holder since PHY devices are usually responsible for the generation of header error checking values. The value contained in the **UDF2** field is only transmitted in outgoing cells if the MT90520 is using a 16-bit UTOPIA interface. If the VC is going to be carrying RTS nibbles, the **SE** bit must be set, as detailed in the figure above. The remaining fields in the control structure should be cleared upon initialization.

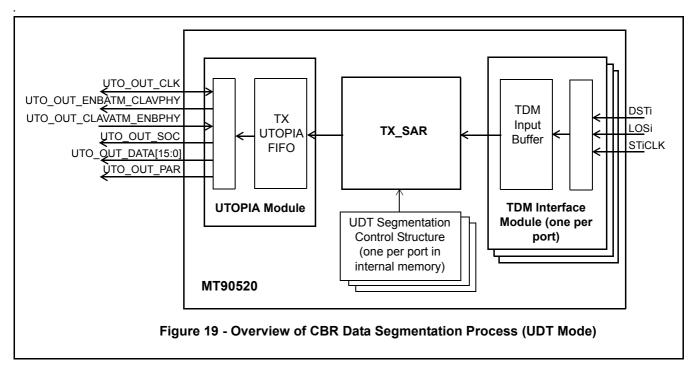
Once the control structure has been configured, the transmission of CBR cells can begin as soon as the TX_SAR is enabled, by setting the TXENB bit in the TX_SAR Master Enable Register at byte address 1044h.

4.5.2.2 Operation

Generally speaking, the generation of CBR cells in UDT mode is performed automatically by the TX_SAR, without any CPU intervention being required. The TDM module reads data from the TDM bus and stores it in 47-byte blocks in internal memory. When a block of memory is full, the TDM module sends an internal flag to the TX_SAR module, indicating that it is time to generate a cell. The TX_SAR prepends the 47-byte block of data with an AAL1 header byte consisting of an in-order sequence number and related protection fields. The resulting 48-byte block is then prepended with the 6-byte ATM cell header as configured via the fields in the UDT

Segmentation Control Structure for the VC. The complete cells are then transferred to the UTOPIA module for transmission onto the ATM network.

Figure 19 below shows the complete segmentation data path in UDT mode, from the incoming TDM data bus to the outgoing UTOPIA data bus.



4.5.3 SDT Mode of Operation

In the SDT mode of operation, the TX_SAR is capable of generating cells on multiple VCs, independent of the originating port on which the TDM data to be transmitted was received. Specifically, the TX_SAR is capable of generating cells for a maximum of 256 different VCs (the equivalent of 32 VCs originating from each of the TDM ports) in SDT mode. Unlike UDT mode, a single SDT VC does not need to transmit all of the data from a particular port. Instead, VCs can contain various combinations of channels, ranging from N=1 VCs to VCs carrying up to 128 channels, in accordance with the af-vtoa-0089.000 standard for AAL1 narrowband trunking.

4.5.3.1 Control Structure Configuration

4.5.3.1.1 SDT Segmentation Control Structures

There must be one control structure for each SDT VC that the TX_SAR is to transmit. The format for the SDT Segmentation Control Structures is shown in Figure 20. SDT control structures may be located at any address within the internal memory space (starting at byte address 80000h) which is reserved for Segmentation Control Structures.

Byte Add	151	413	12	11	10	9	8	7	6	5	4	3	2	1	0	Word Add
+00	Number of TDM Octets					Number of R Channels M					+00					
+02		Re Poi	ead ntei	r		R	w	F	ç	SR	тs		SN			+01
+04			Str	uct	ure	e Lo	eng	gth				F	R	Ν	N	+02
+06		Stru	ctu	re E	3οι	unc	lar	уP	oin	ter		S E	P S	P E	Ρ	+03
+08	Current CAS							C	Cur	ren	t TI	DM		•	+04	
+0A	Last							N	um	be	r of	CA	٩S		+05	
+0C	Cell Count Statistic								+06							
+0E	(GFC					V	PI VCI						+07		
+10				•	V	CI						PTI C			С	+08
+12			HE	С				UDF2						+09		
+14	Res	5						Circular Buffer 0 ss (bits<19:6>)					+0A			
+16	Res	S							Circular Buffer 1 ss (bits<19:6>)					+0B		
Minimum Structure Size - 22 bytes (1 channel) Maximum Structure Size - 276 bytes (128 channels)																
+110	Re	S	Se	gm Ba					cul (bi					6		+88
+112	Res	s	Se	gm	en	tati	on	Cir	`	ar	Bu	ffer	, 12	7		+89

Note 1: Fields which appear in dark grey are reserved fields which must be cleared by software upon initialization. **Note 2:** Fields which appear in light grey are those which are updated by hardware. Number of TDM Octets: Indicates the number of TDM octets required to fill the next cell of the corresponding VC. Initialize to 47d.

Number of Channels: Indicates the number of TDM channels in the VC associated with this control structure (possible values = 1d to 128d).

RM (Remainder): When set, this bit indicates that there is enough TDM data to create more than one cell in the current frame. Initialize to '0'.

Read Pointer: This value represents the location in the circular buffers from which the next TDM value will be read. Should generally be initialized to "0", but if the chip is supporting a large number of VCs, this field may be used to distribute cell generation over more than 1 frame. See "Read Pointer Field" on page 60 for more details.

W (Wait for Multiframe): When set, the TX_SAR module waits for the multiframe boundary to produce the first cell (seq. num = 0; pointer = 0).

F (First Cell): If set, indicates that the next cell is the first one to be sent for the current VC. Should be initialized to '1', except if the **Read Pointer** is used to scatter the cell generation over multiple frames (this bit should then be cleared).

SRTS: If **SE** is set, an SRTS value is read from the Clock Management module at the beginning of each cell sequence (SN = 0) and stored in this field. In cells with odd sequence numbers, the MSB from this field is placed into the CSI bit of the SAR-PDU header. The **SRTS** value is then shifted left.

SN (Sequence Number): Holds the sequence number of the next cell to be generated. Must be initialized to "0".

Structure Length: This field contains the length of the multiframe structure (payload substructure + signalling substructure). For non-CAS VCs, this field should be initialized to Number of Channels. For CAS VCs, this field = (Number of Channels)*m + roundup(Number of Channels/2) where m=24 for DS1 and 16 for E1.

M (Mode): "01" = (DS1 with CAS and **Number of Channels** = 1); "10" = (E1 with CAS and **Number of Channels** = 1); "11" = (E1 with CAS and **Number of Channels** = 2); "00" = all other cases.

Structure Boundary Pointer: Indicates the distance, in octets, between the last payload byte written and the next structure boundary. Initialize to "0".

SE (SRTS Enable): When set, indicates that the VC is transmitting SRTS data. When cleared, the CSI bit of outgoing odd-numbered cells is set to '0'. Only one VC per port may carry SRTS information.

PS (Pointer Sent): Used to ensure that only a single pointer cell is sent within an eight-cell sequence. Initialize to '0'.

PE (Pointer Enable): When set, a pointer cell will be generated once per 8-cell sequence. This bit must be cleared to '0' for single-channel VCs not transporting CAS, but set in all other cases.

P (Pointer Cell): Indicates that the next cell to be produced will be a pointer cell. Should be initialized to the same value as the PE bit.

Current CAS: When transporting CAS, this field is used to keep track of which circular buffer pointer to read next. Must be initialized to 0Ah.

Current TDM: Used to keep track of which circular buffer pointer to read next. Must be initialized to 0Ah.

Last: Contains the address (relative to word 0) of the last valid Segmentation Circular Buffer Base Address in the control structure. The formula for this field is: 09h + Number of Channels.

Number of CAS: Contains the size, in octets, of the signalling substructure. If CAS is not being transmitted, this field should be initialized to "0". Otherwise, the formula is: roundup(**Number of Channels**/2).

Cell Count Statistic: Rollover counter which counts the number of cells transmitted on this VC by the TX_SAR module. Initialize to "0".

GFC: The Generic Flow Control value is placed in the GFC field of cell headers in a UNI cell. If the cell is using NNI formatting, these bits hold the four MSBs of the VPI.

VPI: This value is placed in the VPI field of outgoing cell headers.

 $\ensuremath{\text{VCI}}$ This value is placed in the VCI field of the generated cell headers.

PTI: This value is placed in the PTI field of outgoing cell headers.

C (CLP): This value is placed in the CLP field of the cell headers.

HEC: This value is placed in the HEC (UDF1) field of outgoing cell headers. The physical layer is generally responsible for calculating HEC values; therefore, this field is used as a place holder. If the physical layer does not calculate the HEC, the user may generate the appropriate HEC value by performing a modulo-2 division of the first four octets of the cell header using the generator polynomial $G(x) = x^8 + x^2 + x + 1$.

UDF2: This value is placed in the UDF2 field of the cell header when the UTOPIA is operating in 16-bit mode.

Segmentation Circular Buffer X Base Address: The bits of this field are concatenated with the **Read Pointer** bits to form a 20-bit word address to external memory. This value is used to address a particular TDM or CAS value in a particular buffer. One pointer is needed for each channel in the VC.

Figure 20 - Segmentation Control Structure - SDT Format

In general, Figure 20 should be referred to for explicit details regarding the initialization of the fields within the SDT Segmentation Control Structures. However, one field needs more explanation, which is provided in the following text:

Read Pointer Field

When operating in SDT mode, each VC has an associated read pointer, which is configured within the VC's Segmentation Control Structure. This value, as described in the text accompanying Figure 20, is used by the TX_SAR to determine the location within the Segmentation Circular Buffers from which the next byte of TDM data will be read. In general, this field should be initialized to "0", so that the TX_SAR reads the first data byte that was written into the buffer by the TDM module. However, in the case of a large number of VCs with small N, the read pointer value can be used to ease the job of the TX_SAR by distributing the cell generation over more than one frame. When the read pointer is used to scatter the cell generation, the F (First) bit of the Segmentation Control Structure should be set to '0'.

For example, when N=1 VCs are used, it is possible for the MT90520 to handle up to 256 VCs simultaneously. In this case, each VC only needs to be serviced once every 47 frames (once enough data from the TDM channel has been received to complete an ATM cell). Ideally, the Segmentation Control Structures should be configured to distribute cell generation so that the TX_SAR does not sit idle for 46 frames, and then try to create up to 256 cells in the 47th frame. In order to eliminate this burstiness problem (and the resulting negative impact on the CDV), the read pointer for each VC can be set to a non-zero value. For example:

VC_0 read pointer = 0 VC_1 read pointer = 1 ... VC_46 read pointer = 46 VC_47 read pointer = 0

By setting the read pointers of various VCs to different values, the user ensures that the TX_SAR will not be required to generate all of the cells simultaneously. For example, in frame 47, rather than having to generate 256 cells, the TX_SAR will only have to generate 6cells (from VCs numbered 0, 47, 94, 141, 188, 235).

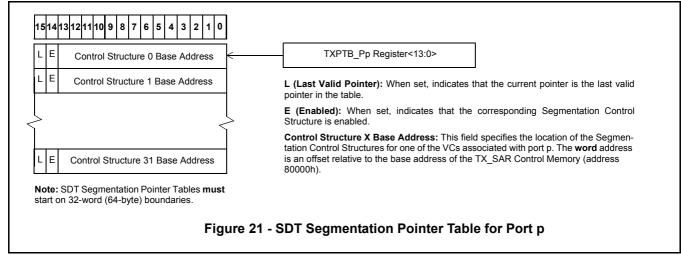
Therefore, when configuring the MT90520 to handle many VCs with low N values, it is recommended that the read pointers be distributed over multiple frames.

4.5.3.1.2 SDT Segmentation Pointer Tables

After writing control structures into internal memory, software must configure a pointer table in the same block of internal memory (i.e., between addresses 80000h and 87FFEh) to permit the TX_SAR hardware to locate the control structures. An SDT Segmentation Pointer Table must be created on a per-port basis for all ports which are configured to transmit SDT ATM cells. The table conforms to the format shown in Figure 21 and must start on a 32-word (64-byte) boundary. There can be up to 32 entries in each table, as there can be a maximum of 32 N=1 VCs associated with any one TDM port. Each entry in the pointer table contains a field which gives the **word** address of the SDT Segmentation Control Structure associated with a particular VC. Two extra bits in the pointer table entry indicate whether the corresponding control structure is enabled, as well as whether this is the final control structure pointer contained in the table.

For VCs transmitting channels from multiple ports, any one of the ports' SDT Pointer Table can be chosen to contain the VC entries. If any SDT Pointer Table entry points to a VC having more than 46 channels, the TDM_DATA_FORMAT field of the corresponding TDM port's TDM1 register must be programmed as "11".

The per-port TX_SAR Pointer Table Base Registers (at byte addresses 1000h + p*2h) must be configured to point to the SDT Segmentation Pointer Tables for their respective ports. As well, the TXCFG bits in the register must be set to "11", indicating that the control structures being pointed to by the table are configured for SDT mode.

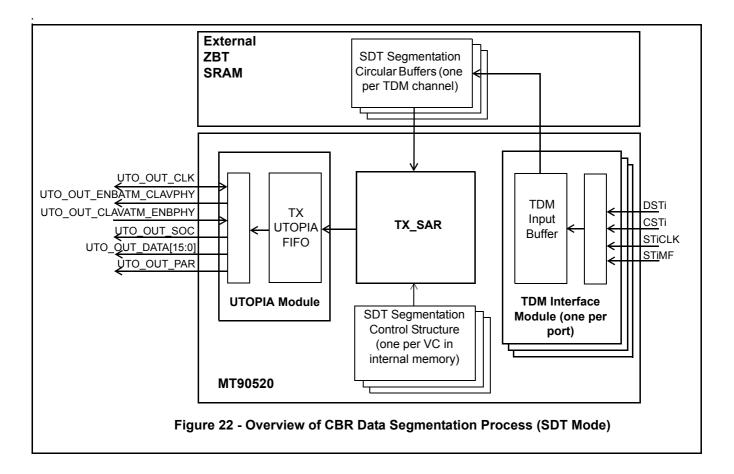


Once the control structures and accompanying pointer tables have been configured, the transmission of CBR cells can begin as soon as the TX_SAR is enabled, by setting the TXENB bit in the TX_SAR Master Enable Register at byte address 1044h.

4.5.3.2 Operation

In SDT mode, once the SDT Segmentation Control Structure has been configured and the TX_SAR enabled, the TX_SAR begins to generate cells with the appropriate formatting, without further software intervention. The TX_SAR reads data (consisting of TDM data bytes and, where appropriate, CAS signalling bytes) from the perchannel SDT Segmentation Circular Buffers in external memory. Refer to Section 4.3.2.1.2 and Figure 9, "Per-Port SDT Segmentation Circular Buffers," on page 42 for details regarding the formatting of the data which is written to these circular buffers by the TDM module. The TX_SAR prepends the TDM data with an AAL1 sequence number and with a 6-byte header as specified by the VC's SDT Segmentation Control Structure. Additionally, as defined in the AAL1 specifications, one even-numbered cell out of each eight-cell sequence contains a pointer byte. The TX_SAR uses internal counters to determine the appropriate value for the pointer byte, which indicates the start of the next structure within the outgoing cell stream on a VC.

Figure 22 shows the complete segmentation data path in SDT mode, from the incoming TDM data bus to the outgoing UTOPIA data bus.



4.5.4 Data TX_SAR Module

The TX_SAR (and specifically the sub-module which shall henceforth be called the Data TX_SAR) is capable of transmitting non-CBR data cells which are not associated with any TDM port. These cells may be AAL5 signalling cells, OAM-type data cells, or any other ATM cells which need to be transmitted from a system containing an MT90520 device.

The Data TX_SAR does not process or manipulate the data cells. Rather, it simply reads cells which have been written to a multi-cell circular buffer in external memory by a CPU. It then transfers those cells to the UTOPIA module for transmission onto the UTOPIA bus.

The Data TX_SAR can operate simultaneously with the generation of AAL1 CBR cells by the TX_SAR.

4.5.4.1 Mode of Operation

The Data TX_SAR within the MT90520 must be enabled, by setting the **Data TX_SAR Enable** bit in the Data TX_SAR Control Register at address 103Eh.

The user writes the cells to a buffer located in external memory. The address and size of this buffer are programmed in the DTCON register, located at address 1038h. The cell structure format is illustrated in Figure 23.

When the Data TX_SAR is enabled, it begins to send cells from the cell buffer beginning with the cell pointed to by the Data TX_SAR Read Pointer. The Read Pointer is incremented after each cell is sent. Cell transmission halts when the Read Pointer is equal to the user-defined Data TX_SAR Write Pointer, which indicates the cell structure number being written to by the CPU. Cell transmission begins again after the Write Pointer is changed to a different value than the Read Pointer. The cell buffer is circular; the Read Pointer will never point above the top of the buffer.

A cell buffer empty event occurs whenever the Read Pointer equals the Write Pointer. This condition is cleared when the Data TX_SAR is disabled or when the Write Pointer is changed.

If the Write Pointer is set to a value equal to or greater than the cell buffer size, the cells in the buffer will be sent repetitively.

The Write Pointer should never be set to the same value as the Read Pointer when there are cells in the buffer awaiting transmission or during transmission of the cell pointed to by the Read Pointer.

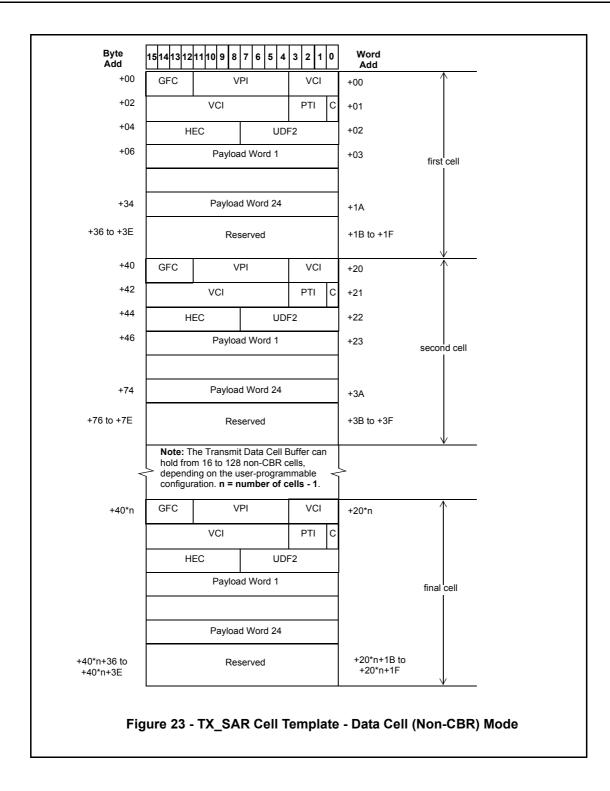
If the AUTO bit is set in the Data TX_SAR Control Register at 103Eh, the Data TX_SAR sends cells to the UTOPIA module whenever the TX_SAR module is not busy transmitting CBR cells (i.e., either UDT- or SDT-formatted AAL1 cells). Contrarily, if the AUTO bit is not set, the Data TX_SAR sends out cells at a user-configurable data rate. The user may configure the time between cell transmissions by programming the Data Cell Generation Time Out Register at 1040h. Cells may be sent in time intervals from 1ms to 1s.

As mentioned above, the Data TX_SAR does not actually generate the cells to be transmitted. Rather, it simply reads 54-byte cells (consisting of 5 bytes of header, 1 "filler" header byte (UDF2 field) required for the 16-bit UTOPIA bus, and 48 bytes of payload) directly from a location in external memory which is identified by a Data TX_SAR Cell Buffer base address and the Read Pointer. The base address of the buffer is user-programmable, as is the number of cells that can be stored in the buffer. The user can select (via the register at byte address 1038h) a buffer capable of holding 16, 32, 64, or 128 cells. Each cell is allocated 64 bytes in external memory. Cells written into the Data TX_SAR Cell Buffer must conform to the format shown in Figure 23.

4.5.4.2 Error Handling

The Data TX_SAR has a single status bit to indicate whether the Data TX_SAR Cell Buffer in external memory is empty (declared when the Data TX_SAR's read pointer is equal to the write pointer controlled by the CPU). The **Transmit Cell Buffer Empty** bit in the Data TX_SAR Status Register at 1042h can be enabled to cause an interrupt to be generated on IRQ.

MT90520



4.6 RX_SAR Modules

The RX_SAR modules of the MT90520 device (consisting of the UDT RX_SAR, the SDT RX_SAR, and the Data RX_SAR) are primarily responsible for the reassembly of TDM data extracted from CBR ATM cells. In addition, in certain modes of operation, the SDT RX_SAR extracts CAS data from received cells and sends that information, as well as multiframe indication signals, to the TDM module.

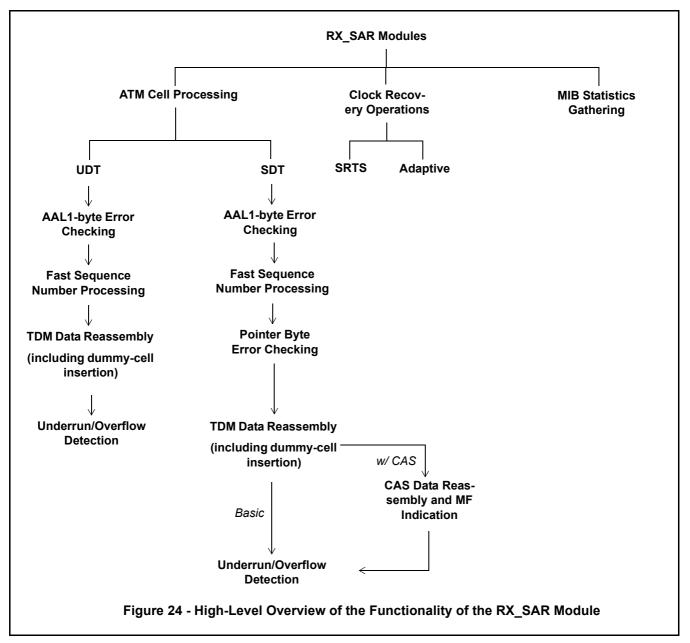
The UDT RX_SAR and SDT RX_SAR modules provide the Clock Management module with clocking information obtained from received cells.

A secondary Data RX_SAR transfers non-CBR cells from the UTOPIA interface to external memory, where the cells may be processed by user software.

4.6.1 UDT RX_SAR and SDT RX_SAR Modules

4.6.1.1 Data Flow and Processing Path Overview

At a high level of abstraction, Figure 24 shows the functionality implemented within the UDT RX_SAR and SDT RX_SAR reassembly paths of the MT90520. Within the "ATM Cell Processing" path there are a number of different steps which must be taken, depending upon the operating mode of the device. The "Clock Recovery Operations" and "MIB Statistics Gathering" paths may be taken in conjunction with any of the operating modes.



The UDT RX_SAR and SDT RX_SAR modules are explained in the following sections.

In Section 4.6.1.2, the use of Reassembly Control Structures is detailed. These control structures, which are stored in internal memory, control the operation of the UDT RX_SAR and the SDT RX_SAR on a per-VC basis.

The flow of the documentation starting in Section 4.6.1.3 on page 70 generally follows the flow of received cells through the data path shown in Figure 24.

4.6.1.2 Reassembly Control Structures

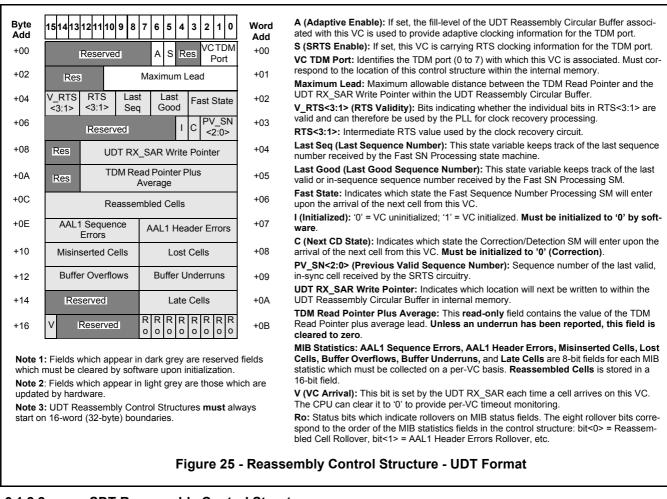
The UDT RX_SAR and the SDT RX_SAR are both instantiated only once per MT90520 device. As a result, each module must handle all of the cells being received at the device in a particular mode of operation. However, due to the nature of the device, it is possible for multiple cell streams (i.e., cells being carried on different VCs) to be received at the MT90520's UTOPIA receive interface and then sent for processing by one of the RX_SARs. In order to keep statistics and other information (e.g., current state of the Correction/ Detection state machine, last received sequence number) updated on a per-VC basis, the MT90520 employs two internal memories (one each for the UDT RX_SAR and the SDT RX_SAR) to hold Reassembly Control Structures. The user must configure a control structure for each VC which is receiving cells via the MT90520.

4.6.1.2.1 UDT Reassembly Control Structures

Within the UDT RX_SAR, there is an internal memory which can be configured to hold up to 8 UDT Reassembly Control Structures (one per port). Each UDT Reassembly Control Structure is allocated a 32-byte block. The control structures for the various ports must be located at pre-defined locations within the internal memory. If the data on a VC is destined for port 0, the UDT Reassembly Control Structure for the VC must be programmed to begin at CPU byte-address BE000h (the base address for the UDT Reassembly Control Structure memory in the MT90520 memory map). The control structure for a VC destined for port 1 must be configured to start at CPU byte-address BE020h, and so on.

All of the fields within the control structure are explained in the text accompanying Figure 25. Upon initialization, only a few of the fields within the UDT Reassembly Control Structure need to be explicitly configured by the user. **VC TDM Port** must be configured to match the desired destination port for the VC's data. As such, the only permissible values for this field are "000" (representing port 0) to "111" (representing port 7). If SRTS or Adaptive clock recovery methods are to be employed on the VC, the appropriate configuration bit (either **S** or **A**) must be set. As well, the **Maximum Lead** field must be configured to a value which accounts for the expected cell delay variation (CDV) of the network, and the desired distance to be maintained between the UDT RX_SAR's write pointer and the TDM module's read pointer. More details regarding the programming of Maximum Lead are given within the section "UDT Reassembly Circular Buffers" on page 77. All of the remaining fields within the UDT Reassembly Control Structure must be cleared to '0' upon initialization. This ensures that the statistics and status fields for the VC are configured to start with cleared values.

For debug and statistics-gathering purposes, the CPU can read the UDT Reassembly Control Structure contents.



4.6.1.2.2 SDT Reassembly Control Structures

Within the SDT RX_SAR, there is an internal memory which is 16 Kwords long and 16 bits wide, to permit the setup of VCs of varying size and configuration. The MT90520 can handle up to 256 single-channel VCs (a full E1 of 32 channels on each of the 8 ports). However, many other configurations with different "n" are also permissible.

Unlike the control structures in UDT mode, SDT Reassembly Control Structures do not have as many restrictions on their location. Although all of the SDT control structures must start on 32-byte (16-word) boundaries, the boundary which is selected for each control structure does not matter (e.g., the control structure for a VC on port 5 may be physically located in memory at an earlier location than the control structure for a VC on port 0). As well, it is possible for a VC to be carrying data which is destined for multiple TDM ports (e.g., Channel 0 of the VC may be destined for port 0, but channel 1 might be destined for port 7). The TDM port destination of the data is ultimately determined by the programming of the TDM SDT Reassembly Control Structure (see Figure 11 on page 45). It is important to note that the location of the SDT Reassembly Control Structure in internal memory must be correlated with the Reassembly Control Structure Address within the UTOPIA's look-up table entry for the particular VC.

When a VC is configured as basic SDT, the control structure uses from 30 bytes to 284 bytes, depending on the number of channels carried by the VC (up to 128). The various fields of the SDT Reassembly Control Structure are shown in Figure 26 and explained in Table 12.

For debug and statistics-gathering purposes, the CPU can read the SDT Reassembly Control Structure contents, one word at a time.

SDT Control Structure Fields - Initialization

As in the UDT case, upon initialization, only a few of the fields within the SDT Reassembly Control Structure need to be explicitly configured by the user. The fields which must be configured are listed below. Details of the appropriate values for configuration can be found in Table 12 on page 70.

- Maximum Lead must be configured to a value which accounts for the expected CDV of the network, and the desired distance to be maintained between the SDT RX_SAR's write pointer and the TDM module's read pointer. More details regarding the programming of Maximum Lead are given within the section "SDT Reassembly Circular Buffers" on page 79.
- If all of the data within the VC is destined for the same TDM port, VC TDM Port must be configured to match the desired destination port for the VC's data. However, if the data is destined for multiple ports (trunking), this field must be configured to match the port whose TDM read pointer will be used for slip-checking and clock recovery.
- First Entry must always be set to 0Eh. Last Entry must be programmed to the word-address of the last Reassembly Circular Buffer Base Address within the control structure.
- If SRTS or Adaptive clock recovery methods are to be employed on this VC, the appropriate configuration bit (either **S** or **A**) must be set.
- The **M** (Multiframe Type) bit is used to select either DS1 ('0') or E1 ('1') multiframing format for use when the VC is carrying CAS signalling bits. If "basic" SDT mode is being used, the value of this field does not matter.
- **Structure Length** must contain the length (less one) of the AAL1 structure size for this VC, including both TDM and CAS bytes.
- The CAS field must be configured if the VC being received is carrying CAS signalling nibbles.
- The **BS** field should be set to the desired size of the SDT Reassembly Circular Buffers for the VC. The configurable buffer sizes range from 64 entries to 1024 entries per channel. Note that all of the channels within the VC are allocated the same size buffers in external memory. It should also be noted that the size of the buffers must correspond to the size field given within the TDM SDT Reassembly Control Structure for the chosen TDM channel destination (port and channel specific), as shown in Figure 11 on page 45.
- **Number of Channels** must be set to the number of channels in the VC, less one (therefore, allowable values for the field are 00h to 7Fh).
- The **Pi (Pointer Initialization)** bit within the SDT Reassembly Control Structure **must** be set to '1', indicating that the control structure is ready to start receiving pointers.
- Current Entry must be programmed to contain the value in the First Entry field (i.e., 0Eh).
- The **Reassembly Circular Buffer Base Address** fields must contain the values of the word-addresses of the corresponding circular buffers in external memory. A two-bit value, the Reassembly Circular Buffer Base Address, is obtained from the CB_BASE_ADD field of the SDT Reassembly Control Register at byte-address 2040h. These bits form the two most significant bits of a word-address formed by concatenating these bits with the 12-bit value obtained from the Reassembly Circular Buffer Base Address are used to form the actual address to external memory is determined by the size of the buffers selected for the VC. For details regarding how these addresses are formed, See "SDT Reassembly Circular Buffers" on page 79., particularly Table 19. It should be noted that the Reassembly Circular Buffer Base Address must correspond to the address given within the TDM SDT Reassembly Control Structure for the chosen TDM channel destination (port and channel specific), as shown in Figure 11 on page 45.
- The CASx field for each channel in the VC (where x represents the channel within the VC) should be cleared if the VC is not carrying CAS. However, if the VC is programmed to receive CAS nibbles, software can configure these nibbles to contain any values desired by the user. The software-programmed values within these fields will be transferred to the TDM module (and therefore output on CSTo) until valid CAS nibbles have been extracted from received cells.

All of the remaining fields within the SDT Reassembly Control Structure **must** be cleared to '0' upon initialization. This ensures that the initialization, statistics, and status fields for the VC are configured to start with cleared values.

Byte Add	15 14 13 12 11 10 9 8 7 6 5 4 3 2 1	0 Word Add
+00	Maximum Lead Res Por	DM +00
+02	First Entry Last Entry	+01
+04	R A S M Structure Length	+02
+06	CAS BS Res Number of Channels	+03
+08	V_RTS RTS Last Last <3:1> <3:1> Seq Good	+04
+0A	PV_SN I SDT RX_SAR Write Pointer	+05
+0C	C P P Current i Frame Current Entry	+06
+0E	Res Location in Structure	+07
+10	Reassembled Cells	+08
+12	AAL1 Sequence AAL1 Header Error	+09
+14	Misinserted Cells Lost Cells	+0A
+16	Pointer Parity Errors Pointer Reframe	+0B
+18	Buffer Overflows Buffer Underruns	+0C
+1A	V Res C P R R R R R R R R R R R R R R R R R R	R +0D
+1C	CAS0 Reassembly Circular Buffer Base Address	+0E
+1E	CAS1 Reassembly Circular Buffer Base Address	+0F
+20	CAS2 Reassembly Circular Buffer Base Address	+10
	Minimum Structure	
	Size - 30 bytes (1 channel)	
<	Maximum Structure Size - 284 bytes (128 channels)	
+114	CAS124 Reassembly Circular Buffer Base Address	+8A
+116	CAS125 Reassembly Circular Buffer Base Address	+8B
+118	CAS126 Reassembly Circular Buffer Base Address	+8C
+11A	CAS127 Reassembly Circular Buffer Base Address	+8D
	elds which appear in dark grey are reserved eared by software upon initialization.	fields which
	elds which appear in light grey are those wh / hardware.	ich are
Note 3: SI	DT Reassembly Control Structures must alw 2-byte) boundaries.	vays start on
	- Possombly Control Struc	turo - SDT Format
rigure 2	6 - Reassembly Control Struc	luie - JUI FUIIIal

MT90520

Table 12 - Fields within the SDT Reassembly Control Structure

Maximum Lead: Maximum allowable distance between the TDM Read Pointer and the SDT RX_SAR Write Pointer within a Reassembly Circular Buffer. **VC TDM Port:** Identifies the TDM port (0 to 7) with which this VC is associated for slip detection and (optionally) for clock recovery.

First Entry: Indicates the location of the first Reassembly Circular Buffer Base Address within the Reassembly Control Structure. Must be programmed to 0Eh.

Last Entry: Indicates where the last Reassembly Circular Buffer Base Address is located within the Reassembly Control Structure. Must be programmed to have the word-address of the last Reassembly Circular Buffer address (e.g., if n = 2, this field contains 0Fh).

A (Adaptive Enable): If set, the fill-level of the Reassembly Circular Buffer(s) associated with this VC are used to provide adaptive clocking information for the VC TDM Port. Only one VC per TDM port can have this bit set.

S (SRTS Enable): If set, this VC is carrying RTS clocking information for the VC TDM Port. Only one VC per TDM port can have this bit set. **M (Multiframe Type):** '0' = DS1 (24 frames); '1' = E1 (16 frames).

Structure Length: Indicates the length of the AAL1 structure, including TDM and CAS bytes. This field must be programmed by the user to be one less than the actual structure length. For non-CAS VCs, this field is equal to the number of channels in the VC, less one. For CAS VCs, the formula for calculating the Structure Length field is: DS1 = N*24 + roundup(N/2) - 1; E1 = N*16 + roundup(N/2) - 1.

CAS: If set, bit<0> indicates that this VC is carrying CAS information; if set, bit<1> indicates that the user wishes to control the CAS values via S/W (received CAS values not written back to control structure); if set, bit<2> indicates that a CPU service request should be sent if the new CAS value for a channel differs from the old (or if the received CAS value differs from the value set by hardware).

BS (Circular Buffer Size): "000" = 64 entries; "001" = 128 entries; "010" = 256 entries; "011" = 512 entries; "100" = 1024 entries; other = reserved. **Number of Channels:** Indicates the number of channels within this VC. Field must be programmed by user to be one less than the actual number of channels in the VC (possible values = 0d to 127d).

V_RTS<3:1> (RTS Validity): Bits indicating whether the individual bits in RTS<3:1> are valid and can therefore be used by the PLL for clock recovery processing.

RTS<3:1>: Intermediate RTS value used by the Receive SRTS circuitry.

Last Seq (Last Sequence Number): This state variable keeps track of the last sequence number received by the Fast SN Processing SM.

Last Good (Last Good Sequence Number): This state variable keeps track of the last valid or in-sequence sequence number received by the Fast SN Processing SM.

Fast State: Indicates which state the Fast Sequence Number Processing state machine will enter upon the arrival of the next cell from this VC.

PV_SN<2:0> (Previous Valid Sequence Number): Sequence number of the last valid, in-sync cell received by the SRTS circuitry.

I (Initialized): '0' = VC uninitialized; '1' = VC initialized. Must be initialized to '0' by software.

SDT RX_SAR Write Pointer: Indicates which location will next be written within a Reassembly Circular Buffer.

C (Next CD State): Indicates which state the Correction/Detection state machine will enter upon the arrival of the next cell from this VC. This bit must be initialized to '0' (Correction).

P (Pointer Reframe Pending): Status bit indicating that a pointer reframe error has occurred and has yet to be compensated for or reported to the MIB. Must be set to '0' by software.

Pi (Pointer Initialization): Must be set to '1' by software.

Current Frame: This field indicates which frame of the multiframe is currently being received. Used only if VC is carrying CAS data.

Current Entry: Points to the address of the Reassembly Circular Buffer currently being written. Must be initialized to 0Eh.

Location in Structure: This field indicates how many bytes remain before the start of the next AAL1 structure. This field must be set to '0' by software. MIB Statistics: AAL1 Sequence Errors, AAL1 Header Errors, Misinserted Cells, Lost Cells, Pointer Parity Errors, Pointer Reframes, Buffer Overflows, and Buffer Underruns are 8-bit fields for each MIB statistic which must be collected on a per-VC basis. Reassembled Cells is stored in a 16-bit field. NOTE: The pointer reframe field will usually be incremented to '1' upon the arrival of the first valid pointer.

V (VC Arrival): This bit is set by the SDT RX_SAR each time a cell arrives on this VC. The CPU can clear it to '0' to provide per-VC timeout monitoring. Cc (CAS Changed): Status bit indicating that at least one CAS nibble in VC has changed since last received CAS value.

Po (Pointer Out-of-Range): Pointer out-of-range error noted if pointer-byte has an invalid value (i.e., > 93 and not a dummy value of 127).

Ro: Status bits which indicate rollovers on MIB status fields. The nine rollover bits correspond to the order of the MIB statistics fields in the control structure: bit<0> = Reassembled Cell Rollover, bit<1> = AAL1 Header Rollover, etc.

Reassembly Circular Buffer Base Address: This field forms part of the address of a Reassembly Circular Buffer. Refer to Table 19 on page 80 and the accompanying text for information regarding the addresses of SDT Reassembly Circular Buffers in external memory.

CAS0 - CAS127: Fields containing the four-bit nibbles representing the Channel Associated Signalling for the corresponding channel. These values are transmitted to the TDM module regardless of whether the received VC is configured for CAS. Must be set to initial values by software.

4.6.1.3 Sequence Number Checking (Correction/Detection State Machine)

In both the UDT and SDT modes of operation, each AAL1 cell which is destined for the RX_SAR has its AAL1 header byte processed by a sequence number checking process standardized in ITU-T I.363.1. The first portion of the processing occurs in the Correction/Detection state machine, which is explained in this section. This algorithm examines the received AAL1 byte and determines whether the sequence number protection on the byte is correct by checking for CRC and parity errors. This state machine is primarily responsible for sending a corrected sequence number and CSI bit to the Fast Sequence Number Processing state machine (outlined in Section 4.6.1.4) for further sequence number processing.

Based on the ITU-T I.363.1 standard, the Correction/Detection state machine is capable of analyzing a byte of data. It can then correct a single-bit error in the data or detect (but not correct) a two-bit error. A single-bit error is classified as the occurrence of either: (i) a parity error or (ii) a CRC error AND a parity error. An uncorrectable error occurs if a CRC error is detected without a corresponding parity error.

A brief description of the functionality is outlined below.

- 1. The state machine examines the AAL1 byte and checks for CRC and parity errors, based on hard-wired values contained within the MT90520. The state machine then outputs two pieces of information for use by the Fast SN Processing state machine: a validity indicator and a sequence number. The validity signal indicates whether or not the received byte was determined to be valid (i.e., it was either correct upon arrival, or was corrected by the Correction/Detection state machine). The sequence number is that which was determined by the Correction/Detection machine to be the intended sequence number.
- 2. The type of error-processing which is performed depends upon the current state of the standardized state machine, either Correction or Detection:

CRC Error?	Parity Error?	Correctable?	Resulting SN	Valid?	AAL1 Header Error	Next State
No	No	correct - no need	SN of input byte	Yes	+0	Correction
No	Yes	Yes	SN of input byte	Yes	+1	Detection
Yes	No	No	don't care *	No	+1	Detection
Yes	Yes	Yes	corrected SN	Yes	+1	Detection

Table 13 - Operation of Correction/Detection State Machine in Correction State

Table 14 - Operation of Correction/Detection State Machine in Detection State

CRC Error?	Parity Error?	Correctable?	Resulting SN	Valid?	AAL1 Header Error	Next State
No	No	correct - no need	SN of input byte	Yes	+0	Correction
No	Yes	No	don't care *	No	+1	Detection
Yes	No	No	don't care *	No	+1	Detection
Yes	Yes	No	don't care *	No	+1	Detection

Note * - When an errored SN cannot be corrected, the Correction/Detection state machine outputs the SN of the input byte, uncorrected.

- 3. The most significant bit of the resulting sequence number (i.e., the CSI bit) may be processed further by the SRTS clock recovery sub-module (see Section 4.6.1.6.2) or, in the SDT case, by the pointer-processing sub-module (see "Pointer Processing" on page 78). The 3 least significant bits are transmitted to the Fast Sequence Number Processing state machine as the current cell's sequence number.
- 4. At the end of cell processing, two pieces of information related to the Correction/Detection state machine are updated in the Reassembly Control Structure for the VC: the next state of this state machine (either Correction or Detection) and the AAL1 Header Errors field.

4.6.1.4 Sequence Number Checking (Fast SN Processing State Machine)

After being processed by the Correction/Detection state machine, **all** AAL1 header bytes (whether correctable or not) and their corresponding validity indicators are passed to the Fast SN Processing state machine standardized within ITU-T I.363.1. This second portion of the Sequence Number Checking sub-module is responsible for analyzing the received sequence number values and determining whether the cells are being received in the correct order. The Fast Sequence Number Processing state machine can detect and compensate for lost cells. In addition, it can compensate for events which it determines to be misinserted cells.

UDT Mode of Operation

Although based on the state machine standardized in ITU-T I.363.1, additional functionality was added to the UDT RX_SAR's state machine in the form of two extra states:

• The single_cell_loss_misinsertion state was added to provide for the insertion of in-order dummy cells in the event of a single cell loss or misinsertion. As outlined in the table below, any time that an apparent single-cell loss occurs, a dummy cell is inserted and then the received cell is accepted into the port's Reassembly Circular Buffer. If the event is indeed a single-cell loss, the subsequent received cell is accepted and the state machine returns to the sync state. If the apparent single-cell loss turns out to have been a cell misinsertion event, the

state machine returns to **sync**, but the most recently received (i.e., late) cell is discarded because a dummy cell was previously inserted in place of the misinserted cell. Similarly, if the apparent single-cell loss turns out to have been a sequence number protection failure, the state machine returns to **sync** and the most recently received cell is discarded because a dummy cell was previously inserted (erroneously) when all of the cells were actually being received in order.

• The late_cell_insertion state was added as a special user-programmable feature to provide CDV monitoring. If the user enables the late-cell-checking feature (by setting the CHECK_LATE_ARRIVALS bit in the UDT Reassembly Control Register at 2000h), when a per-port late-cell timeout counter reaches the value programmed by the user, a late cell timeout is reached and the Fast SN Processing state machine transitions into the late_cell_insertion state, inserting a single dummy cell on the transition. Once in the late_cell_insertion state, the subsequent cell arrival will determine the type of event that occurred. If the originally expected cell arrives, this is a late cell arrival case; the late cell is discarded and the state machine returns to sync. If the cell which arrives has a sequence number greater by one than that which was originally expected, a single cell loss has occurred; the received cell is accepted and the state machine returns to sync.

The operation of the state machine is summarized in the following table:

Current State	Transition Event	Action Taken	Next State	Note
x (don't care)	reset asserted	- none	reset_state	
reset_state	reset de-asserted	- none	start	
start	invalid sequence number	- discard cell	start	
	valid sequence number	- discard cell	out_of_sync	
out_of_sync	invalid sequence number	- discard cell	start	
	received cell is not in sequence with previous cell	- discard cell	out_of_sync	
	received cell is in sequence with previous cell	 accept received cell per-port timeout circuitry is enabled to permit late-cell insertions 	sync	**
sync	late cell timeout period reached and CHECK_LATE_ARRIVALS = '1'	 UDT RX_SAR inserts a single dummy cell 	late_cell_insertion	
	invalid sequence number	- accept received cell	invalid	
	received cell is in sequence with previous cell	 accept received cell per-port timeout circuitry is enabled to permit late-cell insertions 	sync	**
	received cell is not in sequence with the previously-received cell -> received cell has a sequence number one greater than the expected sequence number	 - assume single-cell loss event - UDT RX_SAR inserts a single dummy cell - after dummy cell insertion, accept received cell (in-order dummy cell insertion) - declare aal1_seq_error 	single_cell_loss_ misinsertion	
	received cell is not in sequence with the previously-received cell -> received cell has a sequence number that is NOT one greater than the expected sequence number	 cannot assume what happened (may be a multi-cell loss case) accept received cell (thus, if this is a multi-cell loss case, out-of-order dummy cell insertion will occur) declare aal1_seq_error 	out_of_seq	

Table 15 - Operation of UDT Fast Sequence Number Processing State Machine

Current State	Transition Event	Action Taken	Next State	Note
invalid	invalid sequence number	- discard cell	start	
	received cell is in sequence with last "good" cell (i.e., cell misinsertion)	 discard cell declare misinserted_cell_error per-port timeout circuitry is enabled to permit late-cell insertions 	sync	**
	received cell has a valid sequence number that is two greater than the last "good" cell (i.e., sequence number protection failure)	 accept received cell per-port timeout circuitry is enabled to permit late-cell insertions 	sync	**
	received cell has valid sequence number, but doesn't meet either of the 2 previous criteria	- discard cell	out_of_sync	
out_of_seq	invalid sequence number	- discard cell	start	
	received cell is in sequence with last received cell (i.e., multiple cell loss)	 calculate number of lost cells (up to 7) UDT RX_SAR inserts dummy cell(s) after dummy cell insertion(s), accept received cell declare lost_cell_error per-port timeout circuitry is enabled to permit late-cell insertions 	sync	**
	received cell has a valid sequence number that is two greater than the last in-sequence cell (i.e., sequence number protection failure)	 accept received cell per-port timeout circuitry is enabled to permit late-cell insertions 	sync	**
	received cell has valid sequence number, but doesn't meet either of the 2 previous criteria	- discard cell	out_of_sync	
single_cell_loss_	invalid sequence number	- discard cell	start	
misinsertion	received cell is in sequence with last received cell (i.e., single cell loss)	 accept received cell declare lost_cell_error per-port timeout circuitry is enabled to permit late-cell insertions 	sync	**
	received cell is in sequence with last in- sequence cell (i.e., cell misinsertion)	 discard cell (dummy cell already inserted to take place of misinserted cell) declare misinserted_cell_error per-port timeout circuitry is enabled to permit late-cell insertions 	sync	**
	received cell has a valid sequence number that is two greater than the last in-sequence cell (i.e., sequence number protection failure)	 discard received cell (extra dummy cell was inserted when all cells were actually received in order) per-port timeout circuitry is enabled to permit late-cell insertions 	sync	**
	received cell has valid sequence number, but doesn't meet any of the 3 previous criteria	- discard cell	out_of_sync	

Table 15 - Operation of UDT Fast Sequence Number Processing State Machine

Current State	Transition Event	Action Taken	Next State	Note
late_cell_insertion	invalid sequence number	- discard cell	start	
	received cell has a sequence number one greater than the originally expected sequence number (i.e., this appears to be a single-cell loss)	 accept received cell (dummy cell was already inserted to replace the lost cell) declare lost_cell_error declare aal1_seq_error per-port timeout circuitry is enabled to permit late-cell insertions 	sync	**
	received cell is that which was originally expected (i.e., late cell arrival)	 discard cell (because a dummy cell was already inserted to replace this one) declare late_cell_error per-port timeout circuitry is enabled to permit late-cell insertions 	sync	**
	received cell has valid sequence number, but doesn't meet either of the 2 previous criteria	 discard cell declare aal1_seq_error 	out_of_sync	

Table 15 - Operation of UDT Fast Sequence Number Processing State Machine

Note **: The per-port timeout circuitry for late-cell insertion is enabled only when the state machine is entering the sync state. Therefore, late-cell insertion is only possible when the Fast SN Processing SM is in the "sync" state.

Here are some examples of incoming cell streams containing errors and the corresponding corrective actions taken by the UDT RX_SAR.

Table 16 - Examples of Operation of the UDT Fast Sequence Number Processing State Machine

Description of Error	Sample Incoming Cell Stream	Cells Used for Reassembly	Errors Declared
Sequence number protection failure (looks like single cell loss)	1 - 3* - 3 - 4 - 5	1 - D ₂ - 3* - 4 - 5	1 AAL1 Sequence Error
Sequence number protection failure (looks like multiple cell loss)	1 - 4* - 3 - 4 - 5	1 - 4* - 3 - 4 - 5	1 AAL1 Sequence Error
Single lost cell	1 - 2 - 4 - 5	1 - 2 - D ₃ - 4 - 5	1 AAL1 Sequence Error 1 Lost Cell
Multiple lost cells (from 2 to 7 lost cells)	1 - 2 - 6 - 7	1 - 2 - 6 - D ₃ - D ₄ - D ₅ - 7	1 AAL1 Sequence Error 3 Lost Cells
Misinserted (swapped) cell	1 - 2 - 4 - 3 - 5 - 6	1 - 2 - D ₃ - 4 - 5 - 6	1 AAL1 Sequence Error 1 Misinserted Cell

SDT Mode of Operation

The SDT version of the Fast Sequence Number Checking state machine is very similar to the UDT version. However, in the SDT version, no extra states are added for increased functionality. Unlike the UDT version, there is no provision for the insertion of dummy cells in late-cell cases, nor for in-order dummy cell insertion when single-cell losses are assumed. Because the SDT machine has fewer states than the UDT version, there

are some differences in the way in which certain cell arrival sequences are interpreted by the state machines. The following table outlines the operation of the SDT state machine:

Current State	Transition Event	Action Taken	Next State
x (don't care)	reset asserted	- none	reset_state
reset_state	reset de-asserted	- none	start
start	invalid sequence number	- discard cell	start
	valid sequence number	- discard cell	out_of_sync
out_of_sync	invalid sequence number	- discard cell	start
	received cell is not in sequence with previous cell	- discard cell	out_of_sync
	received cell is in sequence with previous cell	- accept received cell	sync
sync	invalid sequence number	- accept received cell	invalid
	received cell is not in sequence with the previously-received cell	 accept received cell declare aal1_seq_error 	out_of_seq
	received cell is in sequence with previous cell	 accept received cell permit SDT RX_SAR to update CAS information based on this cell's contents 	sync
invalid	invalid sequence number	- discard cell	start
	received cell is in sequence with last "good" cell (i.e., cell misinsertion)	 discard cell (because misinserted cell was accepted when it shouldn't have been) declare misinserted_cell_error 	sync
	received cell has a valid sequence number that is two greater than the last "good" cell (i.e., sequence number protection failure)	- accept received cell	sync
	received cell has valid sequence number, but doesn't meet either of the 2 previous criteria	- discard cell	out_of_sync
out_of_seq	invalid sequence number	- discard cell	start
	received cell is in sequence with last "good" cell (i.e., cell misinsertion)	 discard cell (because misinserted cell was accepted when it shouldn't have been) declare misinserted_cell_error 	sync
	received cell is in sequence with last received cell (i.e., cell loss)	 calculate number of lost cells (up to 6) SDT RX_SAR inserts dummy cell(s) after dummy cell insertion(s), accept received cell declare lost_cell_error 	sync
	received cell has a valid sequence number that is two greater than the last in-sequence cell (i.e., sequence number protection failure)	- accept received cell	sync
	received cell has valid sequence number, but doesn't meet any of the 3 previous criteria	- discard cell	out_of_sync

Table 17 - Operation of SDT Fast Sequence Number Processing State Machine

Here are some examples of incoming cell streams containing errors and the corresponding corrective actions taken by the SDT RX_SAR.

3* - 3 - 4 - 5 4* - 3 - 4 - 5	1 - 3* - 3 - 4 - 5 1 - 4* - 3 - 4 - 5	1 AAL1 Sequence Error 1 AAL1 Sequence Error
4* - 3 - 4 - 5	1 - 4* - 3 - 4 - 5	1 AAL1 Sequence Error
- 2 - 4 - 5	1 - 2 - 4 - D ₃ - 5	1 AAL1 Sequence Error 1 Lost Cell
- 2 - 6 - 7	1 - 2 - 6 - D ₃ - D ₄ - D ₅ - 7	1 AAL1 Sequence Error 3 Lost Cells
2 - 4 - 3 - 5 - 6	1 - 2 - 4 - 5 - D ₄ - 6	2 AAL1 Sequence Errors 1 Misinserted Cell 1 Lost Cell
•	- 2 - 6 - 7 2 - 4 - 3 - 5 - 6	- 2 - 6 - 7 1 - 2 - 6 - D ₃ - D ₄ - D ₅ - 7

4.6.1.5 Received Cell Processing

The RX_SARs are responsible for extracting data from received cells and transferring that data to the TDM module, for eventual transmission onto the TDM output bus. In addition, these modules are responsible for:

- performing slip checking and RX_SAR write-pointer adjustment prior to transferring data to the TDM module
- generating dummy cells in the case of sequence errors such as lost or misinserted cells
- SDT pointer processing
- extracting CAS from SDT cells and transferring it to the TDM module

4.6.1.5.1 UDT Mode of Operation

In "normal" operation (i.e., the UDT RX_SAR's Fast SN Processing state machine is in "sync"), the UDT RX_SAR is responsible for transferring a UDT cell received at the UTOPIA interface to a single UDT Reassembly Circular Buffer in internal memory (corresponding to the TDM port for which the data is destined). However, if it is not in "sync", the UDT RX_SAR may also be responsible for inserting up to 7 dummy cells (each filled with 47 bytes of user-defined data) into the port's UDT Reassembly Circular Buffer.

Regardless of the state of the Fast SN Processing state machine, a comparison is made between the value of the UDT RX_SAR's write pointer and the TDM module's read pointer, prior to the transfer of each cell to the circular buffer. The result of the comparison determines whether a slip-error needs to be reported in the MIB statistics, and may also result in an adjustment of the write pointer's location before a cell is written to the UDT Reassembly Circular Buffer (see UDT Overflow and Underrun Detection below).

TDM Data Transfer

Normally the UDT RX_SAR simply transfers 47-byte blocks of data from the UTOPIA interface to a port's UDT Reassembly Circular Buffer. However, in the case of a cell loss or misinsertion, up to 7 dummy cells may be inserted into the circular buffer before the received cell is accepted. If the user has set the **UDT_INSERT_LOST** bit in the UDT Reassembly Control Register at byte-address 2000h, the UDT RX_SAR is configured to insert the number of dummy cells calculated by the Fast SN Processing state machine in a cell loss case. On the other hand, if the user has not set the UDT_INSERT_LOST bit, the UDT RX_SAR will insert a maximum of 2 dummy cells (i.e., even if the number of lost cells is greater than 2, only 2 dummy cells may be inserted) into the UDT Reassembly Circular Buffer in a cell-loss event.

UDT Reassembly Circular Buffers

In the UDT mode of operation, each VC has a specified UDT Reassembly Circular Buffer located in internal memory. Each buffer is 2048 bytes long and is therefore capable of storing over 43 cells worth of data. The user can adjust the **Maximum Lead** field in the VC's UDT Reassembly Control Structure to control the CDV tolerance of the VC. The Maximum Lead field, as explained in Section 4.6.1.2.1, "UDT Reassembly Control Structures," on page 66, is user-programmable and determines the maximum distance between the TDM module's read pointer and the UDT RX_SAR's write pointer. In general, the operations of the UDT RX_SAR and the TDM module are synchronized so that the UDT RX_SAR's write pointer and the TDM module's read pointer are always an average distance (equivalent to Maximum Lead / 2) apart. This phenomenon occurs because most of the time, each time that the UDT RX_SAR writes a complete cell to the circular buffer, the TDM module reads the complete cell (1:1 relationship).

UDT Overflow and Underrun Detection

The UDT RX_SAR is responsible for generating buffer overflow and buffer underrun error notifications on a per-VC basis. In addition to determining if errors occur, the UDT RX_SAR also attempts to compensate for these slips by adjusting its write pointer. The goal of the write pointer adjustment is to prevent the occurrence of subsequent slips.

When the first cell is about to be written to the UDT Reassembly Circular Buffer for a VC, the UDT RX_SAR looks at the current value of the TDM read pointer and adjusts the value of its write pointer to be equal to **TDM read pointer + avg_lead** (where avg_lead is equal to Maximum_Lead / 2). Therefore, if no slips occur, the write pointer should always be an "average" distance away from the TDM read pointer.

For all subsequent cells, an algorithmic slip-checking routine is performed for every cell which is written to the UDT Reassembly Circular Buffer, whether it is a dummy cell or a received ATM cell. Each time a cell is to be written to internal memory, the algorithm looks at the relationship between the UDT RX_SAR's write pointer and the TDM module's read pointer. The algorithm then determines whether the next write to occur will be an "okay" condition, an overflow, or an underrun. Generally speaking, an "okay" condition means that the UDT RX_SAR is trying to write to a memory location which is within a distance of Maximum Lead from the TDM read pointer. Overflow conditions are conditions in which there is a risk of the UDT RX_SAR over-writing data which has yet to be read by the TDM module. Underruns occur when the TDM has begun to re-read data from the buffer because it has not been replaced by new data from the UDT RX_SAR.

If an "okay" condition is detected, the UDT RX_SAR is permitted to write to the UDT Reassembly Circular Buffer at the location determined by the UDT RX_SAR write pointer from the VC's UDT Reassembly Control Structure. In the case of a slip (either an underrun or an overflow), the UDT RX_SAR's write pointer is adjusted such that the cell is written to the circular buffer at the location of TDM read pointer + avg_lead. In addition, when slips are detected, the corresponding MIB statistics fields (**Buffer Underruns** or **Buffer Overflows**) in the active VC's UDT Reassembly Control Structure are incremented.

Only in rare instances (e.g., when the TDM output clock, SToCLK, is very different from the TDM input clock, STiCLK) will slips occur. In such a case, two cells may be written to internal memory before the TDM module can read a single cell (or, perhaps two cells may be read from memory before another one can be written by the UDT RX_SAR). Since both the UDT RX_SAR and the TDM module operate with 47-byte blocks of data, it is necessary to set Maximum Lead to at least 94d (so that the average distance between the read and write pointers is 47d, or the equivalent of one cell of data). If Maximum Lead is not set to > 94d, even a minor slip (e.g., a cell that arrives one clock cycle after the TDM starts reading from the buffer) appears as a gross slip (i.e., underrun or overflow). Because gross slips cause the UDT RX_SAR's write pointer to be re-aligned, data in the buffers may be overwritten. As well, if adaptive clock recovery is being used (see Section 4.6.1.6.1, "Digital Phaseword Generation for Adaptive Clock Recovery," on page 85), repeated gross slips mean that the PLL cannot track the incoming data to SToCLK, and gross slips will likely continue to occur. The following equation can be used for setting Maximum Lead:

maxlead = 2*n*CDV+94 where n=256 for E1 and n=193 for DS1, and CDV is in milliseconds.

Overall, the Reassembly Circular Buffers in UDT mode are very large. Therefore, there is ample room to adjust the value of Maximum Lead and thereby reduce the risk of overflows. It should be stated, however, that the penalty for a large Maximum Lead value will be a start-up delay: the TDM module will read invalid data until it reaches the location of "TDM read pointer + avg_lead" at which the UDT RX_SAR started writing to the buffer.

Also, there will be a continuing delay in the reception of data on DSTo because of the distance between the write pointer and the read pointer (i.e., data written to the buffer by the UDT RX_SAR isn't immediately read out by the TDM module).

UDT Received Cell Counter

The UDT RX_SAR also provides the user with the number of UDT cells received from the UTOPIA block. This 16-bit counter value can be viewed in register URCCR at address 2006h. This counter is an overall UDT cell counter: it is incremented every time a UDT cell is received from the UTOPIA (regardless of whether the cells are discarded by the UDT RX_SAR). When this counter rolls over, a status bit gets set in the URSR register at address 2004h. This status bit can be cleared by software. This rollover condition can also generate a service request to the CPU if the corresponding service enable bit is set.

The user is also provided with a per-VC cell counter. This counter is located in the UDT Reassembly Control Structure (see Figure 25 on page 67). The operation of this counter is similar to the overall UDT cell counter. When the per-VC counter rolls over, a status bit gets set in the control structure and can be cleared by the user. The rollover condition can also generate a request to the CPU if the UDT_REAS_ROLL_SE bit is set in the URSER register at address 2002h. The CPU can then read the contents of the SERVICE_PORT field of the URSR register at address 2004h to identify which control structure generated the service request.

4.6.1.5.2 SDT Mode of Operation

In "normal" operation (i.e., the SDT RX_SAR's Fast SN Processing state machine is in "sync"), the SDT RX_SAR is primarily responsible for transferring TDM and CAS data (if applicable) from SDT cells received at the UTOPIA interface to multiple SDT Reassembly Circular Buffers in external memory. In addition, SDT pointers must be analyzed to ensure that the extracted data is being directed to the correct TDM channels.

As in the UDT RX_SAR, the SDT RX_SAR is responsible for compensating for sequence number error conditions. Up to 6 dummy cells may be inserted into the various SDT Reassembly Circular Buffers corresponding to the VC in question.

The SDT RX_SAR compares the value of the SDT RX_SAR's write pointer and the TDM module's read pointer, prior to the transfer of each cell to the SDT Reassembly Circular Buffers. The result of the comparison determines whether a slip-error needs to be reported in the MIB statistics, and may also result in an adjustment of the write pointer's location before a cell is written to the SDT Reassembly Circular Buffers (see "SDT Overflow and Underrun Detection" on page 83).

Pointer Processing

Within SDT-formatted cells, pointers are used to indicate the location of the first channel of data within an AAL1 structure.

A pointer can be received only from an even-numbered cell which is identified as a pointer-type cell because its CSI bit is set. Pointers are received in this manner for all SDT VCs, except for non-CAS cells carrying one channel. In that special case, no pointers should be received.

Once an even-numbered cell with a set CSI bit is received, the pointer byte of the cell is processed. First, some error-checking procedures are performed:

- the pointer byte is examined for even-parity errors. If there is a parity error, the contents of the pointer byte are ignored, the **Pointer Parity Errors** MIB statistic field in the SDT Reassembly Control Structure is incremented, and the pointer-processing routine is exited.
- if no parity error is found, the 7 least-significant bits of the pointer byte (the 8-bit pointer byte, less the parity bit) are then examined to see if they exceed the maximum allowable "valid" pointer value of 93d (5Dh). If either of the following cases is true, the pointer processing routine is exited:
 - if the pointer byte has a value of 127d (7Fh), it is a "dummy" pointer (a valid pointer value); this pointer value is ignored by the SDT RX_SAR.
 - if the pointer byte has a value exceeding 93d and does not equal 127d, it is an illegal pointer value; therefore, the pointer value is ignored and a Pointer_Out_of_Range error is detected, causing the Po status bit of the SDT Reassembly Control Structure for the VC to be set.

If the above error conditions are not met, the pointer byte is considered to be valid and is processed as such by the SDT RX_SAR:

 the pointer byte is automatically considered to be correct (based on the fact that there is a lot of protection on the AAL1 byte, so bytes should not be received marked erroneously as pointers). Therefore, the "golden" received pointer value is always used to determine where the SDT RX_SAR should currently be operating within a VC's AAL1 structure. Regardless of where the SDT RX_SAR is pointing in the AAL1 structure, it is adjusted to point to the location identified by the received pointer byte.

- if the received pointer matches the SDT RX_SAR's internal location controller, all is well and no errors are reported.

- if the internal location controller doesn't match the received pointer, a framing/data misalignment error has occurred:

- if the received pointer is equal to 0, the pointer misalignment is corrected immediately; therefore, the **Pointer Reframes** statistic field in the SDT Reassembly Control Structure is incremented.

- if the received pointer is not equal to 0, the misalignment between the internal controller and the received pointer is not resolved immediately:

- if the internal controller reaches the start of the AAL1 structure during the current cell, re-synchronization occurs and the Pointer Reframes statistic field in the SDT Reassembly Control Structure is incremented.

- if the internal controller does not reach the start of the AAL1 structure during the current cell, the **P** (Pointer Reframe Pending) bit of the SDT Reassembly Control Structure is set. Ultimately, when re-synchronization does occur, the P status bit is cleared and the Pointer Reframes statistic field in the SDT Reassembly Control Structure is incremented.

Note: Even in normal operation, one pointer reframe will usually be reported on each SDT VC, shortly after startup. Because the first cell received on a VC is always discarded by the SDT Fast SN Processing state machine (as per the ITU-T I.363.1 standard), the first available pointer is always discarded. Therefore, the SDT RX_SAR processes a minimum of 7 cells before another pointer is received. Thus, the data for the first 8-cell sequence is generally misaligned and directed toward the wrong TDM channels. When the second pointer is received, the internal location controller is adjusted to the value contained in the received pointer byte and, in most cases, a pointer reframe is reported.

SDT Reassembly Circular Buffers

In the SDT mode of operation, TDM data is processed on a per-channel basis, rather than on a per-VC basis, as in the UDT case. As a result, when operating in SDT mode, each channel within a VC is allocated its own SDT Reassembly Circular Buffer in external memory.

SDT Reassembly Circular Buffers have programmable lengths (on a per-VC basis). The user may configure a VC such that the buffers associated with the VC have lengths of 64, 128, 256, 512, or 1024 entries, based on the configuration of the **BS (Buffer Size)** bits in the SDT Reassembly Control Structure for the VC. Note that all of the buffers for a particular VC have the same size. The size of buffers selected should be influenced by the expected CDV on a VC. For instance, if a large CDV is expected, a longer buffer would be desirable, so that there is sufficient data to play out to the TDM bus in the period between cell arrivals.

The user can adjust the **Maximum Lead** field in the VC's SDT Reassembly Control Structure to provide further control over the CDV tolerance of the VC. The Maximum Lead field, as outlined in "SDT Reassembly Control Structures" on page 67, is user-programmable and determines the maximum distance between the TDM module's read pointer and the SDT RX_SAR's write pointer. In general, Maximum Lead should be set to a value which, when used in combination with Buffer Size, will result in the desired CDV buffering. The setting of Maximum Lead effectively shortens the buffer length, ensuring that there is no excessive delay between the time that data is received at the buffer input and when it is played out on the TDM output bus. However, if Maximum Lead is not set in accordance with the CDV of the incoming cells, it can result in the reporting of slips (underruns

or overflows), which may cause data received at the SDT Reassembly Circular Buffers to be overwritten or skipped. In general, Maximum Lead should be set to a value calculated as follows:

Maximum Lead in bytes = desired buffer limit in bytes = 2 + (2 * CDV) / 0.125ms, where CDV is in milliseconds.

Because there is no pre-defined mapping for the SDT Reassembly Circular Buffers, they can be programmed to start anywhere in the external memory for the MT90520 device (with some restrictions, explained here). The address of each SDT Reassembly Circular Buffer is formed as follows. A two-bit value is obtained from the **CB_BASE_ADD** field of the SDT Reassembly Control Register at byte-address 2040h. These bits form the two most significant bits of the address to external memory. The complete address is formed by concatenating these bits with the 12-bit value obtained from a **Reassembly Circular Buffer Base Address** field within each SDT Reassembly Control Structure.

The number of bits of the concatenated (i.e., 14-bit) address which are used to form the actual address to external memory is determined by the size of the buffers selected for the VC. For instance, if 64-entry buffers are selected, all 14 bits of the concatenated address are used. However, if 1024-entry buffers are selected, only the bottom 10 bits of the address are used. Refer to Table 19 below for more details regarding how the base addresses of the SDT Reassembly Circular Buffers are formed.

For ease of programming, it is suggested that consecutive addresses be used. For instance, in a 3-channel VC, the addresses configured in the Reassembly Circular Buffer Base Address fields should be set to 000h, 001h, and 002h, regardless of the size of the buffers selected. It must be noted that the Reassembly Circular Buffer Base Address must correspond to the address given within the TDM SDT Reassembly Control Structure (see Figure 11 on page 45) for the chosen TDM channel destination (port- and channel- specific).

Buffer Size	Address to External Memory		
64 entries	{cb_base_add<1:0>,reassembly_circular_buffer_base_add<11:0>,6'b0}		
128 entries	{cb_base_add<0>,reassembly_circular_buffer_base_add<11:0>,7'b0}		
256 entries	{reassembly_circular_buffer_base_add<11:0>,8'b0}		
512 entries	{reassembly_circular_buffer_base_add<10:0>,9'b0}		
1024 entries	{reassembly_circular_buffer_base_add<9:0>,10'b0}		

Table 19 - Formation of SDT Reassembly Circular Buffer Base Addresses to External Memory

Each 16-bit entry in external memory contains a variety of information. Each entry is composed of the fields shown in Figure 27 and explained in the text below.

MF	Res	Turn	CAS	TDM Byte
0	0	0 1	X X X X	x x x x x x x x
0	0	01	X X X X	X X X X X X X X
0	0	01	X X X X	X X X X X X X X
0	0	01	X X X X	X X X X X X X X
0	0	01	X X X X	X X X X X X X X
0	0	01	X X X X	X X X X X X X X
0	0	01	X X X X	X X X X X X X X
0	0	01	X X X X	X X X X X X X X
0	0	01	XXXX	X X X X X X X X X
0	0	01	X X X X	X X X X X X X X
0	0	01	X X X X	X X X X X X X X
0	0	01	XXXX	X X X X X X X X X
1	0	01	ABCD	00101010
0	0	0 0	XXXX	X X X X X X X X
0	0	0 0	XXXX	X X X X X X X X
0	0	00	XXXX	X X X X X X X X
0	0	00	XXXX	X X X X X X X X
0	0	00	XXXX	X X X X X X X X X
0	0	00	XXXX	X X X X X X X X X
0	0	00	XXXX	X X X X X X X X
0	0	00	XXXX	X X X X X X X X

- **MF** multiframe indicator; this bit is used only when a VC is carrying CAS data (if a VC isn't carrying CAS, the MF bits are always zero); the MF bit is set in the buffer for every channel of a VC, each time that the SDT RX_SAR determines the location of the start of the next multiframe
- Res reserved field; this field always contains a zero
- **Turn** this field contains a copy of the two most-significant bits of the SDT RX_SAR write pointer for the VC. These bits represent the "turn" of the circular buffer and are used by the TDM module for underrun detection.
- **CAS** If CAS data is being processed, this field contains the nibble of data which was last received by this channel (i.e., in the previous multiframe). CAS data is repeated for an entire multiframe (i.e., 24 consecutive entries in DS1 case; 16 consecutive entries in E1 case).
- **TDM Byte** This field contains the TDM data bytes which are extracted from received cells. If dummy cells have been inserted, this field contains the value of the dummy data programmed by the user.

SDT TDM Data Transfer and CAS Nibble Processing

The overall byte extraction process within the SDT RX_SAR is quite similar to that used by the UDT RX_SAR. In general, the SDT RX_SAR is responsible for transferring a cell received at the UTOPIA interface to the (one or many) SDT Reassembly Circular Buffer(s) for the VC. In a cell loss or misinsertion condition, the SDT RX_SAR is responsible for determining the number of dummy cells to be inserted, transferring the appropriate dummy data to the various SDT Reassembly Circular Buffers and, ultimately, transferring the received cell from the UTOPIA module to the SDT Reassembly Circular Buffer(s). Besides extracting TDM data bytes, the SDT RX_SAR must also, in certain modes, extract CAS nibbles, which were previously explained in "SDT Reassembly Circular Buffers" on page 79.

As in the UDT mode of operation in a cell insertion case, the SDT RX_SAR, under user control, can limit the number of cells to be inserted into the SDT Reassembly Circular Buffer(s). By default, a maximum of two dummy cells will be inserted in a cell loss case. However, if the user sets the **SDT_INSERT_LOST** bit in the SDT Reassembly Control Register at byte-address 2040h, the SDT RX_SAR inserts the number of dummy cells calculated by the Fast SN Processing state machine in a cell loss case. SDT dummy cells always contain 47 bytes of user-defined data - no attempt is made to speculate whether pointers or CAS data were present in lost cells. Therefore, it is possible for pointer reframes to occur after dummy-cell insertions, because extra dummy bytes may have been inserted into the circular buffers (e.g., if a missing cell contained a pointer, only 46 bytes of dummy fill should have been inserted into the buffers; however, 47 bytes were inserted, causing a misalignment between the internal counters of the SDT RX_SAR and the received SDT pointers).

Once the pointer byte (if present) has been processed and before any accesses are made to the SDT Reassembly Circular Buffers in external memory, the SDT RX_SAR accesses the SDT Reassembly Control Structure in internal memory to obtain the value of the internal pointer, **Current Entry**. This field, which is used to determine to which channel within the VC the next byte of data is destined, is initialized to point to the **First Entry** in the VC. Once Current Entry reaches the last channel in a VC (identified by **Last Entry**, as programmed by the user in the control structure), it wraps around to First Entry, and the process starts again. The only time that Current Entry digresses from this path (advancing from First Entry to Last Entry, and then wrapping around) is when a pointer reframe occurs, as explained in "Pointer Processing" on page 78. When a reframe occurs, the Current Entry pointer is reset to point to First Entry.

In CAS VCs, another internal variable, **Current Frame**, tracks the advancement through the SDT Reassembly Control Structure. This variable is used to determine the location at which processing is occurring within a multiframe. Current Frame increments by one each time that Current Entry wraps around (indicating that all of the channels in the VC and, therefore, the frame have been serviced). The SDT RX_SAR uses the Current Frame variable to determine whether to process the current frame of data as TDM payload bytes, or as CAS nibbles; the last frame of each multiframe (frame 16 in the E1 case, frame 24 in the DS1 case) carries CAS data. Current Frame is reset to 0 each time it finishes processing the final frame of a multiframe, or when a forced pointer reframe occurs.

The Current Entry field points to the **Reassembly Circular Buffer Base Address** within the SDT Reassembly Control Structure which corresponds to the output TDM channel to which the current byte of received cell data is destined. The pointer is used in combination with the SDT RX_SAR Write Pointer to determine the exact location in external memory to which the data is written. Each SDT Reassembly Circular Buffer for a VC is addressed by the same write pointer. The write pointer is incremented by one each time that all of the buffers for the VC have been written to (i.e., each time Current Entry wraps around).

The data written to each circular buffer entry has the format shown in Figure 27, "Per-Channel SDT Reassembly Circular Buffer," on page 81. When a VC is not carrying CAS, multiframes are not used. Therefore, the MF bit is always 0. Also, in non-CAS VCs, since no CAS is being extracted from received cells, the user should, in most cases, configure the SDT Reassembly Control Structure for the VC so that the **CASx** field in each entry in the control structure is 0. Therefore, all zeroes will be written to the CAS field within the corresponding channel's Reassembly Circular Buffer. However, if the user wants to send specific CPU-defined signalling out on a channel's CSTo output, the user can put the desired data in the CASx fields of the control structure. Whatever data is present in the CASx fields is always transferred to external memory.

When the processing of CAS nibbles is enabled (i.e., the **CAS**<0> bit in the SDT Reassembly Control Structure for a VC is set) the module first has to determine the location of the CAS nibbles within the received cells. In general, data which is extracted from cells when the Current Frame is equal to the CAS frame (frame 16 in E1 mode; frame 24 in DS1 mode), is considered to be CAS. However, within the MT90520, extra checking routines are performed to ensure that the data that is extracted from the received cells is really CAS, before it is treated as such. If there is any doubt about the integrity of the CAS (e.g., Fast SN Processing state machine is not in sync; a pointer reframe is pending), the received data is not processed as CAS. Instead, the CASx fields in the SDT Reassembly Control Structure are not updated until the error conditions have been removed and there is confidence regarding the alignment of TDM and CAS data with the correct TDM output channels. Another point should be made: the CASx fields are only updated if the **CAS**<1> bit in the SDT Reassembly Control Structure for the VC is **cleared**, indicating that the user wishes to use the received CAS nibbles, rather than user-defined signalling.

If all of the error-checking conditions outlined above are met, the extracted CAS nibble is written to the CASx field of the SDT Reassembly Control Structure, corresponding to the Current Entry pointer. Note that strict multiframing is not used in the MT90520 device, due to concern about delay. Although CAS and TDM data are meant to be aligned, the MT90520 device would have to store up all of the data for an entire AAL1 structure (i.e., a complete multiframe) if the TDM data was to be output simultaneously with the corresponding CAS data. The resultant delay in the reception of data at the TDM ports is considered to be undesirable, so extra buffering of TDM data is not performed. Instead, when all of the channels in the VC have had their corresponding CAS nibbles processed, the Current Entry and Current Frame values wrap around. In the frame following that in which CAS data is received (i.e., the first frame of the multiframe), the new CAS data is output to the TDM module. As well, the **MF** (multiframe) bit is set in each SDT Reassembly Circular Buffer corresponding to the VC. This indicator is used by the TDM module to align data with the STOMF signal on the TDM interface bus.

One other user-programmable option is possible with respect to the reception of CAS data. When a CAS nibble is received and is considered valid, regardless of whether the user has decided to enable write-backs via the clearing of CAS<1>, it is possible for an examination of the nibble to be performed. If the user sets **CAS**<2>, the received nibble is compared to the previous CAS nibble for the channel (stored in CASx). If the nibble has changed, the **Cc (CAS Changed)** bit of the VC's SDT Reassembly Control Structure is set. User software could be configured to read the VC's CAS nibbles and monitor for changes when the Cc bit is set.

SDT Overflow and Underrun Detection

The SDT RX_SAR is responsible for generating buffer overflow and buffer underrun error notifications on a per-VC basis. In addition to determining if errors occur, the SDT RX_SAR also attempts to compensate for these slips by adjusting its write pointer. The goal of the write pointer adjustment is to prevent the occurrence of multiple consecutive slips.

Upon start-up, the SDT RX_SAR write pointer is set to a pre-defined slip-pointer value, regardless of the current relationship between the SDT RX_SAR write pointer and the TDM read pointer. Therefore, if no slips occur, the write pointer should always be an "average" distance away from the TDM read pointer.

For all cells other than the first cell received on a VC, an algorithmic slip-checking routine is performed when the cell is about to be written to the SDT Reassembly Circular Buffer(s). Each time a cell is to be written to external memory, the algorithm looks at the relationship between the SDT RX_SAR's write pointer and the controlling port's TDM module's read pointer (the controlling port is determined by the setting of the **VC TDM Port** field). The algorithm then determines whether the next write to occur will be an "okay" condition, an overflow, or an underrun. Generally speaking, an "okay" condition means that the SDT RX_SAR is trying to write to a memory location which is within a pre-defined distance (determined by Maximum Lead) from the TDM read pointer. Overflow conditions are conditions in which there is a risk of the SDT RX_SAR over-writing data which has yet to be read by the TDM module. Underruns occur when the TDM has begun to re-read data from the buffer because it has not been replaced by new data from the SDT RX_SAR.

If an "okay" condition is detected, the SDT RX_SAR is permitted to write to the SDT Reassembly Circular Buffer(s) at the location determined by the **SDT RX_SAR Write Pointer** and the **Reassembly Circular Buffer Base Addresses** fields from the VC's SDT Reassembly Control Structure. In the case of a slip (either an underrun or an overflow), the SDT RX_SAR's write pointer is adjusted such that the cell is written to the circular buffer at the location of the pre-calculated slip pointer. In addition, when slips are detected, the corresponding MIB statistics fields (**Buffer Underruns** or **Buffer Overflows**) in the active VC's SDT Reassembly Control Structure are incremented.

SDT Received Cell Counter

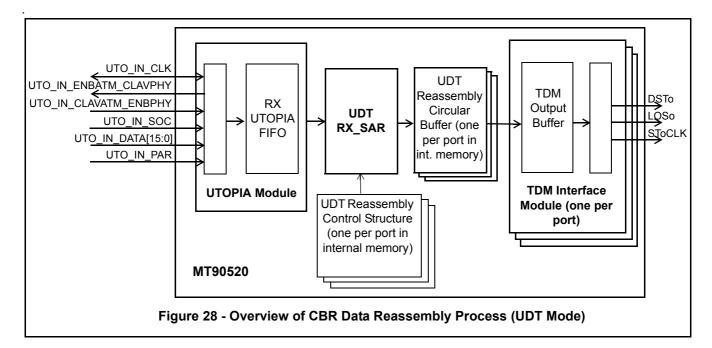
The SDT RX_SAR also provides the user with the number of SDT cells received from the UTOPIA block. This 16bit counter value can be viewed in register SRCCR at address 2048h. This counter is an overall SDT cell counter: it is incremented every time an SDT cell is received from the UTOPIA (regardless of whether the cells are discarded by the SDT RX_SAR). When this counter rolls over, a status bit gets set in the SRCSR register at address 2046h. This status bit can be cleared by software. This rollover condition can also generate a service request to the CPU if the corresponding service enable bit is set.

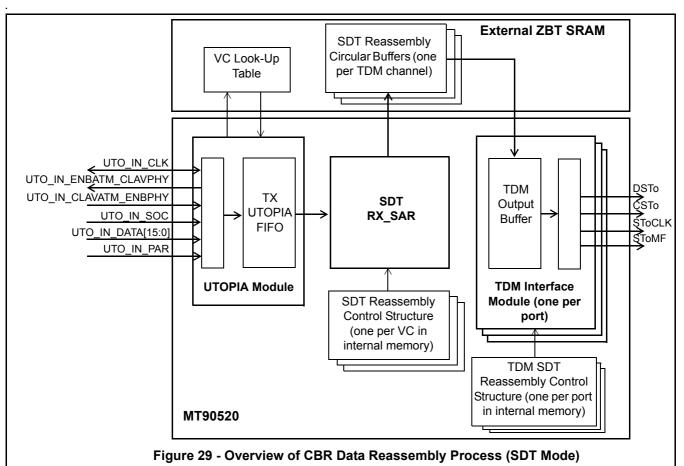
The user is also provided with a per-VC cell counter. This counter is located in the SDT Reassembly Control Structure (see Figure 26 on page 69). The operation of this counter is similar to the overall SDT cell counter. When the per-VC counter rolls over, a status bit gets set in the control structure and can be cleared by the user. The rollover condition can also generate a request to the CPU if the SDT_REAS_ROLL_SE bit is set in the SRSER register at address 2042h. The CPU can then read the contents of the SERVICE_ADD field of the SRSR register at address 2044h to identify which control structure generated the service request.

4.6.1.5.3 Complete Reassembly Data Flow Overview

The following figures give a top-level view of the data flow in the reassembly direction within the MT90520 device.

Figure 28 shows the complete segmentation data path in UDT mode, from the incoming TDM data bus to the outgoing UTOPIA data bus, whereas Figure 29 shows the complete segmentation data path in SDT mode.





4.6.1.6 Clock Recovery Operations

The SDT RX_SAR and the UDT RX_SAR are responsible for generating data required for the performance of clock recovery operations within the MT90520. In the case of adaptive clock recovery, the active RX_SAR must generate a digital phaseword for transport to the internal per-port PLL. If SRTS clock recovery is being used, the RX_SAR extracts 4-bit RTS values from incoming ATM cells and sends them to the corresponding port's PLL.

4.6.1.6.1 Digital Phaseword Generation for Adaptive Clock Recovery

If the user has decided to use adaptive clock recovery to generate the TDM output clock, SToCLK, for a port, the **A (Adaptive Enable)** bit in the UDT/SDT Reassembly Control Structure for the port must be set. In the UDT case, there is only one VC per port. However, in the SDT case, only a single VC per port (where the port is identified by the value in the **VC TDM Port** field of the Reassembly Control Structure) may have its A bit set. **Note:** In addition to the Reassembly Control Structure, the PLL for the port must also be configured to operate in adaptive mode.

If the A bit is set, the UDT RX_SAR or the SDT RX_SAR is responsible for generating a digital phaseword for the port's PLL. These phasewords represent the fill level of the Reassembly Circular Buffer(s) for a port.

In UDT mode, if it is determined that a VC is cut (see Section 4.6.2.1 on page 87), no cells are being received at the UDT RX_SAR. As a result, there is no frame of reference with which to adjust the output TDM clock rate. Accordingly, the PLL is placed into holdover mode until cells are once again being received on the VC. At that point, the output clock rate can be adjusted based on the buffer fill level.

For more information, see Section 4.7.2.6, "Adaptive Clock Recovery Circuit," on page 102.

4.6.1.6.2 RTS Reception for SRTS Clock Recovery

Although the actual SRTS clock recovery processing is a function of the Clock Management module of the MT90520 device, the UDT RX_SAR and the SDT RX_SAR are responsible for the extraction of RTS nibbles from incoming cells, for transfer to the clocking module.

In order to provide SRTS clock recovery, the UDT RX_SAR and SDT RX_SAR extract the RTSs (Residual Time Stamps) carried in the CSI bits of received ATM cells. Each time an odd-sequence-numbered cell from a preselected VC arrives, the RX_SAR extracts the CSI bit from the AAL1 header byte for the cell and stores it. When the entire RTS nibble (4 bits) has been received, it is transmitted to the Clock Management module of the MT90520 device.

In UDT mode, there is only one VC per TDM port, so the user may select it to recover RTS timing information by setting the **S** (SRTS Enable) bit in the UDT Reassembly Control Structure for the port's VC. In SDT mode, it is possible to have multiple VCs per TDM port; however, the user may select only a single VC as the source of clock recovery data for a port (the port identified by the VC TDM Port field). This selection is made by setting the **S** (SRTS Enable) bit in the SDT Reassembly Control Structure for the selected VC.

SRTS clock recovery within the MT90520 device is performed on a per-port basis, with a maximum of one VC per port carrying clocking information. Because there is only one RTS Reception sub-module to handle all of the UDT VCs (and another RTS Reception sub-module for all of the SDT VCs), variables associated with the recovery of the individual RTS bits are stored in internal memory (in the form of fields within the Reassembly Control Structures for the VCs).

Because RTS values are extracted from received cells, there is always the possibility of error (e.g., cells are received out of order, so the RTS bits are also in the wrong order). As such, a protection mechanism is included in the RTS extraction sub-module. Each time that the RX_SAR sends an RTS nibble to the port's Clock Management module, it also sends an extra bit. This bit indicates whether the current RTS value is valid. If the RTS value is invalid, the PLL discards the RTS value (as well as the locally-generated RTS value used for comparison). The PLL goes into holdover mode, in which the output clock rate is not adjusted based on the input signals. When the next "valid" RTS value is received, the PLL resumes making adjustments to the output clock rate.

For more information, see Section 4.7.2.5, "Receive SRTS Circuit Sub-Module," on page 101.

Note that in SDT mode, when using SRTS clock recovery, the MT90520 can have a maximum of 32 channels per VC. Also, no support for SRTS clock recovery is provided when operating in CAS mode.

4.6.2 Timeout Circuitry

The timeout circuitry is used to perform a variety of tasks related to the inter-arrival time between two consecutive cells on a VC.

4.6.2.1 Cut VC Monitoring

The first task performed by the timeout circuitry is related to the per-VC MIB statistic, **atmfCESCellLossStatus**. According to the CES standard, this integer-valued status field must be set to a loss value "when cells are continuously lost for the number of milliseconds specified by **atmfCESCellLossIntegrationPeriod**". Within the MT90520, rudimentary support for this statistic is provided on a per-VC basis. This functionality is supported via the **VC Arrival** (**V**) bit within each UDT/SDT Reassembly Control Structure. This bit is set by the UDT RX_SAR or the SDT RX_SAR each time a cell arrives on a particular VC. However, the CPU can, via software, clear this bit to a value of '0'. Software can then monitor the value of this bit at regular intervals. If the bit is still '0' when polled, no cells have been received on the VC since the bit was last cleared by the CPU. If the bit is still '0' after a user-configurable period of time, as defined within the user's software, a cut-VC (cell loss) may be declared. Therefore, the usage of this control structure bit, with software support, provides per-VC timeout monitoring as defined within the CES specification.

In addition to the above per-VC monitoring, the MT90520 also features extra cut-VC monitoring in the UDT case. This extra functionality is provided on a per-port basis (note that for the UDT mode of operation, per-port is the equivalent of per-VC). In order to enable this monitoring, the user must configure the MIB Timeout Configuration Register at byte-address 3000h to set the **Reassembly Cell Loss Integration Period**. The value written in this field is used by each of the per-port timeout circuits in the MT90520 (i.e., it is a device-wide value and is not programmable on a per-port basis). The value within the field is expressed in terms of milliseconds and has a default value of 2.5 s. When any of the 8 per-port timeout counters reaches the timeout period without a cell arriving on the VC for the port, the **CUT_VC_STATUS** bit for the port is set in the port's corresponding Timeout Configuration Register.

4.6.2.2 Late Cell Insertion

In UDT mode, the MT90520 provides per-port CDV monitoring. The user must, on a per-port basis, configure the **LATE_CELL_PERIOD** field in the port's Timeout Configuration Register. The value within the field is expressed in terms of 125 μ s increments, and has a default value of 256 ms. If an internal counter reaches the LATE_CELL_PERIOD, the **LATE_CELL_STATUS** bit for the "late" VC will be set in the Timeout Configuration Register for the port.

Additionally, as explained in section "UDT Mode of Operation" on page 71, if the UDT RX_SAR has been configured by the user to insert dummy cells in late-cell cases and the internal counter reaches LATE_CELL_PERIOD, a dummy cell will be inserted into the port's UDT Reassembly Circular Buffer.

4.6.2.3 Underrun Detection

The per-port timeout circuitry provides underrun detection in the UDT mode of operation.

In UDT mode, underruns are detected automatically if the TDM read pointer to a UDT Reassembly Circular Buffer is ever equal to the UDT RX_SAR's current write pointer for the corresponding port. An underrun is noted because the TDM module is reading an address within the UDT Reassembly Circular Buffer which has yet to be written by the UDT RX_SAR. When a UDT underrun is detected, notification is sent to the UDT RX_SAR, so that it can make adjustments to its next write pointer value, and so that the MIB statistics can be updated accordingly. At the same time, notification of the underrun is sent to the TDM module, causing the TDM module to output silence data (i.e., all ones) on DSTo for the port, until the underrun condition is resolved.

4.6.3 Data RX_SAR Module

Whereas the UDT RX_SAR and SDT RX_SAR handle CBR AAL1 cells, the Data RX_SAR handles non-CBR data cells. These cells may be AAL5 signalling cells, OAM-type data cells, or any other ATM cells which are received on VCs which meet the VPI/VCI matching restrictions of the UTOPIA interface of the MT90520.

The Data RX_SAR does not process or manipulate the data cells. Rather, it simply accepts cells which have been sent to it by the UTOPIA's VPI/VCI filter mechanism. Once cells are accepted by the Data RX_SAR, they are stored in a multi-cell circular buffer in external memory, where they can be analyzed by a CPU, under software control.

4.6.3.1 Mode of Operation

Unlike the UDT RX_SAR and the SDT RX_SAR, the Data RX_SAR within the MT90520 can be disabled (default = "off"). Unless enabled by setting the **Data RX_SAR Enable** bit in the Data RX_SAR Control Register at address 2020h, the Data RX_SAR ignores any incoming data cells, even if they are recognized as data cells by the UTOPIA module.

The entire 54-byte received cell (i.e., 5 bytes of header, 1 "filler" header byte (UDF2 field) required for the 16-bit UTOPIA bus, and 48 bytes of payload) is copied to a location in external memory which is identified by the Data RX_SAR Cell Buffer base address and a hardware write pointer. The base address of the buffer is user-programmable (in the Data RX_SAR Configuration Register at 2024h), as is the number of cells that can be stored in the buffer. The user can select (via the register at byte address 2024h) a buffer capable of holding 16, 32, 64, or 128 cells. Each cell is allocated 64 bytes in external memory.

A particular cell entry within the buffer is selected to be written to via the Data RX_SAR write pointer. The write pointer can not be modified by the CPU; therefore, following the assertion of Data RX_SAR Enable, writes always begin at cell location #0 within the buffer.

Received Data Cell Counter

The Data RX_SAR also provides the user with the number of data cells received from the UTOPIA block. This 16-bit counter value can be viewed in register DRCCR at address 202Ah. This counter is incremented every time a data cell is received from the UTOPIA. It is not reset when the Data RX_SAR is disabled. When this counter rolls over, a status bit gets set in the DRSR register at address 2022h. This status bit can be cleared by software. This rollover condition can also generate a service request to the CPU if the corresponding service enable bit is set in the DRCR register at address 2020h.

4.6.3.2 Error Handling

In order to prevent the CPU from reading cell locations that have not yet been written, a register is provided to store the value of the CPU's read pointer. Upon start-up, this register is reset to point to the final cell location within the buffer. In general, to prevent slip conditions, software should be designed to ensure that the CPU's read pointer is never pointing to a cell location pointed to by the Data RX_SAR write pointer. During a cell-write operation, the write pointer indicates the cell location which is currently being written (the cell is not yet valid for reading). At the end of the write process, the write pointer is incremented, pointing to the cell location which will be written with the next received data cell. Contrarily, the CPU's read pointer should be incremented at the beginning of a cell-read, to point to the cell location that is **currently** being read. At the end of a cell-read, software should **not** increment the read pointer.

The **Data RX_SAR Cell Arrival** status bit is provided to permit greater software control. This bit in the Data RX_SAR Status Register (address 2022h) is set each time that a cell has been completely written into the Data RX_SAR Cell Buffer. The bit signifies to the CPU that valid data has been written into the buffer. Software can clear this status bit by performing a write of '0' to the register bit location.

At the end of each cell-write cycle, a comparison is made between the CPU's read pointer and the Data RX_SAR's write pointer. If the write pointer is at a distance of half the buffer size from the CPU's read pointer, a buffer half full condition is flagged by setting a status bit (**Data RX_SAR Buffer Half Full**) in the Data RX_SAR Status Register (DRSR). Software can clear this bit by writing '0' to the register bit location.

If a buffer half full condition is not detected, the CPU's read pointer is compared to the Data RX_SAR's write pointer. If they are equal, an overrun condition is flagged by setting a status bit (**Data RX_SAR Cell Buffer Overrun Error**) in the Data RX_SAR Status Register at address 2022h. This status bit can be cleared by

performing a write of '0' to the register bit location. The overrun status bit may be interpreted by the user's software in two possible ways:

- If the CPU is in the middle of a read operation (i.e., it has started processing a cell in the buffer, but has not read the entire cell), this flag signifies that a buffer overrun event has occurred the Data RX_SAR has over-written the cell location which is being read by the CPU. In this case, software should discard the portion of the cell already read by the CPU and advance the read pointer so that it is pointing to a valid cell location.
- On the other hand, if the CPU is not performing a read operation, the flag signifies that a buffer overrun is about to occur. Specifically, an overrun could occur on the next cell-write. If the CPU does not read the complete subsequent cell in the buffer before the next cell-write occurs, any data stored in that cell location will be overwritten by the Data RX_SAR. As such, the next cell (which may or may not actually be overwritten) should still be treated as corrupted.

4.7 Clock Management Module

The Clock Management module of the MT90520 is designed to provide both clock control and clock recovery functions. The primary control function of the module is to generate clock signals and frame pulses to be output via the MT90520's TDM interface. With regard to clock recovery, the Clock Management module is responsible for performing synchronous clock recovery, Synchronous Residual Time Stamp (SRTS) clock recovery, and Adaptive (ACM) clock recovery, as required to meet the CES specification, af-vtoa-0078.000.

4.7.1 Overview

4.7.1.1 Clock Control

When the DS1/E1 ports of the device are operating in UDT mode, the Clock Management module generates the per-port PCM output clocks required to interface with LIUs or framer/LIUs, based on a user-selectable clock source. When operating in SDT mode, the Clock Management module generates the output clock signals as in UDT mode. However, rather than interfacing with LIUs or framer/LIUs, these signals are output to framer devices.

TDM backplane mode is a sub-set of SDT operation in which the MT90520 device interfaces directly to a TDM backplane. In this mode, each TDM port of the device is serviced by a common clock in both the input and output directions. When operating in TDM backplane mode, the Clock Management module is responsible for the generation of bidirectional clock and frame pulse signals. In order to support a variety of customer applications, the clock can be running at either once or twice the TDM data rate.

When operating in backplane slave mode, the backplane clock signal and frame pulse are routed directly from the external pins through the Clock Management module to the TDM bus module. Contrarily, when the MT90520 is operating as the TDM backplane master, it is the responsibility of the Clock Management module to generate both the clock and frame pulse signals. These signals are transmitted to external device pins as well as to the TDM bus module.

As a secondary clock control function, the Clock Management module always provides a continuous TDM line rate clock to the TDM bus module when operating in UDT mode. In the event of a Loss of Signal (LOS) condition, the Clock Management module automatically routes the port's internally-generated PLL clock to the TDM bus module if the user has selected the port's STICLK as the source for SToCLK. The TDM bus module uses a user-programmable configuration bit (TDM_LOS_CLK in the per-port TDM Control Register 1) to select either the external input clock for the port or the port's internally-generated PLL clock as the source of the TDM sampling clock.

As a clock control function which permits clock recovery at the remote end, the Clock Management module generates Residual Time Stamp (RTS) signals based on the relationship between the network clock and the local bit-rate clock, on a per-port basis. In the segmentation direction, the RTS values are output to the TX_SAR header generation module, where they are inserted into ATM cells for transmission to the remote end.

4.7.1.2 Clock Recovery

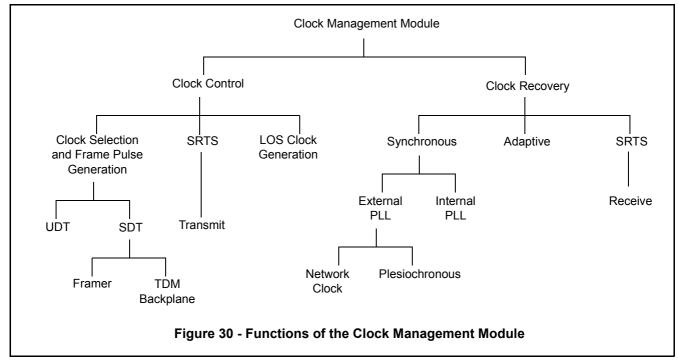
In order to meet the CES specification for SDT and UDT operation, the MT90520 provides synchronous, SRTS, and adaptive clock recovery methods.

The MT90520 permits synchronous clock recovery in UDT, SDT, and TDM backplane modes. The MT90520 provides synchronous clock recovery via either an internal PLL or an external PLL. In order to comply with the CES specification, the reference source for the optional external PLL must be traceable to a Primary Reference Source (PRS). The user has the option of sourcing the external PLL from a network clock, clocks generated by the MT90520's internal PLLs, or TDM input clocks.

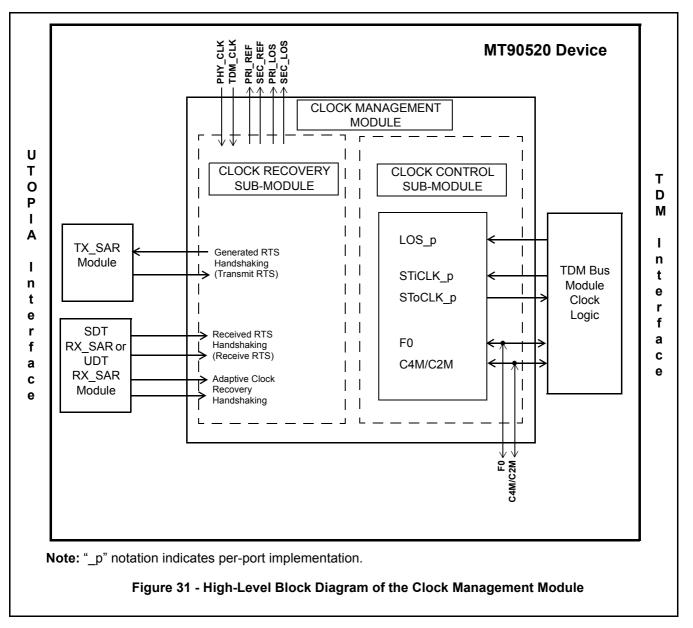
SRTS clock recovery is provided as outlined in U.S. Patent No. 5,260,978. Although the CES specification indicates that SRTS is not required for SDT clock recovery, the MT90520 device permits the use of SRTS in the SDT mode of operation when not operating in the CAS sub-mode. In the reassembly direction, RTS values extracted from incoming ATM cells by the UDT RX_SAR or SDT RX_SAR are input to the Clock Management module. Within this module, the RTS values are compared with the network clock and a new line-rate clock is generated by an internal PLL. This clock may be sent directly to the TDM bus module for use as a TDM output clock or it may be used as a reference clock for an external PLL.

Adaptive clock recovery is performed by the Clock Management module on a per-port basis, based on the fill level of the Reassembly Circular Buffers.

An overview of the functionality of the Clock Management module is given in Figure 30.



At a high level of abstraction, Figure 31 gives a general overview of the interaction between the Clock Management module and other modules within the MT90520 device. The internal configuration of the Clock Management module is examined more fully in the subsequent sub-module descriptions.



4.7.2 Functional Description

4.7.2.1 Interface to TDM Sub-Module

This sub-module acts as the interface between the Clock Management module and the TDM Interface module. STiCLK_p signals received at the TDM interface are input to this sub-module and are directed to other portions of the Clock Management module. In the output direction, SToCLK_p, C4M/C2M, and framing signals are generated by this sub-module for output to the TDM Interface module. The user has full programmability to select the source of the output clock for each TDM port.

A single interface is used to communicate with the TDM Interface module when using either UDT or SDT formatting. A separate interface and additional clocking circuitry are provided for operation in TDM backplane mode. Both interfaces and the associated circuitry are shown in Figure 32 on page 94 and are explained more fully in the text which follows.

4.7.2.1.1 Operation of SDT/UDT Interface

There are 4 possible user-selectable clock sources for SToCLK:

• the STiCLK signal for the port

- the clock generated by the port's internal digital PLL and transmitted via PLLCLK
- a synchronous clock generated from one of a number of user-selectable sources. This is a common clock which is available to all of the DS1/E1 ports of the MT90520.
- a divided-down version of the system clock (MCLK/2).

The user is able to select the desired clock source via the CLKSEL bits (found in the per-port Clocking Configuration Register at 5200h + p*10h), with MCLK/2 being the default clock which is output on SToCLK. In the event of an LOS condition, the multiplexer automatically selects the port's PLLCLK reference to be output on SToCLK, if the user had originally selected to use STiCLK as the source of SToCLK. In this way, even if the port's TDM input clock signal fails, the SToCLK signal is still valid. (**Note:** The port's internal PLL goes into holdover mode upon receiving the LOS indication.)

The user selects (via register bits) what type of clock is generated by the internal PLL. This clock may have one of the following possible sources:

- a synchronous clock generated using the port's STiCLK input reference (in Line Clocking mode)
- a synchronous clock generated using a network reference (in Network mode)
- the SRTS-recovered clock for the port (in SRTS mode)
- the clock generated using Adaptive Clock Recovery methods for the port (in Adaptive mode).

More information about the PLL implementation can be found in Section 4.7.2.7, "Internal Digital PLL Sub-Module," on page 103.

4.7.2.1.2 Operation in TDM Backplane Mode

When operating in TDM backplane mode, there are two signals which are exchanged between the backplane and the MT90520 device: F0 and C4M/C2M. These bidirectional signals (inputs when the MT90520 is slaved to the backplane; outputs when the MT90520 is the backplane master) are generated only once per device. Unlike the per-port clock and framing signals, these signals are directed into the Clock Management module from the external pins. These signals are then transferred to the TDM bus module.

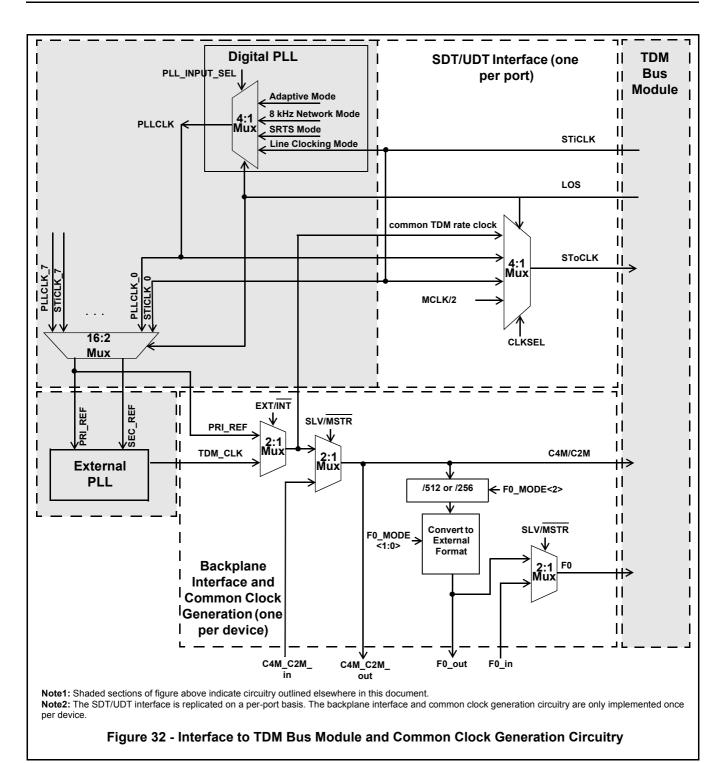
If the MT90520 is operating in slave mode, the C4M/C2M signal is routed to the TDM bus module, where it is used as both the sample and drive clock for each of the DS1/E1 ports. The F0 signal from the external pin is transmitted, unchanged, to the TDM bus module.

When operating in master mode, the Clock Management module generates both the C4M/C2M signal and the F0 signal. These signals are transmitted to external device pins as well as to the TDM bus module. The C4M/C2M signal is generated from a common TDM line rate clock, as explained in Section 4.7.2.1.3 below. The internal frame pulse signal, F0, is generated as a divided-down version of the C4M/C2M clock. The frame pulse signal is configured to a user-programmable format (either an ST-BUS or Generic frame pulse) prior to being output to both the TDM bus module and the F0 pin.

4.7.2.1.3 Common Clock Source Generation

An additional function of the circuitry shown in Figure 32 is the generation of a common TDM line rate clock for use by all of the DS1/E1 ports of the MT90520 device when it is **not** in backplane mode. The user is able to select the source for this signal (labelled as common TDM rate clock in Figure 32) as coming from either an internal or an external reference. If an external reference is selected, the common clock is sourced from the TDM_CLK pin. On the other hand, should the user not want to employ an external PLL, an internal reference may be selected. In this case, the common clock comes from the PRI_REF reference signal. The PRI_REF signal, which is explained in Section 4.7.2.2, "Synchronous Clocking Circuit" may be sourced from the internal PLL clock or the TDM input clock for any DS1/E1 port of the device.

MT90520



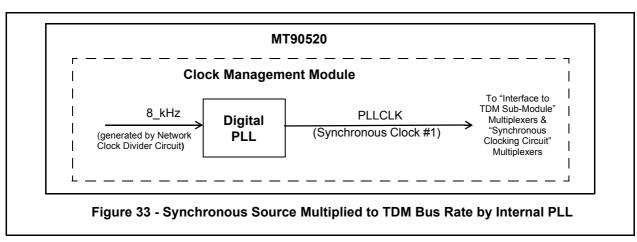
4.7.2.2 Synchronous Clocking Circuit

There are two possible options for generating a synchronous clock which is traceable to a Primary Reference Source (PRS). The first option, referred to as Synchronous Clock #1, is generated via an internal digital PLL. The second, Synchronous Clock #2, is provided via an external PLL. These options are available for UDT, SDT, and TDM Backplane modes of operation.

4.7.2.2.1 Synchronous Clock #1 (Internal Digital PLL)

Each port within the MT90520 device has its own internal digital PLL. Refer to Section 4.7.2.7, "Internal Digital PLL Sub-Module," on page 103 for information regarding the specifics of the design and its operation. This PLL performs various functions within the MT90520, including SRTS clock recovery (outlined in Section 4.7.2.5), adaptive clock recovery (described in Section 4.7.2.6), and PRS-traceable clock generation, which is explained here. Each PLL continuously generates a clock which runs at the TDM line rate.

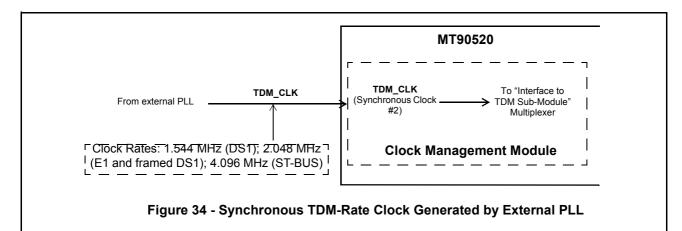
In this mode, the reference clock for all of the PLLs is provided by an 8 kHz clock, derived as a divided-down version of the network clock. The generation of this reference clock is explained in Section 4.7.2.3 on page 97. The implementation of the synchronous clock generation is shown in Figure 33.



The clock output from the PLL (PLLCLK for each of the DS1/E1 ports) is transmitted to the port's corresponding SToCLK multiplexer.

4.7.2.2.2 Synchronous Clock #2 (External PLL)

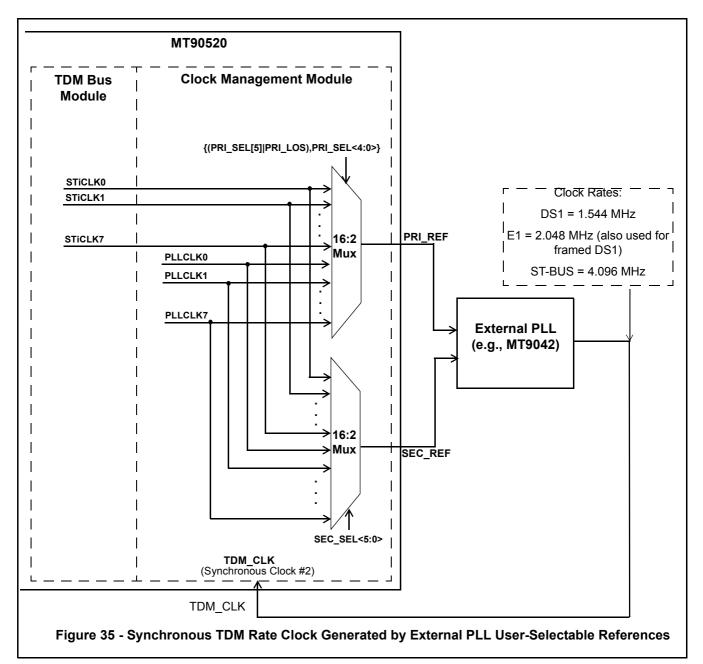
As an alternative to the internal PLL, an external PLL may be used to provide a synchronous clock for transmission onto the TDM output bus. Using this method, a PRS-traceable signal from an external PLL is input to the MT90520 via the TDM_CLK pin. Since this is a "common" clock signal (i.e., one per device), TDM_CLK is routed to a multiplexer, as shown previously in Figure 32. The output of this multiplexer is a common clock which is routed to the clock selection multiplexers (one per port) in the "Interface to TDM sub-module", detailed previously in Section 4.7.2.1. The implementation of the synchronous clock generation is shown in Figure 34.



Although the simple process outlined above provides synchronous clocking, the MT90520 also provides circuitry internal to the device which allows the use of plesiochronous clock recovery methods. Using the circuitry shown in Figure 35, the user is able to select a signal to provide a reference clock for the external PLL. The sources available are the per-port STICLK inputs and the PLLCLK signals which are generated or recovered for each DS1/E1 port of the MT90520.

The user can select the STiCLK input or the internal PLL clock from any DS1/E1 port to serve as a reference signal for the generation of SToCLK for any other port. The user is able to choose any of the 16 (2 * 8 ports) sources for the primary reference (PRI_REF), and any of the 16 sources as the secondary reference (SEC_REF). PRI_LOS and SEC_LOS are set to their selected port's LOS. The user selection for PRI_REF is overridden in an LOS condition to always provide the corresponding port's internal PLL clock as the primary reference. The user selection for SEC_REF is not overridden by an LOS condition.

It is up to the user to select mutually-exclusive sources for the external PLL if redundancy is the goal. Regardless of whether the primary or secondary reference is used, the external PLL output must be programmed to match the desired line rate. The line rate signal which is output from the external PLL is input to the MT90520 device at the TDM_CLK input pin. Alternatively, if the user does not wish to use an external PLL, the PRI_REF signal can be routed directly to the "common clock" multiplexer described previously. This implementation was shown in Figure 32.



4.7.2.3 Network Clock Divider Circuit

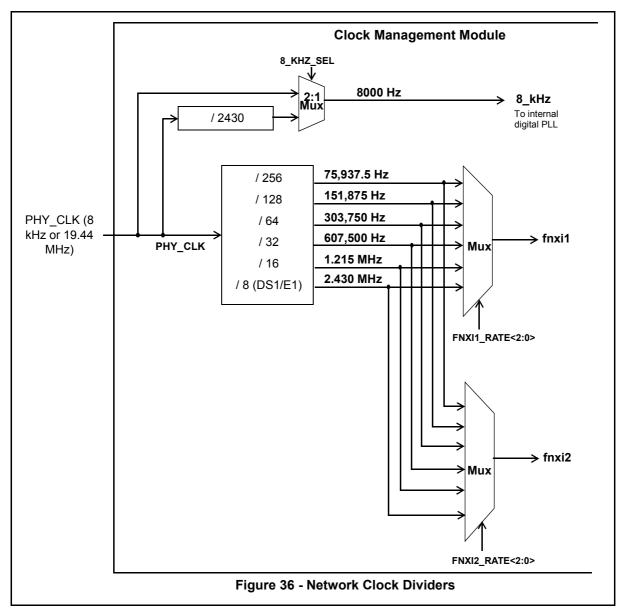
This sub-module is implemented only once within the MT90520 device and is used by both the Transmit SRTS and Receive SRTS processes. The required circuitry is shown in Figure 36.

The primary function of this sub-module is to create a divided-down network clock, fnxi, from a PHY rate clock (19.44 MHz) which is obtained from an external pin. This sub-module generates a number of different clock rates in accordance with the requirements of the SRTS patent and the CES specification.

When operating in UDT mode, only a single multiplexer is required for RTS generation and SRTS clock recovery. Since all of the VCs contain the same amount of data, only one network clock rate is required. This rate is set out in the CES specification, af-vtoa-0078.000, as 2.430 MHz.

In SDT mode, additional network clock rates are required because the size of the transmitted VCs can differ. The MT90520 permits RTS generation and SRTS clock recovery to be conducted on two different VC sizes (ranging from n = 1 to n = 32) for each device configuration.

A secondary function of the network clock divider circuit is the generation of an internal 8 kHz clock signal from the 19.44 MHz network clock. This 8 kHz signal can then be used as a reference clock to the internal PLLs outlined in Section 4.7.2.7. As an alternative, if the user wishes to provide his own 8 kHz reference for the internal PLL, an 8 kHz signal can be input directly on the PHY_CLK pin, provided that SRTS clock generation/ recovery will not be used.

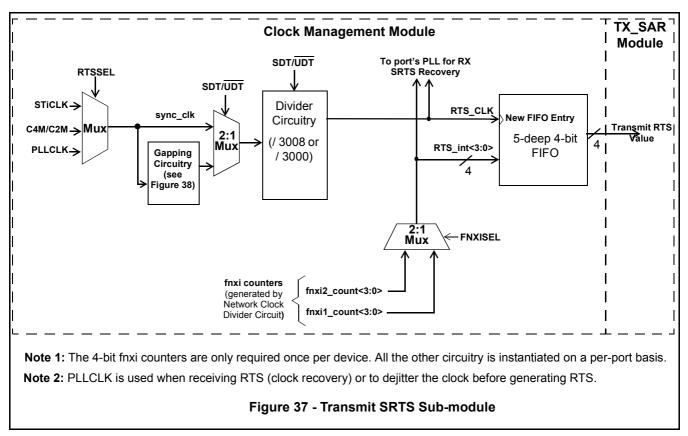


4.7.2.4 Transmit SRTS Circuit Sub-module

In the segmentation direction, the purpose of the transmit SRTS circuit sub-module is to generate 4-bit Residual Time Stamps (RTSs) to be inserted within the headers of ATM cells output on the UTOPIA bus. In the reassembly direction, this circuit is used to generate local RTS values which are compared (by an internal PLL) with the RTS values extracted from received cells. Segmentation operation is explained in this section, but the reassembly function is discussed in Section 4.7.2.5, "Receive SRTS Circuit Sub-Module".

As outlined in U.S. Patent No. 5,260,978, in the segmentation direction, the transmit SRTS circuit compares the local clock rate, determined by STiCLK for a particular port (in independent clocking or ST-BUS backplane mode) or C4M/C2M (when operating in Generic backplane mode) with the output of an fnxi counter clocked by the Network Clock Divider circuit examined in Section 4.7.2.3 on page 97. The result of the comparison is stored in a FIFO, for eventual transmission of the RTS nibbles to the TX_SAR. Underrun and overflow

detection are provided on the Transmit SRTS FIFO via status bits in CPU-accessible registers. The circuit operates in essentially the same way in the reassembly direction, except that the local clock rate is determined by the clock at the output of the port's internal PLL, PLLCLK. As well, in the reassembly direction, data is sent to the Receive SRTS sub-module rather than being sent to the Transmit SRTS FIFO. Figure 37 shows how the circuit is implemented.

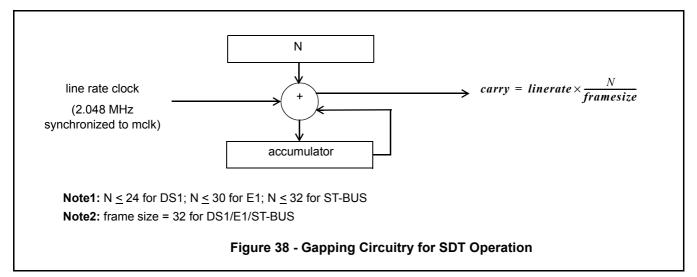


4.7.2.4.1 UDT Operation

The STICLK or PLLCLK signal for each port (C4M/C2M isn't used, because it is an SDT-mode signal) is divided down to generate a clock, RTS_CLK. This clock has the same frequency as a cycle of RTS. Since one RTS value is transmitted over the course of 8 cells, the division is by 3008, the number of payload bits transmitted within one RTS period (8 cells containing 47 payload bytes). Every time RTS_CLK pulses, the current value of the appropriate fnxi counter is stored in a FIFO. A value from the FIFO is transmitted to the TX_SAR cell header generator circuit once every 8-cell sequence.

4.7.2.4.2 SDT Operation

In some cases, the STiCLK/C4M/C2M/PLLCLK input clock requires modification prior to being used in the RTS generator circuit described above. The line rate clock (i.e., 2.048 MHz for DS1/E1/backplane) which is input to the MT90520 represents the rate at which bits are being received on a particular port. In SDT mode, the line rate only represents the bit rate of a VC if the entire stream (e.g., 32 channels in ST-BUS mode) is transmitted in a single VC. For all other cases (i.e., for N-channel VCs, where N is less than the maximum number of channels on a port), the RTS-generating clock must represent the bit rate of a particular VC. This bit rate is determined by the number of channels transmitted within a VC. Figure 38 below shows the line rate clock being passed through the gapping divider circuitry to generate a bit-rate clock.



The gapping circuit operates as follows: the line rate clock (STiCLK, C4M/C2M, or PLLCLK) must be equal to a framed clock rate. For DS1, E1, and backplane modes, this rate must be 2.048 MHz. However, the user must provide this clock differently, depending on the mode being employed. If the port is operating in **independent** clock mode, the 2.048 MHz clock is presented on STICLK and the user should select the port's STICLK as the source for the RTSSEL mux. When operating in Generic backplane mode, the desired 2.048 MHz clock rate is available at C4M/C2M. Therefore, the user should select C4M/C2M as the source for the RTSSEL mux. When operating in ST-BUS backplane mode, the C4M/C2M signal has a clock rate of 4.096 MHz. This clock is too high to be the line rate clock for the port. Therefore, the user must provide an appropriate 2.048 MHz clock on the STICLK input for the port. The user must then select the STICLK input as the source of the RTSSEL mux. This half-rate STICLK signal will not be used elsewhere in the port's circuitry, because the TDM module will use the C4M/C2M clock if it is programmed in backplane mode. In any case, the signal which is output from the RTSSEL multiplexer is input to the circuit at "line rate clock". "N" in the above figure represents the number of channels in the VC (N \leq 24 for DS1; N \leq 30 for E1; N \leq 32 for ST-BUS). Adding the number of channels to the accumulator at the rate of the line rate clock, the "carry" of the adder provides the desired clock rate. For example, if using a 2.048 MHz line rate with an 18-channel VC, we want to achieve the following result: carry = 2.048 MHz * (18/32) = 1.152 MHz. Looking at the hardware implementation, we would see the following:

N	accumulator output	accumulator input	carry
18	0	18	0
18	18	4	1
18	4	22	0
18	22	8	1
18	8	26	0
18	26	12	1
18	12	30	0
18	30	16	1
18	16	2	1
18	2	20	0
18	20	6	1
18	6	24	0

Table 20 - Sample Gapping Circuitry Calculation (N = 18)

N	accumulator output	accumulator input	carry
18	24	10	1
18	10	28	0
18	28	14	1
18	14	0	1
18	0	18	0

 Table 20 - Sample Gapping Circuitry Calculation (N = 18)

Thus, the "carry" signal results in the desired clock rate (in this case, it is slightly greater than 1/2 the line rate clock).

After the gapping circuitry, the resulting clock (carry) is divided by 3000, which represents the number of payload bits transmitted within one RTS period (7 cells containing 47 payload bytes, and one cell containing 46 payload bytes). As with UDT operation, every time RTS_CLK pulses, the current value of the finxi counter is stored in a FIFO. A value from the FIFO is transmitted to the TX_SAR cell header generator circuit every 8-cell sequence.

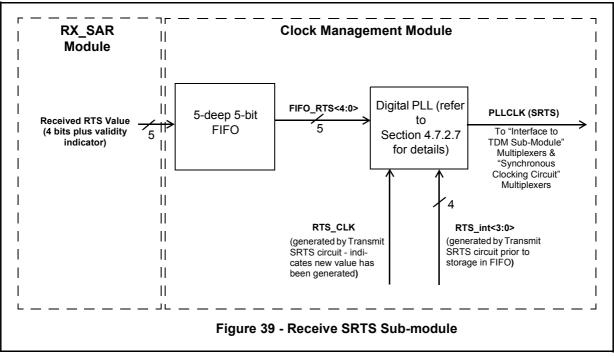
Note: Because of the divide-by-3000 circuitry, the TX SRTS circuitry won't work when a VC is set up for the SDT w/ CAS mode of operation. The problem is caused by the fact that there aren't necessarily 3000 TDM payload bits in an 8-cell cycle in these operational modes. Therefore, RTS nibble generation and SRTS clock recovery are only supported in "basic" SDT operation.

4.7.2.5 Receive SRTS Circuit Sub-Module

The receive SRTS circuit sub-module generates a bit-rate clock based on RTS values extracted from the headers of ATM cells received on the UTOPIA bus.

As outlined in U.S. Patent No. 5,260,978, the receive SRTS circuit generates a recovered clock based on a comparison between the incoming RTS values and the network clock, fnxi. This comparison provides enough information to re-create the remote (transmit) clock at the local end.

The Receive SRTS circuitry is quite simple, consisting only of a FIFO and a digital PLL, as seen in Figure 39. In addition, the Receive SRTS circuit makes use of signals generated within the Transmit SRTS circuitry, explained in Section 4.7.2.4. These pre-generated signals are also shown in Figure 39.



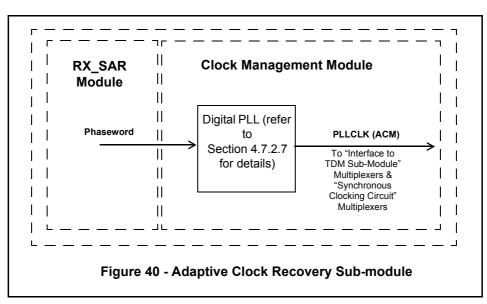
In general, the Receive SRTS sub-module simply holds a FIFO of RTS values which were extracted from received cells by either the UDT RX_SAR or the SDT RX_SAR. The RTS value transmitted from the RX_SAR to the Clock Management module is actually 5 bits long, rather than a 4-bit RTS nibble. The extra bit provides error-detection to the internal digital PLL. In the event of a lost cell or unrecoverable error being detected by the RX_SAR, the MSB of the received RTS value is set to 1. The internal digital PLL detects this error and discards the current RTS value from both the RX_SAR and the local Transmit SRTS circuit. More detail about this error protection scheme can be found in Section 4.6.1.6.2, "RTS Reception for SRTS Clock Recovery," on page 85. When the port's PLL requests a new RTS value, the Receive SRTS sub-module sends the required nibble and validity indicator to the PLL. The actual generation of the output clock based on the RTS nibbles is performed within the digital PLL. Refer to Section 4.7.2.7 on page 103 for a detailed explanation of the digital PLL design.

Note that underrun and overflow detection is provided on the Receive SRTS FIFO. Two register bits are provided to inform the user that underruns or overflows have been detected. If there were not enough RTS values placed into the Receive RTS FIFO by the UDT RX_SAR or the SDT RX_SAR (e.g., because of multiple consecutive sequence number errors, as explained above), the FIFO would eventually underrun. However, the Receive SRTS FIFO underrun protection puts the PLL into holdover mode automatically. Once an entry has been read from the Receive SRTS FIFO by the PLL, the data at that location in the FIFO is overwritten, marking the data as "invalid". Although during an underrun event, new RTS values are not being placed into the Receive SRTS FIFO, the PLL continues to read RTS values from the FIFO. Eventually, the PLL will read out previously-read data. The reception of these now-invalid RTS values forces the PLL into automatic holdover mode.

4.7.2.6 Adaptive Clock Recovery Circuit

The adaptive clock recovery technique is recommended in ITU-T I.363.1, but not standardized. The general approach is to monitor the fill-level of the received data buffers to determine the clocking rate. If the fill-level is above average, the local clock must be operating at a lower rate than the remote clock. As such, the local clock frequency should be increased so that the buffer is emptied more quickly. On the other hand, if the fill-level measured is below average, the buffer is being emptied too quickly and the local clock rate should be decreased to match the rate of the remote clock.

Within the Clock Management module, the adaptive clock recovery technique is implemented via an internal PLL, as shown in Figure 40. Each port has its own PLL, which is the same as the one outlined for SRTS operation in the preceding section. There is not any additional circuitry within the Clock Management module since the RX_SAR is responsible for providing the information required by the PLL.



Explanation of Operation: The UDT RX_SAR or the SDT RX_SAR generates a digital phaseword based on the fill-level of the UDT/SDT Reassembly Circular Buffers of the MT90520. The PLL compares the phaseword with an average value for the buffer fill of the Reassembly Circular Buffer in question. The PLL then adjusts the TDM output clock accordingly. As mentioned previously, the phaseword of the Reassembly Circular Buffer is transmitted to the Clock Management module by the RX_SAR. In the case of a slip, the phaseword is set to a pre-determined value within the RX_SAR module. In such a case, the phaseword indicates to the PLL the type of slip which occurred (i.e., underrun or overflow) so that the PLL can adjust the clock rate appropriately. In the case of a cut VC (i.e., no cells are arriving at the RX_SAR) or upon initialization, the phaseword is set in such a way that the PLL does not adjust the TDM output clock.

More explanation regarding phaseword generation can be found in Section 4.6.1.6.1, "Digital Phaseword Generation for Adaptive Clock Recovery," on page 85.

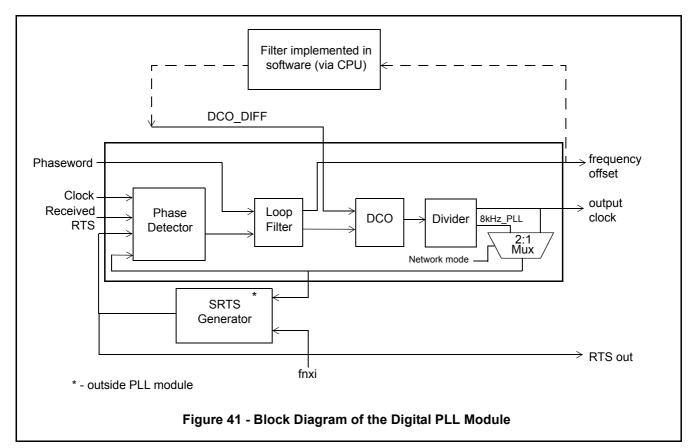
4.7.2.7 Internal Digital PLL Sub-Module

There is a separate Stratum 4 digital PLL for each of the 8 ports in the MT90520 device. This module takes care of generating several network clocks with the appropriate quality. The same PLL is used for clock recovery from TDM clocks, network clocks, SRTS data, or buffer pointer data in adaptive mode.

In all modes of operation (explained below), the PLL is capable of generating an output clock of 1.544 MHz, 2.048 MHz, or 4.096 MHz. The frequency generated is determined by the PLL_FREQ_SEL bits in the per-port Clocking Configuration Registers.

4.7.2.7.1 Architecture

A digital PLL must provide a clock synchronous to some input signal. Since there are several types of incoming signals to synchronize to, the per-port PLLs require dedicated phase detectors for the various types of input. The basic PLL architecture, however, is the same for all situations. It consists of a phase detector, a loop filter, a digital controlled oscillator and a divider (see Figure 41).



4.7.2.7.2 Modes of Operation (PLL_INPUT_SEL bits)

The PLL has four major modes of operation which are configured on a per-port basis via the PLL_INPUT_SEL bits in the Clocking Configuration Registers. The four modes are, briefly, as follows:

- Line-clocking mode: Synchronize to a 1.544 MHz, 2.048 MHz, or 4.096 MHz clock input to the chip on the
 port's corresponding STiCLK input line. Generate an outgoing clock with the appropriate frequency. The
 outgoing service clock (1.544 MHz, 2.048 MHz, or 4.096 MHz) is phase-locked to the input clock. This mode of
 operation may be used to "clean up" a jittery input clock. In line-clocking mode, the maximum locking time is
 about 15 seconds.
- SRTS mode: Synchronize to the incoming RTS nibbles (time stamps). Generate a 1.544 MHz, 2.048 MHz, or 4.096 MHz clock. The proper service output clock is fed into the per-port SRTS generator (outlined in Section 4.7.2.4, "Transmit SRTS Circuit Sub-module," on page 98) to generate a local RTS value that is compared with subsequent received RTS values. In SRTS mode, the maximum locking time is approximately 100 seconds.
- Network mode: Similar to line-clocking mode, but the input clock is an 8 kHz clock (coming either directly from the PHY_CLK pin or from a divided down version of a 19.44MHz clock input at the PHY_CLK pin). The 8 kHz clock is sourced from the Clock Management module, as explained in Section 4.7.2.3, "Network Clock Divider Circuit," on page 97. The output clock (1.544 MHz, 2.048 MHz, or 4.096 MHz) is synchronous and phaselocked to the 8 kHz input clock. In network mode, the maximum locking time is about 40 seconds.
- Adaptive mode: Synchronize to the incoming cell stream by monitoring the fill level of a VC's Reassembly Circular Buffers. The PLL receives a phaseword from the UDT RX_SAR or SDT RX_SAR. A clock rate of approximately 1.544 MHz, 2.048 MHz, or 4.096 MHz is generated, depending upon the PLL_FREQ_SEL bits.

Note that the UDT RX_SAR and SDT RX_SAR Reassembly Control Structures must be configured appropriately if either Adaptive or SRTS Clock Recovery methods are to be used. For more details, refer to the UDT RX_SAR and SDT RX_SAR module descriptions in Section 4.6.1, "UDT RX_SAR and SDT RX_SAR Modules" earlier in this document.

4.7.2.7.3 Sub-modes of Operation (PLL_MODE_SEL bits)

Within each mode described above, the PLL has four sub-modes:

- Normal sub-mode: The input (be it a clock, RTS nibbles, or phasewords) is used to synchronize the PLL output clock to the input.
- Holdover sub-mode: Either when configured as such by the user (via the PLL_MODE_SEL bits) or when a port
 experiences an LOS condition (while operating in UDT mode), the PLL is switched to holdover sub-mode. When
 in the holdover state, the PLL ignores the input and holds the output clock at its current deviation from the center
 frequency.
- Freerun sub-mode: In this sub-mode, a clock rate of 1.544 MHz, 2.048 MHz, or 4.096 MHz is generated. No input is used and the output frequency is fixed to the nominal center frequency.
- CPU sub-mode: In this mode of operation, the offset from the center frequency of the output clocks is determined by the value written to the per-port Clocking DCO Difference Register by an external CPU. The value programmed by the CPU is used to set the PLL output frequency directly, instead of using the PLL's internal filter output. This mode is intended to put an external CPU into the PLL loop. The CPU can read the filter output (from the per-port Clocking Phase Accumulator Register), process it, and write the desired factor to the DCO. This mode of operation might be used if the user wanted to implement a loop filter with a very large time constant.

More detail regarding how to configure the PLL for the various modes of operation can be found in the register descriptions for the Clock Management Module, found in Section 6.2.8 on page 138.

4.7.2.7.4 Frequency Behaviour

The PLL must generate frequencies with an accuracy as stated in Table 21. The accuracy defines the freerun accuracy and the locking range of the PLL. The accuracy of the master clock (MCLK), which has to be running at 66 MHz, must be incorporated into these figures. A freerun accuracy of approximately 0.1 ppm and a locking range of approximately 250 ppm has been implemented, thereby allowing 100 ppm MCLK accuracy and a 150 ppm input clock / RTS nibble range.

Clock	Frequency (MHz)	Accuracy (ppm)	1 UI (ns)
C1M5 (DS1)	1.544	-0.13	648
C2M (E1)	2.048	0.05	488
C4M	4.096	0.05	244

Table 21 - Center Frequency and Accuracy

4.7.2.7.5 Jitter and Wander

The af-vtoa-0078.000 standard with respect to jitter and wander points to several ANSI and ITU-T standards, as summarized in Table 22. The jitter requirements are met in all clocking modes. The wander requirements may not (nor need they) be met in adaptive mode.

Clock	Jitter	Wander
C1M5 (DS1)	ANSI T1.102	ANSI T1.403
	ITU-T G.824	ITU-T G.824
C2M (E1)	ITU-T G.823	ITU-T G.823

Table 22 - Relevant Specifications

The standards from Table 22 specify wander/jitter input tolerance and maximum output jitter. For the input wander/jitter tolerance, the low frequency parts are the largest and are therefore the most important for the PLL requirements (see Table 23). With a corner frequency larger than 1.2 Hz, the PLL will follow wander below 0.1

Hz. The range of the phase detector is therefore based upon the wander tolerance at 0.1 Hz and will be 32 UI peak-to-peak (+/- 16 UI).

Clock	A0 [UI _{pp}]	A1 [UI _{pp}]	F0 [Hz]	F1 [Hz]	@ 0.1 Hz
C1M5	28	5	1.2E-5	10	6.2
C2M	37	18	1.2E-5	20	23

Table 23 - Minimum Input Wander and Jitter Tolerance

The maximum intrinsic output jitter allowed on the output of the PLL is specified in ITU-T G.823/G.824 and is listed in Table 24. That said, the PLL within the MT90520 has a maximum intrinsic output jitter of one half of an MCLK cycle. However, any jitter on MCLK will be directly transferred to the output clocks.

Table 24 - Maximum	Allowed	Intrinsic	Output Jitter
	/		output ontion

Clock	A [UI _{pp}]	A [ns]
C1M5	0.1	65
C2M	0.2	98

4.7.2.7.6 MTIE (Maximum Time Interval Error)

ANSI T1.403 and T1.101 require that the output phase change at a speed of no more than 81 ns per 1.326 ms, with a maximum phase change of 1 μ s. Therefore, the slew rate of the DCO input is no more than 61 ppm of the center frequency setting. The "no more than 81 ns / 1.326 ms" requirement is met in all modes.

Since the period of the 1.544 MHz, 2.048 MHz, and 4.096 MHz signals is less than 1 μ s, that requirement is met automatically when the PLL is in synchronous mode. When switching between modes, the 1 μ s MTIE is not guaranteed.

4.7.2.7.7 Locking Range

When using an 8 kHz, 2.048 MHz, or 4.096 MHz input clock, a locking range of \pm 246 ppm is provided. When the input clock is 1.544 MHz, the locking range is \pm 245 ppm. Note that the locking range is related to the master clock. If the master clock (i.e., MCLK) is 100 ppm too low, the whole locking range also shifts 100 ppm downwards.

4.8 Test Interface

The MT90520 contains an IEEE 1149 standard Test Access Port (TAP), which provides Boundary-Scan test access to aid board-level testing. (IEEE 1149 is often referred to by its older designation: JTAG - Joint Test Action Group.)

4.8.1 Test Access Port

The test port is a standard IEEE 1149 interface, with the optional TRST pin. The Test Access Port consists of 5 pins:

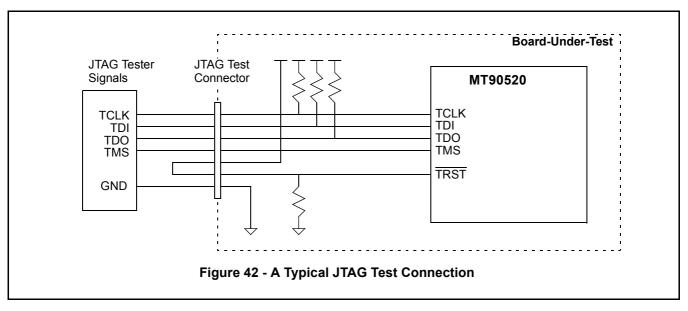
TCK: Boundary-scan Test Clock.

TDI: Test Data In; input pin clocked in on the rising edge of TCK. TDI should be pulled HIGH if boundaryscan is not in use.

TDO: Test Data Out; output pin updated on the falling edge of TCK. The output is in high-impedance except when data is actually being shifted out.

TMS: Test Mode Select; input control line clocked in on the rising edge of TCK. TMS should be pulled HIGH if boundary-scan is not in use.

TRST: Test Reset; asynchronous, active-low, input which is used to reset the JTAG interface, and the TAP controller. The TRST pin has an internal pull-down, and should also be pulled LOW externally whenever boundary-scan is not in use, to ensure normal operation of the MT90520. Figure 42 below shows a typical board-level design, including how TRST can be pulled HIGH by the test connector in cases where the tester does not provide a TRST pin.



4.8.2 JTAG ID

The JTAG device ID for the MT90520 is 1052814Bh:

Version<31:28>:	0001
Part Number<27:12>:	0000 0101 0010 1000 = 0528h
Manufacturer ID<11:1>:	0001 0100 101
LSB<0>:	1

Note that by mistake, two Zarlink products (MT90520 and MT90528) have been coded with the same Part Number into the JTAG Device ID Register.

4.8.3 Boundary Scan Instructions

The TAP Controller of the MT90520 supports the following instructions: IDCODE, BYPASS, EXTEST, SAMPLE, HIGHZ, CLAMP.

4.8.4 BSDL

A BSDL (Boundary Scan Description Language) file is available from Zarlink Semiconductor to aid in the use of the IEEE 1149 test interface.

5. Memory

5.1 Internal Memory Map

CPU Byte Address (hex)	Description	Notes
8 xxxx - TX_SAR Control Me	mory	
80000 - 87FFE	Per-VC UDT and SDT Segmentation Con- trol Structures Segmentation SDT Pointer Tables	Normal CPU access - writes and reads Buffer is 16 Kwords long
9 xxxx - SDT RX_SAR Contr	ol Memory	
90000 - 97FFE	Per-VC SDT Reassembly Control Struc- tures	Normal CPU access - writes and reads Buffer is 16 Kwords long
A xxxx - TDM Output Control		
A0000 - A003E	TDM SDT Reassembly CS - port #0	Normal CPU access - writes and reads
A0800 - A083E	TDM SDT Reassembly CS - port #1	Each per-port buffer is 32 words long.
A3800 - A3FFE	TDM SDT Reassembly CS - port #7	
B xxxx - UDT RX_SAR Contr	ol Memory	
BE000 - BE01E	UDT RX_SAR CS - port #0	Normal CPU access - writes and reads
BE020 - BE03E	UDT RX_SAR CS - port #1	Each per-port buffer is 16 words long.
BE0E0 - BE0FE	UDT RX_SAR CS - port #7	
C xxxx - UTOPIA		
C 0000 - C07FE	UTOPIA RX FIFO	CPU read access for debug
		32 cells X 64 bytes/cell = 2048 bytes
C 1000 - C11FE	UTOPIA TX FIFO	CPU read access for debug
		8 cells X 64 bytes/cell = 512 bytes

Table 25 - Internal Memory Map

5.2 External Memory

Several buffers and structures are stored in external memory when transmitting and receiving SDT and/or data cells. Since the location of the buffers and structures is not hard-coded in the hardware, the user can program the chip to put these at any location in the external memory. The following list describes the various items located in external memory, if the chip is programmed to support data and SDT cells.

As pointed out previously in this document, note that **no** external memory is required if the device is configured solely for UDT operation, provided that no data cell transmission or reception is required.

• UTOPIA Look-up Table

- configured based on N, the number of least-significant VCI bits, and M, the number of least-significant VPI bits, (programmed by the user in the UNCB register) used to form the search addresses within the look-up table
- maximum of **64K** words
- Data TX_SAR Cell Buffer
 - possible sizes: 16 cells, 32 cells, 64 cells, 128 cells (each cell occupies 64 bytes; 32 words)
 - maximum of **4K** words
- Data RX_SAR Cell Buffer
 - possible sizes: 16 cells, 32 cells, 64 cells, 128 cells (each cell occupies 64 bytes; 32 words)
 - maximum of **4K** words

• SDT Segmentation Circular Buffers

- each channel to be transmitted in ATM cells requires its own Segmentation Circular Buffer. Each buffer occupies 64 words
- up to 256 channels (8 ports x 32 channels per port) can be transmitted
- maximum of **16K** words

• SDT Reassembly Circular Buffers

- each channel which will be receiving data from ATM cells requires its own Reassembly Circular Buffer. Each buffer has a programmable size, on a per-VC basis.
- the size selected for a Reassembly Circular Buffer should be based upon the amount of CDV expected on the VC, as well as the number of channels being carried on the VC (more buffering is required on a per-channel basis for VCs with fewer channels, because more data for each channel is received at once upon cell reception). Note that CDV can be accounted for within a larger-than-necessary buffer by programming the Maximum Lead value.

Circular Buffer Size > Maximum Lead + Number of Bytes per Channel per Cell

Maximum Lead = 2 bytes + ((2*CDV) / (0.125 ms/byte)). CDV is in ms.

Number of Bytes per Channel per Cell = roundup(N/47). N = # of channels per VC.

- programmable sizes for Reassembly Circular Buffers are as follows: 64 words, 128 words, 256 words, 512 words, and 1024 words
- up to 256 channels (8 ports x 32 channels per port) can be received
- maximum of **256K** words

Figure 43 shows an example external memory allocation for the structures listed above. The example assumes the maximum memory allocation for each of the structures. The size and location of the structures are programmable and do not necessarily have to be located at the addresses given in the example. The base address in the figure is the base address of external memory.

Figure 44 shows another sample external memory allocation for the structures listed above. The example assumes the minimum memory allocation for each of the structures. The example assumes that no data cell transmission or reception is required, that all channels are transmitted in trunking VCs carrying 128 channels (therefore requiring only 2 VCs), and that minimum-sized Reassembly Circular Buffers are required. The size and location of the structures are programmable and do not necessarily have to be located at the addresses given in the example. The base address in the figure is the base address of external memory.

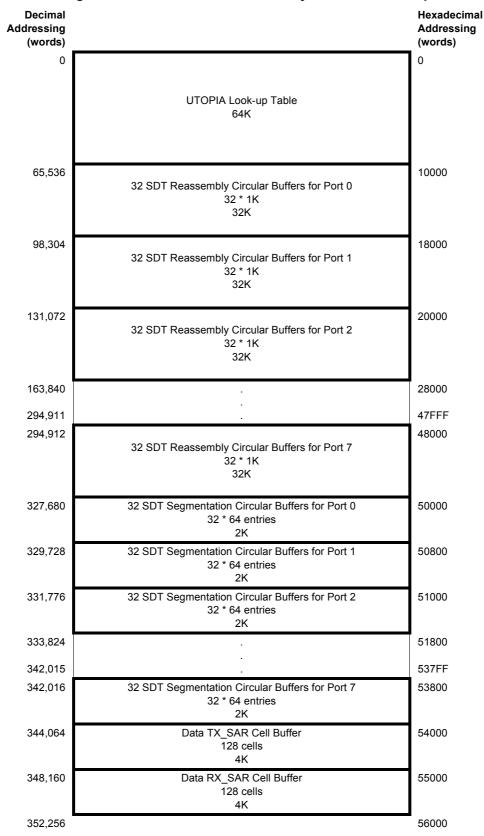


Figure 43 - Maximum External Memory Allocation - Example

Decimal Addressing (words)	с ў	· Hexadecimal Addressing (words)
0	UTOPIA Look-up Table 16 words	0
16	32 SDT Reassembly Circular Buffers for Port 0 32 * 64 words 2K	10
2064	32 SDT Reassembly Circular Buffers for Port 1 32 * 64 words 2K	810
4112	32 SDT Reassembly Circular Buffers for Port 2 32 * 64 words 2K	1010
6160		1810
14,351		380F
14352	32 SDT Reassembly Circular Buffers for Port 7 32 * 64 words 2K	3810
16,400	32 SDT Segmentation Circular Buffers for Port 0 32 * 64 entries 2K	4010
18,448	32 SDT Segmentation Circular Buffers for Port 1 32 * 64 entries 2K	4810
20,496	32 SDT Segmentation Circular Buffers for Port 2 32 * 64 entries 2K	5010
22,544	· ·	5810
30,735	:	780F
30,736	32 SDT Segmentation Circular Buffers for Port 7 32 * 64 entries 2K	7810
32,784		8010

Figure 44 - Minimum External Memory Allocation - Example

6. Registers

This section describes the registers contained within the MT90520. The MT90520 is mapped over 1 Mbyte of internal address space. The first 512 Kbytes of address space are allocated for internal register use, while the latter half of address space contains internal memory blocks within the MT90520. As shown in Table 26 on page 115, the device does not implement all of the register space available inside the chip. The unused address space is reserved for future variants of the device.

The internal registers are used by the following modules within the device:

- Microprocessor Interface
- TX_SAR
- RX_SARs (UDT, Data, and SDT)
- Reassembly-Side Timeout
- UTOPIA Interface
- Clock Management
- TDM Interface
- External Memory Interface

All registers are 16 bits long. The device only allows 16-bit (word) microprocessor accesses; byte access is not supported. However, the addresses given in the following tables are given as byte addresses.

All register addresses and reset values are listed in hexadecimal (Hex) format.

The register bit types are:

- Read / Write (R/W) can be read or written via the microprocessor interface.
- **Read Only Latched (R/O/L)** these bits are set by an activated status source (e.g., counter rollover) within the chip; once set, they remain set even if the status source is deactivated. The microprocessor can read an R/O/L bit and clear it by writing a logic '0' into it (as long as the status source is not active). Writing logic '1' has no effect on this type of register bit.
- **Read Only (R/O)** can be read via the microprocessor interface. A write to this type of register bit is ignored by the chip. However, these bits should be written with '0' to ensure software compatibility with future versions of the MT90520.

6.1 Register Overview

Table 26 - Register Summary

Byte Address Hex	Reset Value	Label	Description			
Microprocessor Interface Module						
0000	0001	CWRR	Chip Wide Reset Register			
0002	0000	MSR	Main Status Register			
0004	0000	LAWI	Low Address Word Indirection Register			
0006	0000	HAIC	High Address Indirection Command Register			
0008	0000	IDR	Indirection Data Register			
000A	0000	MIER	Main Interrupt Enable Register			
000C	0001	MRR	MT90520 Revision Register			
TX_SAR Module	9					
Per-Port TX_SA	R Registers					
1000	0000	TXPTB_P0	TX_SAR Pointer Table Base Register Port 0			
1002	0000	TXPTB_P1	TX_SAR Pointer Table Base Register Port 1			
1004	0000	TXPTB_P2	TX_SAR Pointer Table Base Register Port 2			
1006	0000	TXPTB_P3	TX_SAR Pointer Table Base Register Port 3			
1008	0000	TXPTB_P4	TX_SAR Pointer Table Base Register Port 4			
100A	0000	TXPTB_P5	TX_SAR Pointer Table Base Register Port 5			
100C	0000	TXPTB_P6	TX_SAR Pointer Table Base Register Port 6			
100E	0000	TXPTB_P7	TX_SAR Pointer Table Base Register Port 7			
Main TX_SAR R	legisters	•				
1038	0000	DTCON	Data TX_SAR Configuration Register			
103A	0000	DTWPR	Data TX_SAR Write Pointer Register			
103C	0000	DTRPR	Data TX_SAR Read Pointer Register			
103E	0000	DTCR	Data TX_SAR Control Register			
1040	0001	DCGTOR	Data Cell Generation Time Out Register			
1042	0000	DTSR	Data TX_SAR Status Register			
1044	0000	TXEN	TX_SAR Master Enable Register			
UDT RX_SAR M	lodule					
2000	00FF	URCR	UDT Reassembly Control Register			
2002	0000	URSER	UDT Reassembly Service Enable Register			
2004	001F	URSR	UDT Reassembly Status Register			
2006	0000	URCCR	UDT Reassembly Cell Counter Register			
Data RX_SAR M	lodule					
2020	0000	DRCR	Data RX_SAR Control Register			
2022	0000	DRSR	Data RX_SAR Status Register			
2024	0000	DRCON	Data RX_SAR Configuration Register			
2026	0000	DRWPR	Data RX_SAR Write Pointer Register			
2028	007F	DRRPR	Data RX_SAR Read Pointer Register			
202A	0000	DRCCR	Data RX_SAR Cell Counter Register			
SDT RX_SAR M						
2040	00FF	SRCR	SDT Reassembly Control Register			
2042	0000	SRSER	SDT Reassembly Service Enable Register			
2044	0000	SRSR	SDT Reassembly Status Register			

Byte Address Hex	Reset Value	Label	Description
2046	0000	SRCSR	SDT Reassembly Cell Counter Status Register
2048	0000	SRCCR	SDT Reassembly Cell Counter Register
Reassembly-Sic	le Timeout N	lodule	
Main Timeout R	egisters		
3000	09C4	MTCR	MIB Timeout Configuration Register
3002	0000	MTSR1	MIB Timeout Status Register 1
Per-Port Timeou	ut Registers		
3200	07FF	TCR_P0	Timeout Configuration Register Port 0
3202	07FF	TCR_P1	Timeout Configuration Register Port 1
3204	07FF	TCR_P2	Timeout Configuration Register Port 2
3206	07FF	TCR_P3	Timeout Configuration Register Port 3
3208	07FF	TCR_P4	Timeout Configuration Register Port 4
320A	07FF	TCR_P5	Timeout Configuration Register Port 5
320C	07FF	TCR_P6	Timeout Configuration Register Port 6
320E	07FF	TCR_P7	Timeout Configuration Register Port 7
UTOPIA Interfac	e Module		
Main UTOPIA R	egisters		
4000	0004	UCR	UTOPIA Configuration Register
4002	0000	UNCB	UTOPIA Number of Concatenated Bits Register
4004	0000	ULBA	LUT Base Address Register
4006	0000	UVCM	VC Match Register
4008	0000	UVCME	VC Match Enable Register
400A	0000	UVPM	VP Match Register
400C	0000	UVPME	VP Match Enable Register
400E	0000	UPM	UTOPIA Parity Mismatches Register
4010	0030	UFS	UTOPIA FIFO Status Register
4012	0000	USR	UTOPIA Status Register
4014	0000	USER	UTOPIA Service Enable Register
4016	0000	UICC	UTOPIA Incoming Cell Counter
Per-Port UTOPI	A Registers		
4200	0000	UVC_P0	UDT VCI for Port 0
4202	0000	UVP_P0	UDT VPI for Port 0
4204	0000	UVC_P1	UDT VCI for Port 1
4206	0000	UVP_P1	UDT VPI for Port 1
4208	0000	UVC_P2	UDT VCI for Port 2
420A	0000	UVP_P2	UDT VPI for Port 2
420C	0000	UVC_P3	UDT VCI for Port 3
420E	0000	UVP_P3	UDT VPI for Port 3
4210	0000	UVC_P4	UDT VCI for Port 4
4212	0000	UVP_P4	UDT VPI for Port 4
4214	0000	UVC_P5	UDT VCI for Port 5
4216	0000	UVP_P5	UDT VPI for Port 5
4218	0000	UVC_P6	UDT VCI for Port 6
421A	0000	UVP_P6	UDT VPI for Port 6
421C	0000	UVC_P7	UDT VCI for Port 7

Byte Address Hex	Reset Value	Label	Description
421E	0000	UVP_P7	UDT VPI for Port 7
Clock Managem	ent Module		
Main Clocking F	Registers		
5000	0001	CMCR	Clock Management Configuration Register
5002	0000	PLLCS	External PLL Clock Source Register
Per-Port Clockin	ng Registers	5	
Port 0			
5200	0000	CCR_P0	Clocking Configuration Register
5202	8000	CPAR_P0	Clocking Phase Accumulator Register
5204	0000	CDDR_P0	Clocking DCO Difference Register
5206	0000	CSFSR_P0	SRTS FIFO Status Register
5208	0001	PLLEN_P0	PLL Enable Register
Port 1			
5210	0000	CCR_P1	Clocking Configuration Register
5212	8000	CPAR_P1	Clocking Phase Accumulator Register
5214	0000	CDDR_P1	Clocking DCO Difference Register
5216	0000	CSFSR_P1	SRTS FIFO Status Register
5218	0001	PLLEN_P1	PLL Enable Register
Port 2			
5220	0000	CCR_P2	Clocking Configuration Register
5222	8000	CPAR_P2	Clocking Phase Accumulator Register
5224	0000	CDDR_P2	Clocking DCO Difference Register
5226	0000	CSFSR_P2	SRTS FIFO Status Register
5228	0001	PLLEN_P2	PLL Enable Register
Port 3			
5230	0000	CCR_P3	Clocking Configuration Register
5232	8000	CPAR_P3	Clocking Phase Accumulator Register
5234	0000	CDDR_P3	Clocking DCO Difference Register
5236	0000	CSFSR_P3	SRTS FIFO Status Register
5238	0001	PLLEN_P3	PLL Enable Register
Port 4			
5240	0000	CCR_P4	Clocking Configuration Register
5242	8000	CPAR_P4	Clocking Phase Accumulator Register
5244	0000	CDDR_P4	Clocking DCO Difference Register
5246	0000	CSFSR_P4	SRTS FIFO Status Register
5248	0001	PLLEN_P4	PLL Enable Register
Port 5			
5250	0000	CCR_P5	Clocking Configuration Register
5252	8000	CPAR_P5	Clocking Phase Accumulator Register
5254	0000	CDDR_P5	Clocking DCO Difference Register
5256	0000	CSFSR_P5	SRTS FIFO Status Register
5258	0001	PLLEN_P5	PLL Enable Register
Port 6			
5260	0000	CCR_P6	Clocking Configuration Register
5262	8000	CPAR_P6	Clocking Phase Accumulator Register

Byte Address Hex	Reset Value	Label	Description
5264	0000	CDDR_P6	Clocking DCO Difference Register
5266	0000	CSFSR_P6	SRTS FIFO Status Register
5268	0001	PLLEN_P6	PLL Enable Register
Port 7			
5270	0000	CCR_P7	Clocking Configuration Register
5272	8000	CPAR_P7	Clocking Phase Accumulator Register
5274	0000	CDDR_P7	Clocking DCO Difference Register
5276	0000	CSFSR_P7	SRTS FIFO Status Register
5278	0001	PLLEN_P7	PLL Enable Register
TDM Interface N	lodule		
Main TDM Regis	sters		
6000	FFFF	MAINTDM1	Main TDM Control Register 1
6002	F000	MAINTDM2	Main TDM Control Register 2
Per-Port TDM R	egisters		
Port 0			
6200	0000	TDM1_P0	TDM Control Register 1
6202	0000	TDM2_P0	TDM Control Register 2
6204	0000	TDM3_P0	TDM Control Register 3
6206	0000	TDM4_P0	TDM Control Register 4
6208	0000	TDM5_P0	TDM Control Register 5
620A	0000	TDM6_P0	TDM Control Register 6
Port 1			
6210	0000	TDM1_P1	TDM Control Register 1
6212	0000	TDM2_P1	TDM Control Register 2
6214	0000	TDM3_P1	TDM Control Register 3
6216	0000	TDM4_P1	TDM Control Register 4
6218	0000	TDM5_P1	TDM Control Register 5
621A	0000	TDM6_P1	TDM Control Register 6
Port 2			
6220	0000	TDM1_P2	TDM Control Register 1
6222	0000	TDM2_P2	TDM Control Register 2
6224	0000	TDM3_P2	TDM Control Register 3
6226	0000	TDM4_P2	TDM Control Register 4
6228	0000	TDM5_P2	TDM Control Register 5
622A	0000	TDM6_P2	TDM Control Register 6
Port 3			
6230	0000	TDM1_P3	TDM Control Register 1
6232	0000	TDM2_P3	TDM Control Register 2
6234	0000	TDM3_P3	TDM Control Register 3
6236	0000	TDM4_P3	TDM Control Register 4
6238	0000	TDM5_P3	TDM Control Register 5
623A	0000	TDM6_P3	TDM Control Register 6
Port 4			
6240	0000	TDM1_P4	TDM Control Register 1
6242	0000	TDM2_P4	TDM Control Register 2

Byte Address Hex	Reset Value	Label	Description
6244	0000	TDM3_P4	TDM Control Register 3
6246	0000	TDM4_P4	TDM Control Register 4
6248	0000	TDM5_P4	TDM Control Register 5
624A	0000	TDM6_P4	TDM Control Register 6
Port 5			
6250	0000	TDM1_P5	TDM Control Register 1
6252	0000	TDM2_P5	TDM Control Register 2
6254	0000	TDM3_P5	TDM Control Register 3
6256	0000	TDM4_P5	TDM Control Register 4
6258	0000	TDM5_P5	TDM Control Register 5
625A	0000	TDM6_P5	TDM Control Register 6
Port 6			
6260	0000	TDM1_P6	TDM Control Register 1
6262	0000	TDM2_P6	TDM Control Register 2
6264	0000	TDM3_P6	TDM Control Register 3
6266	0000	TDM4_P6	TDM Control Register 4
6268	0000	TDM5_P6	TDM Control Register 5
626A	0000	TDM6_P6	TDM Control Register 6
Port 7			
6270	0000	TDM1_P7	TDM Control Register 1
6272	0000	TDM2_P7	TDM Control Register 2
6274	0000	TDM3_P7	TDM Control Register 3
6276	0000	TDM4_P7	TDM Control Register 4
6278	0000	TDM5_P7	TDM Control Register 5
627A	0000	TDM6_P7	TDM Control Register 6
External Memor	ry Interface M	lodule	
7000	0000	MACR	Memory Arbiter Configuration Register
7004	0000	PERS	Parity Error Status Register

6.2 Register Description

Note: Unused bits (labeled as "Reserved") are reserved for future use and although most of them are read-only (R/O) bits, they should be written with '0' to ensure software compatibility with future versions of the MT90520.

6.2.1 Microprocessor Interface Module

Address: 0000 (Hex) Label: CWRR Reset Value: 0001 (Hex)						
Label	Label Bit Type Description					
RESET	0	R/W	When set to 1, the chip is put into reset mode.			
Reserved	15:1	R/O	Always reads "0000_0000_0000".			

Table 27 - Chip Wide Reset Register

Table 28 - Main Status Register

Address: 0002 (Hex) Label: MSR Reset Value: 0000 (Hex)					
Label	Bit Position	Туре	Description		
TX_SAR_SRV	0	R/O	TX_SAR Service Request.		
SDT_RXSAR_SRV	1	R/O	SDT RX_SAR Service Request.		
UDT_RXSAR_SRV	2	R/O	UDT RX_SAR Service Request.		
TDM_SRV	3	R/O	TDM Service Request.		
UTOPIA_SRV	4	R/O	UTOPIA Service Request.		
XMEMA_SRV	5	R/O	External Memory Arbiter Service Request.		
DATA_RXSAR_ SRV	6	R/O	Data RX_SAR Service Request.		
RX_TIMEOUT_SRV	7	R/O	Reassembly-Side Timeout Service Request.		
CPU_SRV	8	R/O	CPU Service Request		
Reserved	15:9	R/O	Always reads "0000_000".		

Table 29 - Low Address Word Indirection Register

Address: 0004 (Hex) Label: LAWI Reset Value: 0000 (Hex)					
Label	Bit Position	Туре	Description		
Reserved	0	R/O	Always reads '0'.		
LAW	15:1	R/W	Low Address Word. These bits represent bits<15:1> of the indirection address (in bytes). This register must be written before the HAIC register at 0006h.		

Label	Bit Position	Туре	Description
HAB	4:0	R/W	High Address Bits. These bits represent bits<20:16> of the indirection address (in bytes).
AEM	5	R/W	Access External Memory. When this bit is set, the indirection access will be to/from external memory. When this bit is cleared, the indirection access will be to/from internal memory.
RD_N_WR	6	R/W	Read/Write. '0' = CPU write. '1' = CPU read.
ACC	7	R/W	Access Cycle Complete. When this bit is set by the CPU, the indirection cycle is initiated. When low, indicates that the last indirection cycle has been completed. While an indirection access is in progress, the Microprocessor Interface Module register can be accessed. However, the CPU must wait for the ACC bit to be cleared before initiating the next access to another register block, internal memory, or external memory of the MT90520. Software cannot clear this bit (it can only be cleared by hardware).
ACC_DONE_SE	8	R/W	Access Cycle Complete Service Enable. When this bit is set and the ACC bit is low, the CPU_SRV status bit is set in the Mai Status Register at 0002h.
Reserved	15:9	R/O	Always read "0000 000".

Table 31 - Indirection Data Register

Address: 0008 (Hex) Label: IDR Reset Value: 0000 (Hex)					
Label	Bit Position	Туре	Description		
IDV	15:0	R/W	Indirection Data Value. During an indirection write cycle, the value written to this register is placed in the memory location selected in the LAWI and HAIC registers. During an indirection read cycle, the contents of the memory location selected in LAWI and HAIC are transferred to this register. In the case of a write cycle, this register must be written before the LAWI and HAIC registers . The CPU must wait for the ACC bit in the HAIC Register to be cleared before initiating the next write cycle. In the case of a read access to memory, the CPU must write the target address to the LAWI and HAIC registers and wait for ACC = 0 before reading this register.		

Table 32 - Main Interrupt Enable Register

Address: 000A (Hex) Label: MIER Reset Value: 0000 (Hex)					
Label	Bit Position	Туре	Description		
TX_SAR_IE	0	R/W	TX_SAR Interrupt Enable.		
SDT_RXSAR_IE	1	R/W	SDT RX_SAR Interrupt Enable.		
UDT_RXSAR_IE	2	R/W	UDT RX_SAR Interrupt Enable.		
TDM_IE	3	R/W	TDM Interrupt Enable.		

Table 32 - Main Interrupt Enable Register

Address: 000A (Hex) Label: MIER Reset Value: 0000 (Hex)				
Label	Bit Position	Туре	Description	
UTOPIA_IE	4	R/W	UTOPIA Interrupt Enable.	
XMEMA_IE	5	R/W	External Memory Arbiter Interrupt Enable.	
DATA_RXSAR_IE	6	R/W	Data RX_SAR Interrupt Enable.	
RX_TIMEOUT_IE	7	R/W	Reassembly-Side Timeout Interrupt Enable.	
CPU_IE	8	R/W	CPU Interrupt Enable.	
Reserved	15:9	R/O	Always reads "0000_000".	
Note: An interrupt will be generated on the IRQ pin if any of the above Interrupt Enable bits is set and there is a corresponding module-level Service Request asserted in the Main Status Register at 0002h.				

Table 33 - MT90520 Revision Register

Address: 000C (Hex) Label: MRR Reset Value: 0001 (Hex)				
Label	Label Bit Type		Description	
REV	15:0	R/O	MT90520 hardware revision.	

6.2.2 TX_SAR Module

Table 34 - TX_SAR Pointer Table Base Register (one per port)

Label: TXPTB_Pp	Address: 1000 + p*2 (Hex) Label: TXPTB_Pp (where p represents the port number) Reset Value: 0000 (Hex)				
Label	Bit Position	Туре	Description		
ТХРТВ	13:0	R/W	In SDT mode, these bits hold the base word address of the port p SDT Segmentation Pointer Table (see Figure 21 on page 61). In UDT mode, these bits form a pointer to the base word address of the UDT Segmentation Control Structure associated with port p. The SDT Segmentation Pointer Tables must start on 32-word (64-byte) boundaries.		
TXCFG	15:14	R/W	Port p Configuration: "00" = Port p is disabled "01" = UDT mode "10" = Reserved "11" = SDT mode.		

Table 35 - Data	TX_SAR	Configuration	Register
-----------------	--------	---------------	----------

Address: 1038 (Hex) Label: DTCON Reset Value: 0000 (Hex)				
Label	Bit Position	Туре	Description	
DTSIZE	1:0	R/W	Data TX_SAR Cell Buffer Size. This field indicates the number of non-CBR data cells which can be held in the Data TX_SAR's Cell Buffer: "00" = 16 cells "01" = 32 cells "10" = 64 cells "11" = 128 cells.	
DTBASE	9:2	R/W	Data TX_SAR Cell Buffer Base Address. These bits represent address bits<19:12> of the base address (in words) of the cell buffer in external memory.	
Reserved	15:10	R/O	Always reads "0000_00".	

Table 36 - Data TX_SAR Write Pointer Register

Address: 103A (Hex) Label: DTWPR Reset Value: 0000 (Hex)				
Label	Bit Position	Туре	Description	
DTWP	7:0	R/W	Data TX_SAR Write Pointer. Indicates the cell structure number to which the CPU is currently writing (the cell is not yet valid).	
Reserved	15:8	R/O	Always reads "0000_0000".	

Table 37 - Data TX_SAR Read Pointer Register

Address: 103C (Hex) Label: DTRPR Reset Value: 0000 (Hex)					
Label	Bit Position	Туре	Description		
DTRP	6:0	R/O	Data TX_SAR Read Pointer. Indicates the cell structure number from which the Data TX_SAR is currently reading. This pointer is cleared when the TDSENB bit in the Data TX_SAR Control Register at 103Eh is cleared.		
Reserved	15:7	R/O	Always reads "0000_0000_0".		

Table 38 - Data TX	_SAR Control Register
--------------------	-----------------------

Address: 103E (Hex) Label: DTCR Reset Value: 0000 (Hex)			
Label	Bit Position	Туре	Description
TDSENB	0	R/W	Data TX_SAR Enable. When cleared, the Data TX_SAR Read Pointer (register at 103Ch) is reset to "000_0000" and no data cells are transmitted. When set, the Data TX_SAR sends the cells stored in the Data TX_SAR Cell Buffer.
AUTO	1	R/W	When set, the Data TX_SAR transmits cells when the CBR TX_SAR is not busy. When cleared, data cell transmission is controlled by the DCGTOR register at 1040h.
TCBE_SE	2	R/W	Transmit Cell Buffer Empty Service Request Enable. When set, a service request to the CPU is asserted when the cell buffer is empty, as indicated by the assertion of the TCBE bit in the Data TX_SAR Status Register at 1042h. When cleared, this service request is masked.
Reserved	15:3	R/O	Always reads "0000_0000_0000_0".

Table 39 - Data Cell Generation Time Out Register

Address: 1040 (Hex) Label: DCGTOR Reset Value: 0001 (Hex)				
Label	Bit Position	Туре	Description	
DCGP	9:0	R/W	These bits control the time between data cell transmissions when the Data TX_SAR is in timer mode (i.e., AUTO=0 in Data TX_SAR Control Register at 103Eh). A value of all zeros disables data cell transmission. The time between cells is determined as follows: $\Delta(\text{Seconds}) = \frac{65535}{mclk(Hz)} \times DCGP$	
Reserved	15:10	R/O	Always reads "0000_00".	

Table 40 - Data TX_SAR Status Register

Address: 1042 (Hex) Label: DTSR Reset Value: 0000 (Hex)				
Label	Bit Position	Туре	Description	
TCBE	0	R/O	Transmit Cell Buffer Empty. This bit is set when the read pointer is equal to the write pointer and indicates that all of the cells in the buffer have been sent. This bit is cleared when the TDSENB bit in the DTCR register at 103Eh is cleared.	
Reserved	15:1	R/O	Always reads "0000_0000_0000".	

Table 41 - 7	TX SAR	Master	Enable	Register

Address: 1044 (Hex) Label: TXEN Reset Value: 0000 (H			
Label	Bit Position	Туре	Description
TXENB	0	R/W	When cleared, the TX_SAR will not produce UDT or SDT cells for any port.
Reserved	15:1	R/O	Always reads "0000_0000_0000".

6.2.3 UDT RX_SAR Module

Table 42 - UDT	Reassembly		Register
	reassembly	001101	register

Address: 2000 (Hex) Label: URCR Reset Value: 00FF (Hex)				
Label	Bit Position	Туре	Description	
UDT_DUMMY	7:0	R/W	UDT RX_SAR Dummy Cell Octet. This octet is inserted into a port's UDT Reassembly Circular Buffer 47 times when dummy cell insertion is required. Defaults to FFh, to represent silence .	
UDT_INSERT_ LOST	8	R/W	UDT Insert Number of Lost Cells Flag. When set, the number of dummy cells inserted into the UDT Reassembly Circular Buffer in the case of a multi-cell loss equals the number of lost cells (up to 7). When this bit is cleared (default), a maximum of 2 dummy cells are inserted in a multi-cell loss case.	
CHECK_ LATE_ARRIVALS	9	R/W	Check for Late Cell Arrivals in UDT mode. When set, this bit causes a dummy cell to be inserted into the UDT Reassembly Circular Buffer for the corresponding port, if the late cell timeout period for this port is passed while the port is in "sync". The late cell timeout period for the port is configured in the port's Timeout Configuration Register at 3200h + p*2h. Default value: disabled.	
Reserved	15:10	R/O	Always reads "0000_00".	

Table 43 - UDT Reassembly Service Enable Register

Address: 2002 (Hex) Label: URSER Reset Value: 0000 (Hex)					
Label	Bit Position	Туре	Description		
UDT_REASS_ ROLL_SE	0	R/W	When set, the assertion of the Reassembled Cells Counter Rollover status bit in a UDT Reassembly Control Structure will cause the UDT_RXSAR_STATUS bit to be set in the UDT Reassembly Status Register at 2004h.		
UDT_HDR_ROLL _SE	1	R/W	When set, the assertion of the AAL1 Header Byte Error Counter Rollover status bit in a UDT Reassembly Control Structure will cause the UDT_RXSAR_STATUS bit to be set in the UDT Reassembly Status Register at 2004h.		
UDT_SEQ_ROLL _SE	2	R/W	When set, the assertion of the AAL1 Sequence Error Counter Rollover status bit in a UDT Reassembly Control Structure will cause the UDT_RXSAR_STATUS bit to be set in the UDT Reassembly Status Register at 2004h.		
UDT_LOST_ ROLL_SE	3	R/W	When set, the assertion of the Lost Cells Counter Rollover status bit in a UDT Reassembly Control Structure will cause the UDT_RXSAR_STATUS bit to be set in the UDT Reassembly Status Register at 2004h.		

Address: 2002 (Hex) Label: URSER Reset Value: 0000 (Hex)				
Label	Bit Position	Туре	Description	
UDT_MIS_ROLL_ SE	4	R/W	When set, the assertion of the Misinserted Cells Counter Rollover status bit in a UDT Reassembly Control Structure will cause the UDT_RXSAR_STATUS bit to be set in the UDT Reassembly Status Register at 2004h.	
UDT_UNDER_ ROLL_SE	5	R/W	When set, the assertion of the Buffer Underrun Counter Rollover status bit in a UDT Reassembly Control Structure will cause the UDT_RXSAR_STATUS bit to be set in the UDT Reassembly Status Register at 2004h.	
UDT_OVER_ ROLL_SE	6	R/W	When set, the assertion of the Buffer Overrun Counter Rollover status bit in a UDT Reassembly Control Structure will cause the UDT_RXSAR_STATUS bit to be set in the UDT Reassembly Status Register at 2004h.	
UDT_LATE_ROLL _SE	7	R/W	When set, the assertion of the Late Cells Counter Rollover status bit in a UDT Reassembly Control Structure will cause the UDT_RXSAR_STATUS bit to be set in the UDT Reassembly Status Register at 2004h.	
Reserved	15:8	R/O	Always reads "0000_0000".	

Table 44 - UDT Reassembly Status Register

Label: URSR	Address: 2004 (Hex) Label: URSR Reset Value: 001F (Hex)					
Label	Bit Position	Туре	Description			
SERVICE_PORT	4:0	R/O	TDM port associated with the last UDT Reassembly Control Structure to generate a serviceable event (i.e., a control structure status field rollover). Defaults to 1Fh (illegal port) and returns to 1Fh when the UDT_RXSAR_STATUS bit in this register is cleared.			
Reserved	11:5	R/O	Always reads "0000_000".			
CELL_COUNTER _RO_SE	12	R/W	UDT RX_SAR Cell Counter Rollover Service Enable When set, a '1' on CELL_COUNTER_RO_STATUS in this register will cause the UDT_RXSAR_SRV bit to be set in the Main Status Register at 0002h.			
CELL_COUNTER _RO_STATUS	13	R/O/L	If set, indicates that the UDT RX_SAR Cell Counter located in register 2006h has overflowed.			
UDT_RXSAR_SE	14	R/W	UDT RX_SAR Service Enable. When set, a '1' on UDT_RXSAR_STATUS in this register will cause the UDT_RXSAR_SRV bit to be set in the Main Status Register at 0002h.			
UDT_RXSAR_ STATUS	15	R/O/L	If set, indicates that an unmasked (due to settings of the Service Enable bits in the UDT Reassembly Service Enable Register at 2002h) UDT RX_SAR serviceable event has occurred. Writing a '0' to this bit clears it and sets SERVICE_PORT to 1Fh.			

Table 45 - UDT Reassembly Cell Counter Register

Address: 2006 (Hex) Label: URCCR Reset Value: 0000 (Hex)				
Label	Bit Position	Туре	Description	
CELL_COUNTER	15:0	R/O	Number of cells received by the UDT RX_SAR.	

6.2.4 Data RX_SAR Module

Label: DRCR	Address: 2020 (Hex) .abel: DRCR Reset Value: 0000 (Hex)					
Label	Bit Position	Туре	Description			
DRENB	0	R/W	Data RX_SAR Enable. When cleared, the Data RX_SAR Write Pointer (DRWP at 2026h) is reset to 00h and all received data cells are ignored. When set, received data cells are processed normally. Default of '0' means that the Data RX_SAR is usually disabled.			
DROR_SE	1	R/W	Data RX_SAR Cell Buffer Overrun Service Enable. When set, a '1' on DROR in Register 2022h will cause the DATA_RXSAR_SRV bit to be set in the Main Status Register at 0002h.			
DRCA_SE	2	R/W	Data RX_SAR Cell Arrival Service Enable. When set, a '1' on DRCA in Register 2022h will cause the DATA_RXSAR_SRV bit to be set in the Main Status Register at 0002h.			
DRBHF_SE	3	R/W	Data RX_SAR Buffer Half Full Service Enable. When set, a '1' on DRBHF in Register 2022h will cause the DATA_RXSAR_SRV bit to be set in the Main Status Register at 0002h.			
DRCCR_SE	4	R/W	Data RX_SAR Cell Counter Rollover Service Enable. When set, a '1' on DRCCR in Register 2022h will cause the DATA_RXSAR_SRV bit to be set in the Main Status Register at 0002h.			
Reserved	15:5	R/O	Always reads "0000_0000_000".			

Table 46 - Data RX_SAR Control Register

Table 47 - Data RX_SAR Status Register

Address: 2022 (Hex) Label: DRSR Reset Value: 0000 (Hex)					
Label	Bit Position	Туре	Description		
Reserved	0	R/O	Always reads '0'.		
DROR	1	R/O/L	Data RX_SAR Cell Buffer Overrun Error. If this bit is set, the DRWP (Register 2026h) = DRRP (Register 2028h). This signifies that either a non-CBR cell has been overwritten or is about to be overwritten. Software must take appropriate actions to adjust the read pointer so that further overruns do not occur. Writing a '0' to this bit clears it.		
DRCA	2	R/O/L	Data RX_SAR Cell Arrival. This bit is set each time a data cell is written to the Data RX_SAR Cell Buffer. Writing a '0' to this bit clears it.		
DRBHF	3	R/O/L	Data RX_SAR Buffer Half Full This bit is set when the buffer is determined to be half full by comparing the read and write pointers. Writing a '0' to this bit clears it.		
DRCCR	4	R/O/L	Data RX_SAR Cell Counter Rollover. This bit is set when the Data RX_SAR Cell Counter, located in register 202Ah, overflows. Writing a '0' to this bit clears it.		
Reserved	15:5	R/O	Always reads "0000_0000_000".		

Table 48 - Data RX_SAR	Configuration Register
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Address: 2024 (Hex) .abel: DRCON Reset Value: 0000 (Hex)					
Label	Bit Position	Туре	Description		
DRSIZE	1:0	R/W	Data RX_SAR Cell Buffer Size. This field indicates the number of non-CBR data cells which can be held in the Dat RX_SAR's Cell Buffer: "00" = 16 cells "01" = 32 cells "10" = 64 cells "11" = 128 cells.		
DRBASE	12:2	R/W	Data RX_SAR Cell Buffer Base Address. Represents address bits <19:9> that point to the word address of the first structure in th cell buffer in external memory. The lower address bits <8:0> of the pointer are preset t "0_0000_0000". Cell buffers must start on boundaries corresponding to the size of the buffer (e.g 32-cell buffers must start on boundaries which are integer multiples of 32 cells * 3 words/cell). As a result, in some cases, DRBASE<2:0> (bits<11:9> of the actual address must to be set to '0', depending on the number of cells allocated in the cell buffer: 16-cell buffer: no restrictions 32-cell buffer: DRBASE<0> must equal '0' (buffers start on 1024-word boundaries) 64-cell buffer: DRBASE<1:0> must equal "00" (buffers start on 2048-word boundaries) 128-cell buffer: DRBASE<2:0> must equal "000" (buffers start on 4096-word boundaries).		
Reserved	15:13	R/O	Always reads "000".		

Table 49 - Data RX_SAR Write Pointer Register

Address: 2026 (Hex) Label: DRWPR Reset Value: 0000 (Hex)					
Label	Bit Position	Туре	Description		
DRWP	6:0	R/O	Data RX_SAR Cell Buffer Write Pointer. Indicates the cell structure number which is currently being written by the Data RX_SA (the cell is not yet valid). This value is incremented at the end of each cell-write procedur (indicates the next cell location to be written). Allowable values: 0h -> Fh (16-cell buffer) 0h -> 1Fh (32-cell buffer) 0h -> 3Fh (64-cell buffer) 0h -> 7Fh (128-cell buffer).		
Reserved	15:7	R/O	Always reads "0000_0000_0".		

Address: 2028 (.abel: DRRPR Reset Value: 00	, , ,		
Label	Bit Position	Туре	Description
DRRP	6:0	R/W	Data RX_SAR Cell Buffer Read Pointer. Indicates the cell structure number which is currently being read by the CPU. This value should not be incremented by the CPU at the end of a cell-read; therefore, if a read operation is not in progress, the pointer indicates the cell location which was last read by the microprocessor.
Reserved	15:7	R/O	Always reads "0000_0000_0".
			pon start-up, pointing to the final location within the cell buffer. Upon the start of the first reacter to point to the first cell location.

Table 51 - Data RX_SAR Cell Counter Register

Address: 202A (Hex) Label: DRCCR Reset Value: 0000 (Hex)				
Label Bit Position Type Description		Description		
CELL_COUNTER	15:0	R/O	Number of cells received by the Data RX_SAR.	

6.2.5 SDT RX_SAR Module

Address: 2040 (Hex) Label: SRCR Reset Value: 00FF (Hex)					
Label	Bit Position	Туре	Description		
SDT_DUMMY	7:0	R/W	SDT RX_SAR Dummy Cell Octet. A 47-byte cell filled with this octet is inserted into the appropriate SDT Reassembly Circular Buffer(s) when dummy cell insertion is required. Defaults to FFh, but should be set to appropriate silence value for the TDM type.		
SDT_INSERT_ LOST	8	R/W	SDT Insert Number of Lost Cells Flag. When set, the number of dummy cells inserted into the SDT Reassembly Circular Buffer(s) in the case of a multi-cell loss equals the number of lost cells (up to 6). When this bit is cleared (default), a maximum of 2 dummy cells are inserted in a multi-cell loss case.		
CB_BASE_ADD	10:9	R/W	Reassembly Circular Buffer Base Address. These bits form the 2 MSBs (bits<19:18>) of the external memory base addresses (in words) of the SDT Reassembly Circular Buffers.		
Reserved	15:11	R/O	Always reads "0000_0".		

Table 52 - SDT Reassembly Control Register

Address: 2042 (Hex) Label: SRSER Reset Value: 0000 (Hex)				
Label	Bit Position	Туре	Description	
SDT_REASS_ ROLL_SE	0	R/W	When set, the assertion of the Reassembled Cells Counter Rollover status bit in an SDT Reassembly Control Structure will cause the SDT_RXSAR_STATUS bit to be set in the SDT Reassembly Status Register at 2044h.	
SDT_HDR_ROLL _SE	1	R/W	When set, the assertion of the AAL1 Header Byte Error Counter Rollover status bit in an SDT Reassembly Control Structure will cause the SDT_RXSAR_STATUS bit to be set in the SDT Reassembly Status Register at 2044h.	
SDT_SEQ_ROLL _SE	2	R/W	When set, the assertion of the AAL1 Sequence Error Counter Rollover status bit in an SDT Reassembly Control Structure will cause the SDT_RXSAR_STATUS bit to be set in the SDT Reassembly Status Register at 2044h.	
SDT_LOST_ ROLL_SE	3	R/W	When set, the assertion of the Lost Cells Counter Rollover status bit in an SDT Reassembly Control Structure will cause the SDT_RXSAR_STATUS bit to be set in the SDT Reassembly Status Register at 2044h.	
SDT_MIS_ROLL_ SE	4	R/W	When set, the assertion of the Misinserted Cells Counter Rollover status bit in an SDT Reassembly Control Structure will cause the SDT_RXSAR_STATUS bit to be set in the SDT Reassembly Status Register at 2044h.	
REFRAME_ROLL _SE	5	R/W	When set, the assertion of the Pointer Reframes Counter Rollover status bit in an SDT Reassembly Control Structure will cause the SDT_RXSAR_STATUS bit to be set in the SDT Reassembly Status Register at 2044h.	
PARITY_ROLL_ SE	6	R/W	When set, the assertion of the Pointer Parity Counter Rollover status bit in an SDT Reassembly Control Structure will cause the SDT_RXSAR_STATUS bit to be set in the SDT Reassembly Status Register at 2044h.	
SDT_UNDER_ ROLL_SE	7	R/W	When set, the assertion of the Buffer Underrun Counter Rollover status bit in an S Reassembly Control Structure will cause the SDT_RXSAR_STATUS bit to be set in SDT Reassembly Status Register at 2044h.	
SDT_OVER_ ROLL_SE	8	R/W	When set, the assertion of the Buffer Overrun Counter Rollover status bit in an SDT Reassembly Control Structure will cause the SDT_RXSAR_STATUS bit to be set in the SDT Reassembly Status Register at 2044h.	
POINTER_OUT_ OF_RANGE_SE	9	R/W	When set, the assertion of the Pointer Out-of-Range status bit in an SDT Reassembly Control Structure will cause the SDT_RXSAR_STATUS bit to be set in the SDT Reassembly Status Register at 2044h.	
CAS_CHANGE_ SE	10	R/W	When set, the assertion of the CAS Changed status bit in an SDT Reassembly Control Structure will cause the SDT_RXSAR_STATUS bit to be set in the SDT Reassembly Status Register at 2044h.	
Reserved	15:11	R/O	Always reads "0000_0".	

Table 54 - SD	F Reassembly	v Status	Reaister
		- uuuu	

Address: 2044 (Hex) Label: SRSR Reset Value: 0000 (Hex)				
Label Bit Type		Туре	Description	
SERVICE_ADD	13:0	R/O	Base word address of the last SDT Reassembly Control Structure to generate a serviceable event (i.e., a status field rollover or bit setting). This field is cleared when the SDT_RXSAR_STATUS bit in this register is cleared.	

Table 54 - SDT Reassembly Status Register

Address: 2044 (Hex Label: SRSR Reset Value: 0000 (,		
Label	Bit Position	Туре	Description
SDT_RXSAR_SE	14	R/W	SDT RX_SAR Service Enable. When set, a '1' on SDT_RXSAR_STATUS in this register will cause the SDT_RXSAR_SRV bit to be set in the Main Status Register at 0002h.
SDT_RXSAR_ STATUS	15	R/O/L	If set, indicates that an unmasked (due to the settings of the Service Enable bits in the SDT Reassembly Service Enable Register at 2042h) SDT RX_SAR serviceable event has occurred. Writing a '0' to this bit clears it and clears the SERVICE_ADD field.

Table 55 - SDT Reassembly Cell Counter Status Register

Address: 2046 (Hex Label: SRCSR Reset Value: 0000 (,		
Label	Bit Position	Туре	Description
CELL_COUNTER _RO_SE	0	R/W	SDT RX_SAR Cell Counter Rollover Service Enable. When set, a '1' on CELL_COUNTER_RO_STATUS in this register will cause the SDT_RXSAR_SRV bit to be set in the Main Status Register at 0002h.
CELL_COUNTER _RO_STATUS	1	R/O/L	If set, indicates that the SDT Reassembly Cell Counter Register in register 2048h has overflowed. Writing a '0' to this bit clears it.
Reserved	15:2	R/O	Always reads "0000_0000_0000_00".

Table 56 - SDT Reassembly Cell Counter Register

Address: 2048 (Hes Label: SRCCR Reset Value: 0000 (
Label	Bit Position	Туре	Description
CELL_COUNTER	15:0	R/O	Number of cells received by the SDT RX_SAR.

6.2.6 Reassembly-Side Timeout Module

Table 57 - MIB Timeout Configuration Register

Address: 3000 (He) Label: MTCR Reset Value: 09C4 (,		
Label	Bit Position	Туре	Description
CUT_VC _PERIOD	15:0	R/W	Reassembly Cell Loss Integration Period. If cells on a VC are continuously lost for this period of time (given in ms), the CUT_VC_STATUS bit is set in the Timeout Configuration Register (3200h + p*2h) corresponding to the VC's "VC TDM Port". Default value = 2.5 s.

Address: 3002 (He Label: MTSR1 Reset Value: 0000	•		
Label	Bit Position	Туре	Description
STATUS_0	0	R/O	If set, indicates that either an unmasked late cell event or an unmasked cut VC event has occurred on port 0.
STATUS_1	1	R/O	If set, indicates that either an unmasked late cell event or an unmasked cut VC event has occurred on port 1.
STATUS_2	2	R/O	If set, indicates that either an unmasked late cell event or an unmasked cut VC event has occurred on port 2.
STATUS_3	3	R/O	If set, indicates that either an unmasked late cell event or an unmasked cut VC event has occurred on port 3.
STATUS_4	4	R/O	If set, indicates that either an unmasked late cell event or an unmasked cut VC event has occurred on port 4.
STATUS_5	5	R/O	If set, indicates that either an unmasked late cell event or an unmasked cut VC event has occurred on port 5.
STATUS_6	6	R/O	If set, indicates that either an unmasked late cell event or an unmasked cut VC event has occurred on port 6.
STATUS_7	7	R/O	If set, indicates that either an unmasked late cell event or an unmasked cut VC event has occurred on port 7.
Reserved	15:8	R/O	Always reads "0000_0000".

Table 59 - Timeout Configuration Register (one per port)

Address: 3200 + p* Label: TCR_Pp (wh Reset Value: 07FF (ere p represe	nts the por	t number)
Label	Bit Position	Туре	Description
LATE_CELL_ PERIOD	10:0	R/W	Late Cell Timeout. If a cell has not been received prior to this timeout (measured in 125µs increments), an internal flag is set, indicating a late cell arrival. This timer should generally be set to a value equal to the cell assembly time, plus the expected CDV. Default: 256ms In UDT mode, if this timeout period is passed, the LATE_CELL_STATUS bit in this per-port register will be set. Additionally, if the CHECK_LATE_ARRIVALS bit is set in the UDT Reassembly Control Register at 2000h, a dummy cell will also be inserted into the UDT Reassembly Circular Buffer for the port.
LATE_CELL_ SE	11	R/W	Late Cell Status Service Enable. When set, a '1' on LATE_CELL_STATUS in this register will cause the RX_TIMEOUT_SRV bit to be set in the Main Status Register at 0002h. As well, the per- port status bit for the corresponding port will be set in the MIB Timeout Status Register at 3002h.
LATE_CELL_ STATUS	12	R/O/L	If set, indicates that a late cell event has occurred on this port. This bit can be cleared by writing with '0'. Note: This bit will only be set if a port is operating in UDT mode.
CUT_VC_SE	13	R/W	Cut VC Status Service Enable. When set, a '1' on CUT_VC_STATUS in this register will cause the RX_TIMEOUT_SRV bit to be set in the Main Status Register at 0002h. As well, the per-port status bit for the corresponding port will be set in the MIB Timeout Status Register at 3002h.

Table 59 -	Timeout (Configuration	Reaister ((one per port)
		••••••••••••••••••••••••••••••••••••••		

Address: 3200 + p Label: TCR_Pp (w Reset Value: 07FF	here p represe	nts the por	t number)
Label	Bit Position	Туре	Description
CUT_VC_ STATUS	14	R/O/L	If set, indicates that a cut VC event has occurred on this port (i.e, the CUT_VC_PERIOD set in the MIB Timeout Configuration Register at 3000h has been passed without a cell arrival). This bit can be cleared by writing with '0'.
Reserved	15	R/O	Always reads '0'.

6.2.7 UTOPIA Interface Module

Table 60 - UTOPIA Configuration Register

Address: 4000 (Hex) Label: UCR Reset Value: 0004 (Hex)			
Label	Bit Position	Туре	Description
SDT_N_UDT	0	R/W	SDT/UDT. Selects between SDT mode (when set) and UDT mode (when cleared). To operate in both modes simultaneously, this bit must be cleared. When operating in UDT mode, the UDT VCI/VPI comparison is performed followed by the LUT (if necessary). In SDT mode, the look-up is performed first (the UDT VPI/VCI comparison is skipped).
UNI_N_NNI	1	R/W	UNI/NNI. Selects between UNI (when set) and NNI mode (when cleared). If NNI mode is enabled, the GFC field of the cell header will be used in the UDT VPI/VCI comparison.
UTO_CLK_SEL	2	R/W	Selects between an external clock (when set) and an internal clock (when cleared). If an internal clock is selected, UTO_IN_CLK and UTO_OUT_CLK are outputs, and the frequency of the generated clock is equivalent to MCLK/2. If an external clock is selected, UTO_IN_CLK and UTO_OUT_CLK are inputs.
GLOBAL_OAM_SEL	3	R/W	Global OAM Select. When this bit is set, received OAM cells are kept for further processing. When this bit is low, OAM cells are discarded.
EIGHT_N_SIXTEEN	4	R/W	8-bit mode/16-bit mode. Selects between UTOPIA eight-bit (when set) and sixteen-bit (when cleared) operation.
LEVEL1_N_LEVEL2	5	R/W	Level1/Level2. Selects between UTOPIA Level 1 (when set) and UTOPIA Level 2 (when cleared) operation.
UKSEL	6	R/W	When this bit is set, cells which have unknown routing according to the look-up table are placed in the Receive Data Cell Buffer; otherwise these cells are discarded.
CLAV_TRI_OVERRIDE	7	R/W	When set, this bit forces the CLAV signals to always drive a defined value. When this bit is cleared, the CLAV signals become high impedance following a clock cycle in which the MT90520 is not polled.
DATA_TRI_OVERRIDE	8	R/W	When set, this bit forces UTO_OUT_SOC and UTO_OUT_DATA to always drive defined values. When this bit is low, the UTO_OUT_SOC and the UTO_OUT_DATA signals become high impedance, as defined in the ATM Forum UTOPIA Level 2 specification.
PHY_N_ATM	9	R/W	PHY/ATM. When set, the MT90520's UTOPIA interface will operate in PHY mode; when the bit is cleared, the MT90520's UTOPIA interface will operate in ATM mode.

Table 60 - UTOPIA Configuration Register

Address: 4000 (Hex) Label: UCR Reset Value: 0004 (Hex)			
Label	Bit Position	Туре	Description
DEVICE_ADDRESS	14:10	R/W	Defines the address of the MT90520 device used to compare to the UTO_IN_ADD and UTO_OUT_ADD buses when operating in MPHY mode. Note: Only addresses 00h to 1Eh are valid.
UTO_CLK_ CONFIGURED	15	R/W	The user must set this bit at least one clock cycle after the UTO_CLK_SEL bit has been programmed. For normal operation of the UTOPIA port, this bit must be set and must not be cleared. This bit should be set only once the UTOPIA is fully programmed (including the LUT, which should be cleared (all the entries set to 0003h) even if not used).

Table 61 - UTOPIA Number of Concatenated Bits Register

Label	Bit Position	Туре	Description
М	3:0	R/W	M least-significant bits of the VPI used for external memory look-ups. The valid range for this value is 0 to 12.
Ν	8:4	R/W	N least-significant bits of the VCI used for external memory look-ups. The valid range for this value is 4 to 16.
BACK_TO_BACK _DISABLED	9	R/W	When asserted this bit will force the RX UTOPIA ATM state machine to pause after each cell reception by driving the UTO_IN_ENBATM_ CLAVPHY signal to '1'
Reserved	15:10	R/O	Always reads "0000_00".

Table 62 - LUT Base Address Register

Address: 4004 (Hex) Label: ULBA Reset Value: 0000 (Hex)				
Label	Bit Position	Туре	Description	
LUT_BASE_ADD	15:0	R/W	Contains the 16 most significant bits of the Look-Up Table base address. These bits represent byte address bits<20:5> of the external memory. If N+M is greater than 4, bits<(N+M):5> of the Look-Up Table base address should be set to 0. (For example, if N+M=7, bits<7:5> should be set to "000")	

Table 63 - VC Match Register

Address: 4006 (Hex) Label: UVCM Reset Value: 0000 (Hex)				
Label	Bit Position	Туре	Description	
VC_MATCH	15:0	R/W	Contains match values for each of the bits in the VCI.	

Table 64 - VC Match Enable Register

Address: 4008 (He) Label: UVCME Reset Value: 0000 (,		
Label	Bit Position	Туре	Description
VC_MATCH_ENB	15:0	R/W	Each bit, when set, enables the comparison of a cell's VCI and the corresponding VC_MATCH bit. If a bit in this register is not set, the corresponding bit in the received cell VCI is considered valid, regardless of the setting in the VC_MATCH field.

Table 65 - VP Match Register

Address: 400A (Hex) Label: UVPM Reset Value: 0000 (Hex)					
Label	Bit Position	Туре	Description		
VP_MATCH	11:0	R/W	Contains match values for each of the twelve bits in the VPI (including the GFC field).		
Reserved	15:12	R/O	Always reads "0000".		

Table 66 - VP Match Enable Register

Address: 400C (Hex) Label: UVPME Reset Value: 0000 (Hex)					
Label	Bit Position	Туре	Description		
VP_MATCH_ENB	11:0	R/W	Each bit, when set, enables the comparison of a cell's VPI and the corresponding VP_MATCH bit. If a bit in this register is not set, the corresponding bit in the received cell VPI is considered valid, regardless of the setting in the VP_MATCH field. In UNI mode, bits<11:8> should be cleared to avoid the comparison of the GFC.		
Reserved	15:12	R/O	Always reads "0000".		

Table 67 - UTOPIA Parity Mismatches Register

Address: 400E (Hex) Label: UPM Reset Value: 0000 (Hex)				
Label	Bit Position	Туре	Description	
PARITY_ MISMATCHES	15:0	R/O	Contains a count of the mismatches between UTO_IN_DATA and UTO_IN_PARITY. If this counter rolls over, the PARITY_ROLL_STATUS bit in the UTOPIA Status Register at 4012h will be set.	

Address: 4010 (Hex) Label: UFS Reset Value: 0030 (Hex)				
Label	Bit Position	Туре	Description	
UTOPIA_ LOOPBACK	0	R/W	When set, this bit forces the UTOPIA port into loopback mode. Data is looped from the incoming UTOPIA bus to the outgoing UTOPIA bus, through the incoming UTOPIA FIFO and the outgoing UTOPIA FIFO. The incoming data is filtered by the Match and Match Enable filters before being re-transmitted.	
UTO_OUT_FIFO_ RESET	1	R/W	When set, empties the outgoing UTOPIA FIFO.	
UTO_IN_FIFO_ RESET	2	R/W	When set, empties the incoming UTOPIA FIFO.	
UTO_OUT_FIFO_ FULL	3	R/O	If set, this bit indicates that the outgoing UTOPIA FIFO is full.	
UTO_OUT_FIFO EMPTY	4	R/O	If set, this bit indicates that the outgoing UTOPIA FIFO is empty.	
UTO_IN_FIFO_ EMPTY	5	R/O	If set, this bit indicates that the incoming UTOPIA FIFO is empty.	
UTO_IN_FIFO_ FULL	6	R/O	If set, this bit indicates that the incoming UTOPIA FIFO is full.	
Reserved	15:7	R/O	Always reads "0000_0000_0".	

Table 69 - UTOPIA Status Register

Address: 4012 (Hex) Label: USR Reset Value: 0000 (Hex)					
Label	Bit Position	Туре	Description		
CELL_CNT_ROLL _STATUS	0	R/O/L	If set, this status bit indicates that the UTOPIA interface has received 2 ¹⁶ cells, as counted by the UTOPIA Incoming Cell Counter at 4016h.		
PARITY_ROLL_ STATUS	1	R/O/L	If set, this status bit indicates that the UTOPIA interface has received 2 ¹⁶ data words containing parity errors, as counted by the UTOPIA Parity Mismatches Register at 400Eh.		
Reserved	15:2	R/O	Always reads "0000_0000_0000_00".		

Table 70 - UTOPIA Service Enable Register

Address: 4014 (Hex) Label: USER Reset Value: 0000 (Hex)					
Label	Label Bit Type Description				
CELL_CNT_ROLL _SE	0	R/W	When set, a '1' on CELL_CNT_ROLL_STATUS will cause the UTOPIA_SRV bit to be set in the Main Status Register at 0002h.		
PARITY_ROLL_ SE	1	R/W	When set, a '1' on PARITY_ROLL_STATUS will cause the UTOPIA_SRV bit to be set in the Main Status Register at 0002h.		
Reserved	15:2	R/O	Always reads "0000_0000_0000_00".		

Table 71 - UTOPIA Incoming Cell Counter

Address: 4016 (Hex) Label: UICC Reset Value: 0000 (Hex)					
Label	Bit Position	Туре	Description		
CELL_CNT	15:0	R/O	Counter indicating the number of cells received by the UTOPIA interface. If this counter rolls over, the CELL_CNT_ROLL_STATUS status bit in the UTOPIA Status Register at 4012h will be set. Note: This counter counts the number of SOC signals detected at the incoming UTOPIA interface. Therefore, both "good" and errored cells are counted.		

Table 72 - UDT VCI for Port p (one per port)

Address: 4200 + p*4 (Hex) Label: UVC_Pp (where p represents the port number) Reset Value: 0000 (Hex)				
Label	Bit Position	Туре	Description	
UDT_VCI	15:0	R/W	UDT VCI for TDM port p. The VCI value of the incoming cell is compared to this value to determine if the cell is destined for port p.	

Table 73 - UDT VPI for Port p (one per port)

Address: 4202 + p*4 (Hex) Label: UVP_Pp (where p represents the port number) Reset Value: 0000 (Hex)				
Label	Bit Position	Туре	Description	
UDT_VPI	11:0	R/W	UDT VPI for TDM port p. The VPI value of the incoming cell is compared to this value to determine if the cell is destined for port p. In UNI mode, only the 8 least significant bits of this field are used for the comparison. In NNI mode, all 12 bits are used.	
OAM_SEL	12	R/W	OAM select for port p. When set, OAM cells with matching VPI/VCI are sent to the Receive Data Cell Buffer. When cleared, OAM cells arriving on this VC are discarded.	
Reserved	15:13	R/O	Always reads "000".	

6.2.8 Clock Management Module

Label	Bit Position	Туре	Description		
SLV_N_MSTR	0	R/W	Slave/Master. When set, the signals F0 and C4M_C2M are sourced from the TDM backplane (input: When cleared, the MT90520 generates these signals (outputs). When the MT90520 is not operating in backplane mode, this bit should be set to (i.e., slave mode). Furthermore, if operating in backplane mode, this bit shou only be cleared if the user wishes the MT90520 to control the F0 and C4M_C2 backplane signals.		
EXT_N_INT	1	R/W	External/Internal. When set, the common clock and the "master" C4M_C2M and F0 signals are generate from the clock input to the MT90520 at TDM_CLK (this is usually sourced from an extern PLL). When cleared and if in master mode, the C4M_C2M and F0 signals are generated from a internal version of the output signal PRI_REF.		
F0_MODE	4:2	R/W	Frame Pulse Format Selector. F0_MODE<0> - Frame Pulse Polarity (used only in Generic mode): '0' = Negative polarity '1' = Positive polarity. F0_MODE<1> - Frame Pulse Trigger Edge (used only in Generic mode): '0' = Negative-edge trigger '1' = Positive-edge trigger. F0_MODE<2> - Frame Pulse Format: '0' = Generic '1' = ST-BUS.		
8_KHZ_SEL	5	R/W	Internal 8 kHz clock source. Used to select the origin of the 8 kHz clock source used by the internal PLLs. When set, the 8 kHz clock is generated as a divided-down version of the 19.44 MHz input to the MT90520 at PHY_CLK. When cleared, an 8 kHz clock is expected to be input directly at PHY_CLK.		
FNXI1_RATE	8:6	R/W	FNXI Rate Selector 1. (See Notes 1 and 2) These bits are used to select the rate of the FNXI clock (#1) from which outgoing R' values will be generated, and to which incoming RTS values will be compared: "000" = 75,937.5 Hz "001" = 151,875 Hz "010" = 303,750 Hz "011" = 607,500 Hz "100" = 1.215 MHz "101" = 2.43 MHz (UDT rate) "110" = 4.86 MHz "111" = 9.72 MHz.		
FNXI2_RATE	11:9	R/W	FNXI Rate Selector 2. (See Notes 1 and 2) These bits are used to select the rate of the FNXI clock (#2) from which outgoing R' values will be generated, and to which incoming RTS values will be compared: "000" = 75,937.5 Hz "001" = 151,875 Hz "010" = 303,750 Hz "011" = 607,500 Hz "100" = 1.215 MHz "101" = 2.43 MHz (UDT rate) "110" = 4.86 MHz "111" = 9.72 MHz.		

Table 74 - Clock Management Configuration Register

Table 74 - Clock Management Configuration Register

Label	Bit Position	Туре	Description
BACKPLANE_CLK _CONFIGURED	12	R/W	TDM Backplane Clock Configured Must be set once the C4M_C2M and F0 signals are stable. This bit needs to be high in order to ensure the synchronization of the TDM ports programmed in backplane mode. A toggle of this bit resets the synchronization of all the TDM ports programmed in backplane mode.
Reserved	15:13	R/O	Always reads "000".

Label	Bit Position	Туре	Description
PRI_SEL	5:0	R/W	 Primary Clock Source for External PLL. Used to select the primary clock source for the external PLL (signals output on PRI_REF and PRI_LOS). Bits<4:0> indicate which port should provide the clock source (only "00000":"00111" are valid choices). Bit<5> indicates whether the port's TDM input clock (STiCLK) or the port's internally generated PLL clock should be used as the clock source. '0' = STiCLK; '1' = PLLCLK. Note: If the port selected to provide the primary reference experiences an LOS condition that port's PLLCLK will be used as PRI_REF, even if the port's STiCLK is selected via PRI_SEL<5>.
SEC_SEL	11:6	R/W	Secondary Clock Source for External PLL. Used to select the secondary clock source for the external PLL (signals output or SEC_REF and SEC_LOS). Bits<4:0> indicate which port should provide the clock source (only "00000": "00111" are valid choices). Bit<5> indicates whether the port's TDM input clock (STiCLK) or the port's internally generated PLL clock should be used as the clock source. '0' = STiCLK; '1' = PLLCLK. Note: An LOS condition on the port selected to provide the secondary reference clock wi have no effect on the selection of the clock source for SEC_REF.
Reserved	15:12	R/O	Always reads "0000".

Table 75 - External PLL Clock Source Register

Table 76 - Clocking Configuration Register (one per port)

Label	Bit Position	Туре	Description	
CLKSEL	1:0	R/W	STOCLK Selector. These bits are used to select the source for the port's SToCLK output signal: "00" = MCLK/2 "01" = STICLK "10" = PLLCLK (generated by the port's internal PLL) "11" = common clock; sourced from either the TDM_CLK input pin (if the EXT_N_INT bit is set in the Clock Management Configuration Register at 5000h) or from an internal versior of the output signal PRI_REF (if the EXT_N_INT bit is cleared). Note: If there is an LOS signal received on this port and the user has selected to source SToCLK from STiCLK, the user's configuration will be overridden and SToCLK will be sourced from PLLCLK.	
RTSSEL	3:2	R/W	RTS Clock Selector. These bits are used to select the source for the internal RTS clock: "00" = STiCLK (used when transmitting RTS in independent mode or in ST-BUS backplane mode) "01" = C4M_C2M (used when transmitting RTS in Generic backplane mode) "10" = PLLCLK (used when receiving RTS & performing clock recovery) "11" = Reserved. Note: When transmitting RTS from a TDM port that is operating in ST-BUS backplane mode, it is necessary to present a bit-rate clock to the Tx SRTS circuitry. The user muss provide this clock by presenting a 2.048 MHz clock on the STiCLK input of the transmitting port. Due to this restriction, the C4M_C2M backplane clock must be either an input ("slave" mode), or it must be generated from a reference source other than this port's STiCLK input.	
FNXISEL	4	R/W	FNXI Source Selector. This bit is used to select either the FNXI1 or the FNXI2 clock rate for RTS generation comparison: '0' = FNXI1_RATE '1' = FNXI2_RATE.	
PLL_FREQ_SEL	6:5	R/W	Output Frequency Selector for Internal PLL. "00" = 1.544 MHz "01" = 2.048 MHz "10" = 4.096 MHz "11" = Reserved.	
PLL_MODE_SEL	8:7	R/W	Operating Mode for Internal PLL. These bits define the operating mode of the PLL. "00" = Normal mode; output synchronized to the input. "01" = Holdover mode; output no longer follows the input, but holds last frequency setting. "10" = Freerun mode; output is fixed to the nominal frequency. "11" = CPU mode; the output frequency is directly controlled by the programmable DCO_DIFF_p value, regardless of PLL_INPUT_SEL.	
PLL_INPUT_SEL	10:9	R/W	 PLL input mode. These bits define the input used to generate the PLL's output clock. "00" = Line Clocking mode; input is from the port's STiCLK (can also be used to dejitter the clock for timestamp generation; see Figure 37 on page 99 for an illustration). "01" = SRTS mode; input is a digital Synchronous Residual Time Stamp stream from the RX_SAR. "10" = Network mode; input is the 8 kHz network reference (derived from PHY_CLK pin see bit<5> of the Clock Management Configuration Register at 5000h). "11" = Adaptive mode; input is determined by the buffer-fill-level from the RX_SAR. 	
VC_CHANNELS	15:11	R/W	Number of Channels in VC. This field is used when generating or receiving RTS nibbles in SDT mode. It indicates the number of channels in the VC which is carrying timing information for the port. The field must be programmed by the user to be one less than the actual number of channels in the VC (possible values = 00h to 1Fh).	

Table 77 - Clocking Phase Accumulator Register (one per port)

Label	Bit Position	Туре	Description
PHASE_ACCUM	10:0	R/O	Internal PLL Phase Accumulator. This 2's complement value represents the long-term frequency offset of the output clock from the PLL's centre frequency. This value translates to the frequency offset as follows: freq_offset = (phase_accum/3139881) * 1,544,000 Hz for DS1 mode freq_offset = (phase_accum/4164817) * 2,048,000 Hz for E1 mode freq_offset = (phase_accum/4164817) * 4,096,000 Hz for C4 mode.
Reserved	14:11	R/O	Always reads "0000".
PHASE_LIMITER	15	R/O	Internal PLL Phase Limiter. When cleared, indicates that the PLL is limiting its phase detector output so that the PLI output phase changes no more than 6 ns / 125 μs. A change of more than 6 ns / 125 μs typically occurs when the PLL is not locked or when there is large jitter on the input signal of the PLL. When PHASE_LIMITER is high for approximately 30 seconds, one can assume that the PLL is in lock; contrarily, when PHASE_LIMITER is low for approximately 30 seconds, the PLL is out of lock.

Table 78 - Clocking DCO Difference Register (one per port)

Address: 5204 + p*10 (Hex) Label: CDDR_Pp (where p represents the port number) Reset Value: 0000 (Hex)				
Label	Bit Position	Туре	Description	
DCO_DIFF	11:0	R/W	Frequency offset value. When PLL_MODE_SEL (in register 5200h + p*10h) is set to CPU mode, the value in this field is used to set the PLL output frequency directly, instead of using the filter output. In CPU mode, the PLL input selected by PLL_INPUT_SEL (in register 5200h + p*10h) is no longer used. Data read from this field is interpreted as 2's complement format.	
Reserved	15:12	R/O	Always reads "0000".	

Table 79 - SRTS FIFO Status Register (one per port)

Address: 5206 + p*10 (Hex) Label: CSFSR_Pp (where p represents the port number) Reset Value: 0000 (Hex)			
Label	Bit Position	Туре	Description
RX_OVERFLOW_ERROR	0	R/O/L	Receive SRTS FIFO Overflow Error. If set, the Receive SRTS FIFO has overflowed. Writing a '0' to this bit clears it.
RX_UNDERFLOW_ERROR	1	R/O/L	Receive SRTS FIFO Underflow Error. If set, the Receive SRTS FIFO has underrun. Writing a '0' to this bit clears it.
TX_OVERFLOW_ERROR	2	R/O/L	Transmit SRTS FIFO Overflow Error. If set, the Transmit SRTS FIFO has overflowed. Writing a '0' to this bit clears it.
TX_UNDERFLOW_ERROR	3	R/O/L	Transmit SRTS FIFO Underflow Error. If set, the Transmit SRTS FIFO has underrun. Writing a '0' to this bit clears it.
Reserved	15:4	R/O	Always reads "0000_0000_0000".

Table 80 - PLL Enable Register (one per port)

Address: 5208 + p*10 (Hex) Label: PLLEN_Pp (where p represents the port number) Reset Value: 0001 (Hex)					
Label	Bit Position	Туре	Description		
PLL_ENABLE	0	R/W	When cleared, the PLL for this port is held in reset.		
Reserved	15:1	R/O	Always reads "0000_0000_0000_000".		

6.2.9 TDM Interface Module

Table 81 - Main TDM Control Register 1

Address: 6000 (Hex) Label: MAINTDM1 Reset Value: FFFF (Hex)					
Label	Bit Position	Туре	Description		
IDLE_DATA	7:0	R/W	User-programmable idle data. (Applies only to SDT mode.) When a channel is idle (I bit is set in the corresponding TDM SDT Reassembly Control Structure), idle data is output on DSTo.		
SILENCE_DATA	15:8	R/W	User-programmable silence data. (Applies only to SDT mode.) When a channel is experiencing a TDM underrun, this silence data is output on DSTo if REPLAY_N_SILENCE is cleared in the TDM Control Register 3 for that port.		

Table 82 - Main TDM Control Register 2

Address: 6002 (I Label: MAINTDN Reset Value: F00	12		
Label	Bit Position	Туре	Description
Reserved	11:0	R/O	Always reads "0000_0000_0000".
IDLE_CAS	15:12	R/W	User-programmable idle CAS. (Applies only to SDT mode.) When a channel is idle (I bit is set in the corresponding TDM SDT Reassembly Control Structure), idle CAS nibbles are output on CSTo.

Table 83 - TDM Control Register 1 (one per port)

Address: 6200 + p*10 (Hex) Label: TDM1_Pp (where p represents the port number) Reset Value: 0000 (Hex)				
Label	Bit Position	Туре	Description	
TDM_CIR_BUF_ LPBK	0	R/W	TDM Circular Buffer Loopback. (Applies only to SDT mode.) '0' = Normal operation. '1' = Data input on DSTi is output on DSTo, after routing through the SDT circular buffers in external memory.	
TDM_LOS_CLK	1	R/W	Incoming Loss of Signal. (Applies only to UDT mode.) '0' = Normal operation (continue to use STiCLK during an LOS condition). '1' = Switch to MT90520's internal clock source if loss of signal is detected on CSTi/LOSi.	

Table 83 -	TDM Cont	rol Register 1	l (one	per port)

Label	Bit Position	Туре	Description
TDM_LOS_POL	2	R/W	Incoming TDM LOS Polarity. (Applies only to UDT mode; must be set in SDT mode.) '0' = Negative polarity (i.e., zero on CSTi/LOSi means loss of signal). '1' = Positive polarity (i.e., one on CSTi/LOSi means loss of signal).
TDM_CAS_ LOCATION	3	R/W	TDM Signalling. (Applies only to SDT mode.) '0' = Signalling nibbles are located in the LS four bits of each channel. '1' = Signalling nibbles are located in the MS four bits of each channel.
TDM_MAPPING_ SCH	4	R/W	TDM Mapping Scheme. (Applies only to an incoming DS1 link in SDT mode.) In Generic mode: '0' = Use first 24 channels. '1' = Use 3 channels out of every 4. In ST-BUS mode, this bit must be cleared.
TDM_PULSE_ SEL	5	R/W	TDM Frame Pulse Selection. (Applies only to SDT mode.) '0' = STiMF pin is a frame pulse. '1' = STiMF pin is a multiframe pulse. In Backplane SDT mode, this bit must cleared.
TDM_PULSE_ POL	6	R/W	TDM Frame Pulse Polarity. (Applies only to SDT mode.) In Generic mode: '0' = Negative polarity. '1' = Positive polarity. In ST-BUS mode, this bit must be cleared.
TDM_CLK_POL	7	R/W	Segmentation TDM Input Clock Polarity. '0' = TDM data is sampled on the rising edge. '1' = TDM data is sampled on the falling edge. In ST-BUS SDT mode, this bit must be set.
TDM_CLK_RATE	8	R/W	TDM Clock Rate. '0' = TDM clock is 1.544 MHz. '1' = TDM clock is 2.048 MHz or 4.096 MHz.
TDM_LINK_TYPE	9	R/W	TDM Link Type. '0' = E1 link. '1' = DS1 link.
INT_LOS_ ENABLE	10	R/W	Internal LOS Enable (Applies only to UDT mode). '0' = Internal version of LOS disabled. '1' = Internal version of LOS enabled. If this bit is set, the occurrence of an LOS event on the port will be propagated throughout the device, possibly influencing the signals output on PRI_REF, PRI_LOS, and the port's SToCLK. This bit must be set if TDM_LOS_CLK (bit<1>) is set.
TDM_CLK_MODE	11	R/W	TDM Clocking Mode. (Applies only to SDT mode; must be cleared in UDT mode.) '0' = Independent mode (Independent clocks and frame pulses) '1' = Backplane mode (Common clock and frame pulse)
TDM_BUS_ MODE	12	R/W	TDM Bus Mode (Applies only to SDT mode; must be cleared in UDT mode.) '0' = Generic. '1' = ST-BUS. (The clock is 4.096 MHz.)

Table 83 - TDM Control Register 1 (one per port)

Address: 6200 + p*10 (Hex) Label: TDM1_Pp (where p represents the port number) Reset Value: 0000 (Hex)

Reset Value: 0000 (00 (Hex)		
Label	Bit Position	Туре	Description
TDM_DATA_ FORMAT	14:13	R/W	TDM Data Mode. "00" = No cells generated from this port. "01" = UDT mode "10" = SDT mode. "11" = SDT mode with N>46. This mode should be used when any VC associated with this port has more than 46 channels.
TDM_LOW_ LATENCY_LPBK	15	R/W	Low latency loopback. '0' = Normal operation. '1' = Loopback data from DSTi to DSTo. Note 1: If this bit is set, data from DSTi is output on DSTo, regardless of the value of the TDM_REASS_PORT_CONTROL bit in TDM Control Register 3 (i.e., even if the port is apparently inactive, loopback data will be output on DSTo). Note 2: To use low-latency loopback, the clock edge used to sample the incoming TDM data (determined by TDM_CLK_POL in this register) must be opposite to the clock edge used to drive the outgoing TDM data (determined by TDM_REASS_CLK_POL, set at 6204h). Note 3: The delay through the device in low latency loopback mode is approximately 2 TDM clock cycles.

Table 84 - TDM Control Register 2 (one per port)

Address: 6202 + p*10 (Hex) Label: TDM2_Pp (where p represents the port number) Reset Value: 0000 (Hex)					
Label	Bit Position	Туре	Description		
TDM_SEGMEN_ BASE_ADD	8:0	R/W	Segmentation Circular Buffer Base Address. (Applies only to SDT mode.) Represents bits<19:11> of the SDT Segmentation Circular Buffer word address in external memory.		
Reserved	12:9	R/O	Always reads "0000".		
TDM_SEGMEN_ PORT_CONTROL	13	R/W	Segmentation TDM Port Control. '0' = Port is not active (data is not transferred from the TDM module to the rest of the MT90520). '1' = Port is active.		
TDM_SEGMEN_ INT_ENB	14	R/W	Segmentation Internal Enable Process. '0' = Process is disabled. '1' = Process that writes data/CAS to the TDM input buffer is enabled.		
TDM_SEGMEN_ EXT_ENB	15	R/W	Segmentation External Enable Process. (Applies only to SDT mode.) '0' = Process is disabled. '1' = Process that transfers data from the input buffer to external memory is enabled.		

Table 85 - TDM Control Register 3 (one per port)

Label	Bit Position	Туре	Description					
TDM_REASS_ BASE_ADD	4:0	R/W	SDT Reassembly Circular Buffer Base Address. (Applies only to SDT mode.) Represents bits<19:15> of the SDT Reassembly Circular Buffer word address in external memory.					
Reserved	9:5	R/O	Always reads "00_000".					
REPLAY_ N_SILENCE	10	R/W	 Play old data or silence byte on underrun. (Applies only to SDT mode.) '0' = During a TDM underrun, the reassembly process outputs silence bytes (programmed in the MAINTDM1 register at 6000h) on DSTo. '1' = During a TDM underrun, the reassembly process replays the reassembly circular buffer. 					
TDM_REASS_ CLK_POL	11	R/W	Reassembly TDM Output Clock Polarity. '0' = TDM data is driven out on the falling edge of SToCLK or C4M_C2M '1' = TDM data is driven out on the rising edge of SToCLK or C4M_C2M. In ST-BUS, this bit must be set to "0"					
TDM_REASS_ LOS	12	R/W	Outgoing Loss of Signal. (Applies only to UDT mode.) CSTo/LOSo pin drives out the value programmed in this field.					
TDM_REASS_ PORT_CONTROL	13	R/W	Reassembly TDM port control. '0' = Port is not active (output data pins are held in high impedance). '1' = Port is active.					
TDM_REASS_ INT_ENB	14	R/W	Reassembly Internal Enable Process. '0' = Process is disabled. '1' = Process that transfers data/CAS from the TDM output buffer to the output pins is enabled.					
TDM_REASS_ EXT_ENB	15	R/W	Reassembly External Enable Process. (Applies only to SDT mode.) '0' = Process is disabled. '1' = Process that transfers data/CAS from external memory to the TDM output buffer is enabled.					

Table 86 - TDM Control Register 4 (one per port)

Label	Bit Position	Туре	Description
Reserved	0	R/O	Always reads '0'.
UDT_LOS_SE	1	R/W	UDT Loss of Signal (LOS) Service Enable. When this bit is set and UDT_LOS_STATUS is asserted, TDM_SRV is set in the Main Status Register at 0002h.
UDT_TDM_OUT_ BUF_ERROR_SE	2	R/W	UDT TDM Output Buffer Error Service Enable. When this bit is set and UDT_TDM_OUT_BUF_STATUS is asserted, TDM_SRV is set in the Main Status Register at 0002h.
SDT_TDM_OUT_ BUF_ERROR_SE	3	R/W	SDT TDM Output Buffer Error Service Enable. When this bit is set and SDT_TDM_OUT_BUF_STATUS is asserted, TDM_SRV is set in the Main Status Register at 0002h.
SDT_PERM_ UNDER_SE	4	R/W	SDT Permanent Underrun Service Enable. When this bit is set and SDT_PERM_UNDER_STATUS is asserted, TDM_SRV is set in the Main Status Register at 0002h.
SDT_SIMPLE_ UNDER_SE	5	R/W	SDT Simple Underrun Service Enable. When this bit is set and SDT_SIMPLE_UNDER_STATUS is asserted, TDM_SRV is set in the Main Status Register at 0002h.

Table 86 - TDM Control Register 4 (one per port)

Address: 6206 + p*10 (Hex) Label: TDM4_Pp (where p represents the port number) Reset Value: 0040 (Hex)

Reset Value: 0040 (Reset Value: 0040 (Hex)										
Label	Bit Position	Туре	Description								
UDT_LOS_ STATUS	6	R/O/L	UDT Loss of Signal (LOS) Status. This bit is set when a loss of signal is detected on CSTi/LOSi. Writing a '0' to this bit clears it. This bit cannot be cleared until the TDM Control Register 1 is programmed.								
UDT_TDM_OUT_ BUF_STATUS	7	R/O/L	UDT TDM Output Buffer Error Status. This bit is set when there is an error in the UDT TDM output buffer. Writing a '0' to this bit clears it.								
SDT_TDM_OUT_ BUF_STATUS	8	R/O/L	SDT TDM Output Buffer Error Status. This bit is set when there is an error in the SDT TDM output buffer. Writing a '0' to this bit clears it.								
SDT_PERM_ UNDER_STATUS	9	R/O/L	SDT Permanent Underrun Status. This bit is set when a permanent underrun service enable bit is set in the TDM SDT Reassembly Control Structure for the port and the corresponding permanent underrun condition occurs. Writing a '0' to this bit clears it.								
SDT_SIMPLE_ UNDER_STATUS	10	R/O/L	SDT Simple Underrun Status. This bit is set when a simple underrun service enable bit is set in the TDM SDT Reassembly Control Structure for the port and the corresponding simple underrun condition occurs. Writing a '0' to this bit clears it.								
SIMPLE_UNDER RUN_REPORT	15:11	R/O	SDT Simple Underrun Report. Indicates the TDM channel on which a "simple underrun" occurred last.								

Table 87 - TDM Control Register 5 (one per port)

Address: 6208 + p*10 (Hex) Label: TDM5_Pp (where p represents the port number) Reset Value: 0000 (Hex)								
Label Bit Position Type Description								
PERM_ UNDERRUN_ REPORT	15:0	R/O/L	Permanent Underrun Report. (Applies only to SDT mode.) This register represents bits<31:16> of the 32-bit permanent underrun report. Bits <31:30> are reserved (see Section "Underrun Detection in SDT Mode" on page 45). Bit<29> corresponds to channel 29, bit<28> corresponds to channel 28, etc. When an underrun occurs on a certain channel, the corresponding bit is set high; the microprocessor can clear these bits by writing them to '0'.					

Table 88 - TDM Control Register 6 (one per port)

Address: 620A + p*10 (Hex) Label: TDM6_Pp (where p represents the port number) Reset Value: 0000 (Hex)								
Label Bit Position Type Description								
PERM_ UNDERRUN_ REPORT	15:0	R/O/L	Permanent Underrun Report. (Applies only to SDT mode.) This register represents bits<15:0> of the 32-bit permanent underrun reports. Bit<15> corresponds to channel 15, bit<14> corresponds to channel 14, etc. When an underrun occurs on a certain channel, the corresponding bit is set high; the microprocessor can clear these bits by writing them to '0'.					

6.2.10 External Memory Interface Module

	Bit		
Label	Position	Туре	Description
MCFG	2:0	2:0 R/W	Memory Configuration: "000" = No external memory "100" = Bank of 1M words (max. 1 bank) "101" = Banks of 512K words (max. 2 banks) "110" = Banks of 256K words (max. 4 banks) "111" = Banks of 128K words (max. 4 banks) All others = Reserved.
ΜΤΥΡ	3	R/W	Memory Type: '0' = Flow-through '1' = Pipelined.
PESE	4	R/W	Parity Error Service Enable. When this bit is set and either the LPPRTY_E bit or the HBPRTY_E bit is asserted 7004h, the XMEMA_SRV bit is set in the Main Status Register at 0002h.
Reserved	15:5	R/O	Always reads "0000_0000_000".

Table 89 - Memory Arbiter Configuration Register

Table 90 - Parity Error Status Register

Address: 7004 (Hex) Label: PERS Reset Value: 0000 (Hex)									
Label	Bit Position	Туре	Description						
LBPRTY_E	0	R/O/L	Low Byte Parity Error. If set, this bit indicates that a parity error has occurred in the lower 8 bits of the data word being read from external memory. A parity error may occur if a location in memory is read before being written. Writing '0' to this bit clears it.						
HBPRTY_E	1	R/O/L	High Byte Parity Error. If set, this bit indicates that a parity error has occurred in the high 8 bits of the data word being read from external memory. A parity error may occur if a location in memory is read before being written. Writing '0' to this bit clears it.						
Reserved	15:2	R/O	Always reads "0000_0000_0000_00".						

7. Electrical Specification

7.1 DC Characteristics

;

	Parameter	Symbol	Min	Мах	Units
1	Supply Voltage - 2.5 Volt Rail	V _{DD2}	V _{SS}	3.5	V
2	Supply Voltage - 3.3 Volt Rail	V _{DD3}	V _{SS}	4.5	V
3	Voltage on 3.3V Input pins	V _{I3}	- 0.5	6	V
4	Voltage on 3.3V Output pins	V _{O3}	- 0.5	4.6	V
5	Continuous current at digital inputs	I _I		±10	mA
6	Continuous current at digital outputs	Ι _Ο		± 24	mA
7	Storage Temperature	Τ _S	- 40	+125	°C

* Exceeding these figures may cause permanent damage. Functional operation under these conditions is not guaranteed. Voltage measurements are with respect to ground (V_{SS}) unless otherwise stated. Long-term exposure to absolute maximum ratings may affect device reliability, and exceeding the maximum ratings may cause permanent damage. The device should be operated under recommended operating conditions.

Table 92 - Recommended Operating Conditions

	Characteristics	Sym	Min	Тур ^а	Мах	Units	Test Conditions
	Characteristics	Sym	IVIIII	тур	IVIAX	Units	lest conditions
1	Operating Temperature	T _{OP}	- 40	25	+ 85	°C	
2	Supply Voltage, 2.5 Volt Rail	V _{DD2}	2.37	2.5	2.63	V	
3	Supply Voltage, 3.3 Volt Rail	V _{DD3}	3.13	3.3	3.46	V	
4	Input Voltage, 3.3 V inputs	V _{I3}	- 0.5		5.5	V	

a. Typical figures are at 25°C and are for design aid only; not guaranteed and not subject to production testing. Voltage measurements are with respect to ground (V_{SS}) unless otherwise stated.

Table 93 - DC Characteristics

	Characteristics	Sym	Min	Тур ^а	Мах	Units	Test Conditions ^b
1	Supply Current - 2.5 V supply	I _{DD2}		395	590	mA	66.0 MHz, UDT mode
2	Supply Current - 2.5 V supply	I _{DD2}		400	620	mA	66.0 MHz, SDT mode
3	Supply Current - 3.3 V supply	I _{DD3}		16	42	mA	66.0 MHz, UDT mode, Notes 1, 2
4	Supply Current - 3.3 V supply	I _{DD3}		24	57	mA	66.0 MHz, SDT mode, Notes 1, 3
5	Device Power Dissipation (2.5V and 3.3V supplies)	P _{DDU}		1.0	1.7	W	66.0 MHz, UDT mode, Notes 1, 2
6	Device Power Dissipation (2.5V and 3.3V supplies)	P _{DDS}		1.1	1.8	W	66.0 MHz, SDT mode, Notes 1, 3
7	Input High Voltage (3.3V CMOS)	V _{IH3}	2.3		5.5	V	
8	Input Low Voltage (3.3V CMOS)	V _{IL3}	-0.5		1.0	V	
9	Switching Threshold (3.3V CMOS)	V _{TC3}	1.24	1.36	1.59	V	
10	Schmitt Trigger Positive Threshold	V _{t+}		1.57	1.72	V	

	Characteristics	Sym	Min	Тур ^а	Max	Units	Test Conditions ^b				
11	Schmitt Trigger Negative Threshold	V _{t-}	0.825	1.18		V					
12	Input Leakage Current	I		± 0.01	± 1	μA	$V_{IN} = V_{DDx} \text{ or } V_{ss}$				
	Inputs with pull-down resistors	I _{IH}	16	35	70	μA	V _{IN} = V _{DD3}				
	Inputs with pull-up resistors	۱ _{IL}	-18	-35	- 70	μA	V _{IN} = V _{ss}				
13	Input Pin Capacitance	CI			10	pF					
14	Output Pin Capacitance	CO			10	pF					
15	Output High Impedance Leakage	I _{oz}		± 0.01	±1	μA	$V_{O} = V_{SS} \text{ or } V_{DDx}$				
16	Output HIGH Voltage (3.3V CMOS)	V _{OH3}	2.4			V	I _{OH =} rated current				
17	Output LOW Voltage (3.3V CMOS)	V _{OL3}			0.4	V	I _{OL =} rated current				
18	3.3V output HIGH current (4 mA buffer)	I _{OH3}	- 5.9	- 12.7		mA	V _{OH} = 2.4 V				
19	3.3V output LOW current (4 mA buffer)	I _{OL3}	4.1	6.9		mA	V _{OL} = 0.4 V				
20	3.3V output HIGH current (24 mA buffer)	I _{OH3}	- 24.1	- 50.5		mA	V _{OH} = 2.4 V				
21	3.3V output LOW current (24 mA buffer)	I _{OL3}	24.6	41.3		mA	V _{OL} = 0.4 V				
22	Junction-to-Ambient Thermal Resistance	$\theta_{\text{J-A}}$		19.4		°C/W	0 Ifm air flow (natural convection airflow only)				

 Table 93 - DC Characteristics

a. Typical figures are at 25°C and are for design aid only; not guaranteed and not subject to production testing.

b. T_{OP} = -40°C to 85°C; V_{DD2} = 2.5V ± 5%; V_{DD3} = 3.3V ± 5%

Voltage measurements are with respect to ground (V_{SS}) unless otherwise stated.

Note 1: Supply current and device power is for 8 ports in E1 mode. Typical values are with V_{DD3} and V_{DD2} at nominal, with all output pins loaded with half the rated capacitance (as given in the AC Characteristics section) and with the two UTOPIA clocks as inputs. Maximum values are with V_{DD3} and V_{DD2} at + 5% (2.625 V and 3.465 V), with all output pins loaded with the full rated capacitance, and the two UTOPIA clocks as outputs.

Note 2: UDT mode supply current and device power includes 1800 cells of CPU/OAM traffic in both directions, and no discards of non-AAL1 cells, giving Look-Up Table reads of 1 800 reads/second.

Note 3: SDT mode supply current and device power includes 1800 cells of CPU/OAM traffic in both directions, and sufficient discards of non-AAL1 cells to bring Look-Up Table reads to 1 000 000 reads/second.

7.2 AC Characteristics

Characteristic	Sym	Min	Тур	Max	Units	Test Conditions
MCLK Frequency	t _{MF}		66.0	66.0	MHz	30ppm clock required for proper operation of the TDM PLLs
MCLK Period	t _{MP}		15.2		ns	
MCLK Pulse Width (HIGH / LOW)	t _{MH/L}	6.8	7.6		ns	

Table 94 - MCLK - Master Clock Input Parameters

Table 95 - PHY	_CLK - Clock Input Parameters
----------------	-------------------------------

Characteristic	Sym	Min	Тур	Мах	Units	Test Conditions
PHY_CLK Frequency	t _{PF}		19.44 8		MHz kHz	PHY_CLK frequency determined by 8_KHZ_SEL bit in CMCR register
PHY_CLK Period 19.44 MHz 8 kHz	t _{PP}		51.44 125		ns μs	
PHY_CLK Pulse Width (HIGH / LOW) 19.44 MHz 8 kHz	t _{PH/L}	20 0.1	25.72 62.5		ns μs	

7.2.1 CPU Interface

Table 96 - Intel Microprocessor Interface Timing - Read Cycle Parameters

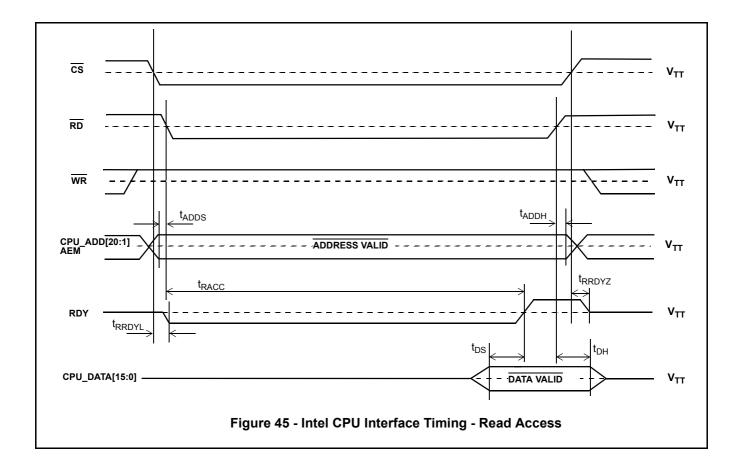
Sym	Min	Тур	Мах	Units	Test Conditions
t _{ADDS}	0			ns	
t _{ADDH}	0			ns	
t _{RRDYL}	0		10	ns	C _L = 75 pF
t _{RACC}					C _L = 100pF
	197 213	228	243 2021	ns ns	13 MCLK < t _{RACC} < 16 MCLK 14 MCLK < t _{RACC} < 133 MCLK
t _{RRDYZ}	0		10	ns	C _L = 75 pF
t _{DS}		16		ns	C _L = 75 pF ~ 1 MCLK cycle
t _{DH}	0			ns	C _L = 75 pF
	t _{ADDS} t _{ADDH} t _{RRDYL} t _{RACC} t _{RRDYZ} t _{DS}	tadds0taddh0taddh0tRRDYL0tRACC197 213tRRDYZ0tDS1	t _{ADDS} 0 t _{ADDH} 0 t _{RRDYL} 0 t _{RACC} 197 213 t _{RRDYZ} 0 t _{RRDYZ} 0 t _{DS} 16	t _{ADDS} 0 11 t _{ADDH} 0 10 t _{RRDYL} 0 10 t _{RACC} 197 213 228 2021 t _{RRDYZ} 0 10 t _{RRDYZ} 0 10 t _{DS} 16 16	$\begin{array}{c c c c c c c c c c c c c c c c c c c $

Note 1: MCLK = 66 MHz (15.2 ns)

Note 2: Both \overline{CS} and \overline{RD} must be asserted for a read cycle to occur. A read cycle is completed when either \overline{CS} or \overline{RD} is de-asserted. **Note 3:** There should be a minimum of 3 MCLK periods between CPU accesses, to allow the MT90520 to recognize the accesses as separate (i.e., \overline{CS} must be de-asserted for 3 MCLK cycles between CPU accesses).

Data Sheet

MT90520

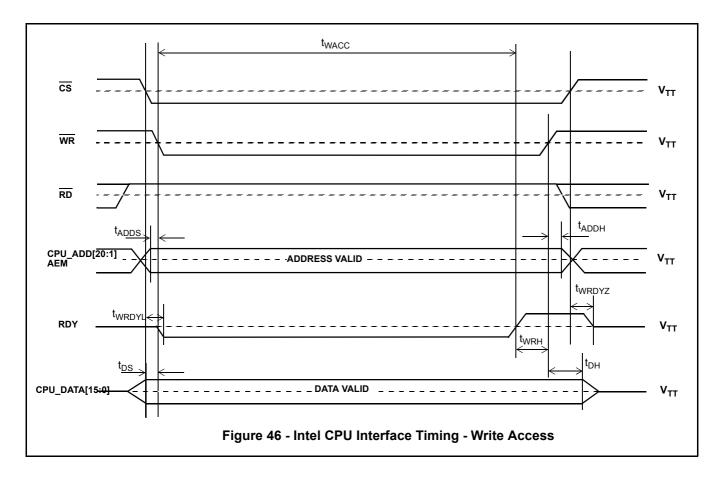


Characteristic	Sym	Min	Тур	Max	Units	Test Conditions
Address Setup - (AEM and CPU_ADD[20:1] VALID) to (CS and WR asserted)	t _{ADDS}	0			ns	
Address Hold - (\overline{CS} or \overline{WR} de-asserted) to (AEM and CPU_ADD[20:1] INVALID)	t _{ADDH}	0			ns	
RDY Low - \overline{CS} asserted to RDY driven low	t _{WRDYL}	0		10	ns	C _L = 75 pF
RDY Delay - (CS and WR asserted) to RDY asserted Register access Memory access	twacc	167 182	197	213 2021	ns ns	C _L = 75 pF 11 MCLK < t _{WACC} < 14 MCLK 12 MCLK < t _{WACC} < 133 MCLK
RDY High-Impedance - CS de-asserted to RDY high-impedance	t _{WRDYZ}	0		10	ns	C _L = 75 pF
Write Cycle Hold Time - RDY asserted to (\overline{CS} or \overline{WR} de-asserted)	t _{WRH}	0			ns	
Data Input Setup - CPU_DATA[15:0] VALID to (CS and WR asserted)	t _{DS}	0			ns	
Data Input Hold - (\overline{CS} or \overline{WR} de-asserted) to CPU_DATA[15:0] INVALID	t _{DH}	0			ns	

Table 97 - Intel Microprocessor Interface Timing - Write Cycle Parameters

Note 1: MCLK = 66 MHz (15.2 ns)

Note 2: Both CS and WR must be asserted for a write cycle to occur. A write cycle is completed when either CS or WR is de-asserted. **Note 3:** There should be a minimum of 3 MCLK periods between CPU accesses, to allow the MT90520 to recognize the accesses as separate (i.e., CS must be de-asserted for 3 MCLK cycles between CPU accesses).

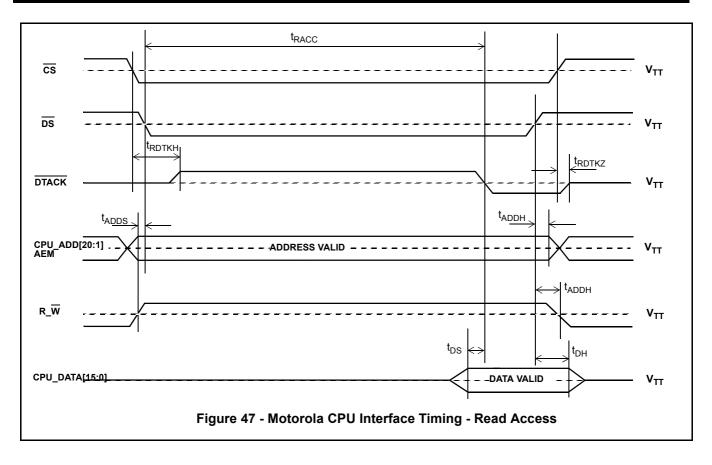


Characteristic	Sym	Min	Тур	Мах	Units	Test Conditions			
Address Setup - $(R/\overline{W}, _AEM and CPU_ADD[20:1] VALID)$ to $(\overline{CS} and \overline{DS} asserted)$	t _{ADDS}	0			ns				
Address Hold - $(\overline{CS} \text{ or } \overline{DS} \text{ de-asserted})$ to (AEM, CPU_ADD[20:1] and R/W INVALID)	t _{ADDH}	0			ns				
DTACK High - \overline{CS} asserted to \overline{DTACK} driven high	t _{RDTKH}	0		10	ns	C _L = 75 pF			
DTACK Delay - (CS and DS asserted) to DTACK asserted Register access Memory access	t _{RACC}	197 213	228	243 2021	ns	C _L = 75 pF 13 MCLK < t _{RACC} < 16 MCLK 14 MCLK < t _{RACC} < 133 MCLK			
DTACK High-Impedance - CS de- asserted to DTACK high-impedance	t _{RDTKZ}	0		10	ns	C _L = 75 pF			
Data Output Setup - CPU_DATA[15:0] VALID to DTACK asserted	t _{DS}		16		ns	C _L = 75 pF ~ 1 MCLK cycle			
Data Output Hold - (CS or DS de- asserted) to CPU_DATA[15:0] INVALID	t _{DH}	0			ns	C _L = 75 pF			

Table 98 - Motorola Microprocessor Interface Timing - Read Cycle Parameters

Note 1: MCLK = 66 MHz (15.2 ns)

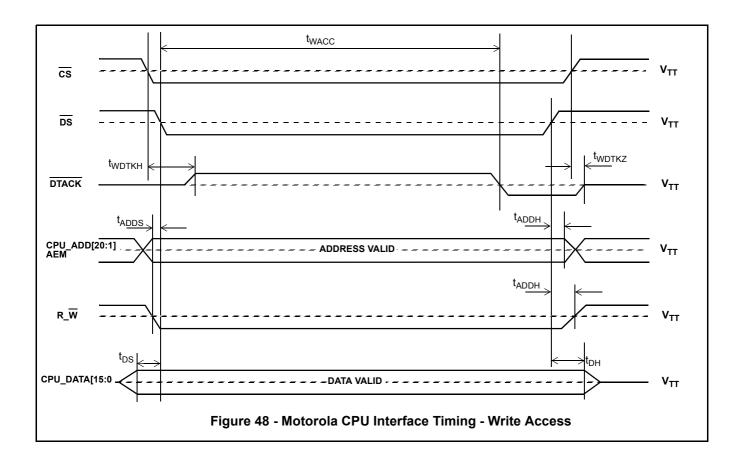
Note 2: Both \overline{CS} and \overline{DS} must be asserted for a read cycle to occur. A read cycle is completed when either \overline{CS} or \overline{DS} is de-asserted. **Note 3:** There should be a minimum of 3 MCLK periods between CPU accesses, to allow the MT90520 to recognize the accesses as separate (i.e., \overline{CS} must be de-asserted for 3 MCLK cycles between CPU accesses).



Characteristic	Sym	Min	Тур	Мах	Units	Test Conditions
Address Setup - $(R/\overline{W}, \underline{AEM} \text{ and } CPU_ADD[20:1] VALID)$ to (CS and DS asserted)	t _{ADDS}	0			ns	
Address Hold - (CS or DS de-asserted) to (AEM, CPU_ADD[20:1] and R/W INVALID)	t _{ADDH}	0			ns	
$\overrightarrow{\textbf{DTACK}} \textbf{ High } - \overrightarrow{\text{CS}} \text{ asserted to } \overrightarrow{\text{DTACK}} \\ \text{driven high}$	t _{wdtkh}	0		10	ns	C _L = 75 pF
DTACK Delay - (CS and DS asserted) to DTACK asserted Register access Memory access	t _{WACC}	167 182	197	213 2021	ns ns	C _L = 75 pF 11 MCLK < t _{WACC} < 14 MCLK 12 MCLK < t _{WACC} < 133 MCLK
DTACK High-Impedance - CS de- asserted to DTACK high-impedance	t _{wdtkz}	0		10	ns	C _L = 75 pF
Data Input Setup - CPU_DATA[15:0] VALID to (CS and DS asserted)	t _{DS}	0			ns	
Data Input Hold - $(\overline{CS} \text{ or } \overline{DS} \text{ de-} asserted)$ to CPU_DATA[15:0] INVALID	t _{DH}	0			ns	
Note 1: MCLK = 66 MHz (15.2 ns)						

Table 99 - Motorola Microprocessor Interface Timing - Write Cycle Parameters

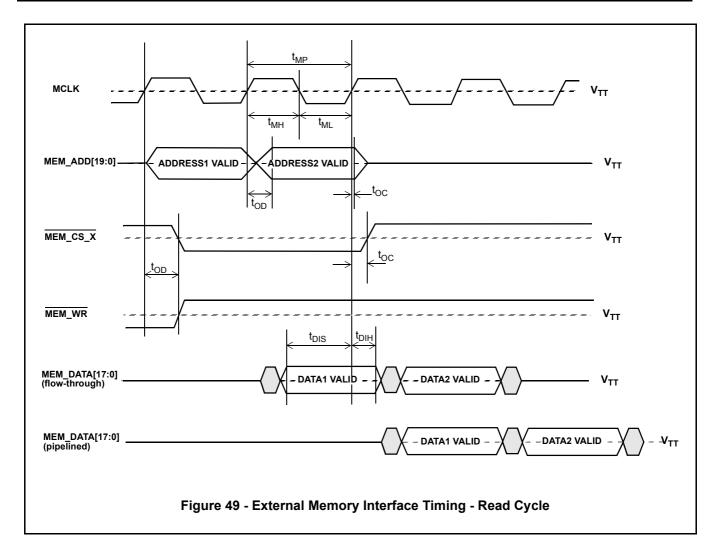
Note 1: MCLK = 66 MHz (15.2 ns) Note 2: Both \overline{CS} and \overline{DS} must be asserted for a write cycle to occur. A write cycle is completed when either \overline{CS} or \overline{DS} is de-asserted. **Note 3:** There should be a minimum of 3 MCLK periods between CPU accesses (CS de-asserted), to allow the MT90520 to recognize the accesses as separate (i.e., CS must be de-asserted for 3 MCLK cycles between CPU accesses).



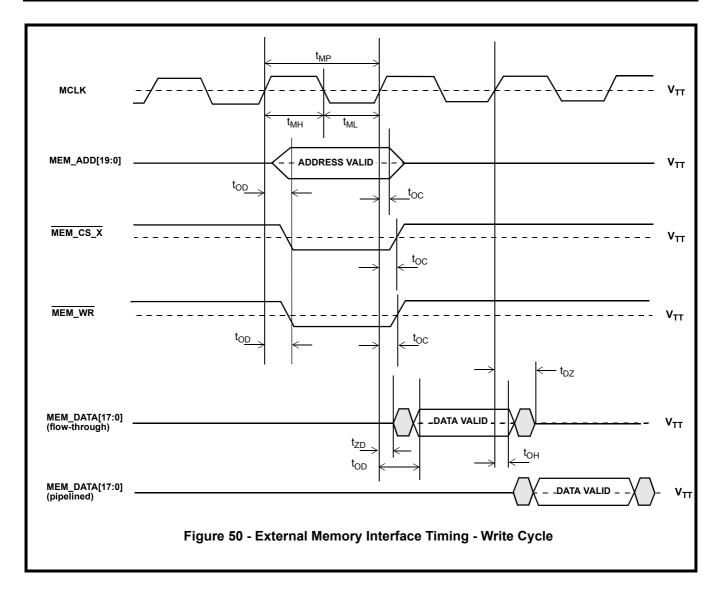
7.2.2 External Memory Interface

Table 100 - External Memory Interface Timing - Read Cycle Parameters

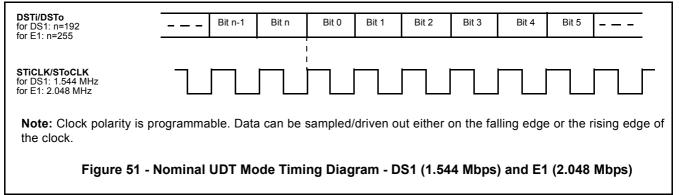
Characteristic	Sym	Min	Тур	Мах	Units	Test Conditions
Data Input Setup - MEM_DATA[17:0] VALID to MCLK rising	t _{DIS}	5			ns	C _L = 35 pF
Data Input Hold Time - MCLK rising to MEM_DATA[17:0] INVALID	t _{DIH}	2			ns	C _L = 35 pF
Clock to Change - MCLK rising to (MEM_ADD[19:0], MEM_CS_X and MEM_WR) change	toc	1			ns	C _L = 35 pF
Output Delay - MCLK rising to (MEM_ADD[19:0] VALID and (MEM_CS_X and MEM_WR) asserted)	t _{OD}			12.5	ns	C _L = 35 pF



	_		_	_		
Characteristic	Sym	Min	Тур	Max	Units	Test Conditions
Output Delay - MCLK rising to (MEM_ADD[19:0], MEM_DATA[17:0]) VALID and (MEM_CS_X and MEM_WR) asserted	t _{OD}			12.5	ns	C _L = 35 pF
Output Hold Time - MCLK rising MEM_DATA[17:0] INVALID	t _{OH}	1			ns	C _L = 35 pF
High-Z to Drive Time - MCLK rising to MEM_DATA[17:0] driven	t _{ZD}	3			ns	C _L = 35 pF
Clock to Change - MCLK rising to (MEM_ADD[19:0], MEM_CS_X and MEM_WR) change	t _{OC}	1			ns	C _L = 35 pF
Drive to High-Z Time - MCLK rising to MEM_DATA[17:0] High-Z	t _{DZ}	1		6.5	ns	C _L = 35 pF



7.2.3 TDM Interface



DSTi/DSTo	Timeslot 31 Bit 0	Timeslot 0 Bit 7	Timeslot 0 Bit 6	Timeslot 0 Bit 5	
STiMF/SToMF or F0 (ST-BUS)					
STICLK/SToCLK or C4M/C2M 4.096 MHz (ST-BUS only)					
STiMF/SToMF or F0 (Generic - see Note)					
STICLK/SToCLK or C4M/C2M 2.048 MHz (Generic only)					
	, both clock polarity and fr edge or the rising edge o				
Figure 52 - Nom	ninal SDT Mode Timing	Diagram - Gene	eric and ST-BU	S DS1 or E1 (2	.048 Mbps)

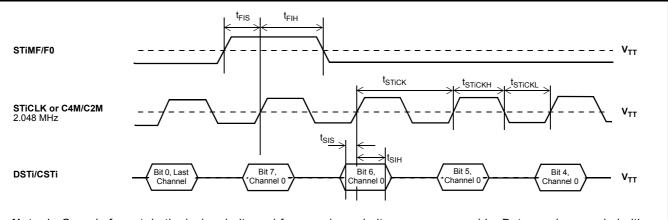
		Timeslot 24	Timoolot 24	Framina	Timeslot 0						
DSTi/DSTo		Bit 1	Bit 0	Framing Bit	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3		
STIMF/SToMF or F0 (See Note)					<u> </u>						
STICLK/SToCLK or C4M/C2M 1.544 MHz											_
Note: Due to the use o out either on the falling					•	<i>,</i>	0			•	
Fi	gure 53	- Nomina	al SDT N	lode Tir	ning Dia	agram -	Generic	: DS1 (1	.544 Mb	ps)	

Table 102 and Table 103 refer to input clock parameters which are displayed in Figure 54 and Figure 55, which follow the tables.

Characteristic	Sym	Min	Тур	Мах	Units	Test Conditions
STiCLK/C4M/C2M Clock Period 1.544 Mbps bus (1.544 MHz clock) 1.544 or 2.048 Mbps bus (2.048 MHz clock) 2.048 Mbps bus (4.096 MHz clock)	t _{STICK}		648 488 244		ns ns ns	
STiCLK/C4M/C2M Pulse Width (HIGH / LOW) 1.544 Mbps bus (1.544 MHz clock) 1.544 or 2.048 Mbps bus (2.048 MHz clock) 2.048 Mbps bus (4.096 MHz clock)	t _{STICKH/L}		324 244 122		ns ns ns	
Frame Pulse Width 1.544 Mbps (Generic) 2.048 Mbps (Generic) 2.048 Mbps (ST-BUS)	t _{FPW}	100 100 100	648 488 244	900 600 300	ns ns ns	
Frame Pulse Setup Time STiMF/F0 valid to STiCLK/C4M/C2M rising STiMF/F0 valid to STiCLK/C4M/C2M falling	t _{FIS}	15 15			ns ns	
Frame Pulse Hold Time STiCLK/C4M/C2M rising to STiMF/F0 invalid STiCLK/C4M/C2M falling to STiMF/F0 invalid	t _{FIH}	10 10			ns ns	

Table 103 - TDM Bus Input Data Parameters

Characteristic	Sym	Min	Тур	Max	Units	Test Conditions
Data Setup Time - DSTi/CSTi VALID to STiCLK/C4M/C2M falling Sampling on falling edge	t _{SIS}	15			ns	
Data Hold Time - STiCLK/C4M/C2M falling to DSTi/CSTi INVALID Sampling on falling edge	t _{SIH}	10			ns	
Data Setup Time - DSTi/CSTi VALID to STiCLK/C4M/C2M rising Sampling on rising edge	t _{SIS}	15			ns	
Data Hold Time - STiCLK/C4M/C2M rising to DSTi/CSTi INVALID Sampling on rising edge	t _{SIH}	10			ns	



Note: In Generic format, both clock polarity and frame pulse polarity are programmable. Data can be sampled either on the falling edge or the rising edge of the clock. The frame pulse can have either positive or negative polarity.

Figure 54 - TDM Bus Inputs - Generic Bus Sampling

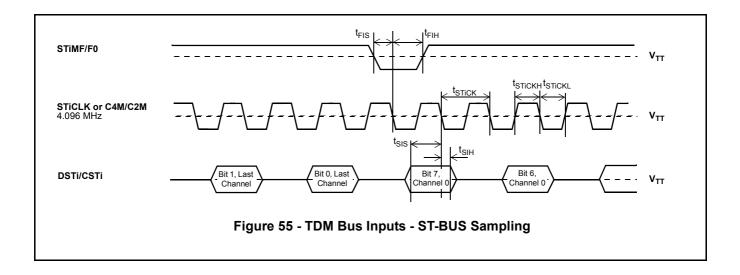


Table 104 and Table 105 refer to output clock parameters which are displayed below in Figure 56, Figure 57, and Figure 58.

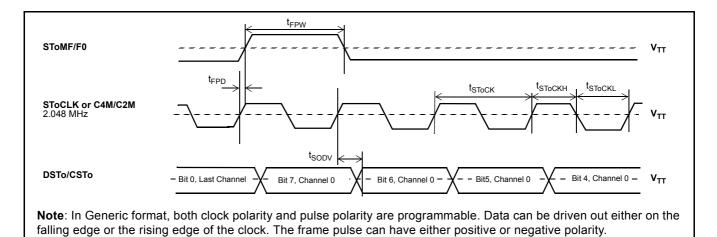
Characteristic	Sym	Min	Тур	Мах	Units	Test Conditions		
SToCLK/C4M/C2M Clock Period 1.544 Mbps bus (1.544 MHz clock) 1.544 or 2.048 Mbps bus (2.048 MHz clock) 2.048 Mbps bus (4.096 MHz clock)	t _{SToCK}		648 488 244		ns ns ns			
SToCLK/C4M/C2M Pulse Width (HIGH / LOW) 1.544 Mbps bus (1.544 MHz clock) 1.544 or 2.048 Mbps bus (2.048 MHz clock) 2.048 Mbps bus (4.096 MHz clock)	t _{SToCKH/L}		324 244 122		ns ns ns			
Frame Pulse Width 1.544 Mbps (Generic) 2.048 Mbps (Generic) 2.048 Mbps (ST-BUS)	t _{FPW}		648 488 244		ns ns ns			
Frame Pulse Delay SToCLK rising to SToMF change (Generic) SToCLK falling to SToMF change (ST-BUS or Generic) C4M/C2M rising to F0 change (Generic) C4M/C2M falling to F0 change (ST-BUS or Generic)	t _{FPD}	0 0 4 4		40 40 40 40	ns ns ns ns	$C_{L} = 30 \text{ pF}$ $C_{L} = 30 \text{ pF}$ $C_{L} = 200\text{pF}$ $C_{L} = 200\text{pF}$		

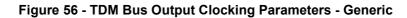
Table 104 - TDM Bus Output Clock Parameters

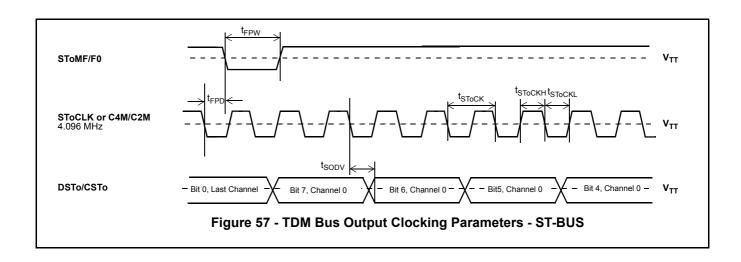
Table 105 - TDM Bus Data Output Parameters

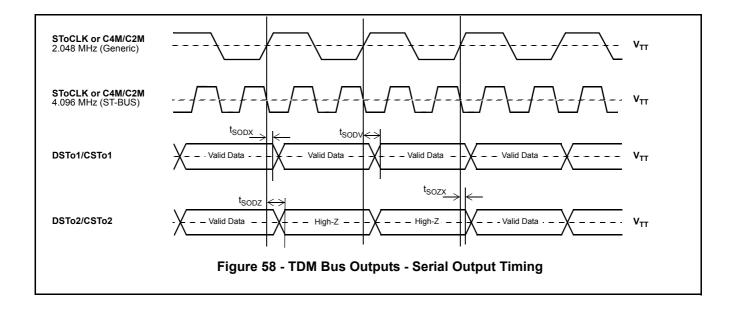
Characteristic	Sym	Min	Тур	Мах	Units	Test Conditions
Data Delay - Clock to Data Change SToCLK/C4M/C2M rising to DSTo or CSTo change (Generic) SToCLK/C4M/C2M falling to DSTo or CSTo change (ST-BUS	t _{SODX}	5			ns	C _L = 30 pF
or Generic)		5			ns	C _L = 30 pF
Data Delay - Clock to Data Valid SToCLK/C4M/C2M rising to DSTo or CSTo valid (Generic) SToCLK/C4M/C2M falling to DSTo or CSTo valid (ST-BUS or Generic)	t _{SODV}			40 40	ns	C _L = 30 pF C ₁ = 30 pF
				40	113	0L - 30 bi
Drive to High-Z SToCLK/C4M/C2M rising to DSTo or CSTo HIGH-Z (Generic) SToCLK/C4M/C2M falling to DSTo or CSTo HIGH-Z (ST-BUS	t _{SODZ}	5		10	ns	C _L = 30 pF
or Generic)		5		10	ns	C _L = 30 pF
High-Z to Drive SToCLK/C4M/C2M rising and DSTo or CSTo HIGH-Z to DSTo	t _{SOZX}					
or CSTo change (Generic) SToCLK/C4M/C2M falling and DSTo or CSTo HIGH-Z to DSTo		5		40	ns	C _L = 30 pF
or CSTo change (ST-BUS or Generic)		5		40	ns	C _L = 30 pF

Data Sheet





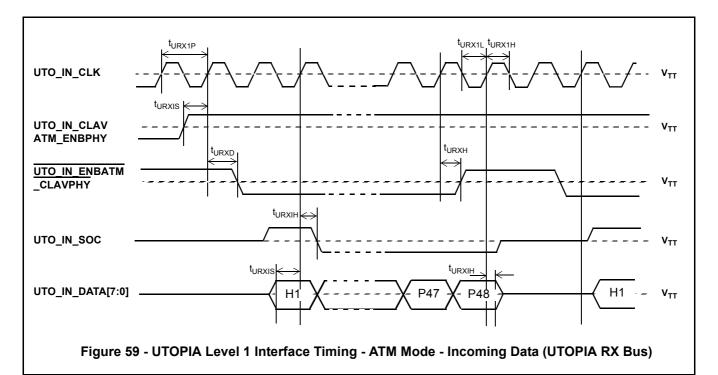




7.2.4 UTOPIA Interface

7.2.4.1 UTOPIA Level 1

Characteristic	Sym	Min	Тур	Max	Units	Test Conditions			
UTO_IN_CLK Period	t _{URX1P}	19.23			ns	UTO_IN_CLK = 52 MHz			
UTO_IN_CLK Pulse Width (HIGH / LOW)	t _{URX1H/L}	7.7	t _{URX1P} /2		ns				
Input Setup Time - (UTO_IN_CLAVATM_ENBPHY, UTO_IN_SOC asserted and UTO_IN_DATA[7:0] VALID) to UTO_IN_CLK rising	t _{URXIS}	4			ns				
Input Hold Time - UTO_IN_CLK rising to (UTO_IN_DATA[7:0] INVALID and UTO_IN_SOC and UTO_IN_CLAVATM_ENBPHY de-asserted)	t _{URXIH}	1			ns				
Output Delay - UTO_IN_CLK rising to UTO_IN_ENBATM_CLAVPHY asserted	t _{URXD}			13.8	ns	C_L =20 pF; UTO_IN_CLK \leq 52 MHz			
Output Hold Time - UTO_IN_CLK rising to UTO_IN_ENBATM_CLAVPHY de-asserted	t _{URXH}	1			ns	C _L =20 pF; UTO_IN_CLK \leq 52 MHz			
Note: The MT90520 operates with the UTOPIA cell-	Note: The MT90520 operates with the UTOPIA cell-level handshake.								



Characteristic	Sym	Min	Тур	Max	Units	Test Conditions
UTO_OUT_CLK Period	t _{UTX1P}	19.23			ns	UTO_OUT_CLK = 52 MHz
UTO_OUT_CLK Pulse Width (HIGH / LOW)	t _{UTX1H/L}	7.7	t _{UTX1P} /2		s	

Table 107 - UTOPIA Level 1 Interface Timing - ATM mode - Outgoing Data (UTOPIA TX Bus)

Characteristic	Sym	Min	Тур	Max	Units	Test Conditions
Input Setup Time - UTO_OUT_CLAVATM_ENBPHY VALID to UTO_OUT_CLK rising	t _{UTXIS}	4			ns	
Input Hold Time - UTO_OUT_CLK rising to UTO_OUT_CLAVATM_ENBPHY de-asserted	t _{UTXIH}	1			ns	
Output Delay - UTO_OUT_CLK rising to (UTO_OUT_DATA[7:0] VALID and UTO_OUT_ENBATM_CLAVPHY and UTO_OUT_SOC asserted)	t _{utxd}			13.8	ns	$C_L = 20 \text{ pF}; \text{UTO}_\text{OUT}_\text{CLK} \le 52 \text{ MHz}$
Output Hold Time - UTO_OUT_CLK rising to (UTO_OUT_DATA[7:0] INVALID and UTO_OUT_ENBATM_CLAVPHY and UTO_OUT_SOC de-asserted)	t _{UTXH}	1			ns	C_L = 20 pF; UTO_OUT_CLK \leq 52 MHz

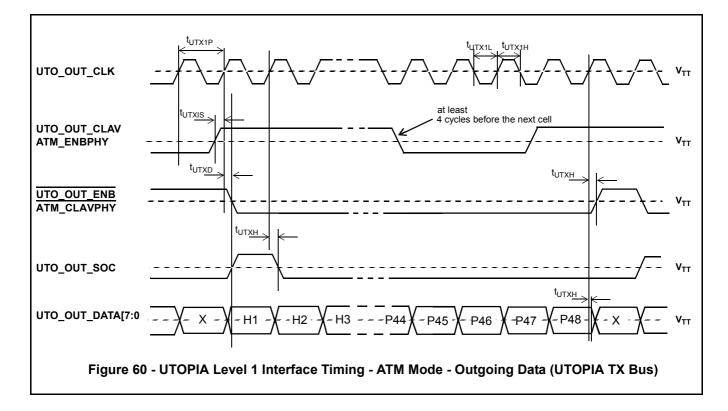
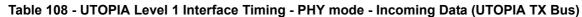


Table 108 - UTOPIA Level 1 Interface Timing - PHY mode - Incoming Data (UTOPIA TX Bus)

Characteristic	Sym	Min	Тур	Мах	Units	Test Conditions
UTO_IN_CLK Period	t _{UTX1P}	19.23			ns	UTO_IN_CLK = 52 MHz
UTO_IN_CLK Pulse Width (HIGH / LOW)	t _{UTX1H/L}	7.7	t _{UTX1P} /2		ns	
Input Setup Time - (UTO_IN_CLAVATM_ENBPHY, UTO_IN_SOC asserted and UTO_IN_DATA[7:0] VALID) to UTO_IN_CLK rising	t _{UTXIS}	4			ns	

Characteristic	Sym	Min	Тур	Мах	Units	Test Conditions			
Input Hold Time - UTO_IN_CLK rising to (UTO_IN_DATA[7:0] INVALID and UTO_IN_SOC, UTO_IN_CLAVATM_ENBPHY de-asserted)	t _{UTXIH}	1			ns				
Output Delay - UTO_IN_CLK rising to UTO_IN_ENBATM_CLAVPHY asserted	t _{UTXD}			13.8	ns	C_L =20 pF; UTO_IN_CLK \leq 52 MHz			
Output Hold Time - UTO_IN_CLK rising to UTO_IN_ENBATM_CLAVPHY de-asserted	t _{UTXH}	1			ns	C_L =20 pF; UTO_IN_CLK \leq 52 MHz			



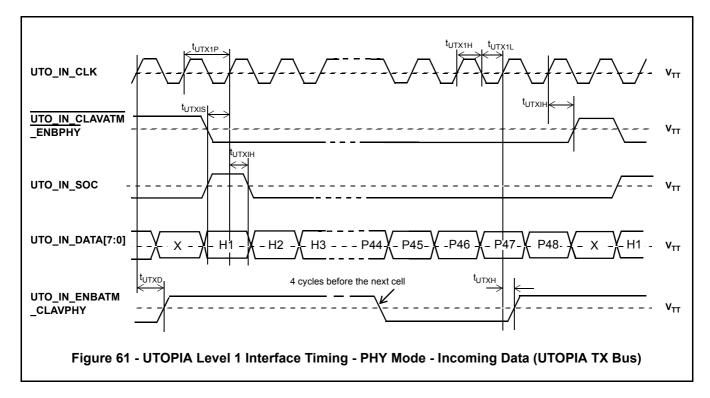
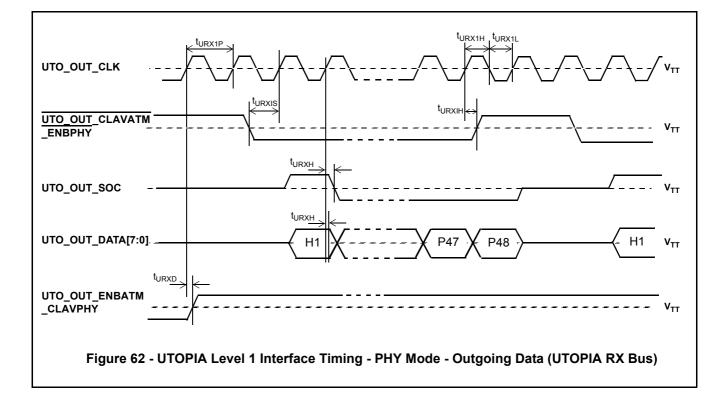


Table 109 - UTOPIA Level 1 Interface Timing - PHY mode - Outgoing Data (UTOPIA RX Bus)

Characteristic	Sym	Min	Тур	Max	Units	Test Conditions
UTO_OUT_CLK Period	t _{URX1P}	19.23			ns	UTO_OUT_CLK = 52 MHz
UTO_OUT_CLK Pulse Width (HIGH / LOW)	t _{URX1H/L}	7.7	t _{URX1P} /2		ns	
Input Setup Time - UTO_OUT_CLAVATM_ENBPHY asserted to UTO_OUT_CLK rising	t _{URXIS}	4			ns	
Input Hold Time - UTO_OUT_CLK rising to UTO_OUT_CLAVATM_ENBPHY de- asserted	t _{URXIH}	1			ns	
Output Delay - UTO_OUT_CLK rising to (UTO_OUT_DATA[7:0] VALID and UTO_OUT_ENBATM_CLAVPHY and UTO_OUT_SOC asserted)	t _{URXD}			13.8	ns	C_L = 20 pF; UTO_OUT_CLK \leq 52 MHz
Output Hold Time - UTO_OUT_CLK rising to (UTO_OUT_DATA[7:0] INVALID and UTO_OUT_ENBATM_CLAVPHY and UTO_OUT_SOC de-asserted)	t _{URXH}	1			ns	C_L = 20 pF; UTO_OUT_CLK \leq 52 MHz

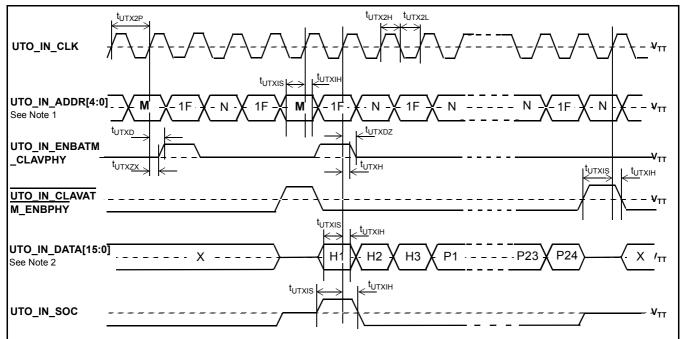


7.2.4.2 UTOPIA Level 2

This section contains the timing diagrams for the MT90520 setup in UTOPIA Level 2 as a PHY device. For functional timing diagrams, refer to the ATM Forum Level 2 specification (af-phy-0039.000).

Since the MT90520 does not support multi-PHY (MPHY) operation in ATM mode, the Level 2 ATM timing diagrams are identical to the ones for Level 1 operation, except that in Level 2, the MT90520 features a 16-bit data bus in both the TX and RX directions and it supports up to 80pF of load at 33MHz and 40pF at 52MHz. Note that the address bus is only used when in PHY mode.

Characteristic	Sym	Min	Тур	Max	Units	Test Conditions
UTO_IN_CLK Period	t _{UTX2P}	19.23			ns	UTO_IN_CLK = 52 MHz
UTO_IN_CLK Pulse Width (HIGH / LOW)	t _{UTX2H/L}	7.7	t _{UTX2P} /2		ns	
Input Setup Time - (UTO_IN_CLAVATM_ENBPHY, UTO_IN_SOC asserted and UTO_IN_DATA[15:0], UTO_IN_ADDR[4:0] VALID) to UTO_IN_CLK rising	t _{UTXIS}	4			ns	
Input Hold Time - UTO_IN_CLK rising to (UTO_IN_DATA[15:0], UTO_IN_ADDR[4:0] INVALID and UTO_IN_SOC, UTO_IN_CLAVATM_ENBPHY de-asserted)	t _{UTXIH}	1			ns	
Output Delay - UTO_IN_CLK rising to UTO_IN_ENBATM_CLAVPHY asserted	t _{UTXD}			13.8 20.5	ns ns	C_L =40 pF; UTO_IN_CLK \leq 52 MHz C_L =80 pF; UTO_IN_CLK \leq 33 MHz
Output Hold Time - UTO_IN_CLK rising to (UTO_IN_ENBATM_CLAVPHY change)	t _{UTXH}	1 1			ns ns	C_L =40 pF; UTO_IN_CLK \leq 52 MHz C_L =80 pF; UTO_IN_CLK \leq 33 MHz
Drive to High-Z - UTO_IN_CLK rising to UTO_IN_ENBATM_CLAVPHY HIGH-Z	t _{UTXDZ}	1 1		17.5 28.5	ns ns	C_L =40 pF; UTO_IN_CLK \leq 52 MHz C_L =80 pF; UTO_IN_CLK \leq 33 MHz
High-Z to Drive - UTO_IN_CLK rising and UTO_IN_ENBATM_CLAVPHY HIGH-Z to UTO_IN_ENBATM_CLAVPHY change	t _{UTXZX}	1 1			ns ns	C_L =40 pF; UTO_IN_CLK \leq 52 MHz C_L =80 pF; UTO_IN_CLK \leq 33 MHz



Note 1: M is the address of the MT90520; N is the address of another PHY device, where N is *not* equal to M. An address of 1Fh (31d) indicates a null PHY port.

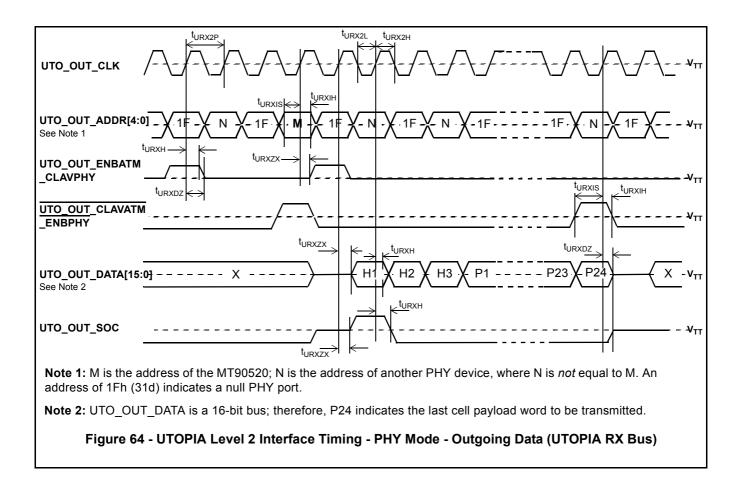
Note 2: UTO_IN_DATA is a 16-bit bus; therefore, P24 indicates the last cell payload word to be transmitted.

Figure 63 - UTOPIA Level 2 Interface Timing - PHY Mode - Incoming Data (UTOPIA TX Bus)

Table 111 - UTOPIA Level 2 Interface Timing	PHY mode - Outgoing Data (UTOPIA RX Bus)

Characteristic	Sym	Min	Тур	Мах	Units	Test Conditions
UTO_OUT_CLK Period	t _{URX2P}	19.23			ns	UTO_OUT_CLK = 52 MHz
UTO_OUT_CLK Pulse Width (HIGH / LOW)	t _{URX2H/L}	7.7	t _{URX2P} /2		ns	
Input Setup Time - (UTO_OUT_CLAVATM_ENBPHY asserted and UTO_OUT_ADDR[4:0] VALID) to UTO_OUT_CLK rising	t _{URXIS}	4			ns	
Input Hold Time - UTO_IN_CLK rising to (UTO_OUT_ADDR[4:0] INVALID and UTO_OUT_CLAVATM_ENBPHY de-asserted)	t _{URXIH}	1			ns	
Output Delay - UTO_OUT_CLK rising to (UTO_OUT_ENBATM_CLAVPHY, UTO_OUT_SOC asserted and UTO_OUT_DATA[15:0] VALID)	t _{URXD}			13.5 20.5	ns ns	C _L = 40 pF; UTO_OUT_CLK \leq 52 MHz C _L = 80 pF; UTO_OUT_CLK \leq 33 MHz
Output Hold Time - UTO_OUT_CLK rising to (UTO_OUT_DATA[15:0] INVALID and UTO_OUT_ENBATM_CLAVPHY, UTO_OUT_SOC de-asserted)	t _{URXH}	1 1			ns ns	C _L = 40 pF; UTO_OUT_CLK \leq 52 MHz C _L = 80 pF; UTO_OUT_CLK \leq 33 MHz
Drive to High-Z - UTO_OUT_CLK rising to (UTO_OUT_ENBATM_CLAVPHY, UTO_OUT_SOC, UTO_OUT_DATA[15:0] HIGH-Z)	t _{urxdz}	1 1		17.5 28.5	ns ns	C _L = 40 pF; UTO_OUT_CLK \leq 52 MHz C _L = 80 pF; UTO_OUT_CLK \leq 33 MHz
High-Z to Drive - UTO_OUT_CLK rising and (UTO_OUT_ENBATM_CLAVPHY, UTO_OUT_SOC, UTO_OUT_DATA HIGH-Z) to (UTO_OUT_ENBATM_CLAVPHY, UTO_OUT_SOC, UTO_OUT_DATA[15:0]) change	t _{URXZX}	1 1			ns ns	C _L = 40 pF; UTO_OUT_CLK \leq 52 MHz C _L = 80 pF; UTO_OUT_CLK \leq 33 MHz

MT90520



8. Applications

8.1 Board-Level Applications

8.1.1 Power-Up and Power-Down Sequence

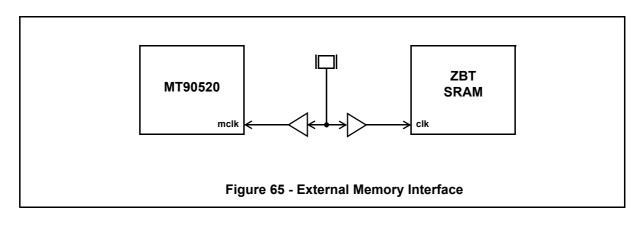
To prevent device latch-up, it is recommended to turn on the I/O power (3.3 V) first, followed by the core power (2.5 V). This can be done in one of two ways:

- By powering up the 3.3 V rail first, preventing the 2.5 V rail from powering up until the 3.3 V rail is stable.
- By placing a Schottky diode between the 3.3 V and 2.5 V power rails (connecting the anode to the 2.5 V rail and the cathode to the 3.3 V rail).

In general, the power-down sequence should be the reverse of the power-up sequence. Thus, the 2.5 V rail should be turned off first, followed by the 3.3 V rail.

8.1.2 External Memory Interface Connections

The MT90520 can interface with both the pipelined and flow-through types of synchronous static zero bus turnaround (ZBT) RAM. The clock driving the external memory device **must** be the same as the clock which is fed to the MT90520 at its MCLK input, as shown in Figure 65 below.



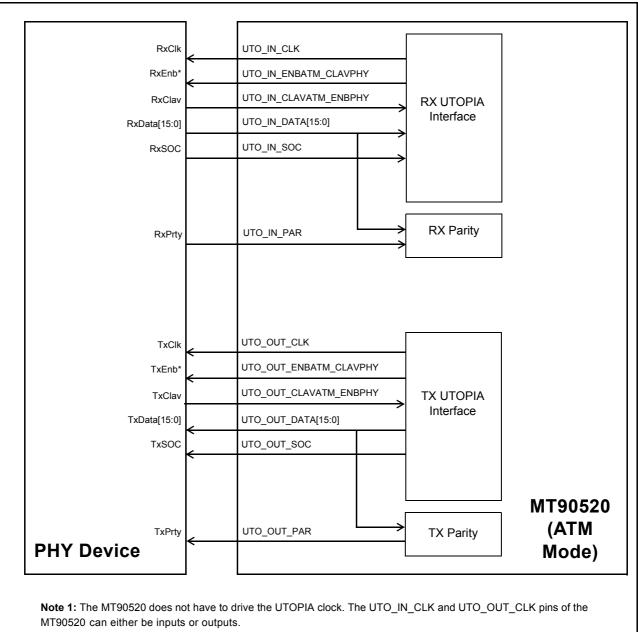
8.1.3 UTOPIA Interface Connections

The following table lists all of the signals on the UTOPIA interface of the MT90520. In addition, it indicates what the pin corresponds to in terms of the functionality of the UTOPIA standard, depending on the mode of operation of the UTOPIA interface.

MT90520 Signal Name	MT90520 Signal Direction	Standard Signal Name - Level 1 ATM	Standard Signal Name - Level 1 PHY	Standard Signal Name - Level 2 ATM	Standard Signal Name - Level 2 PHY
UTO_IN_CLK	1/0	RxClk	TxClk	RxClk	TxClk
UTO_IN_ADD[4:0]	I	-	-	-	TxAddr[4:0]
UTO_IN_DATA[15:8]	Ι	-	-	RxData[15:8]	TxData[15:8]
UTO_IN_DATA[7:0]	Ι	RxData[7:0]	TxData[7:0]	RxData[7:0]	TxData[7:0]
UTO_IN_PAR	I	RxPrty	TxPrty	RxPrty	TxPrty
UTO_IN_SOC	Ι	RxSOC	TxSOC	RxSOC	TxSOC
UTO_IN_CLAVATM _ENBPHY	I	RxClav	TxEnb*	RxClav	TxEnb*
UTO_IN_ENBATM _CLAVPHY	0	RxEnb*	TxClav	RxEnb*	TxClav
UTO_OUT_CLK	1/0	TxClk	RxClk	TxClk	RxClk
UTO_OUT_ADD[4:0]	I	-	-	-	RxAddr[4:0]
UTO_OUT_DATA[15:8]	0	-	-	TxData[15:8]	RxData[15:8]
UTO_OUT_DATA[7:0]	0	TxData[7:0]	RxData[7:0]	TxData[7:0]	RxData[7:0]
UTO_OUT_PAR	0	TxPrty	RxPrty	TxPrty	RxPrty
UTO_OUT_SOC	0	TxSOC	RxSOC	TxSOC	RxSOC
UTO_OUT_CLAVATM _ENBPHY	I	TxClav	RxEnb*	TxClav	RxEnb*
UTO_OUT_ENBATM _CLAVPHY	0	TxEnb*	RxClav	TxEnb*	RxClav

Table 112 - MT90520 UTOPIA Signal Directions

Figure 66 below illustrates the connections from the external pins of the UTOPIA interface to a PHY device, when the MT90520 is operating in ATM mode.



Note 2: When in ATM mode, UTO_IN_CLAVATM_ENBPHY, UTO_IN_SOC, UTO_OUT_CLAVATM_ENBPHY and UTO_OUT_SOC should be pulled down. It is also recommended to pull up UTO_IN_ENBATM_CLAVPHY and UTO_OUT_ENBATM_CLAVPHY.

Figure 66 - ATM Mode: External UTOPIA Pin Connections

Figure 67 illustrates the connections from the external pins of the UTOPIA interface to an ATM device, when the MT90520 device is operating in PHY mode.

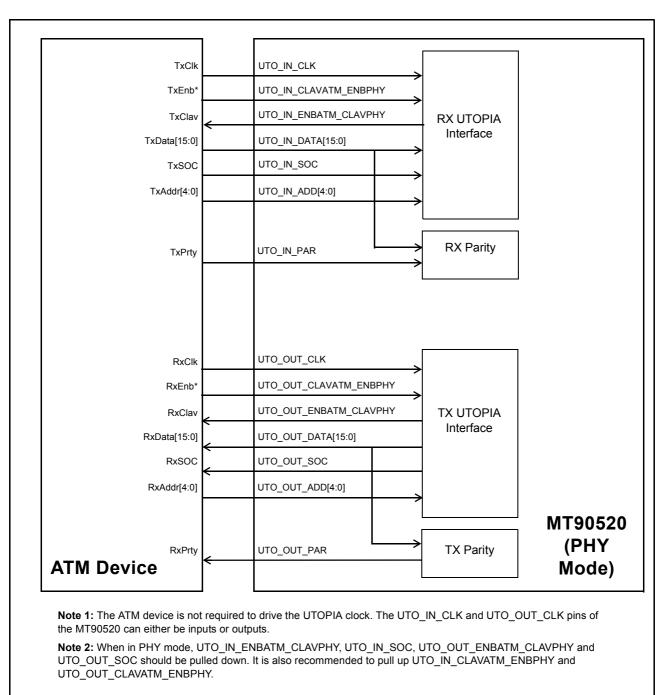


Figure 67 - PHY Mode: External UTOPIA Pin Connections

8.2 Segmentation and Reassembly Latency

End-to-end latency, or delay, of the AAL1 segmentation and reassembly process of the MT90520 can be expressed in a simplified manner as:

end-to-end delay =

cell payload assembly time + internal TX queuing + internal TX processing

- + physical layer and network delays
- + UTOPIA RX queuing + internal RX processing + pointer offset + CDV buffering

Some components of the latency, such as UDT cell payload assembly delay, are determined by the AAL1 standards. Some components of the latency are partially under the control of the application, such as SDT cell payload assembly time where the number of channels can be increased to reduce cell payload assembly time. Some components of the latency are a function of the MT90520 architecture, which has been designed to minimize this latency. Finally, some components are externally determined, such as the physical layer and network delays, and network Cell Delay Variation (CDV) which must be compensated for in the CDV buffering.

Mode	Cell Payload Assembly (μsec)	TX Queuing (μsec)	TX Processing (μsec)	Total TX / Segmentation (μsec)
UDT T1	243.5	min: 0	2.3	min: 245.8
		max: 62.9		max: 308.7
UDT E1	183.6	min: 0	2.3	min: 185.9
		max: 62.9		max: 248.8
SDT	min: FLOOR[46/N] X 125	min: 0	125	min: 125 + FLOOR[46/N] X 125
	max: CEIL[47/N] X 125	max: 125		max: 250 + CEIL[47/N] X 125
SDT Trunking	125	min: 0	125	min: 250
N > 46		max: 125		max: 375

TABLE 113. Segmentation Latency

NOTE: "N" is the number of TDM channels carried by a particular ATM VC.

Cell Payload Assembly delay is the amount of time the TDM interface requires to deliver enough data to fill an AAL1 cell. Note that the latency given in Table 113 is for the first bit of TDM data packed in the AAL1 cell, i.e. the bit which sees the longest delay before cell transmission. Since reassembly latency is inverted from this segmentation latency (first-in-first-out) this method gives correct end-to-end latency for all bits in the cell when segmentation and re-assembly delays are summed. The cell payload assembly delay in SDT mode is a function of "N", the number of TDM channels carried by the VC. The FLOOR[x] function means "the largest integer less than, or equal to, x" and the CEIL[x] function means "the smallest integer greater than, or equal to, x". Cell payload assembly is a static delay in UDT mode. Cell payload assembly is a variable delay in SDT mode, due both to the variation in payload size (46 bytes and 47 bytes) specified in the AAL1 standards, and to remainders when fitting N channels into the cell payload.

TX Queuing represents the possible delay due to cell operations queuing in front of the single high-speed TDM segmentation and cell-assembly engine (TX_SAR). In UDT mode, worst case for this is the time taken to process 27 cells (one for each of the other TDM ports). In SDT mode, worst case for TX Queueing with a porperly configured control structure is always less than a TDM frame (125 microseconds). This is a variable delay, and the number given here is the peak, worst-case, low-probability value.

TX Processing is the time required for internal processing and data moves. This is a fixed delay in UDT and SDT mode.

Physical layer and network delays are the delays due to speed-of-transmission delays in the physical layer, including transmission time on the UTOPIA bus, and queuing delays at the switches through the network, including queuing in front of the physical layer devices directly connected to the MT90520. This is in general a variable delay, and usually represents the largest source of Cell Delay Variation (CDV) that the reassembly path (RX_SAR) has to deal with.

Mode	RX UTOPIA Queuing (μsec)	RX Processing (μsec)	Pointer Offset (μsec)	CDV Buffering (μsec)	Total RX / Reassembly (μsec)
UDT T1	min: 0	1.7	min:0	0.5 X Max_Lead	min: 1.7 + 2.59 X Max_Lead
	max: 45.8		max: 243.5	X 5.18	max: 291 + 2.59 X Max_Lead
UDT E1	min: 0	1.7	min: 0	0.5 X Max_Lead	min: 1.7 + 1.95 X Max_Lead
	max: 45.8		max: 183.6	X 3.91	max: 231 + 1.95 X Max_Lead
SDT	min: 0	125	min: 0	0.5 X Max_Lead	min: 125 + 62.5 X Max_Lead
	max: 125		max: 125	X 125	max: 375 + 62.5 X Max_Lead
SDT Trunking	min: 0	125	min: 0	0.5 X Max_Lead	min: 125 + 62.5 X Max_Lead
N > 46	max: 125		max: 125	X 125	max: 375 + 62.5 X Max_Lead

TABLE 114. Reassembly Latency

RX UTOPIA Queuing represents the possible delay due to a burst of cells arriving faster than the RX_SAR can process them. In UDT mode, the worst case is 27 cells (one for each of the other TDM ports), and in SDT mode the worst case is always less than 125 microseconds. This is a variable delay.

RX Processing delay is the time required for internal processing and data moves. This is a fixed delay in UDT and SDT mode.

Pointer Offset represents the random time-offset between segmentation operation at one end of link, and reassembly operation at the other end of link. In UDT mode this is some fraction of a cell payload assembly period. In SDT mode this is some fraction of the 125 microsecond TDM frame. This is a static delay, except for wander difference in the segmentation and reassembly TDM clocks.

CDV Buffering is the delay due to the cell-delay-variation buffer, and is controlled by the setting (per-VC) of the internal "Maximum Lead" variable. The delay through the CDV buffer is generally one-half of the limit set by the "Maximum Lead" variable.

Mode	Total Static TX / Segmentation (μsec)	Total Static RX / Reassembly (μsec)	End-to-End Latency (μsec)
UDT T1 - min	245.8	1.7 + 2.59 X Max_Lead	490.9 + CDV + network
max	245.8	245.2 + 2.59 X Max_Lead	734.4 + CDV + network
UDT E1 - min	185.9	1.7 + 1.95 X Max_Lead	371.2 + CDV + network
max	185.9	195.3 + 1.95 X Max_Lead	564.8 + CDV + network
SDT - min	125 + FLOOR[46/N] X 125	125 + 62.5 X Max_Lead	375 + FLOOR[46/N] X 125 + CDV + network
max	125 + CEIL[47/N] X 125	250 + 62.5 X Max_Lead	500 + CEIL[47/N] X 125 + CDV + network
SDT Trunking - min	250	125 + 62.5 X Max_Lead	500 + CDV + network
max	250	250 + 62.5 X Max_Lead	625 + CDV + network

TABLE 115. End-to-End Latency

Since the variable portions of the delay in segmentation and reassembly effectively become part of the CDV that must be compensated for in the CDV buffer, we can omit them from the end-to-end calculation. (Also remembering that the variable delays given in Table 113 and Table 114 are worst-case numbers that will never be experienced by most applications.) The delay variation in SDT mode due to payload size variation and divide-by-N remainders is also part of the CDV compensated for by the CDV buffer, but is left in here to illustrate the effects on delay of the value of N.

The Max_Lead values should be set by the user in accordance with the expected or negotiated CDV, as explained in Section 4.6.1.5.1, "UDT Mode of Operation" and in Section 4.6.1.5.2, "SDT Mode of Operation". These recommended settings are used to evaluate Max_Lead in Table 115. It can be seen that the difference between the minimum and maximum static delay in each mode is due largely to the pointer offset, which, as described earlier, is the random offset between the time of the segmentation operation and the time of the reassembly operation.

The delay values for SDT assume no TDM switching delay. This means that the given delay is for a TDM byte which is driven out at the RX end on the same TDM channel number as it was sampled in at the TX end. For example, if the TDM byte comes into the segmentation end on TDM channel 3, it is driven out at the reassembly end on TDM channel 3.

Reference Documents

Normative Standards

- ITU-T Rec. I.363.1, "B-ISDN ATM Adaptation Layer Specification: Type 1 AAL," Aug. 1996.
- ATM Forum af-vtoa-0078.000, "Circuit Emulation Service Interoperability Specification Version 2.0," Jan. 1997.
- ATM Forum, af-vtoa-0089.001, "ATM Trunking using AAL1 for Narrowband Services Version 1.1," Feb. 2000.
- ITU-T I.361, "B-ISDN ATM Layer Specification," Nov. 1995.
- ITU-T I.362, "B-ISDN ATM Adaptation Layer (AAL) Functional Description," Mar. 1993.
- IEEE Std. 1149.1a-1993, "IEEE Standard Test Access Port and Boundary Scan Architecture."
- ATM Forum af-phy-0017.000, "UTOPIA, An ATM-PHY Interface Specification: Level 1, Version 2.01," Mar. 1994.
- ATM Forum af-phy-0039.000, "Utopia Level 2, Version 1.0," June 1995.
- ITU-T G.823, "The Control of Jitter and Wander within Digital Networks which are based on the 2048 kbit/s Hierarchy," Mar. 1993.
- ITU-T G.824, "The Control of Jitter and Wander within Digital Networks which are based on the 1544 kbit/s Hierarchy," Mar. 1993.
- ANSI T1.102, "Telecommunications Digital Hierarchy Electrical Interfaces," 1993.
- ANSI T1.403, "Telecommunications Network and Customer Installation Interfaces DS1 Electrical Interface Informative Standards and References," 1995.

Informative Standards

- ANSI T1.630 -1993, "Broadband ISDN ATM Adaptation Layer for Constant Bit Rate Services Functionality and Specification," Aug. 1993.
- ETSI Std. ETS 300 353, "B-ISDN; ATM Adaptation Layer (AAL) specification type1," Dec. 1996 (2nd Ed, Draft)
- Telcordia GR-1113-CORE, Issue 1, July, 1994, Asynchronous Transfer Mode (ATM) and ATM Adaptation Layer (AAL) Protocols.
- MSAN-163, "Multitrunk System Synchronizer", Issue 1, Mitel Application Note for the MT9042 PLL, December 1996.
- M. Noorchasm et al., "Buffer Design for Constant Bit Rate Services in Presence of Cell Delay Variation," ATM Forum Contribution 95-1454.
- Paul E. Fleischer and Chi-Leung Lau, "Synchronous Residual Time Stamp for Timing Recovery in a Broadband Network," United States Patent 5,260,978, Nov. 1993.

Note: Telcordia (formerly Bellcore) asserts that its U.S. Patent No. 5,260,978 for Synchronous Residual Timestamp (SRTS) Timing Recovery in a Broadband Network may apply to the ATM Adaptation Layer Type 1 (AAL1) ANSI Standard (T1.630-1993) referenced in Section 3.4 of af-vtoa-0078.000.

Glossary

AAL - *ATM* Adaptation Layer; standardized protocols used to translate higher layer services from multiple applications into the size and format of an ATM cell.

AAL1 - *ATM Adaptation Layer 1*, used for the transport of constant bit rate, time-dependent traffic (e.g., voice, video); requires transfer of timing information between source and destination; maximum of 47-bytes of user data permitted in payload as an additional header byte is required to provide sequencing information.

Asynchronous - 1. Not **synchronous**; not periodic. 2. The temporal property of being sourced from independent timing references. Asynchronous signals have different frequencies, and no fixed phase relationship. 3. In telecom, data which is not synchronized to the public network clock. 4. The condition or state when an entity is unable to determine, prior to its occurrence, exactly when an event will transpire.

ATM - Asynchronous Transfer Mode; a method in which information to be transferred is organized into fixedlength cells; asynchronous in the sense that the recurrence of cells containing information from an individual user is not necessarily periodic. (While ATM cells are transmitted synchronously to maintain clock between sender and receiver, the sender transmits data cells when it has something to send and transmits empty cells when idle, and is not limited to transmitting data every Nth cell.)

CBR - *Constant Bit Rate*; an ATM service category supporting a constant or guaranteed rate, with timing control and strict performance parameters. Used for services such as voice, video, or circuit emulation.

CDV - *Cell Delay Variation*; a **QoS** parameter that measures the peak-to-peak cell delay through the network; results from buffering and cell scheduling.

Cell - fixed-size information package consisting of 53 bytes (octets) of data; of these, 5 bytes represent the cell header and 48 bytes carry the user payload and required overhead. **Note:** If a 16-bit UTOPIA interface is used, each cell is 54 bytes long, composed of 6 bytes of cell header and 48 bytes carrying user payload and required overhead.

CES - *Circuit Emulation Service*; ATM Forum service providing a virtual circuit which emulates the characteristics of a constant bit rate, dedicated-bandwidth circuit (e.g., DS1).

CLP - *Cell Loss Priority*; a 1-bit field in the ATM cell header that corresponds to the loss priority of a cell; cells with CLP = 1 can be discarded in a congestion situation.

CSI - *Convergence Sublayer Indication* bit in the AAL1 header byte; when present in an even-numbered cell using SDT, indicates the presence of a pointer byte; used to transport RTS values in odd-numbered cells using SRTS clock recovery.

GFC - *Generic Flow Control*; 4-bit field in the ATM header used for local functions (not carried end-to-end); when cells are configured for NNI formatting, this value forms the four MSBs of the VPI field.

HEC - *Header Error Control*; using the fifth octet in the ATM cell header, ATM equipment (usually the PHY) may check for an error and correct the contents of the header; CRC algorithm allows for single-error correction and multiple-error detection.

Isochronous - The temporal property of an event or signal recurring at known periodic time intervals (e.g., 125 μ s). Isochronous signals are dependent on some uniform timing, or carry their own timing information embedded as part of the signal. Examples are DS1, E1 and TDM in general. From the root words, "iso" meaning equal, and "chronous" meaning time.

OAM - Operations, Administration and Maintenance; MSB within the PTI field of the ATM cell header which indicates if the ATM cell carries management information such as fault indications.

PHY - *Physical Layer*; bottom layer of the ATM Reference Model; provides ATM cell transmission over the physical interfaces that interconnect the various ATM devices.

Plesiochronous - The temporal property of being arbitrarily close in frequency to some defined precision. Plesiochronous signals occur at nominally the same rate, any variation in rate being constrained within specific limits. Since they are not identical, over the long term they will be skewed from each other. This will force a switch to occasionally repeat or delete data in order to handle buffer underflow or overflow. (In telecommunications, this is known as a frame slip.)

PTI - *Payload Type Identifier*; 3-bit field in the ATM cell header - MSB indicates if the cell contains **OAM** information or user data.

QoS - *Quality of Service*; ATM performance parameters that characterize the transmission quality over a given VCC (e.g., cell delay variation; cell transfer delay, cell loss ratio).

RTS - Residual Time Stamp; see SRTS.

SAR - Segmentation and Reassembly; method of partitioning, at the source, frames into ATM cells and reassembling, at the destination, these cells back into information frames; lower sublayer of the **AAL** which inserts data from the information frames into cells and then adds the required header, trailer, and/or padding bytes to create 48-byte payloads to be transmitted to the ATM layer.

SDT - *Structured Data Transfer*; format used within **AAL1** for blocks consisting of Nx64 kbps channels; blocks are segmented into cells for transfer and additional overhead bytes (pointers) are used to indicate structure boundaries within cells (therefore aiding data recovery).

SN - *Sequence Number*, 4-bit field in the **AAL1** header byte used as a sequence counter for detecting lost or misinserted ATM cells.

SNP - *Sequence Number Protection*; 4-bit field in the **AAL1** header byte consisting of a 3-bit CRC and a parity bit which are designed to provide error-correction on the **SN**.

SRTS - *Synchronous Residual Time Stamp*; method for clock recovery in which difference signals between a source clock and the network reference clock (time stamps) are transmitted to allow reconstruction of the source clock. The destination reconstructs the source clock based on the time stamps and the network reference clock. (Note that the same network reference clock is required at both ends.)

Synchronous - 1. The temporal property of being sourced from the same timing reference. Synchronous signals have the same frequency, and a fixed (often implied to be zero) phase offset. 2. A mode of transmission in which the sending and receiving terminal equipment are operating continually at the same rate and are maintained in a desired phase relationship by an appropriate means.

UDT - *Unstructured Data Transfer*; format used within **AAL1** for transmission of user data without regard for structure boundaries (e.g., circuit emulation).

UTOPIA - Universal Test and Operations Physical Interface for ATM; a **PHY**-level interface to provide connectivity between ATM components.

VC - *Virtual Channel* (also, *Virtual Circuit*); one of several logical connections defined within a virtual path (**VP**) between two ATM devices; provides sequential, unidirectional transport of ATM cells.

VCC - Virtual Circuit Connection; term used to include both VPI and VCI.

VCI - *Virtual Channel Identifier*; 16-bit value in the ATM cell header that provides a unique identifier for the virtual channel (**VC**) within a virtual path (**VP**) that carries a particular cell.

VP - *Virtual Path*; a unidirectional logical connection between two ATM devices; consists of a set of virtual channels (**VC**).

VPI - *Virtual Path Identifier*; 8-bit value (in UNI; 12 bits in NNI) in the ATM cell header that indicates the virtual path (**VP**) to which a cell belongs.

VTOA - *Voice and Telephony over ATM*; intended to provide voice connectivity to the desktop, and to provide interoperability with existing N-ISDN and PBX services.

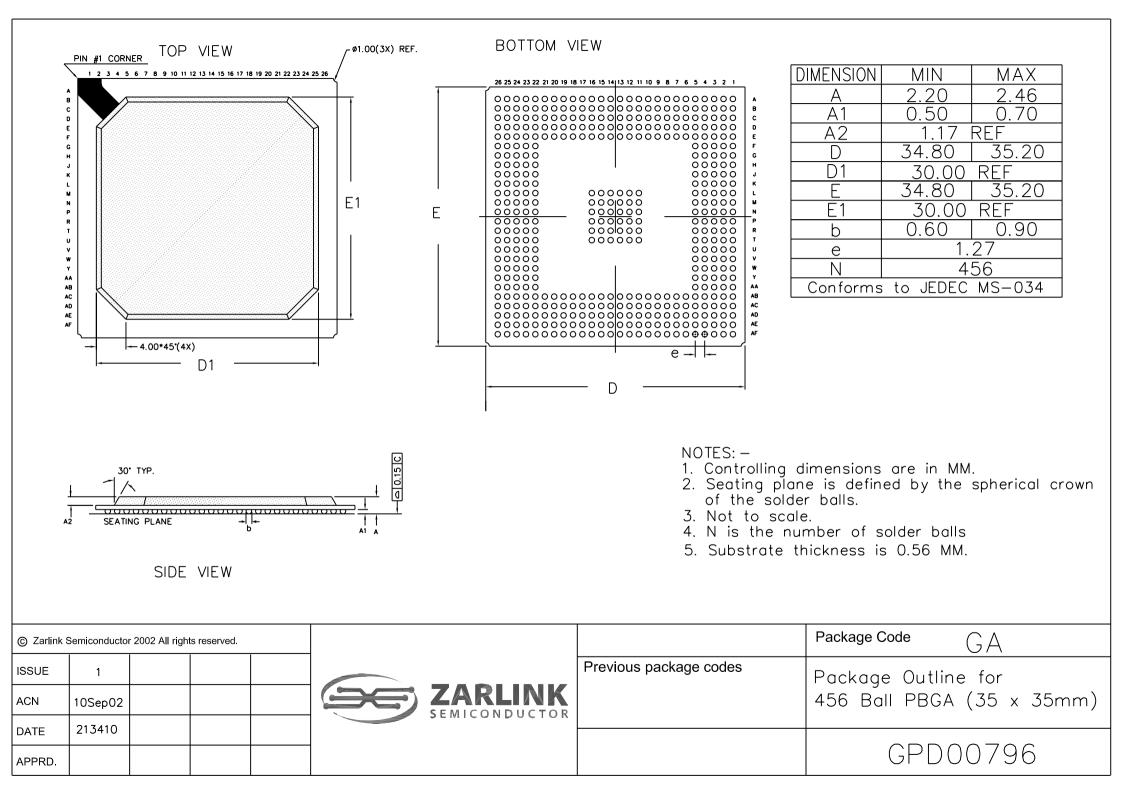
ZBT - *Zero Bus Turnaround;* a type of memory interface which does not require wait states between read and write cycles. ZBT and Zero Bus Turnaround are trademarks held by Integrated Device Technology Inc.

Glossary References:

The ATM Glossary - ATM Year 97 - Version 2.1, March 1997

The ATM Forum Glossary - May 1997

Zarlink Semiconductor Glossary of Telecommunications Terms - May 1995.





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